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The revision list summarizes the locations of revisions and additions. Details should always be checked by referring to the relevant text.

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H8/3827R Group, H8/3827S Group, H8/38327 Group, H8/38427 Group

Hardware Manual

Renesas 8-Bit Single-Chip Microcomputer H8 Family/H8/300L Super Low Power Series H8/3827R Group H8/3822R H8/38327 Group H8/38322 H8/3823R H8/38323 H8/3824R H8/38324 H8/3825R H8/38325 H8/3826R H8/38326 H8/3827R H8/38327 H8/3827S Group H8/3824S H8/38427 Group H8/38422 H8/3825S H8/38423 H8/3826S H8/38424 H8/3827S H8/38425 H8/38426 H8/38427

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Preface

The H8/3827R Group, H8/3827S Group, H8/38327 Group, and H8/38427 Group are high-performance single-chip microcomputers that integrate peripheral functions necessary for system configuration with an H8/300L CPU core.

The on-chip peripheral functions include ROM, RAM, six timers, 14-bit PWM, a serial communication interface (SCI), an A/D converter, LCD controller/driver, and I/O ports, providing an ideal configuration as a microcomputer for embedding in sophisticated control systems. PROM (ZTAT^{TM*1}), flash memory (F-ZTAT^{TM*2}), and mask ROM are available as on-chip ROM, enabling users to respond quickly and flexibly to changing application specifications and the demands of the transition from initial to full-fledged volume production.

- Notes: 1. ZTAT is a trademark of Renesas Technology Corp.
 - 2. F-ZTAT is a trademark of Renesas Technology Corp.

Intended Readershi	p: This manual is intended for users undertaking the design of an application system using the H8/3827R Group, H8/3827S Group, H8/38327 Group, and H8/38427 Group. Readers using this manual require a basic knowledge of electrical circuits, logic circuits, and microcomputers.
Purpose:	The purpose of this manual is to give users an understanding of the hardware functions and electrical characteristics of the H8/3827R Group, H8/3827S Group, H8/38327 Group, and H8/38427 Group. Details of execution instructions can be found in the H8/300L Series Programming Manual, which should be read in conjunction with the present manual.

Using this Manual:

- For an overall understanding of the H8/3827R Group, H8/3827S Group, H8/38327 Group, and H8/38427 Group's functions Follow the Table of Contents. This manual is broadly divided into sections on the CPU, system control functions, peripheral functions, and electrical characteristics.
- For a detailed understanding of CPU functions
 Refer to the separate publication H8/300L Series Programming Manual.
 Note on bit notation: Bits are shown in high-to-low order from left to right.

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Notes: The following limitations apply when using the on-chip emulator for program development and debugging.

- 1. Pin P3₂ is reserved for use exclusively by the on-chip emulator and cannot be used for other operations.
- 2. Pins P8₅, P8₆, and P8₇ cannot be used. In order to use these pins it is necessary to install additional hardware on the user board.
- 3. The address area from H'E000 to H'EFFF is used by the on-chip emulator and therefore cannot be accessed by the user.
- 4. The address area from H'F300 to H'F6FF must not be accessed under any circumstances.
- 5. When the on-chip emulator is used, pin P3₂ functions as an I/O pin, pins P8₅ and P8₆ function as input pins, and pin P8₇ functions as an output pin.
- 6. It is necessary to change the user board for LCD display debugging. This item does not apply if LCD display is not used or if the emulator is not operated in writer mode.

User Board Changes

The following changes are necessary.

- Connect pin V1 to the V_{CC} power supply. Also connect capacitors and resistors to pins V1, V2, and V3. Connect a capacitor and a resistor to pins V1, V2, and V3.
- No SEG signals are output from pins P8₅/SEG30, P8₆/SEG31, and P8₇/SEG32, so the display is unstable. In addition, a DC voltage is applied. If damage to the LCD is a concern, disconnect the above three pins from the LCD.

A connection example is shown below. Refer to the emulator user's manual for information on other settings.



7. During a break, the watchdog timer continues to operate. Therefore, an internal reset is generated if an overflow occurs during the break.

Related Material: The latest information is available at our Web Site. Please make sure that you have the most up-to-date information available. (http://www.renesas.com/)

User's Manuals on this LSI:

Manual Title	Document No.
H8/3827R Group, H8/3827S Group, H8/38327 Group, H8/38427 Group Hardware Manual	This manual
H8/300L Series Programming Manual	REJ09B0214-0200

User's manuals for development tools:

Manual Title	Document No.
C/C++ Compiler, Assembler, Optimizing Linkage Editor User's Manual	REJ10B0161-0100
H8S, H8/300 Series Simulator/Debugger User's Manual	REJ10B0211-0200
High-Performance Embedded Workshop User's Manual	ADE-702-201
H8S, H8/300 Series High-Performance Embedded Workshop, High-Performance Debugging Interface User's Manual	ADE-702-231

Application Note:

Manual Title	Document No.
H8/300L Series Application Note	ADE-502-065

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Main Revisions for this Edition

Item	Page	Revision (See Manual for Details)
All	_	"Under development" indication deleted from H8/38427 Group
Preface	iv	Note 6. (User Board Changes) amended, and note 7. added
		 It is necessary to change the user board for LCD display debugging. This item does not apply if LCD display is not used or if the emulator is not operated in writer mode.
		User Board Changes
		The following changes are necessary.
		 Connect pin V1 to the V_{CC} power supply. Also connect capacitors and resistors to pins V1, V2, and V3. Connect a capacitor and a resistor to pins V1, V2, and V3.
		LCD LCD Dis- connect VC V2 V3 Disconnet P8/SEG30 Disconnet VC P8/SEG31 Vc VC VC VC VC Connect (LV0 VC VC Disconnet VC VC Disconnet VC VC Connect (LV0 VC V2 V3 P8/SEG31 VC VC R=240 0° H8/3827 VC P8/SEG30 P8/SEG31 V2 V3 P8/SEG31 VC V2 P8/SEG32 P8/SEG32 P8/SEG32 V3 P8/SEG32 VC R=V2 VC R=V2 VC P8/SEG32 Connectors
		Normal Operation Debugging
		Note: * R and C values are intended only as guidelines. They may be adjusted based on the indications.
		7. During a break, the watchdog timer continues to operate.
		Therefore, an internal reset is generated if an overflow occurs
		during the break.
1.3.2 Pin Functions	28	Table amended
Table 1.6 Pin Functions		Pin No. FP-80A
FUNCTIONS		Type Symbol TFP-80C FP-80B I/O Name and Functions
		System TEST 8 10 Input Test pin: This pin is reserved and cannot be used. It should be connected to V _{SS} .
8.3.1 Overview	203	Description amended
		Port 3 is a 8-bit I/O port, configured as shown in figure 8.2.
		In the F-ZTAT version, the on-chip pull-up MOS for pin $P3_2$ is on during the reset period. It turns off and normal operation resumes after the reset is cleared. This should be considered when making connections to external circuitry. Note that in the mask ROM and ZTAT versions $P3_2$ continues to operate normally.

ltem	Page	Revision (See Ma	nual for	r Details	5)			
8.3.4 Pin States	211	Table and	notes ar	nended					
Table 8.7 Port 3 Pin		Pins	Reset	Sleep	Subsleep	Standby	Watch	Subactive	Active
States		P3 ₇ /AEVL P3 ₆ /AEVH P3 ₅ /TXD ₃₁ P3 ₄ /RXD ₃₁ P3 ₉ /SCK ₃₁	High- impedance	Retains previous state	Retains previous state	High- impedance ^{*1}	Retains previous state	Functional	Functional
		P3 ₂ /RESO ^{*2}	RESO output	-					
		P32*4	Pull-up MOS on	_					
		P32 ^{*3} P31/UD ^{*2} P31/UD/EXCL ^{*3*4} P30/PWM	High- impedance	_					
		3. Appl	lies to H8/38 lies to the m	27R Group ask ROM ve	and H8/382 ersion of the	• •	roup and H	18/38427 Gr	
8.12.1 The	236	Description	amend	ed					
Management of the Un-Use Terminal		• If an un	used pir	n is an c	output pi	n, handle	e it in o	ne of the	;
			g ways:						
		 Set the output of the unused pin to high and pull it up to Vcc with an external resistor of approximately 100 kΩ. 							
		— Set	the outp	out of th	e unuse	d pin to l or of appi	ow and	pull it d	own to
C.2 Block Diagrams of Port 3	593	Figure title	amende	ed					<u> </u>
Figure C.2 (e-2) Port 3 Block Diagram (Pin P3 ₂ in the Mask ROM Version of the H8/38327 Group and H8/38427 Group)									
Figure C.2 (e-3) Port 3 Block Diagram (Pin P $_2$ in the F-ZTAT Version of the H8/38327 Group and H8/38427 Group)	594	Newly add	ed						

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ltem	Page	Revision (See Manual for Details)
Appendix D Port States in the Different Processing States Table D.1 Port States Overview	608	 Notes amended Notes: 1. High level output when MOS pull-up is in on state. 2. Reset output from P3₂ pin only (H8/3827R Group and H8/3827S Group). On-chip pull-up MOS turns on for pin P3₂ only (F-ZTAT Version of the H8/38327 Group and H8/38427 Group).

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Section 1 Overview

1.1 Overview

The H8/300L Series is a series of single-chip microcomputers (MCU: microcomputer unit), built around the high-speed H8/300L CPU and equipped with peripheral system functions on-chip.

Within the H8/300L Series, the H8/3827R Group, H8/3827S Group, H8/38327 Group, and H8/38427 Group comprise single-chip microcomputers equipped with an LCD (liquid crystal display) controller/driver. Other on-chip peripheral functions include six timers, a 14-bit pulse width modulator (PWM), two serial communication interface channels, and an A/D converter. Together, these functions make the H8/3827R Group, H8/3827S Group, H8/38327 Group, and H8/38427 Group ideally suited for embedded applications in systems requiring low power consumption and LCD display. Also available are models incorporating 16 Kbytes to 60 Kbytes of ROM and 1 Kbyte to 2 Kbytes of RAM on-chip.

The H8/3827R is also available in a ZTAT^{TM*1} version with on-chip PROM which can be programmed as required by the user.

The H8/38327 and H8/38427 are available in a F-ZTAT^{M^{*2}} version with on-chip flash memory that can be programmed on-board.

Table 1.1 summarizes the features of the H8/3827R Group, H8/3827S Group, H8/38327 Group, and H8/38427 Group.

Notes: 1. ZTAT (Zero Turn Around Time) is a trademark of Renesas Technology Corp.

2. F-ZTAT is a trademark of Renesas Technology Corp.

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Table 1.1 Features

Item	Description
CPU	High-speed H8/300L CPU
	General-register architecture
	General registers: Sixteen 8-bit registers (can be used as eight 16-bit registers)
	Operating speed
	 Max. operating speed: 8 MHz
	 — Add/subtract: 0.25 μs (operating at 8 MHz)
	— Multiply/divide: 1.75 μs (operating at 8 MHz)
	 — Can run on 32.768 kHz or 38.4 kHz subclock
	Instruction set compatible with H8/300 CPU
	 Instruction length of 2 bytes or 4 bytes
	 Basic arithmetic operations between registers
	 MOV instruction for data transfer between memory and registers
	Typical instructions
	— Multiply (8 bits \times 8 bits)
	— Divide (16 bits ÷ 8 bits)
	— Bit accumulator
	 Register-indirect designation of bit position
Interrupts	36 interrupt sources
	 13 external interrupt sources (IRQ₄ to IRQ₀, WKP₇ to WKP₀)
	23 internal interrupt sources
Clock pulse generators	Two on-chip clock pulse generators
	System clock pulse generator:
	 — Maximum 16 MHz (H8/3827R, H8/38327, H8/38427 Group)
	— Maximum 10 MHz (H8/3827S Group)
	Subclock pulse generator: 32.768 kHz, 38.4 kHz



Item	Description
Power-down modes	Seven power-down modes
	Sleep (high-speed) mode
	Sleep (medium-speed) mode
	Standby mode
	Watch mode
	Subsleep mode
	Subactive mode
	Active (medium-speed) mode
Memory	Large on-chip memory
	• H8/3822R, H8/38322, H8/38422:
	16-Kbyte ROM, 1-Kbyte RAM
	• H8/3823R, H8/38323, H8/38423:
	24-Kbyte ROM, 1-Kbyte RAM
	 H8/3824R, H8/3824S, H8/38324, H8/38424:
	32-Kbyte ROM, 2-Kbyte RAM
	• H8/3825R, H8/3825S, H8/38325, H8/38425:
	40-Kbyte ROM, 2-Kbyte RAM
	• H8/3826R, H8/3826S, H8/38326, H8/38426:
	48-Kbyte ROM, 2-Kbyte RAM
	• H8/3827R, H8/3827S, H8/38327, H8/38427:
	60-Kbyte ROM, 2-Kbyte RAM
I/O ports	64 pins
	• 55 I/O pins
	9 input pins

Item	Description		
Timers	Six on-chip timers		
	Timer A: 8-bit timer		
	Count-up timer with selection of eight internal clock signals divided from the system clock $\left(\phi\right)^*$ and four clock signals divided from the watch clock $\left(\phi_W\right)^*$		
	Asynchronous event counter: 16-bit timer		
	 Count-up timer able to count asynchronous external events independently of the MCU's internal clocks 		
	Timer C: 8-bit timer		
	 Count-up/down timer with selection of seven internal clock signals or event input from external pin 		
	— Auto-reloading		
	Timer F: 16-bit timer		
	 Can be used as two independent 8-bit timers 		
	 Count-up timer with selection of four internal clock signals or event input from external pin 		
	 Provision for toggle output by means of compare-match function 		
	• Timer G: 8-bit timer		
	 Count-up timer with selection of four internal clock signals 		
	 Incorporates input capture function (built-in noise canceler) 		
	Watchdog timer		
	 Reset signal generated by overflow of 8-bit counter 		
Serial communication	Two serial communication interface channels on chip		
interface	SCI3-1: 8-bit synchronous/asynchronous serial interface		
	Incorporates multiprocessor communication function		
	SCI3-2: 8-bit synchronous/asynchronous serial interface		
	Incorporates multiprocessor communication function		
14-bit PWM	Pulse-division PWM output for reduced ripple		
	 Can be used as a 14-bit D/A converter by connecting to an external low-pass filter. 		
A/D converter	Successive approximations using a resistance ladder		
	8-channel analog input pins		
	• Conversion time: $31/\phi$ or $62/\phi$ per channel		

Description					
LCD controller/driver equipped with a maximum of 32 segment pins and four common pins					
Choice of	four duty cycle	s (static, 1/2, 1	/3, or 1/4)		
 Segment 	pins can be sw	itched to aene	ral-purpose port fu	Inction in 8-	
bit units					
Mask ROM Version	ZTAT Version	F-ZTAT Version	Package	ROM/RAM Size (Byte)	
HD6433827R	HD6473827R	HD64F38327	FP-80B	60 K/2 K	
HD6433827S		HD64F38427	(H8/3827R only)		
HD64338327					
HD64338427					
	_	_		48 K/2 K	
HD64338426					
HD6433825R	_	_		40 K/2 K	
HD6433825S			(H8/3825R only)		
HD64338325			FP-80A		
HD64338425			TFP-80C		
			Die		
HD6433824R	_	HD64F38324	FP-80B	32 K/2 K	
HD6433824S		HD64F38424			
HD64338324					
HD64338424					
HD6433823R			FP-80B	24 K/1 K	
HD64338323			(H8/3823R only)		
HD64338423			FP-80A		
			TFP-80C		
			Die		
HD6433822R	—	—		16 K/1 K	
HD64338322					
HD64338422					
			Die		
	LCD controlle four common Choice of Segment bit units Mask ROM Version HD6433827R HD6433827R HD64338277 HD64338277 HD6433826R HD64338268 HD64338268 HD64338268 HD64338258 HD64338258 HD64338258 HD6433824R HD64338248 HD64338248 HD64338228 HD64338228 HD64338228 HD64338228 HD64338228 HD64338228 HD64338228 HD64338228 HD64338228 HD64338228 HD64338228 HD64338228 HD64338228 HD64338228 HD64338228 HD64338228 HD64338228 HD64338228	LCD controller/driver equipp four common pins Choice of four duty cycle Segment pins can be sw bit units Mask ROM ZTAT Version HD6433827R HD6433827R HD6433827 HD6433826 HD6433826 HD6433826 HD6433826 HD6433825 HD6433825 HD6433825 HD6433824 HD6433824 HD6433824 HD6433822 HD64	LCD controller/driver equipped with a maxi four common pins Choice of four duty cycles (static, 1/2, 1 Segment pins can be switched to gener bit units Mask ROM ZTAT Version F-ZTAT Version HD6433827R HD6473827R HD64F38327 HD6433827S HD6473827R HD64F38327 HD6433827S HD64F38427 HD6433826R — — — HD6433826B — — — HD6433826B — — — HD6433825S HD6433825 HD6433825S HD6433825 HD6433825S HD6433825 HD64338248 — HD64F38324 HD64338248 — HD64F38324 HD64338248 — HD64F38424 HD64338238 — — — HD64338248 — HD64F38424 HD64338238 — — — HD64338238 — — — HD64338248 — HD64F38424 HD64338238 — — — HD64338228 — — —	LCD controller/driver equipped with a maximum of 32 segmer four common pins Choice of four duty cycles (static, 1/2, 1/3, or 1/4) Segment pins can be switched to general-purpose port fubit units Mask ROM Version ZTAT Version F-ZTAT Version Package HD6433827R HD6433827S HD6433827C HD6433827 HD6433827 HD6433827 HD6433827 HD6433827 HD6433827 HD6433827 HD6433826 HD6433826 HD6433826 HD6433826 HD6433826 HD6433826 HD6433825 HD6433825 HD6433825 HD6433825 HD6433825 HD6453824 HD6453824 HD6453824 HD6453824 HD6453824 HD6453824 HD6453824 HD6453824 HD6453824 HD64538224 HD64538224 HD64538224 HD64538228 only) HD64338238 HD64538228 only) HD64338228 only) HD64338238 HD64538228 only) HD64338228 only)	

See appendix E for a list of product codes.

Note: * See section 4, Clock Pulse Generators, for the definition of ϕ and ϕ_W .

1.2 Internal Block Diagram

Figure 1.1(1) shows a block diagram of the H8/3827R Group and H8/3827S Group.

Figure 1.1(2) shows a block diagram of the H8/38327 Group and H8/38427 Group.



Figure 1.1(1) Block Diagram (H8/3827R Group and H8/3827S Group)

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Figure 1.1(2) Block Diagram (H8/38327 Group and H8/38427 Group)

1.3 Pin Arrangement and Functions

1.3.1 Pin Arrangement

The pin arrangements of the H8/3827R Group, H8/3827S Group, H8/38327 Group, and H8/38427 Group are shown in figures 1.2 and 1.3 (figure 1.3 only applies to the H8/3827R Group). The bonding pad location diagram of the H8/3827R Group (mask ROM version) is shown in figure 1.4, and the bonding pad coordinates are given in table 1.2. The bonding pad location diagram of the H8/3827S Group (mask ROM version) is shown in figure 1.5, and the bonding pad coordinates are given in table 1.3. The bonding pad location diagram of the HCD64F38327 and HCD64F38427 is shown in figure 1.6, and the bonding pad coordinates are given in table 1.4. The bonding pad location diagram of the H8/3827 Group (mask ROM version) is shown in figure 1.6, and the bonding pad coordinates are given in table 1.4. The bonding pad location diagram of the H8/38327 Group (mask ROM version) and H8/38427 Group (mask ROM version) is shown in figure 1.7, and the bonding pad coordinates are given in table 1.5.





Figure 1.2 Pin Arrangement (FP-80A, TFP-80C: Top View)

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Figure 1.3 Pin Arrangement (FP-80B: Top View)





Figure 1.4 Bonding Pad Location Diagram of H8/3827R Group (Mask ROM Version) (Top View)

$\begin{array}{c c c c c c c c c c c c c c c c c c c $	(μm) 382 193 694 500 156 10 36 88 16 228 402 576
2 AVss -2866 2 3 X1 -2866 1 4 X2 -2866 1 5 Vss -2866 1 6 OSC2 -2866 8 7 OSC1 -2866 6 8 TEST -2866 2 9 RES -2866 2 9 RES -2866 -2 10 P10/TMOW -2866 -2 11 P11/TMOFL -2866 -2 12 P12/TMOFH -2866 -4 12 P13/TMIG -2866 -4 14 P14/IRQ4/ADTRG -2866 -4 15 P16/IRQ2 -2866 -4 16 P16/IRQ3/TMIF -2866 -4 17 P17/IRQ3/TMIF -2866 -4 18 P30/PWM -2866 -4 20 P32/RESO -2866 -4	193 694 500 156 10 36 88 16 228 402
3 X1 -2866 11 4 X2 -2866 11 5 Vss -2866 1 6 OSC2 -2866 8 7 OSC1 -2866 6 8 TEST -2866 24 9 RES -2866 1 10 P10/TMOW -2866 -2 11 P11/TMOFL -2866 -2 12 P12/TMOFH -2866 -5 13 P13/TMIG -2866 -5 14 P14/IRQ4/ADTRG -2866 -1 15 P15/IRQ2 -2866 -1 16 P16/IRQ2 -2866 -1 17 P17/IRQ3/TMIF -2866 -1 18 P30/PWM -2866 -1 19 P31/UD -2866 -2 20 P32/RESO -2866 -2	694 500 156 10 36 88 16 228 402
4 X_2 -2866 1 5 Vss -2866 1 6 OSC ₂ -2866 8 7 OSC ₁ -2866 6 8 TEST -2866 24 9 RES -2866 24 9 RES -2866 24 10 P1 ₀ /TMOW -2866 -2 11 P1 ₁ /TMOFL -2866 -4 12 P1 ₂ /TMOFH -2866 -5 13 P1 ₃ /TMIG -2866 -5 14 P1 ₄ /IRQ ₄ /ADTRG -2866 -1 15 P1 ₅ /IRQ ₁ /TMIC -2866 -1 16 P1 ₆ /IRQ ₂ -2866 -1 17 P1 ₇ /IRQ ₃ /TMIF -2866 -1 18 P3 ₀ /PWM -2866 -1 19 P3 ₁ /UD -2866 -2 20 P3 ₂ /RESO -2866 -2	500 156 10 36 88 16 228 402
5 Vss -2866 1 6 OSC2 -2866 8 7 OSC1 -2866 63 8 TEST -2866 24 9 RES -2866 1 10 P1 ₀ /TMOW -2866 -2 11 P1 ₀ /TMOFL -2866 -2 12 P1 ₂ /TMOFH -2866 -2 13 P1 ₃ /TMIG -2866 -4 15 P1 ₅ /IRQ ₁ /TMIC -2866 -1 16 P1 ₆ /IRQ ₂ -2866 -1 17 P1 ₇ /IRQ ₃ /TMIF -2866 -1 18 P3 ₀ /PWM -2866 -1 19 P3 ₁ /UD -2866 -2 20 P3 ₂ /RESO -2866 -2	156 10 36 88 16 228 402
6 OSC_2 -2866 8 7 OSC_1 -2866 66 8 TEST -2866 24 9 RES -2866 1 10 P1_0/TMOW -2866 -2 11 P1_0/TMOFL -2866 -2 12 P1_2/TMOFH -2866 -5 13 P1_3/TMIG -2866 -5 14 P1_4/IRQ_4/ADTRG -2866 -1 15 P1_5/IRQ_1/TMIC -2866 -1 16 P1_6/IRQ_2 -2866 -1 17 P1_7/IRQ_3/TMIF -2866 -1 18 P3_0/PWM -2866 -2 20 P3_2/RESO -2866 -2	10 36 88 16 228 402
7 OSC1 -2866 66 8 TEST -2866 24 9 RES -2866 1 10 P10/TMOW -2866 -2 11 P11/TMOFL -2866 -2 12 P12/TMOFH -2866 -5 13 P13/TMIG -2866 -5 14 P14/IRQ4/ADTRG -2866 -1 15 P15/IRQ1/TMIC -2866 -1 16 P16/IRQ2 -2866 -1 18 P30/PWM -2866 -1 19 P31/UD -2866 -2 20 P32/RESO -2866 -2	36 88 16 228 402
8 TEST -2866 24 9 RES -2866 1 10 P1_0/TMOW -2866 -2 11 P1_1/TMOFL -2866 -2 12 P1_2/TMOFH -2866 -5 13 P1_3/TMIG -2866 -5 14 P1_4/IRQ_4/ADTRG -2866 -1 15 P1_5/IRQ_1/TMIC -2866 -1 16 P1_6/IRQ_2 -2866 -1 17 P1_7/IRQ_3/TMIF -2866 -1 18 P3_0/PWM -2866 -2 20 P3_2/RESO -2866 -2	88 16 228 402
9 $\overline{\text{RES}}$ -2866 1 10 P1 ₀ /TMOW -2866 -2 11 P1 ₁ /TMOFL -2866 -4 12 P1 ₂ /TMOFH -2866 -5 13 P1 ₃ /TMIG -2866 -5 14 P1 ₄ /IRQ ₄ /ADTRG -2866 -1 15 P1 ₅ /IRQ ₁ /TMIC -2866 -1 16 P1 ₆ /IRQ ₂ -2866 -1 18 P3 ₀ /PWM -2866 -1 19 P3 ₁ /UD -2866 -2 20 P3 ₂ /RESO -2866 -2	16 228 402
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	228 402
11 $P1_1/TMOFL$ -2866 -4 12 $P1_2/TMOFH$ -2866 -5 13 $P1_3/TMIG$ -2866 -6 14 $P1_4/IRQ_4/ADTRG$ -2866 -1 15 $P1_5/IRQ_1/TMIC$ -2866 -1 16 $P1_6/IRQ_2$ -2866 -1 17 $P1_7/IRQ_3/TMIF$ -2866 -1 18 $P3_0/PWM$ -2866 -1 19 $P3_1/UD$ -2866 -2 20 $P3_2/RESO$ -2866 -2	102
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	
13 P1 ₃ /TMIG -2866 -9 14 P1 ₄ / $\overline{IRQ_4}/ADTRG$ -2866 -1 15 P1 ₅ / $\overline{IRQ_1}/TMIC$ -2866 -1 16 P1 ₆ / $\overline{IRQ_2}$ -2866 -1 17 P1 ₇ / $\overline{IRQ_3}/TMIF$ -2866 -1 18 P3 ₀ /PWM -2866 -1 19 P3 ₁ /UD -2866 -2 20 P3 ₂ / \overline{RESO} -2866 -2	76
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	570
15 $P1_5 / \overline{IRQ}_1 / TMIC$ -2866 -1 16 $P1_6 / \overline{IRQ}_2$ -2866 -1 17 $P1_7 / \overline{IRQ}_3 / TMIF$ -2866 -1 18 $P3_0 / PWM$ -2866 -1 19 $P3_1 / UD$ -2866 -2 20 $P3_2 / \overline{RESO}$ -2866 -2	920
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	094
17 P1 ₇ /IRQ ₃ /TMIF -2866 -1 18 P3 ₀ /PWM -2866 -1 19 P3 ₁ /UD -2866 -2 20 P3 ₂ /RESO -2866 -2	266
18 P3₀/PWM -2866 -1 19 P3₁/UD -2866 -2 20 P3₂/RESO -2866 -2	440
19 P31/UD -2866 -2 20 P32/RESO -2866 -2	785
20 P3 ₂ /RESO -2866 -2	969
	2327
21 P3 ₃ /SCK ₃₁ -2669 -2	2503
	2931
22 P3 ₄ /RXD ₃₁ -2142 -2	2931
23 P3 ₅ /TXD ₃₁ -1971 -2	2931
24 P3 ₆ /AEVH -1798 -2	2931
25 P3 ₇ /AEVL -1624 -2	2931
26 CVcc -1413 -2	
27 Vss -1213 -2	2931
28 V3 -1017 -2	
29 V2 -844 -2	2931

Table 1.2 Bonding Pad Coordinates of H8/3827R Group (Mask ROM Version)

		Coordinates*		
Pad No.	Pad Name	Χ (μm)	Υ (μm)	
30	V1	-672	-2931	
31	V0	-496	-2931	
32	Vcc	-320	-2931	
33	PA ₃ /COM4	-112	-2931	
34	PA ₂ /COM3	76	-2931	
35	PA ₁ /COM2	320	-2931	
36	PA ₀ /COM1	544	-2931	
37	P50/WKP0/SEG1	842	-2931	
38	P5 ₁ /WKP ₁ /SEG ₂	1069	-2931	
39	P5 ₂ /WKP ₂ /SEG ₃	2017	-2931	
40	P5 ₃ /WKP ₃ /SEG ₄	2648	-2931	
41	P5 ₄ /WKP ₄ /SEG ₅	2866	-2484	
42	P5 ₅ /WKP ₅ /SEG ₆	2866	-2296	
43	P5 ₆ /WKP ₆ /SEG ₇	2866	-2061	
44	P57/WKP7/SEG8	2866	-1846	
45	P60/SEG9	2866	-1430	
46	P61/SEG10	2866	-1244	
47	P6 ₂ /SEG ₁₁	2866	-1056	
48	P63/SEG12	2866	-828	
49	P64/SEG13	2866	-452	
50	P6 ₅ /SEG ₁₄	2866	-264	
51	P6 ₆ /SEG ₁₅	2866	-76	
52	P67/SEG16	2866	112	
53	P70/SEG17	2866	528	
54	P7 ₁ /SEG ₁₈	2866	756	
55	P7 ₂ /SEG ₁₉	2866	944	
56	P73/SEG20	2866	1318	
57	P74/SEG21	2866	1506	
58	P75/SEG22	2866	1694	
59	P76/SEG23	2866	2070	
60	P77/SEG24	2866	2367	

		Coordinates*	
Pad No.	Pad Name	Χ (μm)	Υ (μm)
61	P80/SEG25	2866	2931
62	P81/SEG26	2654	2931
63	P82/SEG27	1998	2931
64	P83/SEG28	1803	2931
65	P84/SEG29/M	1585	2931
66	P85/SEG30/DO	1396	2931
67	P86/SEG31/CL2	1209	2931
68	P87/SEG32/CL1	977	2931
69	P40/SCK32	631	2931
70	P41/RXD32	456	2931
71	P4 ₂ /TXD ₃₂	284	2931
72	P4 ₃ /IRQ ₀	109	2931
73	AVcc	-64	2931
74	PB ₀ /AN ₀	-236	2931
75	PB ₁ /AN ₁	-409	2931
76	PB ₂ /AN ₂	-581	2931
77	PB ₃ /AN ₃	-925	2931
78	PB ₄ /AN ₄	-1268	2931
79	PB ₅ /AN ₅	-2048	2931
80	PB ₆ /AN ₆	-2658	2931

Note: * These values show the coordinates of the centers of pads. The accuracy is ±5 μm. The home-point position is the chip's center and the center is located at half the distance between the upper and lower pads and left and right pads.





Figure 1.5 Bonding Pad Location Diagram of H8/38278 Group (Mask ROM Version) (Top View)

		Coordinates*	
Pad No.	Pad Name	Χ (μm)	Υ (μm)
1	PB7/AN7	-1655	1516
2	AVss	-1655	1345
3	X ₁	-1655	999
4	X ₂	-1655	799
5	Vss	-1655	536
6	OSC ₂	-1655	334
7	OSC1	-1655	226
8	TEST	-1655	37
9	RES	-1655	-48
10	P1 ₀ /TMOW	-1655	-223
11	P1 ₁ /TMOFL	-1655	-308
12	P1 ₂ /TMOFH	-1655	-393
13	P1₃/TMIG	-1655	-563
14	P1 ₄ /IRQ ₄ /ADTRG	-1655	-648
15	P1 ₅ /IRQ ₁ /TMIC	-1655	-733
16	P1 ₆ /IRQ ₂	-1655	-818
17	P1 ₇ /IRQ ₃ /TMIF	-1655	-988
18	P3 ₀ /PWM	-1655	-1073
19	P31/UD	-1655	-1243
20	P3 ₂ /RESO	-1655	-1480
21	P3₃/SCK31	-1357	-1605
22	P3₄/RXD31	-1178	-1605
23	P3₅/TXD31	-1093	-1605
24	P3 ₆ /AEVH	-992	-1605
25	P37/AEVL	-906	-1605
26	Vcc	-821	-1605
27	Vss	-736	-1605
28	V3	-651	-1605
29	V2	-566	-1605

Table 1.3 Bonding Pad Coordinates of H8/3827S Group (Mask ROM Version)

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		Coordinates [*]	
Pad No.	Pad Name	Χ (μm)	Υ (μm)
30	V1	-481	-1605
31	V0	-396	-1605
32	Vcc	-310	-1605
33	PA ₃ /COM4	-215	-1605
34	PA ₂ /COM3	-85	-1605
35	PA ₁ /COM2	64	-1605
36	PA ₀ /COM1	197	-1605
37	P50/WKP0/SEG1	421	-1605
38	P5 ₁ /WKP ₁ /SEG ₂	528	-1605
39	P5 ₂ /WKP ₂ /SEG ₃	957	-1605
40	P5 ₃ /WKP ₃ /SEG ₄	1154	-1605
41	P5 ₄ /WKP ₄ /SEG ₅	1655	-1527
42	P5 ₅ /WKP ₅ /SEG ₆	1655	-1294
43	P5 ₆ /WKP ₆ /SEG ₇	1655	-1209
44	P57/WKP7/SEG8	1655	-1117
45	P60/SEG9	1655	-903
46	P61/SEG10	1655	-796
47	P6 ₂ /SEG ₁₁	1655	-689
48	P63/SEG12	1655	-559
49	P6 ₄ /SEG ₁₃	1655	-345
50	P6 ₅ /SEG ₁₄	1655	-237
51	P6 ₆ /SEG ₁₅	1655	-130
52	P67/SEG16	1655	-23
53	P70/SEG17	1655	191
54	P7 ₁ /SEG ₁₈	1655	317
55	P7 ₂ /SEG ₁₉	1655	424
56	P73/SEG20	1655	639
57	P74/SEG21	1655	746
58	P75/SEG22	1655	853
59	P76/SEG23	1655	1067
60	P77/SEG24	1655	1527

		Coordinates [*]	
Pad No.	Pad Name	Χ (μm)	Υ (μm)
61	P80/SEG25	1466	1605
62	P81/SEG26	1230	1605
63	P82/SEG27	1145	1605
64	P83/SEG28	1060	1605
65	P84/SEG29/M	961	1605
66	P85/SEG30/DO	854	1605
67	P86/SEG31/CL2	747	1605
68	P87/SEG32/CL1	640	1605
69	P40/SLK32	524	1605
70	P41/RXD32	439	1605
71	P4 ₂ /TXD ₃₂	354	1605
72	P4 ₃ /IRQ ₀	269	1605
73	AVcc	101	1605
74	PB ₀ /AN ₀	16	1605
75	PB ₁ /AN ₁	-92	1605
76	PB ₂ /AN ₂	-207	1605
77	PB ₃ /AN ₃	-431	1605
78	PB ₄ /AN ₄	-655	1605
79	PB ₅ /AN ₅	-1103	1605
80	PB ₆ /AN ₆	-1290	1605

Note: * These values show the coordinates of the centers of pads. The accuracy is ±5 μm. The home-point position is the chip's center and the center is located at half the distance between the upper and lower pads and left and right pads.





Figure 1.6 Bonding Pad Location Diagram of HCD64F38327 and HCD64F38427 (Top View)

		Coordinates*	*
Pad No.	Pad Name	Χ (μm)	Υ (μm)
1	PB7/AN7	-2056	1943
2	AVss	-2056	1656
3	X ₁	-2056	1570
4	X ₂	-2056	1360
5	Vss	-2056	1158
6	Vss	-2056	1062
7	OSC ₂	-2056	533
8	OSC1	-2056	431
9	TEST	-2056	329
10	RES	-2056	-66
11	P1 ₀ /TMOW	-2056	-244
12	P1 ₁ /TMOFL	-2056	-402
13	P1 ₂ /TMOFH	-2056	-574
14	P1₃/TMIG	-2056	-747
15	P1 ₄ /IRQ ₄ /ADTRG	-2056	-919
16	P1₅/IRQ₁/TMIC	-2056	-1091
17	P1 ₆ /IRQ ₂	-2056	-1263
18	P1 ₇ /IRQ ₃ /TMIF	-2056	-1349
19	P3 ₀ /PWM	-2056	-1521
20	P31/UD/EXCL	-2056	-1607
21	P3 ₂	-2056	-1779
22	P3 ₃ /SCK ₃₁	-1530	-2295
23	P3 ₄ /RXD ₃₁	-1382	-2295
24	P3 ₅ /TXD ₃₁	-1280	-2295
25	P3 ₆ /AEVH	-1178	-2295
26	P37/AEVL	-1076	-2295
27	CVcc	-896	-2295
28	Vss	-710	-2295
29	V3	-584	-2295
30	V2	-483	-2295

Table 1.4Bonding Pad Coordinates of HCD64F38327 and HCD64F38427

		Coordinates*	
Pad No.	Pad Name	Χ (μm)	Υ (μm)
31	V1	-382	-2295
32	V0	-281	-2295
33	Vcc	-145	-2295
34	PA ₃ /COM4	51	-2295
35	PA ₂ /COM3	301	-2295
36	PA ₁ /COM2	441	-2295
37	PA ₀ /COM1	604	-2295
38	P50/WKP0/SEG1	883	-2295
39	P5 ₁ /WKP ₁ /SEG ₂	1022	-2295
40	P5 ₂ /WKP ₂ /SEG ₃	1302	-2295
41	P5 ₃ /WKP ₃ /SEG ₄	1530	-2295
42	P5 ₄ /WKP ₄ /SEG ₅	2056	-1955
43	P55/WKP5/SEG6	2056	-1830
44	P5 ₆ /WKP ₆ /SEG ₇	2056	-1651
45	P57/WKP7/SEG8	2056	-1481
46	P60/SEG9	2056	-1111
47	P61/SEG10	2056	-879
48	P6 ₂ /SEG ₁₁	2056	-671
49	P63/SEG12	2056	-505
50	P64/SEG13	2056	-255
51	P65/SEG14	2056	-130
52	P6 ₆ /SEG ₁₅	2056	-6
53	P67/SEG16	2056	119
54	P70/SEG17	2056	457
55	P71/SEG18	2056	660
56	P7 ₂ /SEG ₁₉	2056	784
57	P73/SEG20	2056	1034
58	P7 ₄ /SEG ₂₁	2056	1159
59	P75/SEG22	2056	1378
60	P76/SEG23	2056	1627
61	P77/SEG24	2056	1840

		Coordinates*	k
Pad No.	Pad Name	Χ (μm)	Υ (μm)
62	P80/SEG25	1777	2295
63	P81/SEG26	1530	2295
64	P82/SEG27	1302	2295
65	P83/SEG28	1147	2295
66	P84/SEG29	1022	2295
67	P85/SEG30	901	2295
68	P86/SEG31	728	2295
69	P87/SEG32	603	2295
70	P40/SCK32	451	2295
71	P41/RXD32	350	2295
72	P4 ₂ /TXD ₃₂	175	2295
73	P4 ₃ /IRQ ₀	73	2295
74	AVcc	-155	2295
75	PB ₀ /AN ₀	-290	2295
76	PB ₁ /AN ₁	-440	2295
77	PB ₂ /AN ₂	-695	2295
78	PB ₃ /AN ₃	-801	2295
79	PB ₄ /AN ₄	-996	2295
80	PB ₅ /AN ₅	-1419	2295
81	PB ₆ /AN ₆	-1530	2295

Note: * These values show the coordinates of the centers of pads. The accuracy is ±5 μm. The home-point position is the chip's center and the center is located at half the distance between the upper and lower pads and left and right pads. Pad numbers 5, 6, and 28 are power supply (Vss) pads and must be connected. They should not be left open. Pad number 9 (TEST) must be connected to the Vss position. The device will not operate properly if the pads are not connected as indicated.





Figure 1.7 Bonding Pad Location Diagram of H8/38327 Group (Mask ROM Version) and H8/38427 Group (Mask ROM Version) (Top View)

Table 1.5Bonding Pad Coordinates of H8/38327 Group (Mask ROM Version) and
H8/38427 Group (Mask ROM Version)

		Coordinates*				
Pad No.	Pad Name	Χ (μm)	Υ (μm)			
1	PB7/AN7	-1605	1227			
2	AVss	-1605	1057			
3	X ₁	-1605	941			
4	X ₂	-1605	843			
5	Vss	-1605	619			
6	OSC ₂	-1605	503			
7	OSC ₁	-1605	405			
8	TEST	-1605	299			
9	RES	-1605	201			
10	P1 ₀ /TMOW	-1605	-185			
11	P1 ₁ /TMOFL	-1605	-283			
12	P1 ₂ /TMOFH	-1605	-382			
13	P1 ₃ /TMIG	-1605	-480			
14	P14/IRQ4/ADTRG	-1605	-578			
15	P1 ₅ /IRQ ₁ /TMIC	-1605	-676			
16	P1 ₆ /IRQ ₂	-1605	-775			
17	P1 ₇ /IRQ ₃ /TMIF	-1605	-873			
18	P3 ₀ /PWM	-1605	-971			
19	P31/UD/EXCL	-1605	-1070			
20	P3 ₂	-1605	-1168			
21	P33/SCK31	-1262	-1577			
22	P34/RXD31	-1164	-1577			
23	P3 ₅ /TXD ₃₁	-1066	-1577			
24	P3 ₆ /AEVH	-967	-1577			
25	P37/AEVL	-869	-1577			
26	CVcc	-704	-1577			
27	Vss	-518	-1577			
28	V3	-368	-1577			
29	V2	-276	-1577			
30	V1	-184	-1577			

		Coordinates*				
Pad No.	Pad Name	Χ (μm)	Υ (μm)			
31	V0	-67	-1577			
32	Vcc	109	-1577			
33	PA ₃ /COM4	237	-1577			
34	PA ₂ /COM3	361	-1577			
35	PA ₁ /COM2	486	-1577			
36	PA ₀ /COM1	611	-1577			
37	P50/WKP0/SEG1	767	-1577			
38	P51/WKP1/SEG2	892	-1577			
39	P5 ₂ /WKP ₂ /SEG ₃	1017	-1577			
40	P5 ₃ /WKP ₃ /SEG ₄	1141	-1577			
41	P5 ₄ /WKP ₄ /SEG ₅	1605	-1224			
42	P5 ₅ /WKP ₅ /SEG ₆	1605	-1100			
43	P5 ₆ /WKP ₆ /SEG ₇	1605	-975			
44	P57/WKP7/SEG8	1605	-850			
45	P60/SEG9	1605	-723			
46	P61/SEG10	1605	-598			
47	P6 ₂ /SEG ₁₁	1605	-473			
48	P63/SEG12	1605	-349			
49	P6 ₄ /SEG ₁₃	1605	-195			
50	P65/SEG14	1605	-70			
51	P6 ₆ /SEG ₁₅	1605	55			
52	P67/SEG16	1605	179			
53	P70/SEG17	1605	336			
54	P71/SEG18	1605	460			
55	P7 ₂ /SEG ₁₉	1605	585			
56	P73/SEG20	1605	710			
57	P7 ₄ /SEG ₂₁	1605	835			
58	P75/SEG22	1605	959			
59	P76/SEG23	1605	1084			
60	P77/SEG24	1605	1209			
61	P80/SEG25	1130	1577			

		Coordinates*	k
Pad No.	Pad Name	Χ (μm)	Υ (μm)
62	P81/SEG26	1006	1577
63	P82/SEG27	881	1577
64	P83/SEG28	756	1577
65	P84/SEG29	631	1577
66	P85/SEG30	507	1577
67	P86/SEG31	382	1577
68	P87/SEG32	257	1577
69	P40/SCK32	-4	1577
70	P4 ₁ /RXD ₃₂	-97	1577
71	P4 ₂ /TXD ₃₂	-196	1577
72	P4 ₃ /IRQ ₀	-294	1577
73	AVcc	-470	1577
74	PB ₀ /AN ₀	-598	1577
75	PB ₁ /AN ₁	-704	1577
76	PB ₂ /AN ₂	-810	1577
77	PB ₃ /AN ₃	-916	1577
78	PB ₄ /AN ₄	-1022	1577
79	PB ₅ /AN ₅	-1128	1577
80	PB ₆ /AN ₆	-1233	1577

Note: * These values show the coordinates of the centers of pads. The accuracy is ±5 µm. The home-point position is the chip's center and the center is located at half the distance between the upper and lower pads and left and right pads. Pad numbers 2, 5, and 27 are power supply (V_{SS}) pads and must be connected. They should not be left open. Pad number 8 (TEST) must be connected to the Vss position. The device will not operate properly if the pads are not connected as indicated.



1.3.2 Pin Functions

Table 1.6 outlines the pin functions of this LSI.

Table 1.6Pin Functions

		Pin No.				
Туре	Symbol	FP-80A TFP-80C	FP-80B	I/O	Name and Functions	
Power source pins	V _{CC} CV _{CC}	32 26	34 28	Input	Power supply: All V_{CC} pins should be connected to the system power supply. See section 14, Power Supply Circuit, for a CV_{CC} pin (V_{CC} pin in the H8/3827S Group).	
	V _{SS}	5 27	7 29	Input	Ground: All V _{SS} pins should be connected to the system power supply (0 V).	
	AV _{CC}	73	75	Input	Analog power supply: This is the power supply pin for the A/D converter. When the A/D converter is not used, connect this pin to the system power supply.	
	AV _{SS}	2	4	Input	Analog ground: This is the A/D converter ground pin. It should be connected to the system power supply (0V).	
	V ₀	31	33	Output		
	V ₁ V ₂ V ₃	30 29 28	32 31 30	Input	[–] power supply pins for the LCD controller/driver. They incorporate a power supply split-resistance, and are normally used with V_0 and V_1 shorted.	

		Pir	n No.		
Туре	Symbol	FP-80A TFP-80C	FP-80B	 I/O	Name and Functions
Clock pins	OSC ₁	7	9	Input	These pins connect to a crystal or
	OSC ₂	6	8	Output	 ceramic oscillator, or can be used to input an external clock. See section 4, Clock Pulse Generators, for a typical connection diagram.
	X ₁	3	5	Input	These pins connect to a 32.768-kHz or
	X ₂	4	6	Output	⁻ 38.4-kHz crystal oscillator. See section 4, Clock Pulse Generators, for a typical connection diagram.
	EXCL	19	_	Input	This pin connects to a 32.768-kHz or 38.4-kHz external clock. See section 4, Clock Pulse Generators, for typical connection diagram. This function is only available on the H8/38327 Group and H8/38427 Group.
System control	RES	9	11	Input	Reset: When this pin is driven low, the chip is reset
	RESO	20	22	Output	Reset output: Outputs the CPU internal reset signal. This function is not implemented in the H8/38327 Group and H8/38427 Group.
	TEST	8	10	Input	Test pin: This pin is reserved and cannot be used. It should be connected to V_{SS} .
Interrupt pins	\overline{IRQ}_{0} \overline{IRQ}_{1} \overline{IRQ}_{2} \overline{IRQ}_{3} \overline{IRQ}_{4}	72 15 16 17 14	74 17 18 19 16	Input	IRQ interrupt request 0 to 4: These are input pins for edge-sensitive external interrupts, with a selection of rising or falling edge
	\overline{WKP}_7 to \overline{WKP}_0	44 to 37	46 to 39	Input	Wakeup interrupt request 0 to 7: These are input pins for rising or falling- edge-sensitive external interrupts.
Timer pins	TMOW	10	12	Output	Clock output: This is an output pin for waveforms generated by the timer A output circuit.
	AEVL AEVH	25 24	27 26	Input	Asynchronous event counter event input: This is an event input pin for input to the asynchronous event counter.

		Pin No.				
Туре	Symbol	FP-80A TFP-80C	FP-80B	I/O	Name and Functions	
Timer pins	TMIC	15	17	Input	Timer C event input: This is an event input pin for input to the timer C counter.	
	UD	19	21	Input	Timer C up/down select: This pin selects up- or down-counting for the timer C counter. The counter operates as a down-counter when this pin is high, and as an up-counter when low.	
	TMIF	17	19	Input	Timer F event input: This is an event input pin for input to the timer F counter.	
	TMOFL	11	13	Output	Timer FL output: This is an output pin for waveforms generated by the timer FL output compare function.	
	TMOFH	12	14	Output	Timer FH output: This is an output pin for waveforms generated by the timer FH output compare function.	
	TMIG	13	15	Input	Timer G capture input: This is an input pin for timer G input capture.	
14-bit PWM pin	PWM	18	20	Output	14-bit PWM output: This is an output pin for waveforms generated by the 14-bit PWM	
I/O ports	PB ₇ to PB ₀	1, 80 to 74	3 to 1, 80 to 76	Input	Port B: This is an 8-bit input port.	
	P43	72	74	Input	Port 4 (bit 3): This is a 1-bit input port.	
	P4 ₂ to P4 ₀	71 to 69	73 to 71	I/O	Port 4 (bits 2 to 0): This is a 3-bit I/O port. Input or output can be designated for each bit by means of port control register 4 (PCR4).	
	PA ₃ to PA ₀	33 to 36	35 to 38	I/O	Port A: This is a 4-bit I/O port. Input or output can be designated for each bit by means of port control register A (PCRA).	
	P17 to P10	17 to 10	19 to 12	I/O	Port 1: This is an 8-bit I/O port. Input or output can be designated for each bit by means of port control register 1 (PCR1).	

	Pin No.				
Туре	Symbol	FP-80A TFP-80C	FP-80B	 I/O	Name and Functions
I/O ports	P37 to P30	25 to 18	27 to 20	Ι/Ο	Port 3: This is an 8-bit I/O port. Input or output can be designated for each bit by means of port control register 3 (PCR3). When the on-chip emulator is used, pin P3 ₂ is reserved for use exclusively by the emulator and therefore cannot be accessed by the user. With the F-ZTAT version, pull up pin P3 ₂ to high level to cancel a reset in the in the user mode.
	$P5_7$ to $P5_0$	44 to 37	46 to 39	I/O	Port 5: This is an 8-bit I/O port. Input or output can be designated for each bit by means of port control register 5 (PCR5).
	P67 to P60	52 to 45	54 to 47	I/O	Port 6: This is an 8-bit I/O port. Input or output can be designated for each bit by means of port control register 6 (PCR6).
	P77 to P70	60 to 53	62 to 55	I/O	Port 7: This is an 8-bit I/O port. Input or output can be designated for each bit by means of port control register 7 (PCR7).
	P87 to P80	68 to 61	70 to 63	I/O	Port 8: This is an 8-bit I/O port. Input or output can be designated for each bit by means of port control register 8 (PCR8). When the on-chip emulator is used, pins P8 ₅ , P8 ₆ , and P8 ₇ are reserved for use exclusively by the emulator and therefore cannot be accessed by the user.
Serial communi-	RXD ₃₁	22	24	Input	SCI3-1 receive data input: This is the SCI31 data input pin.
cation interface (SCI)	TXD ₃₁	23	25	Output	SCI3-1 transmit data output: This is the SCI31 data output pin.
	SCK ₃₁	21	23	I/O	SCI3-1 clock I/O: This is the SCI31 clock I/O pin.
	RXD ₃₂	70	72	Input	SCI3-2 receive data input: This is the SCI32 data input pin.
	TXD ₃₂	71	73	Output	SCI3-2 transmit data output: This is the SCI32 data output pin.
	SCK ₃₂	69	71	I/O	SCI3-2 clock I/O: This is the SCI32 clock I/O pin.

Section 1 Overview

		Pir	No.		
Туре	Symbol	FP-80A TFP-80C	FP-80B	I/O	Name and Functions
A/D converter	AN7 to An0	1 80 to 74	3 to 1 80 to 76	Input	Analog input channels 7 to 0: These are analog data input channels to the A/D converter
	ADTRG	14	16	Input	A/D converter trigger input: This is the external trigger input pin to the A/D converter
LCD controller/	COM ₄ to COM ₁	33 to 36	35 to 38	Output	LCD common output: These are the LCD common output pins.
driver	SEG ₃₂ to SEG ₁	68 to 37	70 to 39	Output	LCD segment output: These are the LCD segment output pins.
	CL ₁	68	70	Output	LCD latch clock: This is the output pin for the segment external expansion display data latch clock. This function is not implemented in the H8/38327 Group and H8/38427 Group.
	CL ₂	67	69	Output	LCD shift clock: This is the output pin for the segment external expansion display data shift clock. This function is not implemented in the H8/38327 Group and H8/38427 Group.
	DO	66	68	Output	LCD serial data output: This is the output pin for segment external expansion serial display data. This function is not implemented in the H8/38327 Group and H8/38427 Group.
	Μ	65	67	Output	LCD alternation signal: This is the output pin for the segment external expansion LCD alternation signal. This function is not implemented in the H8/38327 Group and H8/38427 Group.



Section 2 CPU

2.1 Overview

The H8/300L CPU has sixteen 8-bit general registers, which can also be paired as eight 16-bit registers. Its concise instruction set is designed for high-speed operation.

2.1.1 Features

Features of the H8/300L CPU are listed below.

- General-register architecture Sixteen 8-bit general registers, also usable as eight 16-bit general registers
- Instruction set with 55 basic instructions, including:
 - Multiply and divide instructions
 - Powerful bit-manipulation instructions
- Eight addressing modes
 - Register direct
 - Register indirect
 - Register indirect with displacement
 - Register indirect with post-increment or pre-decrement
 - Absolute address
 - Immediate
 - Program-counter relative
 - Memory indirect
- 64-Kbyte address space
- High-speed operation
 - All frequently used instructions are executed in two to four states
 - High-speed arithmetic and logic operations
 - 8- or 16-bit register-register add or subtract: 0.25 μs^*
 - 8×8 -bit multiply: 1.75 μs^*
 - $16 \div 8$ -bit divide: $1.75 \ \mu s^*$

Note: * These values are at $\phi = 8$ MHz.

Low-power operation modes

SLEEP instruction for transfer to low-power operation

Renesas

2.1.2 Address Space

The H8/300L CPU supports an address space of up to 64 Kbytes for storing program code and data.

See section 2.8, Memory Map, for details of the memory map.

2.1.3 Register Configuration

Figure 2.1 shows the register structure of the H8/300L CPU. There are two groups of registers: the general registers and control registers.





2.2 Register Descriptions

2.2.1 General Registers

All the general registers can be used as both data registers and address registers.

When used as data registers, they can be accessed as 16-bit registers (R0 to R7), or the high bytes (R0H to R7H) and low bytes (R0L to R7L) can be accessed separately as 8-bit registers.

When used as address registers, the general registers are accessed as 16-bit registers (R0 to R7).

R7 also functions as the stack pointer (SP), used implicitly by hardware in exception processing and subroutine calls. When it functions as the stack pointer, as indicated in figure 2.2, SP (R7) points to the top of the stack.



Figure 2.2 Stack Pointer

2.2.2 Control Registers

The CPU control registers include a 16-bit program counter (PC) and an 8-bit condition code register (CCR).

Program Counter (PC)

This 16-bit register indicates the address of the next instruction the CPU will execute. All instructions are fetched 16 bits (1 word) at a time, so the least significant bit of the PC is ignored (always regarded as 0).

Renesas

Condition Code Register (CCR)

This 8-bit register contains internal status information, including the interrupt mask bit (I) and half-carry (H), negative (N), zero (Z), overflow (V), and carry (C) flags. These bits can be read and written by software (using the LDC, STC, ANDC, ORC, and XORC instructions). The N, Z, V, and C flags are used as branching conditions for conditional branching (Bcc) instructions.

Bit 7—Interrupt Mask Bit (I): When this bit is set to 1, interrupts are masked. This bit is set to 1 automatically at the start of exception handling. The interrupt mask bit may be read and written by software. For further details, see section 3.3, Interrupts.

Bit 6—User Bit (U): Can be used freely by the user.

Bit 5—Half-Carry Flag (H): When the ADD.B, ADDX.B, SUB.B, SUBX.B, CMP.B, or NEG.B instruction is executed, this flag is set to 1 if there is a carry or borrow at bit 3, and is cleared to 0 otherwise.

The H flag is used implicitly by the DAA and DAS instructions.

When the ADD.W, SUB.W, or CMP.W instruction is executed, the H flag is set to 1 if there is a carry or borrow at bit 11, and is cleared to 0 otherwise.

Bit 4—User Bit (U): Can be used freely by the user.

Bit 3—Negative Flag (N): Indicates the most significant bit (sign bit) of the result of an instruction.

Bit 2—Zero Flag (Z): Set to 1 to indicate a zero result, and cleared to 0 to indicate a non-zero result.

Bit 1—Overflow Flag (V): Set to 1 when an arithmetic overflow occurs, and cleared to 0 at other times.

Bit 0—Carry Flag (C): Set to 1 when a carry occurs, and cleared to 0 otherwise. Used by:

- Add instructions, to indicate a carry
- Subtract instructions, to indicate a borrow
- Shift and rotate instructions, to store the value shifted out of the end bit

The carry flag is also used as a bit accumulator by bit manipulation instructions.

Some instructions leave some or all of the flag bits unchanged.


Refer to the H8/300L Series Programming Manual for the action of each instruction on the flag bits.

2.2.3 Initial Register Values

When the CPU is reset, the program counter (PC) is initialized to the value stored at address H'0000 in the vector table, and the I bit in the CCR is set to 1. The other CCR bits and the general registers are not initialized. In particular, the stack pointer (R7) is not initialized. The stack pointer should be initialized by software, by the first instruction executed after a reset.

2.3 Data Formats

The H8/300L CPU can process 1-bit data, 4-bit (BCD) data, 8-bit (byte) data, and 16-bit (word) data.

- Bit manipulation instructions operate on 1-bit data specified as bit n in a byte operand (n = 0, 1, 2, ..., 7).
- All arithmetic and logic instructions except ADDS and SUBS can operate on byte data.
- The MOV.W, ADD.W, SUB.W, CMP.W, ADDS, SUBS, MULXU (8 bits × 8 bits), and DIVXU (16 bits ÷ 8 bits) instructions operate on word data.
- The DAA and DAS instructions perform decimal arithmetic adjustments on byte data in packed BCD form. Each nibble of the byte is treated as a decimal digit.

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2.3.1 Data Formats in General Registers

Data of all the sizes above can be stored in general registers as shown in figure 2.3.

Data Type F	Register	· No.						D	ata F	orm	at						
		7							0								
1-bit data	RnH	7	6	5	4	3	2	1	0	[Don'i	t care)		
										1							
										7							0
1-bit data	RnL	-			Don'	t care				7	6	5	4	3	2	1	0
		7							0								
Byte data	RnH	MSB				· ·			LSB	[Don'i	t care)		
										7							0
Byte data	RnL				Don'	t care				MSB	1		1	1		1	LSB
		15															0
Word data	Rn	MSB	1	1	1					1	1		1	1		1	LSB
		7			4	3			0								
4-bit BCD data	RnH		Uppe	er digit	1		Lowe	r digit					Don'	t care)		
										7			4	3			0
4-bit BCD data	RnL				Don'	t care					Uppe	r digit			Lowe	er digit	
Legend:				_													
RnH: Upper byte RnL: Lower byte	of gene	ral reg ral reg	gister gister														
MSB: Most signifi	icant bit																
LSB: Least signit	ficant bit	t															

Figure 2.3 Register Data Formats

2.3.2 Memory Data Formats

Figure 2.4 indicates the data formats in memory. The H8/300L CPU can access word data stored in memory (MOV.W instruction), but the word data must always begin at an even address. If word data starting at an odd address is accessed, the least significant bit of the address is regarded as 0, and the word data starting at the preceding address is accessed. The same applies to instruction codes.

Data Type	Address			Da	ata F	orm	at		
		7							0
1-bit data	Address n	7	6	5	4	3	2	1	0
Byte data	Address n	MSB		I	1	1	I	1	LSB
Word data	Even address	MSB			Jpper	8 bits	S	ı I	r
Word data	Odd address				ower	8 bit	S	1	LSB
Byte data (CCR) on stack	Even address	MSB		ı		CR	ı	ı	LSB
	Odd address	MSB		ı	CC	R*	ı	I	LSB
Word data on stack	Even address	MSB		1	1	1	1	1	r
	Odd address			I	I		I	I	LSB
CCR: Condition code regis	ter								
Note: * Ignored on return									

Figure 2.4 Memory Data Formats

When the stack is accessed using R7 as an address register, word access should always be performed. When the CCR is pushed on the stack, two identical copies of the CCR are pushed to make a complete word. When they are restored, the lower byte is ignored.

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2.4 Addressing Modes

2.4.1 Addressing Modes

The H8/300L CPU supports the eight addressing modes listed in table 2.1. Each instruction uses a subset of these addressing modes.

Table 2.1Addressing Modes

No.	Address Modes	Symbol
1	Register direct	Rn
2	Register indirect	@Rn
3	Register indirect with displacement	@(d:16, Rn)
4	Register indirect with post-increment Register indirect with pre-decrement	@Rn+ @-Rn
5	Absolute address	@aa:8 or @aa:16
6	Immediate	#xx:8 or #xx:16
7	Program-counter relative	@(d:8, PC)
8	Memory indirect	@@aa:8

1. **Register Direct—Rn:** The register field of the instruction specifies an 8- or 16-bit general register containing the operand.

Only the MOV.W, ADD.W, SUB.W, CMP.W, ADDS, SUBS, MULXU (8 bits \times 8 bits), and DIVXU (16 bits \div 8 bits) instructions have 16-bit operands.

- 2. Register Indirect—@Rn: The register field of the instruction specifies a 16-bit general register containing the address of the operand in memory.
- 3. Register Indirect with Displacement—@(d:16, Rn): The instruction has a second word (bytes 3 and 4) containing a displacement which is added to the contents of the specified general register to obtain the operand address in memory.

This mode is used only in MOV instructions. For the MOV.W instruction, the resulting address must be even.



4. Register Indirect with Post-Increment or Pre-Decrement—@Rn+ or @-Rn:

- Register indirect with post-increment-@Rn+

The @Rn+ mode is used with MOV instructions that load registers from memory.

The register field of the instruction specifies a 16-bit general register containing the address of the operand. After the operand is accessed, the register is incremented by 1 for MOV.B or 2 for MOV.W. For MOV.W, the original contents of the 16-bit general register must be even.

- Register indirect with pre-decrement-@-Rn

The @–Rn mode is used with MOV instructions that store register contents to memory. The register field of the instruction specifies a 16-bit general register which is decremented by 1 or 2 to obtain the address of the operand in memory. The register retains the decremented value. The size of the decrement is 1 for MOV.B or 2 for MOV.W. For MOV.W, the original contents of the register must be even.

5. Absolute Address—@aa:8 or @aa:16: The instruction specifies the absolute address of the operand in memory.

The absolute address may be 8 bits long (@aa:8) or 16 bits long (@aa:16). The MOV.B and bit manipulation instructions can use 8-bit absolute addresses. The MOV.B, MOV.W, JMP, and JSR instructions can use 16-bit absolute addresses.

For an 8-bit absolute address, the upper 8 bits are assumed to be 1 (H'FF). The address range is H'FF00 to H'FFFF (65280 to 65535).

6. Immediate #xx:8 or #xx:16: The instruction contains an 8-bit operand (#xx:8) in its second byte, or a 16-bit operand (#xx:16) in its third and fourth bytes. Only MOV.W instructions can contain 16-bit immediate values.

The ADDS and SUBS instructions implicitly contain the value 1 or 2 as immediate data. Some bit manipulation instructions contain 3-bit immediate data in the second or fourth byte of the instruction, specifying a bit number.

- 7. Program-Counter Relative—@(d:8, PC): This mode is used in the Bcc and BSR instructions. An 8-bit displacement in byte 2 of the instruction code is sign-extended to 16 bits and added to the program counter contents to generate a branch destination address. The possible branching range is -126 to +128 bytes (-63 to +64 words) from the current address. The displacement should be an even number.
- 8. Memory Indirect—@@aa:8: This mode can be used by the JMP and JSR instructions. The second byte of the instruction code specifies an 8-bit absolute address. The word located at this address contains the branch destination address.

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The upper 8 bits of the absolute address are assumed to be 0 (H'00), so the address range is from H'0000 to H'00FF (0 to 255). Note that with the H8/300L Series, the lower end of the address area is also used as a vector area. See section 3.3, Interrupts, for details on the vector area.

If an odd address is specified as a branch destination or as the operand address of a MOV.W instruction, the least significant bit is regarded as 0, causing word access to be performed at the address preceding the specified address. See section 2.3.2, Memory Data Formats, for further information.

2.4.2 Effective Address Calculation

Table 2.2 shows how effective addresses are calculated in each of the addressing modes.

Arithmetic and logic instructions use register direct addressing (1). The ADD.B, ADDX, SUBX, CMP.B, AND, OR, and XOR instructions can also use immediate addressing (6).

Data transfer instructions can use all addressing modes except program-counter relative (7) and memory indirect (8).

Bit manipulation instructions can use register direct (1), register indirect (2), or 8-bit absolute addressing (5) to specify the operand. Register indirect (1) (BSET, BCLR, BNOT, and BTST instructions) or 3-bit immediate addressing (6) can be used independently to specify a bit position in the operand.







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2.5 Instruction Set

The H8/300L Series can use a total of 55 instructions, which are grouped by function in table 2.3.

Table 2.3Instruction Set

Function	Instructions	Number
Data transfer	MOV, PUSH ^{*1} , POP ^{*1}	1
Arithmetic operations	ADD, SUB, ADDX, SUBX, INC, DEC, ADDS, SUBS, DAA, DAS, MULXU, DIVXU, CMP, NEG	14
Logic operations	AND, OR, XOR, NOT	4
Shift	SHAL, SHAR, SHLL, SHLR, ROTL, ROTR, ROTXL, ROTXR	8
Bit manipulation	BSET, BCLR, BNOT, BTST, BAND, BIAND, BOR, BIOR, BXOR, BIXOR, BLD, BILD, BST, BIST	14
Branch	Bcc ^{*2} , JMP, BSR, JSR, RTS	5
System control	RTE, SLEEP, LDC, STC, ANDC, ORC, XORC, NOP	8
Block data transfer	EEPMOV	1
		Total: 55

Notes: 1. PUSH Rn is equivalent to MOV.W Rn, @–SP. POP Rn is equivalent to MOV.W @SP+, Rn. The same applies to the machine language.

2. Bcc is a conditional branch instruction in which cc represents a condition code.

The following sections give a concise summary of the instructions in each category, and indicate the bit patterns of their object code. The notation used is defined next.



Notation

Rd	General register (destination)
Rs	General register (source)
Rn	General register
(EAd), <ead></ead>	Destination operand
(EAs), <eas></eas>	Source operand
CCR	Condition code register
Ν	N (negative) flag of CCR
Z	Z (zero) flag of CCR
V	V (overflow) flag of CCR
С	C (carry) flag of CCR
PC	Program counter
SP	Stack pointer
#IMM	Immediate data
disp	Displacement
+	Addition
-	Subtraction
×	Multiplication
÷	Division
^	AND logical
V	OR logical
\oplus	Exclusive OR logical
\rightarrow	Move
~	Logical negation (logical complement)
:3	3-bit length
:8	8-bit length
:16	16-bit length
(), < >	Contents of operand indicated by effective address

2.5.1 Data Transfer Instructions

Table 2.4 describes the data transfer instructions. Figure 2.5 shows their object code formats.

Instru	ctio	n	Size*	Function
MOV			B/W	$(EAs) \rightarrow Rd, Rs \rightarrow (EAd)$
				Moves data between two general registers or between a general register and memory, or moves immediate data to a general register.
				The Rn, @Rn, @(d:16, Rn), @aa:16, #xx:16, @-Rn, and @Rn+ addressing modes are available for word data. The @aa:8 addressing mode is available for byte data only.
				The @–R7 and @R7+ modes require word operands. Do not specify byte size for these two modes.
POP			W	$@SP+ \rightarrow Rn$
				Pops a 16-bit general register from the stack. Equivalent to MOV.W @SP+, Rn.
PUSH			W	$Rn \rightarrow @-SP$
				Pushes a 16-bit general register onto the stack. Equivalent to MOV.W Rn, @–SP.
Note:	*	Size:	Operand size	;
	B:	Byte		
	W:	Word		

Table 2.4 Data Transfer Instructions

Certain precautions are required in data access. See section 2.9.1, Notes on Data Access, for details.



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2.5.2 Arithmetic Operations

Table 2.5 describes the arithmetic instructions.

Table 2.5 Arithmetic Instructions

Instruction	Size*	Function
ADD SUB	B/W	$Rd \pm Rs \to Rd, Rd + \#IMM \to Rd$
		Performs addition or subtraction on data in two general registers, or addition on immediate data and data in a general register. Immediate data cannot be subtracted from data in a general register. Word data can be added or subtracted only when both words are in general registers.
ADDX SUBX	В	$Rd \pm Rs \pm C \to Rd, Rd \pm \#IMM \pm C \to Rd$
		Performs addition or subtraction with carry or borrow on byte data in two general registers, or addition or subtraction on immediate data and data in a general register.
INC DEC	В	$Rd \pm 1 \rightarrow Rd$
		Increments or decrements a general register by 1.
ADDS SUBS	W	$Rd \pm 1 \to Rd, Rd \pm 2 \to Rd$
		Adds or subtracts 1 or 2 to or from a general register
DAA DAS	В	Rd decimal adjust \rightarrow Rd
		Decimal-adjusts (adjusts to 4-bit BCD) an addition or subtraction result in a general register by referring to the CCR
MULXU	В	$Rd \times Rs \to Rd$
		Performs 8-bit $ imes$ 8-bit unsigned multiplication on data in two general registers, providing a 16-bit result
DIVXU	В	$Rd \div Rs \to Rd$
		Performs 16-bit ÷ 8-bit unsigned division on data in two general registers, providing an 8-bit quotient and 8-bit remainder
CMP	B/W	Rd – Rs, Rd – #IMM
		Compares data in a general register with data in another general register or with immediate data, and indicates the result in the CCR. Word data can be compared only between two general registers.
NEG	В	$0 - Rd \rightarrow Rd$
		Obtains the two's complement (arithmetic complement) of data in a general register
Note: * Size:	Operand siz	ze
B: By	te	
W: Wo	ord	

2.5.3 Logic Operations

Table 2.6 describes the four instructions that perform logic operations.

Instruc	ction		Size*	Function
AND			В	$Rd \land Rs \to Rd, Rd \land \#IMM \to Rd$
				Performs a logical AND operation on a general register and another general register or immediate data
OR			В	$Rd \lor Rs \to Rd, Rd \lor \#IMM \to Rd$
				Performs a logical OR operation on a general register and another general register or immediate data
XOR			В	$Rd \oplus Rs \to Rd, \ Rd \oplus \#IMM \to Rd$
				Performs a logical exclusive OR operation on a general register and another general register or immediate data
NOT			В	$\sim \text{Rd} \rightarrow \text{Rd}$
				Obtains the one's complement (logical complement) of general register contents
Note:	* 5	Size:	Operand size	
	B: E	Byte		

Table 2.6 Logic Operation Instructions

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2.5.4 Shift Operations

Table 2.7 describes the eight shift instructions.

Table 2.7Shift Instructions

Instruction	Size*	Function
SHAL	В	$Rd shift \to Rd$
SHAR		Performs an arithmetic shift operation on general register contents
SHLL	В	$Rd shift \to Rd$
SHLR		Performs a logical shift operation on general register contents
ROTL	В	Rd rotate \rightarrow Rd
ROTR		Rotates general register contents
ROTXL	В	Rd rotate through carry \rightarrow Rd
ROTXR		Rotates general register contents through the C (carry) bit
	<u> </u>	

Note: * Size: Operand size

B: Byte



Figure 2.6 shows the instruction code format of arithmetic, logic, and shift instructions.



Figure 2.6 Arithmetic, Logic, and Shift Instruction Codes

2.5.5 Bit Manipulations

Table 2.8 describes the bit-manipulation instructions. Figure 2.7 shows their object code formats.

Table 2.8Bit-Manipulation Instructions
--

Instruction	Size*	Function
BSET	В	$1 \rightarrow (\text{sbit-No.} \text{ of } \text{scale})$
		Sets a specified bit in a general register or memory to 1. The bit number is specified by 3-bit immediate data or the lower three bits of a general register.
BCLR	В	$0 \rightarrow (\text{sbit-No.> of })$
		Clears a specified bit in a general register or memory to 0. The bit number is specified by 3-bit immediate data or the lower three bits of a general register.
BNOT	В	~ (<bit-no.> of <ead>) \rightarrow (<bit-no.> of <ead>)</ead></bit-no.></ead></bit-no.>
		Inverts a specified bit in a general register or memory. The bit number is specified by 3-bit immediate data or the lower three bits of a general register.
BTST	В	~ (<bit-no.> of <ead>) \rightarrow Z</ead></bit-no.>
		Tests a specified bit in a general register or memory and sets or clears the Z flag accordingly. The bit number is specified by 3-bit immediate data or the lower three bits of a general register.
BAND	В	$C \land (<\!bit-No.\!> of <\!EAd\!>) \rightarrow C$
		ANDs the C flag with a specified bit in a general register or memory, and stores the result in the C flag.
BIAND	В	$C \land [\text{~(of)}] \to C$
		ANDs the C flag with the inverse of a specified bit in a general register or memory, and stores the result in the C flag.
		The bit number is specified by 3-bit immediate data.
BOR	В	$C \lor (of) \to C$
		ORs the C flag with a specified bit in a general register or memory, and stores the result in the C flag.
BIOR	В	$C \lor [\sim (<\!bit-No.\!> of <\!EAd\!>)] \to C$
		ORs the C flag with the inverse of a specified bit in a general register or memory, and stores the result in the C flag.
		The bit number is specified by 3-bit immediate data.

Instruction	Size*	Function
BXOR	В	$C \oplus (<\!bit-\!No.\!> of <\!\mathsf{EAd\!\!>) \!\rightarrow C}$
		XORs the C flag with a specified bit in a general register or memory, and stores the result in the C flag.
BIXOR	В	$C \oplus \ [\text{-(of)]} \rightarrow C$
		XORs the C flag with the inverse of a specified bit in a general register or memory, and stores the result in the C flag.
		The bit number is specified by 3-bit immediate data.
BLD	В	(<bit-no.> of <ead>) \rightarrow C</ead></bit-no.>
		Copies a specified bit in a general register or memory to the C flag.
BILD	В	~ (<bit-no.> of <ead>) \rightarrow C</ead></bit-no.>
		Copies the inverse of a specified bit in a general register or memory to the C flag.
		The bit number is specified by 3-bit immediate data.
BST	В	$C \rightarrow (\text{sbit-No.> of } \text{})$
		Copies the C flag to a specified bit in a general register or memory.
BIST	В	~ C \rightarrow (<bit-no.> of <ead>)</ead></bit-no.>
		Copies the inverse of the C flag to a specified bit in a general register or memory.
		The bit number is specified by 3-bit immediate data.
Note: * Size B: Byte	e: Operand si e	ze

Certain precautions are required in bit manipulation. See section 2.9.2, Notes on Bit Manipulation, for details.

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15		8	7					0	BSET, BCLR, BNOT, BTST
	op		,	IMM		rr	יי	0	Operand: register direct (Rn) Bit No.: immediate (#xx:3)
15		8	7					0	-
	ор	1	1	rm		rr	ו	-	Operand: register direct (Rn) Bit No.: register direct (Rm)
15		8	7					0	
	ор	I	1	rn	0	0	0	0	Operand: register indirect (@Rn)
	ор			IMM	0	0	0	0	Bit No.: immediate (#xx:3)
15		8	7					0	
	ор	ļ	I	rn	0	0	0	0	Operand: register indirect (@Rn)
	ор			rm	0	0	0	0	Bit No.: register direct (Rm)
15		8	7					0	
	op		I	1 1	abs	I	1		Operand: absolute (@aa:8)
	ор			IMM	0	0	0	0	Bit No.: immediate (#xx:3)
15		8	7					0	
	ор		I	1 1	abs	1	1		Operand: absolute (@aa:8)
	ор			rm	0	0	0	0	Bit No.: register direct (Rm)
									BAND, BOR, BXOR, BLD, BST
15		8	7	,				0] Operand: register direct (Rn)
	ор			IMM		rr	1		Bit No.: immediate (#xx:3)
15		8	7					0	1
	ор			rn	0	0	0	0	Operand: register indirect (@Rn)
	ор			IMM	0	0	0	0	Bit No.: immediate (#xx:3)
15		8	7					0	-
	ор				abs				Operand: absolute (@aa:8)
	ор			IMM	0	0	0	0	Bit No.: immediate (#xx:3)
Lege	nd:								
op:	Operation field								
abs:	n: Register field Absolute address								
IMM:	Immediate data								



45	7					0	BIAND, BIOR, BIXOR, BILD, BIST
15 8 op	7	IMM		rr	י '	0	Operand: register direct (Rn) Bit No.: immediate (#xx:3)
15 8	7					0	
ор		rn	0	0	0	0	Operand: register indirect (@Rn)
ор		IMM	0	0	0	0	Bit No.: immediate (#xx:3)
158	7					0	
op		a	bs		1		Operand: absolute (@aa:8)
ор		IMM	0	0	0	0	Bit No.: immediate (#xx:3)
Legend: op: Operation field rm, rn: Register field abs: Absolute address IMM: Immediate data							

Figure 2.7 Bit Manipulation Instruction Codes (cont)

2.5.6 Branching Instructions

Table 2.9 describes the branching instructions. Figure 2.8 shows their object code formats.

Table 2.9Branching Instructions

Instruction	Size	Function					
Bcc	_	Branches to the designated address if condition cc is true. The branching conditions are given below.					
		Mnemonic	Description	Condition			
		BRA (BT)	Always (true)	Always			
		BRN (BF)	Never (false)	Never			
		BHI	High	C ∨ Z = 0			
		BLS	Low or same	C ∨ Z = 1			
		BCC (BHS)	Carry clear (high or same)	C = 0			
		BCS (BLO)	Carry set (low)	C = 1			
		BNE	Not equal	Z = 0			
		BEQ	Equal	Z = 1			
		BVC	Overflow clear	V = 0			
		BVS	Overflow set	V = 1			
		BPL	Plus	N = 0			
		BMI	Minus	N = 1			
		BGE	Greater or equal	$N \oplus V = 0$			
		BLT	Less than	N ⊕ V = 1			
		BGT	Greater than	$Z \vee (N \oplus V) = 0$			
		BLE	Less or equal	$Z \lor (N \oplus V) = 1$			
JMP	_	Branches unco	onditionally to a specified address	3			
BSR	_	Branches to a	subroutine at a specified address	3			
JSR	_	Branches to a	subroutine at a specified address	3			
RTS	_	Returns from a	Returns from a subroutine				

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Figure 2.8 Branching Instruction Codes

2.5.7 System Control Instructions

Table 2.10 describes the system control instructions. Figure 2.9 shows their object code formats.

Instruction	Size*	Function					
RTE		Returns from an exception-handling routine					
SLEEP	_	Causes a transition from active mode to a power-down mode. See section 5, Power-Down Modes, for details.					
LDC	В	$Rs \to CCR, \ \ \texttt{\#IMM} \to CCR$					
		Moves immediate data or general register contents to the condition code register					
STC	В	$CCR \rightarrow Rd$					
		Copies the condition code register to a specified general register					
ANDC	В	$CCR \land \#IMM \rightarrow CCR$					
		Logically ANDs the condition code register with immediate data					
ORC	В	$CCR \lor \#IMM \rightarrow CCR$					
		Logically ORs the condition code register with immediate data					
XORC	В	$CCR \oplus \#IMM \to CCR$					
		Logically exclusive-ORs the condition code register with immediate data					
NOP		$PC + 2 \rightarrow PC$					
		Only increments the program counter					
Note: * Size:	Operand size	9					

Table 2.10 System Control Instructions

. 0120. 0p0

B: Byte



Figure 2.9 System Control Instruction Codes

2.5.8 Block Data Transfer Instruction

Table 2.11 describes the block data transfer instruction. Figure 2.10 shows its object code format.

Table 2.11	Block Data	Transfer	Instruction
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Instruction	Size	Function
EEPMOV	_	If R4L ≠ 0 then
		$\begin{array}{ll} \mbox{repeat} & @R5+ \rightarrow @R6+ \\ & R4L-1 \rightarrow R4L \\ \mbox{until} & R4L = 0 \end{array}$
		else next;
		Block transfer instruction. Transfers the number of data bytes specified by R4L from locations starting at the address indicated by R5 to locations starting at the address indicated by R6. After the transfer, the next instruction is executed.

Certain precautions are required in using the EEPMOV instruction. See section 2.9.3, Notes on Use of the EEPMOV Instruction, for details.



Figure 2.10 Block Data Transfer Instruction Code



2.6 Basic Operational Timing

CPU operation is synchronized by a system clock (ϕ) or a subclock (ϕ_{SUB}). For details on these clock signals see section 4, Clock Pulse Generators. The period from a rising edge of ϕ or ϕ_{SUB} to the next rising edge is called one state. A bus cycle consists of two states or three states. The cycle differs depending on whether access is to on-chip memory or to on-chip peripheral modules.

2.6.1 Access to On-Chip Memory (RAM, ROM)

Access to on-chip memory takes place in two states. The data bus width is 16 bits, allowing access in byte or word size. Figure 2.11 shows the on-chip memory access cycle.



Figure 2.11 On-Chip Memory Access Cycle

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2.6.2 Access to On-Chip Peripheral Modules

On-chip peripheral modules are accessed in two states or three states. The data bus width is 8 bits, so access is by byte size only. This means that for accessing word data, two instructions must be used. Figures 2.12 and 2.13 show the on-chip peripheral module access cycle.

Two-state access to on-chip peripheral modules



Figure 2.12 On-Chip Peripheral Module Access Cycle (2-State Access)



Bus cycle - T₁ state -T₂ state -T₃ state ♦ or ♦_{SUB} Internal Address address bus Internal read signal Internal data bus Read data (read access) Internal write signal Internal data bus Write data (write access)

Three-state access to on-chip peripheral modules

Figure 2.13 On-Chip Peripheral Module Access Cycle (3-State Access)

2.7 CPU States

2.7.1 Overview

There are four CPU states: the reset state, program execution state, program halt state, and exception-handling state. The program execution state includes active (high-speed or medium-speed) mode and subactive mode. In the program halt state there are a sleep (high-speed or medium-speed) mode, standby mode, watch mode, and sub-sleep mode. These states are shown in figure 2.14. Figure 2.15 shows the state transitions.

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Figure 2.14 CPU Operation States



Figure 2.15 State Transitions

2.7.2 Program Execution State

In the program execution state the CPU executes program instructions in sequence.

There are three modes in this state, two active modes (high speed and medium speed) and one subactive mode. Operation is synchronized with the system clock in active mode (high speed and medium speed), and with the subclock in subactive mode. See section 5, Power-Down Modes for details on these modes.

2.7.3 Program Halt State

In the program halt state there are five modes: two sleep modes (high speed and medium speed), standby mode, watch mode, and subsleep mode. See section 5, Power-Down Modes for details on these modes.

2.7.4 Exception-Handling State

The exception-handling state is a transient state occurring when exception handling is started by a reset or interrupt and the CPU changes its normal processing flow. In exception handling caused by an interrupt, SP (R7) is referenced and the PC and CCR values are saved on the stack.

For details on interrupt handling, see section 3.3, Interrupts.

Renesas

2.8 Memory Map

2.8.1 Memory Map

The memory map of the H8/3822R, H8/38322, and H8/38422 is shown in figure 2.16 (1), that of the H8/3823R, H8/38323, and H8/38423 in figure 2.16 (2), that of the H8/3824R, H8/3824S, H8/38324, and H8/38424 in figure 2.16 (3), that of the H8/3825R, H8/3825S, H8/38325, and H8/38425 in figure 2.16 (4), that of the H8/3826R, H8/3826S, H8/38326, and H8/38426 in figure 2.16 (5), and that of the H8/3827R, H8/3827S, H8/38327, and H8/38427 in figure 2.16 (6).



Figure 2.16 (1) H8/3822R, H8/38322, and H8/38422 Memory Map



Figure 2.16 (2) H8/3823R, H8/38323, and H8/38423 Memory Map



Figure 2.16 (3) H8/3824R, H8/3824S, H8/38324, and H8/38424 Memory Map

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Figure 2.16 (4) H8/3825R, H8/3825S, H8/38325, and H8/38425 Memory Map



Figure 2.16 (5) H8/3826R, H8/3826S, H8/38326, and H8/38426 Memory Map


Figure 2.16 (6) H8/3827R, H8/3827S, H8/38327, and H8/38427 Memory Map

2.9 Application Notes

2.9.1 Notes on Data Access

1. Access to Empty Areas:

The address space of the H8/300L CPU includes empty areas in addition to the RAM, registers, and ROM areas available to the user. If these empty areas are mistakenly accessed by an application program, the following results will occur.

Data transfer from CPU to empty area:

The transferred data will be lost. This action may also cause the CPU to misoperate.

Data transfer from empty area to CPU:

Unpredictable data is transferred.

2. Access to Internal I/O Registers:

Internal data transfer to or from on-chip modules other than the ROM and RAM areas makes use of an 8-bit data width. If word access is attempted to these areas, the following results will occur.

Word access from CPU to I/O register area:

Upper byte: Will be written to I/O register.

Lower byte: Transferred data will be lost.

Word access from I/O register to CPU:

Upper byte: Will be written to upper part of CPU register.

Lower byte: Unpredictable data will be written to lower part of CPU register.

Byte size instructions should therefore be used when transferring data to or from I/O registers other than the on-chip ROM and RAM areas. Figure 2.17 shows the data size and number of states in which on-chip peripheral modules can be accessed.



			Acc	States	
		<u> </u>	Word	Byte	0.0.00
H'0000	Interrupt vector area (42 bytes)				
H'0029	(+2 bytes)				
H'002A					
	On-chip ROM	32Kbytes ^{*1}	0	0	2
H'7FFF ^{*1}					
	Not used		-	_	-
H'F740					
	LCD RAM (32 bytes)		0	0	2
H'F75F	(02 2)(00)				
	Not used		-	-	-
H'F780			·		
	On-chip RAM	2048 bytes	0	0	2
l'FF7F ^{*2}					
	Not used		-	-	-
H'FF90			×	0	2
	Internal I/O registers	H'FF98 to H'FF9F		0	3
	(112 bytes)		×	0	2
	· · · · · · · · · · · · · · · · · · ·	H'FFA8 to H'FFA		0	3
H'FFFF		┛	×	0	2

- 1. This address is H'3FFF in the H8/3822R (16-Kbyte on-chip ROM), H'5FFF in the H8/3823R (24-Kbyte on-chip ROM), H'9FFF in the H8/3825R and H8/3825S (40-Kbyte on-chip ROM), H'BFFF in the H8/3826R and H8/3826S (48-Kbyte on-chip ROM), and H'EDFF in the H8/3827R and H8/3827S (60-Kbyte on-chip ROM).
- This address is H'FB7F in the H8/3822R, and H8/3823R (1024 bytes of on-chip RAM).

Figure 2.17 Data Size and Number of States for Access to and from On-Chip Peripheral Modules

2.9.2 Notes on Bit Manipulation

The BSET, BCLR, BNOT, BST, and BIST instructions read one byte of data, modify the data, then write the data byte again. Special care is required when using these instructions in cases where two registers are assigned to the same address, in the case of registers that include write-only bits, and when the instruction accesses an I/O port.

Order of Operation		Operation
1	Read	Read byte data at the designated address
2	Modify	Modify a designated bit in the read data
3	Write	Write the altered byte data to the designated address

1. Bit Manipulation in Two Registers Assigned to the Same Address

Example 1: timer load register and timer counter

Figure 2.18 shows an example in which two timer registers share the same address. When a bit manipulation instruction accesses the timer load register and timer counter of a reloadable timer, since these two registers share the same address, the following operations take place.

Order of Operation		Operation
1	Read	Timer counter data is read (one byte)
2	Modify	The CPU modifies (sets or resets) the bit designated in the instruction
3	Write	The altered byte data is written to the timer load register

The timer counter is counting, so the value read is not necessarily the same as the value in the timer load register. As a result, bits other than the intended bit in the timer load register may be modified to the timer counter value.



Figure 2.18 Timer Configuration Example

Example 2: BSET instruction executed designating port 3

 $P3_7$ and $P3_6$ are designated as input pins, with a low-level signal input at $P3_7$ and a high-level signal at $P3_6$. The remaining pins, $P3_5$ to $P3_0$, are output pins and output low-level signals. In this example, the BSET instruction is used to change pin $P3_0$ to high-level output.

P37 P3₀ P36 P35 P3₄ P3₃ P32 **P3**₁ Input/output Input Input Output Output Output Output Output Output Pin state Low level High level Low level Low level Low level Low level Low level PCR3 0 0 1 1 1 1 1 1 PDR3 1 0 0 0 0 0 0 0

[A: Prior to executing BSET]

[B: BSET instruction executed]

BSET #0 , @PDR3

The BSET instruction is executed designating port 3.

[C: After executing BSET]

	P37	P36	P3₅	P34	P3₃	P32	P3 1	P30
Input/output	Input	Input	Output	Output	Output	Output	Output	Output
Pin state	Low level	High level	Low level	High level				
PCR3	0	0	1	1	1	1	1	1
PDR3	0	1	0	0	0	0	0	1

[D: Explanation of how BSET operates]

When the BSET instruction is executed, first the CPU reads port 3.

Since P_{3_7} and P_{3_6} are input pins, the CPU reads the pin states (low-level and high-level input). P_{3_5} to P_{3_0} are output pins, so the CPU reads the value in PDR3. In this example PDR3 has a value of H'80, but the value read by the CPU is H'40.

Next, the CPU sets bit 0 of the read data to 1, changing the PDR3 data to H'41. Finally, the CPU writes this value (H'41) to PDR3, completing execution of BSET.

As a result of this operation, bit 0 in PDR3 becomes 1, and $P3_0$ outputs a high-level signal. However, bits 7 and 6 of PDR3 end up with different values.

To avoid this problem, store a copy of the PDR3 data in a work area in memory. Perform the bit manipulation on the data in the work area, then write this data to PDR3.

[A: Prior to executing BSET]

MOV.	В	#H'80,	ROL
MOV.	В	ROL,	@RAM0
MOV.	В	ROL,	@PDR3

The PDR3 value (H'80) is written to a work area in memory (RAM0) as well as to PDR3

	P3 7	P36	P3₅	P34	P3 ₃	P32	P3 1	P30
Input/output	Input	Input	Output	Output	Output	Output	Output	Output
Pin state	Low level	High level	Low level	Low level	Low level	Low level	Low level	Low level
PCR3	0	0	1	1	1	1	1	1
PDR3	1	0	0	0	0	0	0	0
RAM0	1	0	0	0	0	0	0	0

[B: BSET instruction executed]

BSET #0	,	@RAM0
---------	---	-------

The BSET instruction is executed designating the PDR3 work area (RAM0).

[C: After executing BSET]

MOV.	В	@RAM0	, ROL
MOV.	В	ROL,	@PDR3

The work area (RAM0) value is written to PDR3.

	P37	P36	P3₅	P34	P3₃	P32	P3 1	P30
Input/output	Input	Input	Output	Output	Output	Output	Output	Output
Pin state	Low level	High level	Low level	High level				
PCR3	0	0	1	1	1	1	1	1
PDR3	1	0	0	0	0	0	0	1
RAM0	1	0	0	0	0	0	0	1

2. Bit Manipulation in a Register Containing a Write-only Bit

Example 3: BCLR instruction executed designating port 3 control register PCR3

As in the examples above, P_{3_7} and P_{3_6} are input pins, with a low-level signal input at P_{3_7} and a high-level signal at P_{3_6} . The remaining pins, P_{3_5} to P_{3_0} , are output pins that output low-level signals. In this example, the BCLR instruction is used to change pin P_{3_0} to an input port. It is assumed that a high-level signal will be input to this input pin.

P37 P36 P3₅ **P3**₄ P33 P32 **P**3₁ **P**3₀ Input/output Input Input Output Output Output Output Output Output Pin state Low level High level Low level Low level Low level Low level Low level PCR3 0 0 1 1 1 1 1 1 0 PDR3 1 0 0 0 0 0 0

[A: Prior to executing BCLR]

[B: BCLR instruction executed]

BCLR #0 , @PCR3

The BCLR instruction is executed designating PCR3.

[C: After executing BCLR]

	P37	P36	P3₅	P34	P3 ₃	P32	P31	P30
Input/output	Output	Output	Output	Output	Output	Output	Output	Input
Pin state	Low level	High level	Low level	Low level	Low level	Low level	Low level	High level
PCR3	1	1	1	1	1	1	1	0
PDR3	1	0	0	0	0	0	0	0

[D: Explanation of how BCLR operates]

When the BCLR instruction is executed, first the CPU reads PCR3. Since PCR3 is a write-only register, the CPU reads a value of H'FF, even though the PCR3 value is actually H'3F.

Next, the CPU clears bit 0 in the read data to 0, changing the data to H'FE. Finally, this value (H'FE) is written to PCR3 and BCLR instruction execution ends.

As a result of this operation, bit 0 in PCR3 becomes 0, making $P3_0$ an input port. However, bits 7 and 6 in PCR3 change to 1, so that $P3_7$ and $P3_6$ change from input pins to output pins.

To avoid this problem, store a copy of the PCR3 data in a work area in memory. Perform the bit manipulation on the data in the work area, then write this data to PCR3.

[A: Prior to executing BCLR]

MOV.	В	#H'3F,	ROL
MOV.	В	ROL,	@RAM0
MOV.	В	ROL,	@PCR3

The PCR3 value (H'3F) is written to a work area in memory (RAM0) as well as to PCR3.

	P3 7	P36	P35	P34	P3 ₃	P32	P3 ₁	P30
Input/output	Input	Input	Output	Output	Output	Output	Output	Output
Pin state	Low level	High level	Low level	Low level	Low level	Low level	Low level	Low level
PCR3	0	0	1	1	1	1	1	1
PDR3	1	0	0	0	0	0	0	0
RAM0	0	0	1	1	1	1	1	1

[B: BCLR instruction executed]

BCLR	#0	,	@RAM0
------	----	---	-------

The BCLR instruction is executed designating the PCR3 work area (RAM0).

[C: After executing BCLR]

MOV.	В	@RAM0	, ROL
MOV.	В	ROL,	@PCR3

The work area (RAM0) value is written to PCR3.

	P37	P36	P3₅	P34	P3₃	P32	P3 1	P30
Input/output	Input	Input	Output	Output	Output	Output	Output	Output
Pin state	Low level	High level	Low level	High level				
PCR3	0	0	1	1	1	1	1	0
PDR3	1	0	0	0	0	0	0	0
RAM0	0	0	1	1	1	1	1	0

Table 2.12 lists the pairs of registers that share identical addresses. Table 2.13 lists the registers that contain write-only bits.

Table 2.12 Registers with Shared Addresses

Register Name	Abbr.	Address
Timer counter and timer load register C	TCC/TLC	H'FFB5
Port data register 1*	PDR1	H'FFD4
Port data register 3*	PDR3	H'FFD6
Port data register 4 [*]	PDR4	H'FFD7
Port data register 5*	PDR5	H'FFD8
Port data register 6*	PDR6	H'FFD9
Port data register 7 [*]	PDR7	H'FFDA
Port data register 8*	PDR8	H'FFDB
Port data register A*	PDRA	H'FFDD

Note: * Port data registers have the same addresses as input pins.

Table 2.13 Registers with Write-Only Bits

Register Name	Abbr.	Address
Port control register 1	PCR1	H'FFE4
Port control register 3	PCR3	H'FFE6
Port control register 4	PCR4	H'FFE7
Port control register 5	PCR5	H'FFE8
Port control register 6	PCR6	H'FFE9
Port control register 7	PCR7	H'FFEA
Port control register 8	PCR8	H'FFEB
Port control register A	PCRA	H'FFED
Timer control register F	TCRF	H'FFB6
PWM control register	PWCR	H'FFD0
PWM data register U	PWDRU	H'FFD1
PWM data register L	PWDRL	H'FFD2

2.9.3 Notes on Use of the EEPMOV Instruction

• The EEPMOV instruction is a block data transfer instruction. It moves the number of bytes specified by R4L from the address specified by R5 to the address specified by R6.



• When setting R4L and R6, make sure that the final destination address (R6 + R4L) does not exceed H'FFFF. The value in R6 must not change from H'FFFF to H'0000 during execution of the instruction.





Section 3 Exception Handling

3.1 Overview

Exception handling is performed in this LSI when a reset or interrupt occurs. Table 3.1 shows the priorities of these two types of exception handling.

Table 3.1 Exception Handling Types and Priorities

Priority	Exception Source	Time of Start of Exception Handling
High	Reset	Exception handling starts as soon as the reset state is cleared
Low	Interrupt	When an interrupt is requested, exception handling starts after execution of the present instruction or the exception handling in progress is completed

3.2 Reset

3.2.1 Overview

A reset is the highest-priority exception. The internal state of the CPU and the registers of the onchip peripheral modules are initialized.

3.2.2 Reset Sequence

As soon as the $\overline{\text{RES}}$ pin goes low, all processing is stopped and the chip enters the reset state.

To make sure the chip is reset properly, observe the following precautions.

- At power on: Hold the RES pin low until the clock pulse generator output stabilizes.
- Resetting during operation: Hold the $\overline{\text{RES}}$ pin low for at least 10 system clock cycles.

Reset exception handling takes place as follows.

- The CPU internal state and the registers of on-chip peripheral modules are initialized, with the I bit of the condition code register (CCR) set to 1.
- The PC is loaded from the reset exception handling vector address (H'0000 to H'0001), after which the program starts executing from the address indicated in PC.

When system power is turned on or off, the $\overline{\text{RES}}$ pin should be held low.

Figure 3.1 shows the reset sequence starting from $\overline{\text{RES}}$ input.



Figure 3.1 Reset Sequence

3.2.3 Interrupt Immediately after Reset

After a reset, if an interrupt were to be accepted before the stack pointer (SP: R7) was initialized, PC and CCR would not be pushed onto the stack correctly, resulting in program runaway. To prevent this, immediately after reset exception handling all interrupts are masked. For this reason, the initial program instruction is always executed immediately after a reset. This instruction should initialize the stack pointer (e.g. MOV.W #xx: 16, SP).

3.3 Interrupts

3.3.1 Overview

The interrupt sources include 13 external interrupts (IRQ_4 to IRQ_0 , WKP_7 to WKP_0) and 23 internal interrupts from on-chip peripheral modules. Table 3.2 shows the interrupt sources, their priorities, and their vector addresses. When more than one interrupt is requested, the interrupt with the highest priority is processed.

The interrupts have the following features:

- Internal and external interrupts can be masked by the I bit in CCR. When the I bit is set to 1, interrupt request flags can be set but the interrupts are not accepted.
- IRQ₄ to IRQ₀ and WKP₇ to WKP₀ can be set to either rising edge sensing or falling edge sensing.

Interrupt Source	Interrupt	Vector Number	Vector Address	Priority
RES Watchdog timer	Reset	0	H'0000 to H'0001	High ♠
IRQ ₀	IRQ ₀	4	H'0008 to H'0009	-
IRQ ₁	IRQ ₁	5	H'000A to H'000B	-
IRQ ₂	IRQ ₂	6	H'000C to H'000D	-
IRQ ₃	IRQ ₃	7	H'000E to H'000F	-
ĪRQ ₄	IRQ4	8	H'0010 to H'0011	-
$\label{eq:wkp_0} \hline \hline WKP_1 \\ \hline WKP_2 \\ \hline WKP_3 \\ \hline WKP_4 \\ \hline WKP_5 \\ \hline WKP_6 \\ \hline \end{array}$	WKP ₀ WKP ₁ WKP ₂ WKP ₃ WKP ₄ WKP ₅ WKP ₆	9	H'0012 to H'0013	_
WKP ₇	WKP7			_
Timer A	Timer A overflow	11	H'0016 to H'0017	_
Asynchronous counter	Asynchronous counter overflow	12	H'0018 to H'0019	
Timer C	Timer C overflow or underflow	13	H'001A to H'001B	
Timer FL	Timer FL compare match Timer FL overflow	14	H'001C to H'001D	-
Timer FH	Timer FH compare match Timer FH overflow	15	H'001E to H'001F	-
Timer G	Timer G input capture Timer G overflow	16	H'0020 to H'0021	-
SCI3-1	SCI3-1 transmit end SCI3-1 transmit data empty SCI3-1 receive data full SCI3-1 overrrun error SCI3-1 framing error SCI3-1 parity error	17	H'0022 to H'0023	-
SCI3-2	SCI3-2 transmit end SCI3-2 transmit data empty SCI3-2 receive data full SCI3-2 overrun error SCI3-2 framing error SCI3-2 parity error	18	H'0024 to H'0025	_
A/D	A/D conversion end	19	H'0026 to H'0027	_ ↓
(SLEEP instruction executed)	Direct transfer	20	H'0028 to H'0029	Low

Table 3.2 Interrupt Sources and Their Priorities

Note: Vector addresses H'0002 to H'0007 and H'0014 to H'0015 are reserved and cannot be used.



3.3.2 Interrupt Control Registers

Table 3.3 lists the registers that control interrupts.

Table 3.3 Interrupt Control Registers

Name	Abbreviation	R/W	Initial Value	Address
IRQ edge select register	IEGR	R/W	H'E0	H'FFF2
Interrupt enable register 1	IENR1	R/W	H'00	H'FFF3
Interrupt enable register 2	IENR2	R/W	H'00	H'FFF4
Interrupt request register 1	IRR1	R/W*	H'20	H'FFF6
Interrupt request register 2	IRR2	R/W*	H'00	H'FFF7
Wakeup interrupt request register	IWPR	R/W*	H'00	H'FFF9
Wakeup edge select register	WEGR	R/W	H'00	H'FF90

Note: * Write is enabled only for writing of 0 to clear a flag.

1. IRQ Edge Select Register (IEGR)

Bit	7	6	5	4	3	2	1	0
	—	—	—	IEG4	IEG3	IEG2	IEG1	IEG0
Initial value	1	1	1	0	0	0	0	0
Read/Write	_	_	_	R/W	R/W	R/W	R/W	R/W

IEGR is an 8-bit read/write register used to designate whether pins \overline{IRQ}_4 to \overline{IRQ}_0 are set to rising edge sensing or falling edge sensing.

Bits 7 to 5: Reserved bits

Bits 7 to 5 are reserved: they are always read as 1 and cannot be modified.

Bit 4: IRQ₄ edge select (IEG4)

Bit 4 selects the input sensing of the \overline{IRQ}_4 pin and \overline{ADTRG} pin.

Bit 4		
IEG4	Description	
0	Falling edge of \overline{IRQ}_4 and \overline{ADTRG} pin input is detected	(initial value)
1	Rising edge of \overline{IRQ}_4 and \overline{ADTRG} pin input is detected	

Bit 3: IRQ₃ edge select (IEG3)

Bit 3 selects the input sensing of the \overline{IRQ}_3 pin and TMIF pin.

Bit 3		
IEG3	Description	
0	Falling edge of \overline{IRQ}_3 and TMIF pin input is detected	(initial value)
1	Rising edge of \overline{IRQ}_3 and TMIF pin input is detected	

Bit 2: IRQ₂ edge select (IEG2)

Bit 2 selects the input sensing of pin \overline{IRQ}_2 .

Bit 2 IEG2	Description	
0	Falling edge of \overline{IRQ}_2 pin input is detected	(initial value)
1	Rising edge of \overline{IRQ}_2 pin input is detected	

Bit 1: IRQ₁ edge select (IEG1)

Bit 3 selects the input sensing of the \overline{IRQ}_1 pin and TMIC pin.

Bit 1	Description	
IEG1	Description	
0	Falling edge of \overline{IRQ}_1 and TMIC pin input is detected	(initial value)
1	Rising edge of \overline{IRQ}_1 and TMIC pin input is detected	

Bit 0: IRQ₀ edge select (IEG0)

Bit 0 selects the input sensing of pin \overline{IRQ}_0 .

Bit 0 IEG0	Description	
0	Falling edge of IRQ ₀ pin input is detected	(initial value)
1	Rising edge of \overline{IRQ}_0 pin input is detected	

2. Interrupt Enable Register 1 (IENR1)

Bit	7	6	5	4	3	2	1	0
	IENTA	—	IENWP	IEN4	IEN3	IEN2	IEN1	IEN0
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

IENR1 is an 8-bit read/write register that enables or disables interrupt requests.

Bit 7: Timer A interrupt enable (IENTA)

Bit 7 enables or disables timer A overflow interrupt requests.

Bit 7		
IENTA	Description	
0	Disables timer A interrupt requests	(initial value)
1	Enables timer A interrupt requests	

Bit 6: Reserved bit

Bit 6 is a readable/writable reserved bit. It is initialized to 0 by a reset.

Bit 5: Wakeup interrupt enable (IENWP)

Bit 5 enables or disables WKP₇ to WKP₀ interrupt requests.

Bit 5		
IENWP	Description	
0	Disables \overline{WKP}_7 to \overline{WKP}_0 interrupt requests	(initial value)
1	Enables \overline{WKP}_7 to \overline{WKP}_0 interrupt requests	

Bits 4 to 0: IRQ₄ to IRQ₀ interrupt enable (IEN4 to IEN0)

Bits 4 to 0 enable or disable IRQ₄ to IRQ₀ interrupt requests.

Description	
Disables interrupt requests from pin IRQn	(initial value)
Enables interrupt requests from pin IRQn	
	Disables interrupt requests from pin IRQn

(n = 4 to 0)

3. Interrupt Enable Register 2 (IENR2)

Bit	7	6	5	4	3	2	1	0
	IENDT	IENAD	—	IENTG	IENTFH	IENTFL	IENTC	IENEC
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

IENR2 is an 8-bit read/write register that enables or disables interrupt requests.

Bit 7: Direct transfer interrupt enable (IENDT)

Bit 7 enables or disables direct transfer interrupt requests.

Bit 7 IENDT	Description	
0	Disables direct transfer interrupt requests	(initial value)
1	Enables direct transfer interrupt requests	

Bit 6: A/D converter interrupt enable (IENAD)

Bit 6 enables or disables A/D converter interrupt requests.

Bit 6 IENAD	Description	
0	Disables A/D converter interrupt requests	(initial value)
1	Enables A/D converter interrupt requests	

Bit 5: Reserved bit

Bit 5 is a readable/writable reserved bit. It is initialized to 0 by a reset.

Bit 4: Timer G interrupt enable (IENTG)

Bit 4 enables or disables timer G input capture or overflow interrupt requests.

Bit 4 IENTG	Description	
0	Disables timer G interrupt requests	(initial value)
1	Enables timer G interrupt requests	

Bit 3: Timer FH interrupt enable (IENTFH)

Bit 3 enables or disables timer FH compare match and overflow interrupt requests.

Bit 3		
IENTFH	Description	
0	Disables timer FH interrupt requests	(initial value)
1	Enables timer FH interrupt requests	

Bit 2: Timer FL interrupt enable (IENTFL)

Bit 2 enables or disables timer FL compare match and overflow interrupt requests.

Bit 2 IENTFL	Description	
0	Disables timer FL interrupt requests	(initial value)
1	Enables timer FL interrupt requests	

Bit 1: Timer C interrupt enable (IENTC)

Bit 1 enables or disables timer C overflow and underflow interrupt requests.

Bit 1 IENTC	Description	
0	Disables timer C interrupt requests	(initial value)
1	Enables timer C interrupt requests	

Bit 0: Asynchronous event counter interrupt enable (IENEC)

Bit 0 enables or disables asynchronous event counter interrupt requests.

Bit 0 IENEC	Description	
0	Disables asynchronous event counter interrupt requests	(initial value)
1	Enables asynchronous event counter interrupt requests	

For details of SCI3-1 and SCI3-2 interrupt control, see section 10.2.6, Serial Control Register 3 (SCR3).

4. Interrupt Request Register 1 (IRR1)

Bit	7	6	5	4	3	2	1	0
	IRRTA	—	_	IRRI4	IRRI3	IRRI2	IRRI1	IRRI0
Initial value	0	0	1	0	0	0	0	0
Read/Write	R/W*	R/W^*	_	R/W*	R/W*	R/W*	R/W*	R/W*

Note: * Only a write of 0 for flag clearing is possible

IRR1 is an 8-bit read/write register, in which a corresponding flag is set to 1 when a timer A or IRQ_4 to IRQ_0 interrupt is requested. The flags are not cleared automatically when an interrupt is accepted. It is necessary to write 0 to clear each flag.

Bit 7: Timer A interrupt request flag (IRRTA)

Bit 7 IRRTA	Description	
0	Clearing condition:	(initial value)
	When IRRTA = 1, it is cleared by writing 0	
1	Setting condition:	
	When the timer A counter value overflows from H'FF to H'00	

Bit 6: Reserved bit

Bit 6 is a readable/writable reserved bit. It is initialized to 0 by a reset.

Bit 5: Reserved bit

Bit 5 is reserved; it is always read as 1 and cannot be modified.



Bit n IRRIn	Description	
0	Clearing condition:	(initial value)
	When IRRIn = 1, it is cleared by writing 0	
1	Setting condition:	
	When pin IRQn is designated for interrupt input and the designated sinput	gnal edge is

Bits 4 to 0: IRQ₄ to IRQ₀ interrupt request flags (IRRI4 to IRRI0)

(n = 4 to 0)

5. Interrupt Request Register 2 (IRR2)

Bit	7	6	5	4	3	2	1	0
	IRRDT	IRRAD	—	IRRTG	IRRTFH	IRRTFL	IRRTC	IRREC
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W*	R/W*	R/W	R/W*	R/W^*	R/W *	R/W *	R/W *

Note: * Only a write of 0 for flag clearing is possible

IRR2 is an 8-bit read/write register, in which a corresponding flag is set to 1 when a direct transfer, A/D converter, Timer G, Timer FH, Timer FC, or Timer C interrupt is requested. The flags are not cleared automatically when an interrupt is accepted. It is necessary to write 0 to clear each flag.

Bit 7: Direct transfer interrupt request flag (IRRDT)

Bit 7 IRRDT	Description		
0	Clearing condition:	(initial value)	
	When IRRDT = 1, it is cleared by writing 0		
1	Setting condition:		
	When a direct transfer is made by executing a SLEEP instruction while DTON = 1 in SYSCR2		

Bit 6: A/D converter interrupt request flag (IRRAD)

Bit 6 IRRAD	Description	
0	Clearing condition:	(initial value)
	When IRRAD = 1, it is cleared by writing 0	
1	Setting condition:	
	When A/D conversion is completed and ADSF is cleared to 0 in ADSR	

Bit 5: Reserved bit

Bit 5 is a readable/writable reserved bit. It is initialized to 0 by a reset.

Bit 4: Timer G interrupt request flag (IRRTG)

Bit 4 IRRTG	Description		
0	Clearing condition:	(initial value)	
	When IRRTG = 1, it is cleared by writing 0		
1	Setting condition:		
	When the TMIG pin is designated for TMIG input and the designated signal edge is input, or when TCG overflows while OVIE is set to 1 in TMG		

Bit 3: Timer FH interrupt request flag (IRRTFH)

Bit 3 IRRTFH	Description		
0	Clearing condition:	(initial value)	
	When IRRTFH = 1, it is cleared by writing 0		
1	Setting condition:		
	When TCFH and OCRFH match in 8-bit timer mode, or when TCF (TCFL, TCFH) and OCRF (OCRFL, OCRFH) match in 16-bit timer mode		



Bit 2: Timer FL interrupt request flag (IRRTFL)

Bit 2 IRRTFL	Description	
0	Clearing condition:	(initial value)
	When IRRTFL= 1, it is cleared by writing 0	
1	Setting condition:	
	When TCFL and OCRFL match in 8-bit timer mode	

Bit 1: Timer C interrupt request flag (IRRTC)

Bit 1 IRRTC	Description		
0	Clearing condition:	(initial value)	
	When IRRTC= 1, it is cleared by writing 0		
1	Setting condition:		
	When the timer C counter value overflows (from H'FF to H'00) or underflows (from H'00 to H'FF)		

Bit 0: Asynchronous event counter interrupt request flag (IRREC)

Bit 0 IRREC	Description	
0	Clearing condition:	(initial value)
	When IRREC = 1, it is cleared by writing 0	
1	Setting condition:	
	When ECH overflows in 16-bit counter mode, or ECH or ECL overflow counter mode	vs in 8-bit

6. Wakeup Interrupt Request Register (IWPR)

Bit	7	6	5	4	3	2	1	0
	IWPF7	IWPF6	IWPF5	IWPF4	IWPF3	IWPF2	IWPF1	IWPF0
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W*	R/W*	R/W*	R/W*	R/W*	R/W *	R/W *	R/W*

Note: * Only a write of 0 for flag clearing is possible

IWPR is an 8-bit read/write register containing wakeup interrupt request flags. When one of pins \overline{WKP}_7 to \overline{WKP}_0 is designated for wakeup input and a rising or falling edge is input at that pin, the corresponding flag in IWPR is set to 1. A flag is not cleared automatically when the corresponding interrupt is accepted. Flags must be cleared by writing 0.

Bits 7 to 0: Wakeup interrupt request flags (IWPF7 to IWPF0)

Bit n IWPFn	Description	
0	Clearing condition:	(initial value)
	When IWPFn= 1, it is cleared by writing 0	
1	Setting condition:	
	When pin $\overline{\text{WKP}}_n$ is designated for wakeup input and a rising or fal that pin	lling edge is input at

(n = 7 to 0)



7. Wakeup Edge Select Register (WEGR)

Bit	7	6	5	4	3	2	1	0
	WKEGS7	WKEGS6	WKEGS5	WKEGS4	WKEGS3	WKEGS2	WKEGS1	WKEGS0
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W							

WEGR is an 8-bit read/write register that specifies rising or falling edge sensing for pins $\overline{WKP}n$.

WEGR is initialized to H'00 by a reset.

Bit n: WKPn edge select (WKEGSn)

Bit n selects $\overline{WKP}n$ pin input sensing.

Bit n WKEGSn	Description	
0	WKPn pin falling edge detected	(initial value)
1	WKPn pin rising edge detected	

(n = 7 to 0)

3.3.3 External Interrupts

There are 13 external interrupts: IRQ₄ to IRQ₀ and WKP₇ to WKP₀.

1. Interrupts WKP₇ to WKP₀

Interrupts WKP₇ to WKP₀ are requested by either rising or falling edge input to pins \overline{WKP}_7 to \overline{WKP}_0 . When these pins are designated as pins \overline{WKP}_7 to \overline{WKP}_0 in port mode register 5 and a rising or falling edge is input, the corresponding bit in IWPR is set to 1, requesting an interrupt. Recognition of wakeup interrupt requests can be disabled by clearing the IENWP bit to 0 in IENR1. These interrupts can all be masked by setting the I bit to 1 in CCR.

When WKP_7 to WKP_0 interrupt exception handling is initiated, the I bit is set to 1 in CCR. Vector number 9 is assigned to interrupts WKP_7 to WKP_0 . All eight interrupt sources have the same vector number, so the interrupt-handling routine must discriminate the interrupt source.

2. Interrupts IRQ₄ to IRQ₀

Interrupts IRQ_4 to IRQ_0 are requested by input signals to pins $\overline{IRQ_4}$ to $\overline{IRQ_0}$. These interrupts are detected by either rising edge sensing or falling edge sensing, depending on the settings of bits IEG4 to IEG0 in IEGR.

When these pins are designated as pins \overline{IRQ}_4 to \overline{IRQ}_0 in port mode register 3 and 1 and the designated edge is input, the corresponding bit in IRR1 is set to 1, requesting an interrupt. Recognition of these interrupt requests can be disabled individually by clearing bits IEN4 to IEN0 to 0 in IENR1. These interrupts can all be masked by setting the I bit to 1 in CCR.

When IRQ_4 to IRQ_0 interrupt exception handling is initiated, the I bit is set to 1 in CCR. Vector numbers 8 to 4 are assigned to interrupts IRQ_4 to IRQ_0 . The order of priority is from IRQ_0 (high) to IRQ_4 (low). Table 3.2 gives details.

3.3.4 Internal Interrupts

There are 23 internal interrupts that can be requested by the on-chip peripheral modules. When a peripheral module requests an interrupt, the corresponding bit in IRR1 or IRR2 is set to 1. Recognition of individual interrupt requests can be disabled by clearing the corresponding bit in IENR1 or IENR2. All these interrupts can be masked by setting the I bit to 1 in CCR. When internal interrupt handling is initiated, the I bit is set to 1 in CCR. Vector numbers from 20 to 11 are assigned to these interrupts. Table 3.2 shows the order of priority of interrupts from on-chip peripheral modules.



3.3.5 Interrupt Operations

Interrupts are controlled by an interrupt controller. Figure 3.2 shows a block diagram of the interrupt controller. Figure 3.3 shows the flow up to interrupt acceptance.



Figure 3.2 Block Diagram of Interrupt Controller

Interrupt operation is described as follows.

- When an interrupt condition is met while the interrupt enable register bit is set to 1, an interrupt request signal is sent to the interrupt controller.
- When the interrupt controller receives an interrupt request, it sets the interrupt request flag.
- From among the interrupts with interrupt request flags set to 1, the interrupt controller selects the interrupt request with the highest priority and holds the others pending. (Refer to table 3.2 for a list of interrupt priorities.)
- The interrupt controller checks the I bit of CCR. If the I bit is 0, the selected interrupt request is accepted; if the I bit is 1, the interrupt request is held pending.

- If the interrupt is accepted, after processing of the current instruction is completed, both PC and CCR are pushed onto the stack. The state of the stack at this time is shown in figure 3.4. The PC value pushed onto the stack is the address of the first instruction to be executed upon return from interrupt handling.
- The I bit of CCR is set to 1, masking further interrupts.
- The vector address corresponding to the accepted interrupt is generated, and the interrupt handling routine located at the address indicated by the contents of the vector address is executed.
- Notes: 1. When disabling interrupts by clearing bits in an interrupt enable register, or when clearing bits in an interrupt request register, always do so while interrupts are masked (I = 1).
 - 2. If the above clear operations are performed while I = 0, and as a result a conflict arises between the clear instruction and an interrupt request, exception processing for the interrupt will be executed after the clear instruction has been executed.









Figure 3.4 Stack State after Completion of Interrupt Exception Handling

Figure 3.5 shows a typical interrupt sequence.







3.3.6 Interrupt Response Time

Table 3.4 shows the number of wait states after an interrupt request flag is set until the first instruction of the interrupt handler is executed.

Table 3.4 Interrupt Wait States

Item	States	Total
Waiting time for completion of executing instruction*	1 to 13	15 to 27
Saving of PC and CCR to stack	4	
Vector fetch	2	
Instruction fetch	4	
Internal processing	4	

Note: * Not including EEPMOV instruction.



3.4 Application Notes

3.4.1 Notes on Stack Area Use

When word data is accessed in the H8/3864 Group, the least significant bit of the address is regarded as 0. Access to the stack always takes place in word size, so the stack pointer (SP: R7) should never indicate an odd address. Use PUSH Rn (MOV.W Rn, @–SP) or POP Rn (MOV.W @SP+, Rn) to save or restore register values.

Setting an odd address in SP may cause a program to crash. An example is shown in figure 3.6.



Figure 3.6 Operation when Odd Address is Set in SP

When CCR contents are saved to the stack during interrupt exception handling or restored when RTE is executed, this also takes place in word size. Both the upper and lower bytes of word data are saved to the stack; on return, the even address contents are restored to CCR while the odd address contents are ignored.

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3.4.2 Notes on Rewriting Port Mode Registers

When a port mode register is rewritten to switch the functions of external interrupt pins, the following points should be observed.

When an external interrupt pin function is switched by rewriting the port mode register that controls pins \overline{IRQ}_4 to \overline{IRQ}_0 , \overline{WKP}_7 to \overline{WKP}_0 , the interrupt request flag may be set to 1 at the time the pin function is switched, even if no valid interrupt is input at the pin. Be sure to clear the interrupt request flag to 0 after switching pin functions. Table 3.5 shows the conditions under which interrupt request flags are set to 1 in this way.

Interrupt Request		
Flags Set	to 1	Conditions
IRR1	IRRI4	When PMR1 bit IRQ4 is changed from 0 to 1 while pin \overline{IRQ}_4 is low and IEGR bit IEG4 = 0.
		When PMR1 bit IRQ4 is changed from 1 to 0 while pin \overline{IRQ}_4 is low and IEGR bit IEG4 = 1.
	IRRI3	When PMR1 bit IRQ3 is changed from 0 to 1 while pin \overline{IRQ}_3 is low and IEGR bit IEG3 = 0.
		When PMR1 bit IRQ3 is changed from 1 to 0 while pin \overline{IRQ}_3 is low and IEGR bit IEG3 = 1.
	IRRI2	When PMR1 bit IRQ2 is changed from 0 to 1 while pin \overline{IRQ}_2 is low and IEGR bit IEG2 = 0.
		When PMR1 bit IRQ2 is changed from 1 to 0 while pin \overline{IRQ}_2 is low and IEGR bit IEG2 = 1.
	IRRI1	When PMR1 bit IRQ1 is changed from 0 to 1 while pin \overline{IRQ}_1 is low and IEGR bit IEG1 = 0.
		When PMR1 bit IRQ1 is changed from 1 to 0 while pin \overline{IRQ}_1 is low and IEGR bit IEG1 = 1.
	IRRI0	When PMR3 bit IRQ0 is changed from 0 to 1 while pin \overline{IRQ}_0 is low and IEGR bit IEG0 = 0.
		When PMR3 bit IRQ0 is changed from 1 to 0 while pin $\overline{IRQ_0}$ is low and IEGR bit IEG0 = 1.
IWPR	IWPF7	When PMR5 bit WKP7 is changed from 0 to 1 while pin \overline{WKP}_7 is low.
	IWPF6	When PMR5 bit WKP6 is changed from 0 to 1 while pin \overline{WKP}_6 is low.
	IWPF5	When PMR5 bit WKP5 is changed from 0 to 1 while pin \overline{WKP}_5 is low.
	IWPF4	When PMR5 bit WKP4 is changed from 0 to 1 while pin WKP ₄ is low.
	IWPF3	When PMR5 bit WKP3 is changed from 0 to 1 while pin \overline{WKP}_3 is low.
	IWPF2	When PMR5 bit WKP2 is changed from 0 to 1 while pin \overline{WKP}_2 is low.
	IWPF1	When PMR5 bit WKP1 is changed from 0 to 1 while pin \overline{WKP}_1 is low.
	IWPF0	When PMR5 bit WKP0 is changed from 0 to 1 while pin $\overline{\text{WKP}}_0$ is low.

 Table 3.5
 Conditions Under which Interrupt Request Flag is Set to 1

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Figure 3.7 shows the procedure for setting a bit in a port mode register and clearing the interrupt request flag.

When switching a pin function, mask the interrupt before setting the bit in the port mode register. After accessing the port mode register, execute at least one instruction (e.g., NOP), then clear the interrupt request flag from 1 to 0. If the instruction to clear the flag is executed immediately after the port mode register access without executing an intervening instruction, the flag will not be cleared.

An alternative method is to avoid the setting of interrupt request flags when pin functions are switched by keeping the pins at the high level so that the conditions in table 3.5 do not occur.



Figure 3.7 Port Mode Register Setting and Interrupt Request Flag Clearing Procedure

3.4.3 Method for Clearing Interrupt Request Flags

Use the recommended method, given below when clearing the flags of interrupt request registers (IRR1, IRR2, IWPR).

Recommended method

Use a single instruction to clear flags. The bit control instruction and byte-size data transfer instruction can be used. Two examples of program code for clearing IRR11 (bit 1 of IRR1) are given below.

BCLR #1, @IRR1:8 MOV.B R1L, @IRR1:8 (set the value of R1L to B'11111101)

• Example of a malfunction

When flags are cleared with multiple instructions, other flags might be cleared during execution of the instructions, even though they are currently set, and this will cause a malfunction.

Here is an example in which IRRI0 is cleared and disabled in the process of clearing IRRI1 (bit 1 of IRR1).

```
MOV.B @IRR1:8,R1L ..... IRRIO = 0 at this time
AND.B #B'11111101,R1L .... Here, IRRIO = 1
MOV.B R1L,@IRR1:8 ..... IRRIO is cleared to 0
```

In the above example, it is assumed that an IRQ0 interrupt is generated while the AND.B instruction is executing.

The IRQ0 interrupt is disabled because, although the original objective is clearing IRRI1, IRRI0 is also cleared.


Section 4 Clock Pulse Generators

4.1 Overview

Clock oscillator circuitry (CPG: clock pulse generator) is provided on-chip, including both a system clock pulse generator and a subclock pulse generator. The system clock pulse generator consists of a system clock oscillator and system clock dividers. The subclock pulse generator consists of a subclock oscillator circuit and a subclock divider.

4.1.1 Block Diagram



Figure 4.1 shows a block diagram of the clock pulse generators.

Figure 4.1 Block Diagram of Clock Pulse Generators

4.1.2 System Clock and Subclock

The basic clock signals that drive the CPU and on-chip peripheral modules are ϕ and ϕ_{SUB} . Four of the clock signals have names: ϕ is the system clock, ϕ_{SUB} is the subclock, ϕ_{OSC} is the oscillator clock, and ϕ_W is the watch clock.

The clock signals available for use by peripheral modules are $\phi/2$, $\phi/4$, $\phi/8$, $\phi/16$, $\phi/32$, $\phi/64$, $\phi/128$, $\phi/256$, $\phi/512$, $\phi/1024$, $\phi/2048$, $\phi/4096$, $\phi/8192$, $\phi_W/2$, $\phi_W/4$, $\phi_W/8$, $\phi_W/16$, $\phi_W/32$, $\phi_W/64$, and $\phi_W/128$. The clock requirements differ from one module to another.

4.2 System Clock Generator

Clock pulses can be supplied to the system clock divider either by connecting a crystal or ceramic oscillator, or by providing external clock input.

1. Connecting a Crystal Oscillator

Figure 4.2 shows a typical method of connecting a crystal oscillator. For information on recommended resonators, see the product AC characteristics listed in section 15, Electrical Characteristics. Please consult with the resonator manufacturer when selecting a resonator model.





2. Connecting a Ceramic Oscillator

Figure 4.3 shows a typical method of connecting a ceramic oscillator. For information on recommended resonators, see the product AC characteristics listed in section 15, Electrical Characteristics. Please consult with the resonator manufacturer when selecting a resonator model.



Figure 4.3 Typical Connection to Ceramic Oscillator

3. Notes on Board Design

When generating clock pulses by connecting a crystal or ceramic oscillator, pay careful attention to the following points.

Avoid running signal lines close to the oscillator circuit, since the oscillator may be adversely affected by induction currents. (See figure 4.4.)

The board should be designed so that the oscillator and load capacitors are located as close as possible to pins OSC_1 and OSC_2 .





4. External Clock Input Method

Connect an external clock signal to pin OSC_1 , and leave pin OSC_2 open. Figure 4.5 shows a typical connection.



Figure 4.5 External Clock Input (Example)

Frequency	Oscillator Clock (ø _{osc})
Duty cycle	45% to 55%

Note: The circuit parameters above are recommended by the crystal or ceramic oscillator manufacturer.

The circuit parameters are affected by the crystal or ceramic oscillator and floating capacitance when designing the board. When using the oscillator, consult with the crystal or ceramic oscillator manufacturer to determine the circuit parameters.

4.3 Subclock Generator

1. Connecting a 32.768 kHz/38.4 kHz Crystal Oscillator

Clock pulses can be supplied to the subclock divider by connecting a 32.768 kHz/38.4 kHz crystal oscillator, as shown in figure 4.6. Follow the same precautions as noted under 3. notes on board design for the system clock in 4.2.



Figure 4.6 Typical Connection to 32.768 kHz/38.4 kHz Crystal Oscillator (Subclock)

Figure 4.7 shows the equivalent circuit of the 32.768 kHz/38.4 kHz crystal oscillator.



Figure 4.7 Equivalent Circuit of 32.768 kHz/38.4 kHz Crystal Oscillator

2. Pin Connection when Not Using Subclock

When the subclock is not used, connect pin X_1 to GND and leave pin X_2 open, as shown in figure 4.8.



Figure 4.8 Pin Connection when not Using Subclock

3. External Clock Input

• H8/3827R Group and H8/3827S Group

Connect the external clock to the X1 pin and leave the X2 pin open, as shown in figure 4.9 (a).



Figure 4.9 (a) Pin Connection when Inputting External Clock

Frequency	Subclock (øw)
Duty	45% to 55%

• H8/38327 Group and H8/38427 Group

Connect pin X_1 to GND and leave pin X_2 open. Input an external clock to pin EXCL. Set bit EXCL in register PMR2 to 1 to supply the external clock to the internal components of the device. A connection example is shown in figure 4.9 (b).



Figure 4.9 (b) Pin Connection when Inputting External Clock (H8/38327 Group and H8/38427 Group)

Frequency	Subclock (øw)
Duty	45% to 55%



4.4 Prescalers

The H8/3864 Group is equipped with two on-chip prescalers having different input clocks (prescaler S and prescaler W). Prescaler S is a 13-bit counter using the system clock (ϕ) as its input clock. Its prescaled outputs provide internal clock signals for on-chip peripheral modules. Prescaler W is a 5-bit counter using a 32.768 kHz or 38.4 kHz signal divided by 4 (ϕ_W /4) as its input clock. Its prescaled outputs are used by timer A as a time base for timekeeping.

1. Prescaler S (PSS)

Prescaler S is a 13-bit counter using the system clock (ϕ) as its input clock. It is incremented once per clock period.

Prescaler S is initialized to H'0000 by a reset, and starts counting on exit from the reset state.

In standby mode, watch mode, subactive mode, and subsleep mode, the system clock pulse generator stops. Prescaler S also stops and is initialized to H'0000.

The CPU cannot read or write prescaler S.

The output from prescaler S is shared by timer A, timer C, timer F, timer G, SCI3-1, SC3-2, the A/D converter, the LCD controller, the watchdog timer, and the 14-bit PWM. The divider ratio can be set separately for each on-chip peripheral function.

In active (medium-speed) mode the clock input to prescaler S is ϕ osc/16, ϕ osc/32, ϕ osc/64, or ϕ osc/128.

2. Prescaler W (PSW)

Prescaler W is a 5-bit counter using a 32.768 kHz/38.4 kHz signal divided by 4 ($\phi_W/4$) as its input clock.

Prescaler W is initialized to H'00 by a reset, and starts counting on exit from the reset state.

Even in standby mode, watch mode, subactive mode, or subsleep mode, prescaler W continues functioning so long as clock signals are supplied to pins X1 and X2.

Prescaler W can be reset by setting 1s in bits TMA3 and TMA2 of timer mode register A (TMA).

Output from prescaler W can be used to drive timer A, in which case timer A functions as a time base for timekeeping.

4.5 Note on Oscillators

Oscillator characteristics are closely related to board design and should be carefully evaluated by the user in mask ROM, ZTATTM, and F-ZTATTM versions, referring to the examples shown in this section. Oscillator circuit constants will differ depending on the oscillator element, stray capacitance in its interconnecting circuit, and other factors. Suitable constants should be determined in consultation with the oscillator element manufacturer. Design the circuit so that the oscillator element never receives voltages exceeding its maximum rating.



Figure 4.10 Example of Crystal and Ceramic Oscillator Element Arrangement

Figure 4.11 (1) shows an example measuring circuit with the negative resistance suggested by the oscillator manufacturer. Note that if the negative resistance of the circuit is less than that suggested by the oscillator manufacturer, it may be difficult to start the main oscillator.

If it is determined that oscillation is not occurring because the negative resistance is lower than the level suggested by the oscillator manufacturer, the circuit may be modified as shown in figure 4.11 (2) through (4). Which of the modification suggestions to use and the capacitor capacitance should be decided based upon an evaluation of factors such as the negative resistance and the frequency deviation.





Figure 4.11 Negative Resistance Measurement and Circuit Modification Suggestions

4.5.1 Definition of Oscillation Stabilization Wait Time

Figure 4.12 shows the oscillation waveform (OSC₂), system clock (ϕ), and microcomputer operating mode when a transition is made from standby mode, watch mode, or subactive mode, to active (high-speed/medium-speed) mode, with an oscillator element connected to the system clock oscillator.

As shown in figure 4.12, as the system clock oscillator is halted in standby mode, watch mode, and subactive mode, when a transition is made to active (high-speed/medium-speed) mode, the sum of the following two times (oscillation stabilization time and wait time) is required.

1. Oscillation Stabilization Time (t_{rc})

The time from the point at which the system clock oscillator oscillation waveform starts to change when an interrupt is generated, until the amplitude of the oscillation waveform increases and the oscillation frequency stabilizes.

2. Wait Time

The time required for the CPU and peripheral functions to begin operating after the oscillation waveform frequency and system clock have stabilized.

The wait time setting is selected with standby timer select bits 2 to 0 (STS2 to STS0) (bits 6 to 4 in system control register 1 (SYSCR1)).



Figure 4.12 Oscillation Stabilization Wait Time

When standby mode, watch mode, or subactive mode is cleared by an interrupt or reset, and a transition is made to active (high-speed/medium-speed) mode, the oscillation waveform begins to change at the point at which the interrupt is accepted. Therefore, when an oscillator element is connected in standby mode, watch mode, or subactive mode, since the system clock oscillator is halted, the time from the point at which this oscillation waveform starts to change until the amplitude of the oscillation waveform increases and the oscillation frequency stabilizes—that is, the oscillation stabilization time—is required.

The oscillation stabilization time in the case of these state transitions is the same as the oscillation stabilization time at power-on (the time from the point at which the power supply voltage reaches the prescribed level until the oscillation stabilizes), specified by "oscillation stabilization time t_{rc} " in the AC characteristics.

Meanwhile, once the system clock has halted, a wait time of at least 8 states is necessary in order for the CPU and peripheral functions to operate normally.

Thus, the time required from interrupt generation until operation of the CPU and peripheral functions is the sum of the above described oscillation stabilization time and wait time. This total time is called the oscillation stabilization wait time, and is expressed by equation (1) below.

Oscillation stabilization wait time = oscillation stabilization time + wait time = t_{rc} + (8 to 131,072 states)(1)

Therefore, when a transition is made from standby mode, watch mode, or subactive mode, to active (high-speed/medium-speed) mode, with an oscillator element connected to the system clock oscillator, careful evaluation must be carried out on the installation circuit before deciding on the oscillation stabilization wait time. In particular, since the oscillation stabilization time is affected by installation circuit constants, stray capacitance, and so forth, suitable constants should be determined in consultation with the oscillator element manufacturer.

4.5.2 Notes on Use of Crystal Oscillator Element (Excluding Ceramic Oscillator Element)

When a microcomputer operates, the internal power supply potential fluctuates slightly in synchronization with the system clock. Depending on the individual crystal oscillator element characteristics, the oscillation waveform amplitude may not be sufficiently large immediately after the oscillation stabilization wait time, making the oscillation waveform susceptible to influence by fluctuations in the power supply potential. In this state, the oscillation waveform may be disrupted, leading to an unstable system clock and erroneous operation of the microcomputer.

If erroneous operation occurs, change the setting of standby timer select bits 2 to 0 (STS2 to STS0) (bits 6 to 4 in system control register 1 (SYSCR1)) to give a longer wait time.

For example, if erroneous operation occurs with a wait time setting of 16 states, check the operation with a wait time setting of 8,192 states or more.

If the same kind of erroneous operation occurs after a reset as after a state transition, hold the $\overline{\text{RES}}$ pin low for a longer period.



Section 5 Power-Down Modes

5.1 Overview

The H8/3827R Group has nine modes of operation after a reset. These include eight power-down modes, in which power dissipation is significantly reduced. Table 5.1 gives a summary of the nine operating modes.

Table 5.1 Operating Modes

Operating Mode	Description
Active (high-speed) mode	The CPU and all on-chip peripheral functions are operable on the system clock in high-speed operation
Active (medium-speed) mode	The CPU and all on-chip peripheral functions are operable on the system clock in low-speed operation
Subactive mode	The CPU is operable on the subclock in low-speed operation
Sleep (high-speed) mode	The CPU halts. On-chip peripheral functions are operable on the system clock
Sleep (medium-speed) mode	The CPU halts. On-chip peripheral functions operate at a frequency of 1/64, 1/32, 1/16, or 1/8 of the system clock frequency
Subsleep mode	The CPU halts. The time-base function of timer A, timer C, timer G, timer F,WDT, SCI3-1, SCI3-2, AEC, and LCD controller/driver are operable on the subclock
Watch mode	The CPU halts. The time-base function of timer A, timer F, timer G, AEC, and LCD controller/driver are operable on the subclock
Standby mode	The CPU and all on-chip peripheral functions halt
Module standby mode	Individual on-chip peripheral functions specified by software enter standby mode and halt

Of these nine operating modes, all but the active (high-speed) mode are power-down modes. In this section the two active modes (high-speed and medium speed) will be referred to collectively as active mode.

Figure 5.1 shows the transitions among these operation modes. Table 5.2 indicates the internal states in each mode.



Figure 5.1 Mode Transition Diagram

		Active Mode		Sleep Mode					
Function		High- Speed	Medium- Speed	High- Speed	Medium- Speed	Watch Mode	Subactive Mode	Subsleep Mode	Standby Mode
System clo	ck oscillator	Functions	Functions	Functions	Functions	Halted	Halted	Halted	Halted
Subclock of	scillator	Functions	Functions	Functions	Functions	Functions	Functions	Functions	Functions
CPU	Instructions	Functions	Functions	Halted	Halted	Halted	Functions	Halted	Halted
operations	RAM	_		Retained	Retained	Retained	-	Retained	Retained
	Registers	_							
	I/O ports								Retained*1
External	IRQ ₀	Functions	Functions	Functions	Functions		Functions	Functions	Functions
interrupts	IRQ ₁					Retained*6			
	IRQ ₂								Retained*6
	IRQ ₃	_							
	IRQ ₄								
	WKP ₀	Functions	Functions	Functions	Functions	Functions	Functions	Functions	Functions
	WKP ₁								
	WKP ₂	_							
	WKP ₃								
	WKP ₄	_							
	WKP ₅	_							
	WKP ₆								
	WKP ₇								
Peripheral	Timer A	Functions	Functions	Functions	Functions	Functions ^{*5}	Functions ^{*5}	Functions ^{*5}	Retained
functions	Asynchronous counter					Functions*8	Functions	Functions	Functions*
	Timer C	_				Retained	Functions/ Retained ^{*2}	Functions/ Retained ^{*2}	Retained
	WDT	_					Functions/ Retained ^{*7}	Retained	-
	Timer G, Timer F	-				Functions/ Retained ^{*9}	Functions/ Retained ^{*2}	Functions/ Retained ^{*2}	-
	SCI3-1	-				Reset	Functions/	Functions/	Reset
	SCI3-2	-					Retained*3	Retained ^{*3}	
	PWM	-				Retained	Retained	Retained	Retained
	A/D converter	-				Retained	Retained	Retained	Retained
	LCD	-				Functions/ Retained ^{*4}	Functions/ Retained ^{*4}	Functions/ Retained ^{*4}	Retained

Table 5.2 **Internal State in Each Operating Mode**

2. Functions if an external clock or the $\phi_W/4$ internal clock is selected; otherwise halted and retained.

3. Functions if $\phi_W/2$ is selected as the internal clock; otherwise halted and retained.

4. Functions if ϕ_W , $\phi_W/2$ or $\phi_W/4$ is selected as the operating clock; otherwise halted and retained.

5. Functions if the timekeeping time-base function is selected.

6. External interrupt requests are ignored. Interrupt request register contents are not altered.

7. Functions if $\phi_W/32$ is selected as the internal clock; otherwise halted and retained.

8. Incrementing is possible, but interrupt generation is not.

9. Functions if the $\phi_W/4$ internal clock is selected; otherwise halted and retained.

5.1.1 System Control Registers

The operation mode is selected using the system control registers described in table 5.3.

Table 5.3 System Control Registers

Name	Abbr.	R/W	Initial Value	Address
System control register 1	SYSCR1	R/W	H'07	H'FFF0
System control register 2	SYSCR2	R/W	H'F0	H'FFF1

1. System Control Register 1 (SYSCR1)

Bit	7	6	5	4	3	2	1	0
	SSBY	STS2	STS1	STS0	LSON	_	MA1	MA0
Initial value	0	0	0	0	0	1	1	1
Read/Write	R/W	R/W	R/W	R/W	R/W	—	R/W	R/W

SYSCR1 is an 8-bit read/write register for control of the power-down modes.

Upon reset, SYSCR1 is initialized to H'07.

Bit 7: Software standby (SSBY)

This bit designates transition to standby mode or watch mode.

Bit 7 SSBY	Description
0	When a SLEEP instruction is executed in active mode, (initial value) a transition is made to sleep mode
	 When a SLEEP instruction is executed in subactive mode, a transition is made to subsleep mode
1	When a SLEEP instruction is executed in active mode, a transition is made to standby mode or watch mode
	 When a SLEEP instruction is executed in subactive mode, a transition is made to watch mode

Bits 6 to 4: Standby timer select 2 to 0 (STS2 to STS0)

These bits designate the time the CPU and peripheral modules wait for stable clock operation after exiting from standby mode or watch mode to active mode due to an interrupt. The designation should be made according to the operating frequency so that the waiting time is at least equal to the oscillation settling time.

Bit 6 STS2	Bit 5 STS1	Bit 4 STS0	Description	
0	0	0	Wait time = 8,192 states	(initial value)
0	0	1	Wait time = 16,384 states	
0	1	0	Wait time = 32,768 states	
0	1	1	Wait time = 65,536 states	
1	0	0	Wait time = 131,072 states	
1	0	1	Wait time = 2 states	(External clock mode)
1	1	0	Wait time = 8 states	
1	1	1	Wait time = 16 states	

Note: In the case that external clock is input, set up the "Standby timer select" selection to External clock mode before Mode Transition. Also, do not set up to external clock mode, in the case that it does not use external clock.

Bit 3: Low speed on flag (LSON)

This bit chooses the system clock (ϕ) or subclock (ϕ_{SUB}) as the CPU operating clock when watch mode is cleared. The resulting operation mode depends on the combination of other control bits and interrupt input.

Bit 3		
LSON	Description	
0	The CPU operates on the system clock (ϕ)	(initial value)
1	The CPU operates on the subclock (ϕ_{SUB})	

Bits 2: Reserved bits

Bit 2 is reserved: it is always read as 1 and cannot be modified.

Bits 1 and 0: Active (medium-speed) mode clock select (MA1, MA0)

Bits 1 and 0 choose $\phi_{OSC}/128$, $\phi_{OSC}/64$, $\phi_{OSC}/32$, or $\phi_{OSC}/16$ as the operating clock in active (medium-speed) mode and sleep (medium-speed) mode. MA1 and MA0 should be written in active (high-speed) mode or subactive mode.

Bit 1	Bit 0		
MA1	MA0	Description	
0	0	фоsc/16	
0	1	фоsc/32	
1	0	φosc/64	
1	1	φ _{OSC} /128	(initial value)

2. System Control Register 2 (SYSCR2)

Bit	7	6	5	4	3	2	1	0
	—	—	—	NESEL	DTON	MSON	SA1	SA0
Initial value	1	1	1	1	0	0	0	0
Read/Write	_	_	_	R/W	R/W	R/W	R/W	R/W

SYSCR2 is an 8-bit read/write register for power-down mode control.

Bits 7 to 5: Reserved bits

These bits are reserved; they are always read as 1, and cannot be modified.

Bit 4: Noise elimination sampling frequency select (NESEL)

This bit selects the frequency at which the watch clock signal (ϕ_W) generated by the subclock pulse generator is sampled, in relation to the oscillator clock (ϕ_{OSC}) generated by the system clock pulse generator. When $\phi_{OSC} = 2$ to 16 MHz, clear NESEL to 0.

Bit 4 NESEL	Description	
0	Sampling rate is $\phi_{OSC}/16$	
1	Sampling rate is $\phi_{OSC}/4$	(initial value)

Bit 3: Direct transfer on flag (DTON)

This bit designates whether or not to make direct transitions among active (high-speed), active (medium-speed) and subactive mode when a SLEEP instruction is executed. The mode to which the transition is made after the SLEEP instruction is executed depends on a combination of this and other control bits.

Bit 3 DTON	Description
0	• When a SLEEP instruction is executed in active mode, (initial value) a transition is made to standby mode, watch mode, or sleep mode
	 When a SLEEP instruction is executed in subactive mode, a transition is made to watch mode or subsleep mode
1	 When a SLEEP instruction is executed in active (high-speed) mode, a direct transition is made to active (medium-speed) mode if SSBY = 0, MSON = 1, and LSON = 0, or to subactive mode if SSBY = 1, TMA3 = 1, and LSON = 1
	 When a SLEEP instruction is executed in active (medium-speed) mode, a direct transition is made to active (high-speed) mode if SSBY = 0, MSON = 0, and LSON = 0, or to subactive mode if SSBY = 1, TMA3 = 1, and LSON = 1
	 When a SLEEP instruction is executed in subactive mode, a direct transition is made to active (high-speed) mode if SSBY = 1, TMA3 = 1, LSON = 0, and MSON = 0, or to active (medium-speed) mode if SSBY = 1, TMA3 = 1, LSON = 0, and MSON = 1

Bit 2: Medium speed on flag (MSON)

After standby, watch, or sleep mode is cleared, this bit selects active (high-speed) or active (medium-speed) mode.

Bit 2 MSON	Description	
0	Operation in active (high-speed) mode	(initial value)
1	Operation in active (medium-speed) mode	

Bits 1 and 0: Subactive mode clock select (SA1 and SA0)

These bits select the CPU clock rate ($\phi_W/2$, $\phi_W/4$, or $\phi_W/8$) in subactive mode. SA1 and SA0 cannot be modified in subactive mode.

Bit 1 SA1	Bit 0 SA0	Description	
0	0	φ _W /8	(initial value)
0	1	φ _W /4	
1	*	φ _w /2	

* : Don't care

5.2 Sleep Mode

5.2.1 Transition to Sleep Mode

1. Transition to Sleep (High-Speed) Mode

The system goes from active mode to sleep (high-speed) mode when a SLEEP instruction is executed while the SSBY and LSON bits in SYSCR1 are cleared to 0, the MSON and DTON bits in SYSCR2 are cleared to 0. In sleep mode CPU operation is halted but the on-chip peripheral functions. CPU register contents are retained.

2. Transition to Sleep (Medium-Speed) Mode

The system goes from active mode to sleep (medium-speed) mode when a SLEEP instruction is executed while the SSBY and LSON bits in SYSCR1 are cleared to 0, the MSON bit in SYSCR2 is set to 1, and the DTON bit in SYSCR2 is cleared to 0. In sleep (medium-speed) mode, as in sleep (high-speed) mode, CPU operation is halted but the on-chip peripheral functions are operational. The clock frequency in sleep (medium-speed) mode is determined by the MA1 and MA0 bits in SYSCR1. CPU register contents are retained.

Furthermore, it sometimes acts with half state early timing at the time of transition to sleep (medium-speed) mode.



5.2.2 Clearing Sleep Mode

Sleep mode is cleared by any interrupt (timer A, timer C, timer F, timer G, asynchronous counter, IRQ_4 to IRQ_0 , WKP_7 to WKP_0 , SCI3-1, SCI3-2, A/D converter, or), or by input at the \overline{RES} pin.

• Clearing by interrupt

When an interrupt is requested, sleep mode is cleared and interrupt exception handling starts. A transition is made from sleep (high-speed) mode to active (high-speed) mode, or from sleep (medium-speed) mode to active (medium-speed) mode. Sleep mode is not cleared if the I bit of the condition code register (CCR) is set to 1 or the particular interrupt is disabled in the interrupt enable register.

Interrupt signal and system clock are mutually asynchronous. Synchronization error time in a maximum is $2/\phi$ (s).

• Clearing by RES input

When the $\overline{\text{RES}}$ pin goes low, the CPU goes into the reset state and sleep mode is cleared.

5.2.3 Clock Frequency in Sleep (Medium-Speed) Mode

Operation in sleep (medium-speed) mode is clocked at the frequency designated by the MA1 and MA0 bits in SYSCR1.

5.3 Standby Mode

5.3.1 Transition to Standby Mode

The system goes from active mode to standby mode when a SLEEP instruction is executed while the SSBY bit in SYSCR1 is set to 1, the LSON bit in SYSCR1 is cleared to 0, and bit TMA3 in TMA is cleared to 0. In standby mode the clock pulse generator stops, so the CPU and on-chip peripheral modules stop functioning, but as long as the rated voltage is supplied, the contents of CPU registers, on-chip RAM, and some on-chip peripheral module registers are retained. On-chip RAM contents will be further retained down to a minimum RAM data retention voltage. The I/O ports go to the high-impedance state.

5.3.2 Clearing Standby Mode

Standby mode is cleared by an interrupt (IRQ₁ or IRQ₀), WKP₇ to WKP₀ or by input at the $\overline{\text{RES}}$ pin.

• Clearing by interrupt

When an interrupt is requested, the system clock pulse generator starts. After the time set in bits STS2 to STS0 in SYSCR1 has elapsed, a stable system clock signal is supplied to the entire chip, standby mode is cleared, and interrupt exception handling starts. Operation resumes in active (high-speed) mode if MSON = 0 in SYSCR2, or active (medium-speed) mode if MSON = 1. Standby mode is not cleared if the I bit of CCR is set to 1 or the particular interrupt is disabled in the interrupt enable register.

• Clearing by $\overline{\text{RES}}$ input

When the $\overline{\text{RES}}$ pin goes low, the system clock pulse generator starts. After the pulse generator output has stabilized, if the $\overline{\text{RES}}$ pin is driven high, the CPU starts reset exception handling. Since system clock signals are supplied to the entire chip as soon as the system clock pulse generator starts functioning, the $\overline{\text{RES}}$ pin should be kept at the low level until the pulse generator output stabilizes.



5.3.3 Oscillator Settling Time after Standby Mode is Cleared

Bits STS2 to STS0 in SYSCR1 should be set as follows.

• When a crystal oscillator is used

The table below gives settings for various operating frequencies. Set bits STS2 to STS0 for a waiting time at least as long as the oscillation settling time.

STS2	STS1	STS0	Waiting Time	2 MHz	1 MHz
0	0	0	8,192 states	4.1	8.2
0	0	1	16,384 states	8.2	16.4
0	1	0	32,768 states	16.4	32.8
0	1	1	65,536 states	32.8	65.5
1	0	0	131,072 states	65.5	131.1
1	0	1	2 states (Use prohibited)	0.001	0.002
1	1	0	8 states	0.004	0.008
1	1	1	16 states	0.008	0.016

 Table 5.4
 Clock Frequency and Settling Time (Times are in ms)

• When an external clock is used

STS2 = 1, STS1 = 0, and STS0 = 1 should be set. Other values possible use, but CPU sometimes will start operation before waiting time completion.

5.3.4 Standby Mode Transition and Pin States

When a SLEEP instruction is executed in active (high-speed) mode or active (medium-speed) mode while bit SSBY is set to 1 and bit LSON is cleared to 0 in SYSCR1, and bit TMA3 is cleared to 0 in TMA, a transition is made to standby mode. At the same time, pins go to the high-impedance state (except pins for which the pull-up MOS is designated as on). Figure 5.2 shows the timing in this case.



Figure 5.2 Standby Mode Transition and Pin States

5.3.5 Notes on External Input Signal Changes before/after Standby Mode

- When external input signal changes before/after standby mode or watch mode
 When an external input signal such as IRQ or WKP is input, both the high- and low-level
 widths of the signal must be at least two cycles of system clock φ or subclock φ_{SUB} (referred
 to together in this section as the internal clock). As the internal clock stops in standby mode
 and watch mode, the width of external input signals requires careful attention when a transition
 is made via these operating modes. Ensure that external input signals conform to the conditions
 stated in 3, Recommended timing of external input signals, below
- 2. When external input signals cannot be captured because internal clock stops The case of falling edge capture is illustrated in figure 5.3

As shown in the case marked "Capture not possible," when an external input signal falls immediately after a transition to active (high-speed or medium-speed) mode or subactive mode, after oscillation is started by an interrupt via a different signal, the external input signal cannot be captured if the high-level width at that point is less than 2 t_{evc} or 2 t_{subevc} .

3. Recommended timing of external input signals

To ensure dependable capture of an external input signal, high- and low-level signal widths of at least 2 t_{cyc} or 2 t_{subcyc} are necessary before a transition is made to standby mode or watch mode, as shown in "Capture possible: case 1."

External input signal capture is also possible with the timing shown in "Capture possible: case 2" and "Capture possible: case 3," in which a 2 t_{cvc} or 2 t_{subcvc} level width is secured.





4. Input pins to which these notes apply: \overline{IRQ}_4 to \overline{IRQ}_0 , \overline{WKP}_7 to \overline{WKP}_0 , \overline{ADTRG} , TMIC, TMIF, TMIG

5.4 Watch Mode

5.4.1 Transition to Watch Mode

The system goes from active or subactive mode to watch mode when a SLEEP instruction is executed while the SSBY bit in SYSCR1 is set to 1 and bit TMA3 in TMA is set to 1.

In watch mode, operation of on-chip peripheral modules is halted except for timer A, timer F, timer G, AEC and the LCD controller/driver (for which operation or halting can be set) is halted. As long as a minimum required voltage is applied, the contents of CPU registers, the on-chip RAM and some registers of the on-chip peripheral modules, are retained. I/O ports keep the same states as before the transition.

5.4.2 Clearing Watch Mode

Watch mode is cleared by an interrupt (timer A, timer F, timer G, IRQ_0 , or WKP_7 to WKP_0) or by input at the \overline{RES} pin.

• Clearing by interrupt

When watch mode is cleared by interrupt, the mode to which a transition is made depends on the settings of LSON in SYSCR1 and MSON in SYSCR2. If both LSON and MSON are cleared to 0, transition is to active (high-speed) mode; if LSON = 0 and MSON = 1, transition is to active (medium-speed) mode; if LSON = 1, transition is to subactive mode. When the transition is to active mode, after the time set in SYSCR1 bits STS2 to STS0 has elapsed, a stable clock signal is supplied to the entire chip, watch mode is cleared, and interrupt exception handling starts. Watch mode is not cleared if the I bit of CCR is set to 1 or the particular interrupt is disabled in the interrupt enable register.

• Clearing by $\overline{\text{RES}}$ input

Clearing by $\overline{\text{RES}}$ pin is the same as for standby mode; see 2. Clearing by $\overline{\text{RES}}$ pin in section 5.3.2, Clearing Standby Mode.

5.4.3 Oscillator Settling Time after Watch Mode is Cleared

The waiting time is the same as for standby mode; see section 5.3.3, Oscillator Settling Time after Standby Mode is Cleared.



5.4.4 Notes on External Input Signal Changes before/after Watch Mode

See section 5.3.5, Notes on External Input Signal Changes before/after Standby Mode.

5.5 Subsleep Mode

5.5.1 Transition to Subsleep Mode

The system goes from subactive mode to subsleep mode when a SLEEP instruction is executed while the SSBY bit in SYSCR1 is cleared to 0, LSON bit in SYSCR1 is set to 1, and TMA3 bit in TMA is set to 1. In subsleep mode, operation of on-chip peripheral modules other than the A/D converter WDT and PWM is halted. As long as a minimum required voltage is applied, the contents of CPU registers, the on-chip RAM and some registers of the on-chip peripheral modules are retained. I/O ports keep the same states as before the transition.

5.5.2 Clearing Subsleep Mode

Subsleep mode is cleared by an interrupt (timer A, timer C, timer F, timer G, asynchronous counter, SCI3-2, SCI3-1, IRQ_4 to IRQ_0 , WKP_7 to WKP_0) or by a low input at the \overline{RES} pin.

• Clearing by interrupt

When an interrupt is requested, subsleep mode is cleared and interrupt exception handling starts. Subsleep mode is not cleared if the I bit of CCR is set to 1 or the particular interrupt is disabled in the interrupt enable register.

Interrupt signal and system clock are mutually asynchronous. Synchronization error time in a maximum is $2/\phi_{SUB}$ (s).

• Clearing by RES input

Clearing by $\overline{\text{RES}}$ pin is the same as for standby mode; see 2. Clearing by $\overline{\text{RES}}$ pin in section 5.3.2, Clearing Standby Mode.

5.6 Subactive Mode

5.6.1 Transition to Subactive Mode

Subactive mode is entered from watch mode if a timer A, timer F, timer G, IRQ_0 , or WKP_7 to WKP_0 interrupt is requested while the LSON bit in SYSCR1 is set to 1. From subsleep mode, subactive mode is entered if a timer A, timer C, timer F, timer G, asynchronous counter, SCI3-1, SCI3-2, IRQ_4 to IRQ_0 , or WKP_7 to WKP_0 interrupt is requested. A transition to subactive mode does not take place if the I bit of CCR is set to 1 or the particular interrupt is disabled in the interrupt enable register.

5.6.2 Clearing Subactive Mode

Subactive mode is cleared by a SLEEP instruction or by a low input at the $\overline{\text{RES}}$ pin.

• Clearing by SLEEP instruction

If a SLEEP instruction is executed while the SSBY bit in SYSCR1 is set to 1 and TMA3 bit in TMA is set to 1, subactive mode is cleared and watch mode is entered. If a SLEEP instruction is executed while SSBY = 0 and LSON = 1 in SYSCR1 and TMA3 = 1 in TMA, subsleep mode is entered. Direct transfer to active mode is also possible; see section 5.8, Direct Transfer, below.

• Clearing by $\overline{\text{RES}}$ pin

Clearing by $\overline{\text{RES}}$ pin is the same as for standby mode; see 2. Clearing by $\overline{\text{RES}}$ pin in section 5.3.2.

5.6.3 Operating Frequency in Subactive Mode

The operating frequency in subactive mode is set in bits SA1 and SA0 in SYSCR2. The choices are $\phi_W/2$, $\phi_W/4$, and $\phi_W/8$.

5.7 Active (Medium-Speed) Mode

5.7.1 Transition to Active (Medium-Speed) Mode

If the $\overline{\text{RES}}$ pin is driven low, active (medium-speed) mode is entered. If the LSON bit in SYSCR2 is set to 1 while the LSON bit in SYSCR1 is cleared to 0, a transition to active (medium-speed) mode results from IRQ₀, IRQ₁, or WKP₇ to WKP₀ interrupts in standby mode, timer A, timer F, timer G, IRQ₀, or WKP₇ to WKP₀ interrupts in watch mode, or any interrupt in sleep mode. A transition to active (medium-speed) mode does not take place if the I bit of CCR is set to 1 or the particular interrupt is disabled in the interrupt enable register.

Furthermore, it sometimes acts with half state early timing at the time of transition to active (medium-speed) mode.

5.7.2 Clearing Active (Medium-Speed) Mode

Active (medium-speed) mode is cleared by a SLEEP instruction.

• Clearing by SLEEP instruction

A transition to standby mode takes place if the SLEEP instruction is executed while the SSBY bit in SYSCR1 is set to 1, the LSON bit in SYSCR1 is cleared to 0, and the TMA3 bit in TMA is cleared to 0. The system goes to watch mode if the SSBY bit in SYSCR1 is set to 1 and bit TMA3 in TMA is set to 1 when a SLEEP instruction is executed.

When both SSBY and LSON are cleared to 0 in SYSCR1 and a SLEEP instruction is executed, sleep mode is entered. Direct transfer to active (high-speed) mode or to subactive mode is also possible. See section 5.8, Direct Transfer, below for details.

• Clearing by $\overline{\text{RES}}$ pin

When the $\overline{\text{RES}}$ pin is driven low, a transition is made to the reset state and active (medium-speed) mode is cleared.

5.7.3 Operating Frequency in Active (Medium-Speed) Mode

Operation in active (medium-speed) mode is clocked at the frequency designated by the MA1 and MA0 bits in SYSCR1.

5.8 Direct Transfer

5.8.1 Overview of Direct Transfer

The CPU can execute programs in three modes: active (high-speed) mode, active (medium-speed) mode, and subactive mode. A direct transfer is a transition among these three modes without the stopping of program execution. A direct transfer can be made by executing a SLEEP instruction while the DTON bit in SYSCR2 is set to 1. After the mode transition, direct transfer interrupt exception handling starts.

If the direct transfer interrupt is disabled in interrupt enable register 2, a transition is made instead to sleep mode or watch mode. Note that if a direct transition is attempted while the I bit in CCR is set to 1, sleep mode or watch mode will be entered, and it will be impossible to clear the resulting mode by means of an interrupt.

- Direct transfer from active (high-speed) mode to active (medium-speed) mode When a SLEEP instruction is executed in active (high-speed) mode while the SSBY and LSON bits in SYSCR1 are cleared to 0, the MSON bit in SYSCR2 is set to 1, and the DTON bit in SYSCR2 is set to 1, a transition is made to active (medium-speed) mode via sleep mode.
- Direct transfer from active (medium-speed) mode to active (high-speed) mode When a SLEEP instruction is executed in active (medium-speed) mode while the SSBY and LSON bits in SYSCR1 are cleared to 0, the MSON bit in SYSCR2 is cleared to 0, and the DTON bit in SYSCR2 is set to 1, a transition is made to active (high-speed) mode via sleep mode.
- Direct transfer from active (high-speed) mode to subactive mode When a SLEEP instruction is executed in active (high-speed) mode while the SSBY and LSON bits in SYSCR1 are set to 1, the DTON bit in SYSCR2 is set to 1, and the TMA3 bit in TMA is set to 1, a transition is made to subactive mode via watch mode.
- Direct transfer from subactive mode to active (high-speed) mode When a SLEEP instruction is executed in subactive mode while the SSBY bit in SYSCR1 is set to 1, the LSON bit in SYSCR1 is cleared to 0, the MSON bit in SYSCR2 is cleared to 0, the DTON bit in SYSCR2 is set to 1, and the TMA3 bit in TMA is set to 1, a transition is made directly to active (high-speed) mode via watch mode after the waiting time set in SYSCR1 bits STS2 to STS0 has elapsed.



- Direct transfer from active (medium-speed) mode to subactive mode When a SLEEP instruction is executed in active (medium-speed) while the SSBY and LSON bits in SYSCR1 are set to 1, the DTON bit in SYSCR2 is set to 1, and the TMA3 bit in TMA is set to 1, a transition is made to subactive mode via watch mode.
- Direct transfer from subactive mode to active (medium-speed) mode
 When a SLEEP instruction is executed in subactive mode while the SSBY bit in SYSCR1 is set to 1, the LSON bit in SYSCR1 is cleared to 0, the MSON bit in SYSCR2 is set to 1, the DTON bit in SYSCR2 is set to 1, and the TMA3 bit in TMA is set to 1, a transition is made directly to active (medium-speed) mode via watch mode after the waiting time set in SYSCR1 bits STS2 to STS0 has elapsed.

5.8.2 Direct Transition Times

1. Time for Direct Transition from Active (High-Speed) Mode to Active (Medium-Speed) Mode

A direct transition from active (high-speed) mode to active (medium-speed) mode is performed by executing a SLEEP instruction in active (high-speed) mode while bits SSBY and LSON are both cleared to 0 in SYSCR1, and bits MSON and DTON are both set to 1 in SYSCR2. The time from execution of the SLEEP instruction to the end of interrupt exception handling (the direct transition time) is given by equation (1) below.

Direct transition time = { (Number of SLEEP instruction execution states) + (number of internal processing states) } × (tcyc before transition) + (number of interrupt exception handling execution states) × (tcyc after transition)

Example: Direct transition time = $(2 + 1) \times 2 \text{tosc} + 14 \times 16 \text{tosc} = 230 \text{tosc}$ (when $\phi/8$ is selected as the CPU operating clock)

Notation:

- tosc: OSC clock cycle time
- tcyc: System clock (ϕ) cycle time

2. Time for Direct Transition from Active (Medium-Speed) Mode to Active (High-Speed) Mode

A direct transition from active (medium-speed) mode to active (high-speed) mode is performed by executing a SLEEP instruction in active (medium-speed) mode while bits SSBY and LSON are both cleared to 0 in SYSCR1, and bit MSON is cleared to 0 and bit DTON is set to 1 in SYSCR2. The time from execution of the SLEEP instruction to the end of interrupt exception handling (the direct transition time) is given by equation (2) below.

Direct transition time = { (Number of SLEEP instruction execution states) + (number of internal processing states) } × (tcyc before transition) + (number of interrupt exception handling execution states) × (tcyc after transition)

Example: Direct transition time = $(2 + 1) \times 16$ tosc + 14×2 tosc = 76tosc (when $\phi/8$ is selected as the CPU operating clock)

Notation:

tosc: OSC clock cycle time tcyc: System clock (φ) cycle time

3. Time for Direct Transition from Subactive Mode to Active (High-Speed) Mode

A direct transition from subactive mode to active (high-speed) mode is performed by executing a SLEEP instruction in subactive mode while bit SSBY is set to 1 and bit LSON is cleared to 0 in SYSCR1, bit MSON is cleared to 0 and bit DTON is set to 1 in SYSCR2, and bit TMA3 is set to 1 in TMA. The time from execution of the SLEEP instruction to the end of interrupt exception handling (the direct transition time) is given by equation (3) below.

Direct transition time = { (Number of SLEEP instruction execution states) + (number of in	ternal
processing states) $\} \times (tsubcyc before transition) + \{ (wait time set$	in
STS2 to STS0) + (number of interrupt exception handling execution	on
states) } × (tcyc after transition)	(3)

Example: Direct transition time = $(2 + 1) \times 8tw + (8192 + 14) \times 2tosc = 24tw + 16412tosc$ (when $\frac{\phi w}{8}$ is selected as the CPU operating clock, and wait time = 8192 states)

Notation:

tosc:	OSC clock cycle time	

tw: Watch clock cycle time

tcyc: System clock (ϕ) cycle time

tsubcyc: Subclock (ϕ_{SUB}) cycle time

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4. Time for Direct Transition from Subactive Mode to Active (Medium-Speed) Mode

A direct transition from subactive mode to active (medium-speed) mode is performed by executing a SLEEP instruction in subactive mode while bit SSBY is set to 1 and bit LSON is cleared to 0 in SYSCR1, bits MSON and DTON are both set to 1 in SYSCR2, and bit TMA3 is set to 1 in TMA. The time from execution of the SLEEP instruction to the end of interrupt exception handling (the direct transition time) is given by equation (4) below.

Direct transition time =	{ (Number of SLEEP instruction execution states) + (r	number of internal
	processing states) $\} \times ($ tsubcyc before transition) + { (v	wait time set in
	STS2 to STS0) + (number of interrupt exception handl	ing execution
	states) $\} \times (tcyc after transition)$	(4)

Example: Direct transition time = $(2 + 1) \times 8$ tw + $(8192 + 14) \times 16$ tosc = 24tw + 131296tosc (when ϕ w/8 or ϕ 8 is selected as the CPU operating clock, and wait time = 8192 states)

Notation:

tosc:	OSC clock cycle time
tw:	Watch clock cycle time
tcyc:	System clock (ϕ) cycle time
tsubcyc:	Subclock (ϕ_{SUB}) cycle time

5.8.3 Notes on External Input Signal Changes before/after Direct Transition

- Direct transition from active (high-speed) mode to subactive mode Since the mode transition is performed via watch mode, see section 5.3.5, Notes on External Input Signal Changes before/after Standby Mode.
- Direct transition from active (medium-speed) mode to subactive mode Since the mode transition is performed via watch mode, see section 5.3.5, Notes on External Input Signal Changes before/after Standby Mode.
- Direct transition from subactive mode to active (high-speed) mode Since the mode transition is performed via watch mode, see section 5.3.5, Notes on External Input Signal Changes before/after Standby Mode.
- Direct transition from subactive mode to active (medium-speed) mode Since the mode transition is performed via watch mode, see section 5.3.5, Notes on External Input Signal Changes before/after Standby Mode.

5.9 Module Standby Mode

5.9.1 Setting Module Standby Mode

Module standby mode is set for individual peripheral functions. All the on-chip peripheral modules can be placed in module standby mode. When a module enters module standby mode, the system clock supply to the module is stopped and operation of the module halts. This state is identical to standby mode.

Module standby mode is set for a particular module by setting the corresponding bit to 0 in clock stop register 1 (CKSTPR1) or clock stop register 2 (CKSTPR2). (See table 5.5.)

5.9.2 Clearing Module Standby Mode

Module standby mode is cleared for a particular module by setting the corresponding bit to 1 in clock stop register 1 (CKSTPR1) or clock stop register 2 (CKSTPR2). (See table 5.5.)

Following a reset, clock stop register 1 (CKSTPR1) and clock stop register 2 (CKSTPR2) are both initialized to H'FF.



Register Name	Bit Name		Operation	
CKSTPR1	TACKSTP	1	Timer A module standby mode is cleared	
		0	Timer A is set to module standby mode	
	TCCKSTP	1	Timer C module standby mode is cleared	
		0	Timer C is set to module standby mode	
	TFCKSTP	1	Timer F module standby mode is cleared	
		0	Timer F is set to module standby mode	
	TGCKSTP	1	Timer G module standby mode is cleared	
		0	Timer G is set to module standby mode	
	ADCKSTP	1	A/D converter module standby mode is cleared	
		0	A/D converter is set to module standby mode	
	S32CKSTP	1	SCI3-2 module standby mode is cleared	
		0	SCI3-2 is set to module standby mode	
	S31CKSTP	1	SCI3-1 module standby mode is cleared	
		0	SCI3-1 is set to module standby mode	
CKSTPR2	LDCKSTP	1	LCD module standby mode is cleared	
		0	LCD is set to module standby mode	
	PWCKSTP	1	PWM module standby mode is cleared	
		0	PWM is set to module standby mode	
	WDCKSTP	1	Watchdog timer module standby mode is cleared	
		0	Watchdog timer is set to module standby mode	
	AECKSTP	1	Asynchronous event counter module standby mode is cleared	
		0	Asynchronous event counter is set to module standby mode	

Table 5.5	Setting and Clearing	Module Standby	Mode by Clock	Stop Register
	seeing and erearing	1.10 4410 8000000		Stop register

Note: For details of module operation, see the sections on the individual modules.

5.9.3 Usage Note

If, due to the timing with which a peripheral module issues interrupt requests, the module in question is set to module standby mode before an interrupt is processed, the module will stop with the interrupt request still pending. In this situation, interrupt processing will be repeated indefinitely unless interrupts are prohibited.

It is therefore necessary to ensure that no interrupts are generated when a module is set to module standby mode. The surest way to do this is to specify the module standby mode setting only when interrupts are prohibited (interrupts prohibited using the interrupt enable register or interrupts masked using bit CCR-I).


Section 6 ROM

6.1 Overview

The H8/3822R, H8/38322, and H8/38422 have 16 Kbytes of on-chip mask ROM, the H8/3823R, H8/38323, and H8/38423 have 24 Kbytes, the H8/3824R, H8/3824S, H8/38324, and H8/38424 have 32 Kbytes, the H8/3825R, H8/3825S, H8/38325, and H8/38425 have 40 Kbytes, the H8/3826R, H8/3826S, H8/38326, and H8/38426 have 48 Kbytes, and the H8/3827R, H8/3827S, H8/38327, and H8/38427 have 60 Kbytes. The ROM is connected to the CPU by a 16-bit data bus, allowing high-speed two-state access for both byte data and word data. The H8/3827R has a ZTATTM version with 60-Kbyte PROM.

The H8/3827S Group does not have a ZTAT[™] version. The H8/3827R ZTAT[™] version must be used.

The F-ZTATTM versions of the H8/38327 and H8/38427 are equipped with 60 Kbytes of flash memory. The F-ZTATTM versions of the H8/38324 and H8/38424 are equipped with 32 Kbytes of flash memory.

6.1.1 Block Diagram

Figure 6.1 shows a block diagram of the on-chip ROM.



Figure 6.1 ROM Block Diagram (H8/3824R, H8/3824S, H8/38324, and H8/38424)

6.2 H8/3827R PROM Mode

6.2.1 Setting to PROM Mode

If the on-chip ROM is PROM, setting the chip to PROM mode stops operation as a microcontroller and allows the PROM to be programmed in the same way as the standard HN27C101 EPROM. However, page programming is not supported. Table 6.1 shows how to set the chip to PROM mode.

Table 6.1	Setting to PROM Mode
-----------	----------------------

Pin Name	Setting
TEST	High level
PB ₄ /AN ₄	Low level
PB ₅ /AN ₅	_
PB ₆ /AN ₆	High level

6.2.2 Socket Adapter Pin Arrangement and Memory Map

A standard PROM programmer can be used to program the PROM. A socket adapter is required for conversion to 32 pins, as listed in table 6.2.

Figure 6.2 shows the pin-to-pin wiring of the socket adapter. Figure 6.3 shows a memory map.

Table 6.2Socket Adapter

Package	Socket Adapters (Manufacturer)
80-pin (FP-80B)	ME3867ESFS1H (MINATO) H7386BQ080D3201 (DATA-I/O)
80-pin (FP-80A)	ME3867ESHS1H (MINATO) H7386AQ080D3201 (DATA-I/O)
80-pin (TFP-80C)	ME3867ESNS1H (MINATO) H7386CT080D3201 (DATA-I/O)

FP-80A, TFP-80C	FP-80B	Pin	Pin	HN27C101 (32-pin
9	11	RES	VPP	1
45	47	P60	EO0	13
46	48	P61	EO1	14
47	49	P62	EO2	15
48	50	P63	EO3	17
49	51	P64	EO4	18
50	52	P65	EO5	19
51	53	P66	EO6	20
52	54	P67	EO7	21
68	70	P87	EA0	12
67	69	P86	EA1	11
66	68	P8₅	EA2	10
65	67	P84	EA3	9
64	66	P83	EA4	8
63	65	P82	EA5	7
62	64	P81	EA6	6
61	63	P80	EA7	5
53	55	P70	EA8	27
72	74	P43	EA9	26
55	57	P72	EA1	0 23
56	58	P73	EA1	1 25
57	59	P74	EA1:	2 4
58	60	P75	EA1:	з 28
59	61	P76	EA1	4 29
14	16	P14	EA1	5 3
15	17	P1₅	EA1	6 2
60	62	P77	CE	22
54	56	P71	OE	24
13	15	P13	PGM	vi Vi 31
32, 26	34, 28	Vcc, CVcc	Vcc	32
73	75	AVcc	<u> </u>	
8	10	TEST	<u> </u>	
3	5	X1	<u> </u>	
80	2	PB ₆	<u> </u>	
11	13	P11	<u> </u>	
12	14	P12	I	
16	18	P16		
5, 27	7, 29	Vss	Vss	16
2	4	AVss	— 	
78	80	PB4	— 	
79	1	PB₅		

Figure 6.2 Socket Adapter Pin Correspondence (with HN27C101)



Figure 6.3 H8/3827R Memory Map in PROM Mode



6.3 H8/3827R Programming

The write, verify, and other modes are selected as shown in table 6.3 in H8/3827R PROM mode.

	Pins							
Mode	CE	ŌE	PGM	V _{PP}	Vcc	EO ₇ to EO ₀	EA ₁₆ to EA ₀	
Write	L	Н	L	V_{PP}	Vcc	Data input	Address input	
Verify	L	L	Н	V_{PP}	V _{CC}	Data output	Address input	
Programming	L	L	L	V_{PP}	Vcc	High impedance	Address input	
disabled	L	Н	Н					
	Н	L	L					
	Н	Н	Н					
Notation								
L: Low lev	el							

Table 6.3Mode Selection in PROM Mode (H8/3827R)

H: High level

V_{PP}: V_{PP} level

V_{CC}: V_{CC} level

The specifications for writing and reading are identical to those for the standard HN27C101 EPROM. However, page programming is not supported, and so page programming mode must not be set. A PROM programmer that only supports page programming mode cannot be used. When selecting a PROM programmer, ensure that it supports high-speed, high-reliability byte-by-byte programming. Also, be sure to specify addresses from H'0000 to H'EDFF.

6.3.1 Writing and Verifying

An efficient, high-speed, high-reliability method is available for writing and verifying the PROM data. This method achieves high speed without voltage stress on the device and without lowering the reliability of written data. The basic flow of this high-speed, high-reliability programming method is shown in figure 6.4.



Figure 6.4 High-Speed, High-Reliability Programming Flow Chart

Tables 6.4 and 6.5 give the electrical characteristics in programming mode.

Table 6.4DC Characteristics

Conditions: $V_{CC} = 6.0 \text{ V} \pm 0.25 \text{ V}$, $V_{PP} = 12.5 \text{ V} \pm 0.3 \text{ V}$, $V_{SS} = 0 \text{ V}$, $T_a = 25^{\circ}C \pm 5^{\circ}C$

Item		Symbol	Min	Тур	Max	Unit	Test Condition
Input high- level voltage	$\frac{EO_7}{OE} \frac{\text{to } EO_0, EA_{16} \text{ to } EA_0}{CE, PGM}$	V _{IH}	2.4	_	V _{CC} + 0.3	V	
Input low- level voltage	$\frac{EO_7}{OE} \frac{\text{to } EO_0, EA_{16}}{CE, PGM} \text{to } EA_0$	V _{IL}	-0.3	_	0.8	V	
Output high- level voltage	EO ₇ to EO ₀	V _{OH}	2.4	_	—	V	I _{OH} = -200 μA
Output low- level voltage	EO ₇ to EO ₀	V _{OL}	_	_	0.45	V	I _{OL} = 0.8 mA
Input leakage current	$\frac{EO_7}{OE} \frac{\text{to } EO_0, EA_{16} \text{ to } EA_0}{CE, PGM}$	IL _I	_	_	2	μA	V _{in} = 5.25 V/ 0.5 V
V_{CC} current		I _{CC}	—	—	40	mA	
V _{PP} current		I _{PP}			40	mA	

Table 6.5AC Characteristics

Conditions: $V_{CC} = 6.0 \text{ V} \pm 0.25 \text{ V}$, $V_{PP} = 12.5 \text{ V} \pm 0.3 \text{ V}$, $T_a = 25^{\circ}\text{C} \pm 5^{\circ}\text{C}$

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Address setup time	t _{AS}	2	_	_	μs	Figure 6.5 ^{*1}
OE setup time	toes	2	_	_	μs	
Data setup time	t _{DS}	2	_	_	μs	
Address hold time	t _{AH}	0	_	_	μs	
Data hold time	t _{DH}	2	_	_	μs	
Data output disable time	t _{DF} *2	—	_	130	ns	
V _{PP} setup time	t _{VPS}	2	_	_	μs	
Programming pulse width	t _{PW}	0.19	0.20	0.21	ms	
PGM pulse width for overwrite programming	t _{OPW} *3	0.19	_	5.25	ms	
CE setup time	t _{CES}	2	—	—	μs	
V _{CC} setup time	t _{VCS}	2	_	_	μs	
Data output delay time	t _{OE}	0	_	200	ns	

Notes: 1. Input pulse level: 0.45 V to 2.2 V Input rise time/fall time ≤ 20 ns Timingreference levels Input: 0.8 V, 2.0 V Output: 0.8 V, 2.0 V

- 2. t_{DF} is defined at the point at which the output is floating and the output level cannot be read.
- 3. t_{OPW} is defined by the value given in figure 6.4, High-Speed, High-Reliability Programming Flow Chart.



Write Verify Address tas tан Input data Output data Data tos tDF tdн Vpp Vpp Vcc **t**VPS Vcc⁺¹ Vcc Vcc tvcs CE tces PGM tpw toes toe OE topw* topw is defined by the value shown in figure 6.4, High-Speed, High-Reliability Programming Flowchart. Note: *

Figure 6.5 shows a PROM write/verify timing diagram.

Figure 6.5 PROM Write/Verify Timing

6.3.2 Programming Precautions

• Use the specified programming voltage and timing.

The programming voltage in PROM mode (V_{PP}) is 12.5 V. Use of a higher voltage can permanently damage the chip. Be especially careful with respect to PROM programmer overshoot.

Setting the PROM programmer to Renesas specifications for the HN27C101 will result in correct V_{PP} of 12.5 V.

- Make sure the index marks on the PROM programmer socket, socket adapter, and chip are properly aligned. If they are not, the chip may be destroyed by excessive current flow. Before programming, be sure that the chip is properly mounted in the PROM programmer.
- Avoid touching the socket adapter or chip while programming, since this may cause contact faults and write errors.
- Take care when setting the programming mode, as page programming is not supported.
- When programming with a PROM programmer, be sure to specify addresses from H'0000 to H'EDFF. If programming is inadvertently performed from H'EE00 onward, it may not be possible to continue PROM programming and verification. When programming, H'FF should be set as the data in address area H'EE00 to H'1FFFF.



6.4 Reliability of Programmed Data

A highly effective way to improve data retention characteristics is to bake the programmed chips at 150°C, then screen them for data errors. This procedure quickly eliminates chips with PROM memory cells prone to early failure.

Figure 6.6 Shows the recommended screening procedure.



Figure 6.6 Recommended Screening Procedure

If a series of programming errors occurs while the same PROM programmer is in use, stop programming and check the PROM programmer and socket adapter for defects. Please inform Renesas Technology of any abnormal conditions noted during or after programming or in screening of program data after high-temperature baking.

6.5 Flash Memory Overview

6.5.1 Features

The features of the 60 Kbytes or 32 Kbytes of flash memory built into the F-ZTAT versions are summarized below.

- Programming/erase methods
 - The 60-Kbyte flash memory is programmed 128 bytes at a time. Erase is performed in single-block units. The flash memory is configured as follows: 1 Kbyte × 4 blocks, 28 Kbytes × 1 block, 16 Kbytes × 1 block, 8 Kbytes × 1 block, 4 Kbytes × 1 block. The 32-Kbyte flash memory is configured as follows: 1 Kbyte × 4 blocks, 28 Kbytes × 1 block. To erase the entire flash memory, each block must be erased in turn.
- Reprogramming capability
 - The flash memory can be reprogrammed up to 1,000 times.
- On-board programming
 - On-board programming/erasing can be done in boot mode, in which the boot program built into the chip is started to erase or program of the entire flash memory. In normal user program mode, individual blocks can be erased or programmed.
- Programmer mode
 - Flash memory can be programmed/erased in programmer mode using a PROM programmer, as well as in on-board programming mode.
- Automatic bit rate adjustment
 - For data transfer in boot mode, this LSI's bit rate can be automatically adjusted to match the transfer bit rate of the host.
- Programming/erasing protection
 - Sets software protection against flash memory programming/erasing.
- Power-down mode
 - The power supply circuit is partly halted in the subactive mode and can be read in the power-down mode.



6.5.2 Block Diagram



Figure 6.7 Block Diagram of Flash Memory

6.5.3 Block Configuration

Figure 6.8 shows the block configuration of flash memory. The thick lines indicate erasing units, the narrow lines indicate programming units, and the values are addresses. The flash memory is divided into 1 Kbyte \times 4 blocks, 28 Kbytes \times 1 block, 16 Kbytes \times 1 block, 8 Kbytes \times 1 block, and 4 Kbytes \times 1 block. Erasing is performed in these units. Programming is performed in 128-byte units starting from an address with lower eight bits H'00 or H'80.

	H'0000	H'0001	H'0002	← Programming unit: 128 bytes →	H'007F
	H'0080	H'0081	H'0082		H'00FF
Erase unit 1 Kbyte					
	H'0380	H'0381	H'0382		H'03FF
	H'0400	H'0401	H'0402	← Programming unit: 128 bytes →	H'047F
Erase unit 1 Kbyte	H'0480	H'0481	H'0482		H'04FF
	H'0780	H'0781	H'0782		H'07FF
-	H'0800	H'0801	H'0802	← Programming unit: 128 bytes →	H'087F
F	H'0880	H'0881	H'0882		H'080F
Erase unit 1 Kbyte					
	H'0B80	H'0B81	H'0B82		H'0BFF
Ī	H'0C00	H'0C01	H'0C02	← Programming unit: 128 bytes →	H'0C7F
Ē	H'0C80	H'0C81	H'0C82		H'0CFF
Erase unit 1 Kbyte					
	H'0F80	H'0F81	H'0F82		H'0FFF
	H'1000	H'1001	H'1002	← Programming unit: 128 bytes →	H'107F
	H'1080	H'1081	H'1082		H'10FF
Erase unit 28 Kbytes					
F	H'7F80	H'7F81	H'7F82		H'7FFF
F	H'8000	H'8001	H'8002	← Programming unit: 128 bytes →	H'807F
-	H'8080	H'8081	H'8082		H'8CFF
Erase unit 16 Kbytes					
	H'BF80	H'BF81	H'BF82		H'BFFF
Γ	H'C000	H'C001	H'C002	← Programming unit: 128 bytes →	H'C07F
ſ	H'C080	H'C081	H'C082		H'CCFF
Erase unit 8 Kbytes					
Ē	H'DF80	H'DF81	H'DF82		H'DFFF
Ē	H'E000	H'E001	H'E002	← Programming unit: 128 bytes →	H'E07F
Ē	H'E080	H'E081	H'E082		H'ECFF
Erase unit 4 Kbytes					
Ī	H'EF80	H'EF81	H'EF82		H'EFFF

Figure 6.8 Flash Memory Block Configuration

6.5.4 Register Configuration

Table 6.6 lists the register configuration to control the flash memory when the built in flash memory is effective.

Table 6.6 Register Configuration

Register Name	Abbreviation	R/W	Initial Value	Address
Flash memory control register 1	FLMCR1	R/W	H'00	H'F020
Flash memory control register 2	FLMCR2	R	H'00	H'F021
Flash memory power control register	FLPWCR	R/W	H'00	H'F022
Erase block register	EBR	R/W	H'00	H'F023
Flash memory enable register	FENR	R/W	H'00	H'F02B

Note: FLMCR1, FLMCR2, FLPWCR, EBR, and FENR are 8 bit registers. Only byte access is enabled which are two-state access. These registers are dedicated to the product in which flash memory is included. The product in which PROM or ROM is included does not have these registers. When the corresponding address is read in these products, the value is undefined. A write is disabled.

6.6 Descriptions of Registers of the Flash Memory

Bit	7	6	5	4	3	2	1	0
	_	SWE	ESU	PSU	EV	PV	E	Р
Initial value	0	0	0	0	0	0	0	0
Read/Write	—	R/W						

6.6.1 Flash Memory Control Register 1 (FLMCR1)

FLMCR1 is a register that makes the flash memory change to program mode, program-verify mode, erase mode, or erase-verify mode. For details on register setting, refer to section 6.8, Flash Memory Programming/Erasing. By setting this register, the flash memory enters program mode, erase mode, program-verify mode, or erase-verify mode. Read the data in the state that bits 6 to 0 of this register are cleared when using flash memory as normal built-in ROM.

Bit 7—Reserved

This bit is always read as 0 and cannot be modified.

Bit 6—Software Write Enable (SWE)

This bit is to set enabling/disabling of programming/enabling of flash memory (set when bits 5 to 0 and the EBR register are to be set).

Bit 6 SWE	Description
0	Programming/erasing is disabled. Other FLMCR1 register bits and all EBR bits cannot be set. (initial value)
1	Flash memory programming/erasing is enabled.

Bit 5—Erase Setup (ESU)

This bit is to prepare for changing to erase mode. Set this bit to 1 before setting the E bit to 1 in FLMCR1 (do not set SWE, PSU, EV, PV, E, and P bits at the same time).

Bit 5 ESU	Description	
0	The erase setup state is cancelled	(initial value)
1	The flash memory changes to the erase setup state. Set this bit to 1 the E bit to 1 in FLMCR1.	before setting

Bit 4—Program Setup (PSU)

This bit is to prepare for changing to program mode. Set this bit to 1 before setting the P bit to 1 in FLMCR1 (do not set SWE, ESU, EV, PV, E, and P bits at the same time).

Bit 4 PSU	Description	
0	The program setup state is cancelled	(initial value)
1	The flash memory changes to the program setup state. Set this bit to setting the P bit to 1 in FLMCR1.	1 before

Bit 3—Erase-Verify (EV)

This bit is to set changing to or cancelling erase-verify mode (do not set SWE, ESU, PSU, PV, E, and P bits at the same time).

Bit 3		
EV	Description	
0	Erase-verify mode is cancelled	(initial value)
1	The flash memory changes to erase-verify mode	

Bit 2—Program-Verify (PV)

This bit is to set changing to or cancelling program-verify mode (do not set SWE, ESU, PSU, EV, E, and P bits at the same time).

Bit 2 PV

PV	Description	
0	Program-verify mode is cancelled	(initial value)
1	The flash memory changes to program-verify mode	

Bit 1—Erase (E)

This bit is to set changing to or cancelling erase mode (do not set SWE, ESU, PSU, EV, PV, and P bits at the same time).

Section 6 ROM

Bit 1 E	Description	
0	Erase mode is cancelled	(initial value)
1	When this bit is set to 1, while the SWE = 1 and ESU = 1, the flash m changes to erase mode.	emory

Bit 0—Program (P)

This bit is to set changing to or cancelling program mode (do not set SWE, ESU, PSU, EV, PV, and E bits at the same time).

Bit 0

P	Description	
0	Program mode is cancelled	(initial value)
1	When this bit is set to 1, while the SWE = 1 and PSU = 1, the flash changes to program mode.	memory

6.6.2 Flash Memory Control Register 2 (FLMCR2)

Bit	7	6	5	4	3	2	1	0	
	FLER		—		—	_		—	
Initial value	0	0	0	0	0	0	0	0	
Read/Write	R	_	_	_	_	—	—	_	

FLMCR2 is a register that displays the state of flash memory programming/erasing. FLMCR2 is a read-only register, and should not be written to.

Bit 7—Flash Memory Error (FLER)

This bit is set when the flash memory detects an error and goes to the error-protection state during programming or erasing to the flash memory. See section 6.9.3, Error Protection, for details.

Bit 7 FLER	Description	
0	The flash memory operates normally.	(initial value)
1	Indicates that an error has occurred during an operation on flash me (programming or erasing).	mory

Bits 6 to 0—Reserved

6.6.3

These bits are always read as 0 and cannot be modified.

Erase Block Register (EBR)

Bit 7 6 5 4 3 2 1 0 EB6 EB7 EB5 EB4 EB3 EB2 EB1 EB0 0 0 0 0 0 0 0 Initial value 0 Read/Write R/W R/W R/W R/W R/W R/W R/W R/W

EBR specifies the flash memory erase area block. EBR is initialized to H'00 when the SWE bit in FLMCR1 is 0. Do not set more than one bit at a time, as this will cause all the bits in EBR to be automatically cleared to 0. When each bit is set to 1 in EBR, the corresponding block can be erased. Other blocks change to the erase-protection state. See table 6.7 for the method of dividing blocks of the flash memory. When the whole bits are to be erased, erase them in turn in unit of a block.

EBR	Bit Name	Block (Size)	Address
0	EB0	EB0 (1 Kbyte)	H'0000 to H'03FF
1	EB1	EB1 (1 Kbyte)	H'0400 to H'07FF
2	EB2	EB2 (1 Kbyte)	H'0800 to H'0BFF
3	EB3	EB3 (1 Kbyte)	H'0C00 to H'0FFF
4	EB4	EB4 (28 Kbytes)	H'1000 to H'7FFF
5	EB5	EB5 (16 Kbytes)	H'8000 to H'BFFF
6	EB6	EB6 (8 Kbytes)	H'C000 to H'DFFF
7	EB7	EB7 (4 Kbytes)	H'E000 to H'EFFF

Table 6.7Division of Blocks to Be Erased

6.6.4 Flash Memory Power Control Register (FLPWCR)

Bit	7	6	5	4	3	2	1	0
	PDWND		_	_				—
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	_	_	_	—	—	—	—

FLPWCR enables or disables a transition to the flash memory power-down mode when the LSI switches to subactive mode. The power supply circuit can be read in the subactive mode, although it is partly halted in the power-down mode.

Bit 7—Power-down Disable (PDWND)

This bit selects the power-down mode of the flash memory when a transition to the subactive mode is made.

Bit 7 PDWND	Description
0	When this bit is 0 and a transition is made to the subactive mode, the flash memory enters the power-down mode. (initial value)
1	When this bit is 1, the flash memory remains in the normal mode even after a transition is made to the subactive mode.

Bits 6 to 0—Reserved

These bits are always read as 0 and cannot be modified.



6.6.5 Flash Memory Enable Register (FENR)

Bit	7	6	5	4	3	2	1	0
	FLSHE		—	—	—	_	_	_
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	_	_	_	_	_	_	_

FENR controls CPU access to the flash memory control registers, FLMCR1, FLMCR2, EBR, and FLPWCR.

Bit 7—Flash Memory Control Register Enable (FLSHE)

This bit controls access to the flash memory control registers.

Bit 7 FLSHE	Description	
0	Flash memory control registers cannot be accessed	(initial value)
1	Flash memory control registers can be accessed	

Bits 6 to 0—Reserved

These bits are always read as 0 and cannot be modified.

6.7 On-Board Programming Modes

There are two modes for programming/erasing of the flash memory; boot mode, which enables onboard programming/erasing, and programmer mode, in which programming/erasing is performed with a PROM programmer. On-board programming/erasing can also be performed in user program mode. At reset-start in reset mode, this LSI changes to a mode depending on the TEST pin settings, P32 pin settings, and input level of each port, as shown in table 6.8. The input level of each pin must be defined four states before the reset ends.

When changing to boot mode, the boot program built into this LSI is initiated. The boot program transfers the programming control program from the externally-connected host to on-chip RAM via SCI32. After erasing the entire flash memory, the programming control program is executed. This can be used for programming initial values in the on-board state or for a forcible return when programming/erasing can no longer be done in user program mode. In user program mode, individual blocks can be erased and programmed by branching to the user program/erase control program prepared by the user.

TEST	P32	P86	PB0	PB1	PB2	LSI State after Reset End
0	1	Х	Х	Х	Х	User Mode
0	0	1	Х	Х	Х	Boot Mode
1	Х	Х	0	0	0	Programmer Mode

Table 6.8	Setting Programming Modes
-----------	----------------------------------

X: Don't care

6.7.1 Boot Mode

Table 6.9 shows the boot mode operations between reset end and branching to the programming control program. The device uses SCI32 in the boot mode.

- 1. When boot mode is used, the flash memory programming control program must be prepared in the host beforehand. Prepare a programming control program in accordance with the description in section 6.8, Flash Memory Programming/Erasing.
- 2. SCI3 should be set to asynchronous mode, and the transfer format as follows: 8-bit data, 1 stop bit, and no parity. The inversion function of TXD and RXD pins by the SPCR register is set to "Not to be inverted," so do not put the circuit for inverting a value between the host and this LSI.
- 3. When the boot program is initiated, the chip measures the low-level period of asynchronous SCI communication data (H'00) transmitted continuously from the host. The chip then

calculates the bit rate of transmission from the host, and adjusts the SCI3 bit rate to match that of the host. The reset should end with the RXD pin high. The RXD and TXD pins should be pulled up on the board if necessary. After the reset is complete, it takes approximately 100 states before the chip is ready to measure the low-level period.

- 4. After matching the bit rates, the chip transmits one H'00 byte to the host to indicate the completion of bit rate adjustment. The host should confirm that this adjustment end indication (H'00) has been received normally, and transmit one H'55 byte to the chip. If reception could not be performed normally, initiate boot mode again by a reset. Depending on the host's transfer bit rate and system clock frequency of this LSI, there will be a discrepancy between the bit rates of the host and the chip. To operate the SCI properly, set the host's transfer bit rate and system clock frequency of this LSI within the ranges listed in table 6.10.
- 5. In boot mode, a part of the on-chip RAM area is used by the boot program. The area H'F780 to H'FEEF is the area to which the programming control program is transferred from the host. The boot program area cannot be used until the execution state in boot mode switches to the programming control program.
- 6. Before branching to the programming control program, the chip terminates transfer operations by SCI3 (by clearing the RE and TE bits in SCR to 0), however the adjusted bit rate value remains set in BRR. Therefore, the programming control program can still use it for transfer of write data or verify data with the host. The TXD pin is high (PCR42 = 1, P42 = 1). The contents of the CPU general registers are undefined immediately after branching to the programming control program. These registers must be initialized at the beginning of the programming control program, as the stack pointer (SP), in particular, is used implicitly in subroutine calls, etc.
- Boot mode can be cleared by a reset. End the reset after driving the reset pin low, waiting at least 20 states, and then setting the TEST pin and P32 pin. Boot mode is also cleared when a WDT overflow occurs.
- 8. Do not change the TEST pin and P32 pin input levels in boot mode.

	Host Operation	LSI Operation			
Item	Processing Contents	Processing Contents			
		Branches to boot program at reset-start.			
Bit rate adjustment	Continuously transmits data H'00 at specified bit rate.	 Measures low-level period of receive data H'00. Calculates bit rate and sets it in BRR of SCI3. Transmits data H'00 to the host to indicate that the adjustment has ended. 			
Flash memory erase	Transmits data H'55 when data H'00 is received and no error occurs.	,			
		Checks flash memory data, erases all flash memory blocks in case of written data existing, and transmits data H'AA to host. (If erase could not be done, transmits data H'FF to host and aborts operation.)			
- +	-				
Transfer of programming control program	Transmits number of bytes (N) of programming control program to be transferred as 2-byte data (low-order byte following high-order byte)	Echobacks the 2-byte received data to host.			
Transfer of programming control program (repeated for N times)	Transmits 1-byte of programming control program	Echobacks received data to host and also transfers it to RAM.			
+					
Execution of		Transmits 1-byte data H'AA to host.			
Programming control program		Branches to programming control program transferred to on-chip RAM and starts execution.			

Table 6.9Boot Mode Operation

Table 6.10 Oscillating Frequencies (f_{OSC}) for which Automatic Adjustment of LSI Bit Rate Is Possible

Product Group	Host Bit Rate	Oscillating Frequencies (f _{OSC}) Range of LSI
H8/38327F-ZTAT	19,200 bps	16 MHz
H8/38324F-ZTAT	9,600 bps	8 to 16 MHz
H8/38427F-ZTAT	4,800 bps	6 to 16 MHz
H8/38424F-ZTAT	2,400 bps	2 to 16 MHz
	1,200 bps	2 to 16 MHz

6.7.2 Programming/Erasing in User Program Mode

The term user mode refers to the status when a user program is being executed. On-board programming/erasing of an individual flash memory block can also be performed in user program mode by branching to a user program/erase control program. The user must set branching conditions and provide on-board means of supplying programming data. The flash memory must contain the user program/erase control program or a program that provides the user program/erase control program from external memory. As the flash memory itself cannot be read during programming/erasing, transfer the user program/erase control program to on-chip RAM, as in boot mode. Figure 6.9 shows a sample procedure for programming/erasing in user program mode. Prepare a user program/erase control program in accordance with the description in section 6.8, Flash Memory Programming/Erasing.



Figure 6.9 Programming/Erasing Flowchart Example in User Program Mode

6.8 Flash Memory Programming/Erasing

A software method using the CPU is employed to program and erase flash memory in the onboard programming modes. Depending on the FLMCR1 setting, the flash memory operates in one of the following four modes: Program mode, program-verify mode, erase mode, and erase-verify mode. The programming control program in boot mode and the user program/erase control

program in user program mode use these operating modes in combination to perform programming/erasing. Flash memory programming and erasing should be performed in accordance with the descriptions in section 6.8.1, Program/Program-Verify and section 6.8.2, Erase/Erase-Verify, respectively.

6.8.1 Program/Program-Verify

When writing data or programs to the flash memory, the program/program-verify flowchart shown in figure 6.10 should be followed. Performing programming operations according to this flowchart will enable data or programs to be written to the flash memory without subjecting the chip to voltage stress or sacrificing program data reliability.

- 1. Programming must be done to an empty address. Do not reprogram an address to which programming has already been performed.
- 2. Programming should be carried out 128 bytes at a time. A 128-byte data transfer must be performed even if writing fewer than 128 bytes. In this case, H'FF data must be written to the extra addresses.
- 3. Prepare the following data storage areas in RAM: A 128-byte programming data area, a 128byte reprogramming data area, and a 128-byte additional-programming data area. Perform reprogramming data computation according to table 6.11, and additional programming data computation according to table 6.12.
- 4. Consecutively transfer 128 bytes of data in byte units from the reprogramming data area or additional-programming data area to the flash memory. The program address and 128-byte data are latched in the flash memory. The lower 8 bits of the start address in the flash memory destination area must be H'00 or H'80.
- 5. The time during which the P bit is set to 1 is the programming time. Figure 6.12 shows the allowable programming times.
- 6. The watchdog timer (WDT) is set to prevent overprogramming due to program runaway, etc. An overflow cycle of approximately 6.6 ms is allowed.
- 7. For a dummy write to a verify address, write 1-byte data H'FF to an address whose lower 1 bit is b'0. Verify data can be read in word size from the address to which a dummy write was performed.
- 8. The maximum number of repetitions of the program/program-verify sequence of the same bit is 1,000.







Program Data	Verify Data	Reprogram Data	Comments
0	0	1	Programming completed
0	1	0	Reprogram bit
1	0	1	_
1	1	1	Remains in erased state

Table 6.11 Reprogram Data Computation Table

Table 6.12 Additional-Program Data Computation Table

Reprogram Data	Verify Data	Additional-Program Data	Comments
0	0	0	Additional-program bit
0	1	1	No additional programming
1	0	1	No additional programming
1	1	1	No additional programming

Table 6.13Programming Time

n (Number of Writes)	Programming Time	In Additional Programming	Comments	
1 to 6	30	10		
7 to 1,000	200	—		

Note: Time shown in μ s.



6.8.2 Erase/Erase-Verify

When erasing flash memory, the erase/erase-verify flowchart shown in figure 6.11 should be followed.

- 1. Prewriting (setting erase block data to all 0s) is not necessary.
- 2. Erasing is performed in block units. Make only a single-bit specification in the erase block register (EBR). To erase multiple blocks, each block must be erased in turn.
- 3. The time during which the E bit is set to 1 is the flash memory erase time.
- 4. The watchdog timer (WDT) is set to prevent overerasing due to program runaway, etc. An overflow cycle of approximately 19.8 ms is allowed.
- 5. For a dummy write to a verify address, write 1-byte data H'FF to an address whose lower 1 bit is b'0. Verify data can be read in word size from the address to which a dummy write was performed.
- 6. If the read data is not erased successfully, set erase mode again, and repeat the erase/erase-verify sequence as before. The maximum number of repetitions of the erase/erase-verify sequence is 100.

6.8.3 Interrupt Handling when Programming/Erasing Flash Memory

All interrupts, are disabled while flash memory is being programmed or erased, or while the boot program is executing, for the following three reasons:

- 1. Interrupt during programming/erasing may cause a violation of the programming or erasing algorithm, with the result that normal operation cannot be assured.
- 2. If interrupt exception handling starts before the vector address is written or during programming/erasing, a correct vector cannot be fetched and the CPU malfunctions.
- 3. If an interrupt occurs during boot program execution, normal boot mode sequence cannot be carried out.

Section 6 ROM





6.9 Program/Erase Protection

There are three kinds of flash memory program/erase protection; hardware protection, software protection, and error protection.

6.9.1 Hardware Protection

Hardware protection refers to a state in which programming/erasing of flash memory is forcibly disabled or aborted because of a transition to reset, subactive mode, subsleep mode, watch mode, or standby mode. Flash memory control register 1 (FLMCR1), flash memory control register 2 (FLMCR2), and erase block register (EBR) are initialized. In a reset via the $\overline{\text{RES}}$ pin, the reset state is not entered unless the $\overline{\text{RES}}$ pin is held low until oscillation stabilizes after powering on. In the case of a reset during operation, hold the $\overline{\text{RES}}$ pin low for the $\overline{\text{RES}}$ pulse width specified in the AC Characteristics section.

6.9.2 Software Protection

Software protection can be implemented against programming/erasing of all flash memory blocks by clearing the SWE bit in FLMCR1. When software protection is in effect, setting the P or E bit in FLMCR1 does not cause a transition to program mode or erase mode. By setting the erase block register (EBR), erase protection can be set for individual blocks. When EBR is set to H'00, erase protection is set for all blocks.

6.9.3 Error Protection

In error protection, an error is detected when CPU runaway occurs during flash memory programming/erasing, or operation is not performed in accordance with the program/erase algorithm, and the program/erase operation is aborted. Aborting the program/erase operation prevents damage to the flash memory due to overprogramming or overerasing.

When the following errors are detected during programming/erasing of flash memory, the FLER bit in FLMCR2 is set to 1, and the error protection state is entered.

- When the flash memory of the relevant address area is read during programming/erasing (including vector read and instruction fetch)
- Immediately after exception handling excluding a reset during programming/erasing
- When a SLEEP instruction is executed during programming/erasing

The FLMCR1, FLMCR2, and EBR settings are retained, however program mode or erase mode is aborted at the point at which the error occurred. Program mode or erase mode cannot be re-entered

by re-setting the P or E bit. However, PV and EV bit setting is enabled, and a transition can be made to verify mode. Error protection can be cleared only by a power-on reset.

6.10 Programmer Mode

In programmer mode, a PROM programmer can be used to perform programming/erasing via a socket adapter, just as a discrete flash memory. Use a PROM programmer that supports the MCU device type with the on-chip Renesas Technology (former Hitachi Ltd.) 64-Kbyte flash memory (F-ZTAT64V3). A 10-MHz input clock is required. For the conditions for transition to programmer mode, see table 6.8.

6.10.1 Socket Adapter

The socket adapter converts the pin allocation of the F-ZTAT device to that of the discrete flash memory HN28F101. The address of the on-chip flash memory is H'0000 to H'EFFF. Figure 6.12 shows a socket-adapter-pin correspondence diagram.

6.10.2 Programmer Mode Commands

The following commands are supported in programmer mode.

- Memory Read Mode
- Auto-Program Mode
- Auto-Erase Mode
- Status Read Mode

Status polling is used for auto-programming, auto-erasing, and status read modes. In status read mode, detailed internal information is output after the execution of auto-programming or auto-erasing. Table 6.14 shows the sequence of each command. In auto-programming mode, 129 cycles are required since 128 bytes are written at the same time. In memory read mode, the number of cycles depends on the number of address write cycles (n).



	Number	1st Cycle			2nd Cycle		
Command Name	of Cycles	Mode	Address	Data	Mode	Address	Data
Memory read	1 + n	Write	Х	H'00	Read	RA	Dout
Auto-program	129	Write	Х	H'40	Write	WA	Din
Auto-erase	2	Write	Х	H'20	Write	Х	H'20
Status read	2	Write	Х	H'71	Write	Х	H'71

 Table 6.14
 Command Sequence in Programmer Mode

n: the number of address write cycles

F-ZTAT De	Socket Adapter (Conversion to	iг	HN28E10	I (32 Pins)		
Pin No.	Dia Mara	32-Pin	÷⊢	1111201 10	(JZ 1 113)	
FP-80A TFP-80C	Pin Name	Arrangement)	Ľ	Pin Name	Pin No.	
			ΗL	FWE	1	
54	P71		÷E	A9	26	
			ΗĽ	A16	2	
60	P77		÷Γ	A15	3	
12	P12		÷Ľ	WE	31	
45	P60	1	╢	I/O0	13	
46	P61	•	÷Ľ	I/O1	14	
47	P62	1	÷L	I/O2	15	
48	P63		÷Γ	I/O3	17	
49	P64	1	÷Γ	I/O4	18	
50	P65		÷Ľ	I/O5	19	
51	P66	+	÷	I/O6	20	
52	P67		÷Ľ	I/07	21	
68	P87		÷E	A0	12	
67	P86		÷Γ	A1	11	
66	P85		ΗĽ	A2	10	
65	P84		ΗĽ	A3	9	
64	P83		÷Ε	A4	8	
63	P82		÷F	A5	7	
62	P81		÷Γ	A6	6	
61	P80		÷Ľ	A7	5	
53	P70		÷Γ	A8	27	
71	P42	1	÷L	ŌĒ	24	
55	P72		÷Γ	A10	23	
56	P73	1	÷L	A11	25	
57	P74	!	÷L	A12	4	
58	P75		÷L	A13	28	
59	P76		÷Γ	A14	29	
72	P43		÷L	CE	22	
26, 32	CVcc, Vcc	<u> </u>	ΗĽ	Vcc	32	
73	AVcc	<u>∔</u> ⊢	÷L	Vss	16	
3	X1	÷	1			
8	TEST			egend:		
30	V1				Flash-write er	able
14	P14			07 to I/O0:	Data input/out	tput
					Address input Chip enable	
2, 5	AVss, Vss	+			Output enable	;
27	Vss	+			Write enable	
74	PB0					
75	PB1	÷ • •	No		cillation freque scillator circui	
76	PB2				be 10 MHz.	ı
7, 6	OSC1,OSC2	Oscillator circuit				
9	RES	Power-on reset circuit	1			
ther than the above	(OPEN)		:			

Figure 6.12 Socket Adapter Pin Correspondence Diagram



6.10.3 Memory Read Mode

- 1. After completion of auto-program/auto-erase/status read operations, a transition is made to the command wait state. When reading memory contents, a transition to memory read mode must first be made with a command write, after which the memory contents are read. Once memory read mode has been entered, consecutive reads can be performed.
- 2. In memory read mode, command writes can be performed in the same way as in the command wait state.
- 3. After powering on, memory read mode is entered.
- 4. Tables 6.15 to 6.17 show the AC characteristics.

Table 6.15 AC Characteristics in Transition to Memory Read Mode

Conditions: $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$, $V_{SS} = 0 \text{ V}$, $T_a = 25^{\circ}C \pm 5^{\circ}C$

Item	Symbol	Min	Max	Unit	Notes
Command write cycle	t _{nxtc}	20		μs	Figure 6.13
CE hold time	t _{ceh}	0	—	ns	
CE setup time	t _{ces}	0		ns	
Data hold time	t _{dh}	50	_	ns	
Data setup time	t _{ds}	50	_	ns	
Write pulse width	t _{wep}	70	_	ns	
WE rise time	tr	_	30	ns	
WE fall time	t _f	_	30	ns	





Table 6.16 AC Characteristics in Transition from Memory Read Mode to Another Mode

Conditions: $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$, $V_{SS} = 0 \text{ V}$, $T_a = 25^{\circ}\text{C} \pm 5^{\circ}\text{C}$

Item	Symbol	Min	Max	Unit	Notes
Command write cycle	t _{nxtc}	20	_	μs	Figure 6.14
CE hold time	t _{ceh}	0	_	ns	
CE setup time	t _{ces}	0	_	ns	
Data hold time	t _{dh}	50	_	ns	
Data setup time	t _{ds}	50	_	ns	
Write pulse width	t _{wep}	70	_	ns	
WE rise time	tr		30	ns	
WE fall time	t _f	_	30	ns	



Figure 6.14 Timing Waveforms in Transition from Memory Read Mode to Another Mode


Table 6.17 AC Characteristics in Memory Read Mode

Conditions: $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$, $V_{SS} = 0 \text{ V}$, $T_a = 25^{\circ}C \pm 5^{\circ}C$

Item	Symbol	Min	Max	Unit	Notes
Access time	t _{acc}	—	20	μs	Figure 6.15
CE output delay time	t _{ce}	_	150	ns	Figure 6.16
OE output delay time	t _{oe}	_	150	ns	
Output disable delay time	t _{df}	_	100	ns	
Data output hold time	t _{oh}	5		ns	







Figure 6.16 CE and OE Clock System Read Timing Waveforms

6.10.4 Auto-Program Mode

- 1. When reprogramming previously programmed addresses, perform auto-erasing before autoprogramming.
- 2. Perform auto-programming once only on the same address block. It is not possible to program an address block that has already been programmed.
- 3. In auto-program mode, 128 bytes are programmed simultaneously. This should be carried out by executing 128 consecutive byte transfers. A 128-byte data transfer is necessary even when programming fewer than 128 bytes. In this case, H'FF data must be written to the extra addresses.
- 4. The lower 7 bits of the transfer address must be low. If a value other than an effective address is input, processing will switch to a memory write operation but a write error will be flagged.
- 5. Memory address transfer is performed in the second cycle (figure 6.17). Do not perform transfer after the third cycle.
- 6. Do not perform a command write during a programming operation.
- 7. Perform one auto-program operation for a 128-byte block for each address. Two or more additional programming operations cannot be performed on a previously programmed address block.
- 8. Confirm normal end of auto-programming by checking I/O6. Alternatively, status read mode can also be used for this purpose (I/O7 status polling uses the auto-program operation end decision pin).
- Status polling I/O6 and I/O7 pin information is retained until the next command write. As long as the next command write has not been performed, reading is possible by enabling CE and OE.
- 10. Table 6.18 shows the AC characteristics.



Table 6.18 AC Characteristics in Auto-Program Mode

Conditions: $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$, $V_{SS} = 0 \text{ V}$, $T_a = 25^{\circ}C \pm 5^{\circ}C$

Item	Symbol	Min	Max	Unit	Notes
Command write cycle	t _{nxtc}	20		μs	Figure 6.17
CE hold time	t _{ceh}	0	_	ns	
CE setup time	t _{ces}	0	_	ns	
Data hold time	t _{dh}	50		ns	
Data setup time	t _{ds}	50	_	ns	
Write pulse width	t _{wep}	70	_	ns	
Status polling start time	t _{wsts}	1		ms	
Status polling access time	t _{spa}	_	150	ns	
Address setup time	t _{as}	0	_	ns	
Address hold time	t _{ah}	60	_	ns	
Memory write time	t _{write}	1	3000	ms	
WE rise time	t _r	_	30	ns	
WE fall time	t _f		30	ns	



Figure 6.17 Auto-Program Mode Timing Waveforms

6.10.5 Auto-Erase Mode

- 1. Auto-erase mode supports only entire memory erasing.
- 2. Do not perform a command write during auto-erasing.
- 3. Confirm normal end of auto-erasing by checking I/O6. Alternatively, status read mode can also be used for this purpose (I/O7 status polling uses the auto-erase operation end decision pin).
- Status polling I/O6 and I/O7 pin information is retained until the next command write. As long as the next command write has not been performed, reading is possible by enabling CE and OE.
- 5. Table 6.19 shows the AC characteristics.

Table 6.19 AC Characteristics in Auto-Erase Mode

Conditions: $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$, $V_{SS} = 0 \text{ V}$, $T_a = 25^{\circ}\text{C} \pm 5^{\circ}\text{C}$

Item	Symbol	Min	Max	Unit	Notes
Command write cycle	t _{nxtc}	20	—	μs	Figure 6.18
CE hold time	t _{ceh}	0	—	ns	_
CE setup time	t _{ces}	0	_	ns	_
Data hold time	t _{dh}	50	_	ns	_
Data setup time	t _{ds}	50	—	ns	
Write pulse width	t _{wep}	70	_	ns	_
Status polling start time	t _{ests}	1	_	ms	_
Status polling access time	t _{spa}	—	150	ns	
Memory erase time	t _{erase}	100	40000	ms	_
WE rise time	tr	_	30	ns	_
WE fall time	t _f	_	30	ns	_





Figure 6.18 Auto-Erase Mode Timing Waveforms

6.10.6 Status Read Mode

- 1. Status read mode is provided to identify the kind of abnormal end. Use this mode when an abnormal end occurs in auto-program mode or auto-erase mode.
- 2. The return code is retained until a command write other than a status read mode command write is executed.
- 3. Table 6.20 shows the AC characteristics and 6.21 shows the return codes.

Table 6.20 AC Characteristics in Status Read Mode

Conditions: $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$, $V_{SS} = 0 \text{ V}$, $T_a = 25^{\circ}C \pm 5^{\circ}C$

Item	Symbol	Min	Мах	Unit	Notes
Read time after command write	t _{nxtc}	20	_	μs	Figure 6.19
CE hold time	t _{ceh}	0	_	ns	
CE setup time	t _{ces}	0	_	ns	
Data hold time	t _{dh}	50	_	ns	
Data setup time	t _{ds}	50	_	ns	
Write pulse width	t _{wep}	70	_	ns	
OE output delay time	t _{oe}	_	150	ns	
Disable delay time	t _{df}	_	100	ns	
CE output delay time	t _{ce}	_	150	ns	
WE rise time	tr	_	30	ns	
WE fall time	t _f		30	ns	



Figure 6.19 Status Read Mode Timing Waveforms



Pin Name	Initial Value	Indications
I/07	0	1: Abnormal end
		0: Normal end
I/O6	0	1: Command error
		0: Otherwise
I/O5	0	1: Programming error
		0: Otherwise
I/O4	0	1: Erasing error
		0: Otherwise
I/O3	0	_
I/O2	0	_
I/O1	0	1: Over counting of writing or erasing
		0: Otherwise
I/O0	0	1: Effective address error
		0: Otherwise

 Table 6.21
 Status Read Mode Return Codes

6.10.7 Status Polling

- 1. The I/O7 status polling flag indicates the operating status in auto-program/auto-erase mode.
- 2. The I/O6 status polling flag indicates a normal or abnormal end in auto-program/auto-erase mode.

Table 6.22	Status	Polling	Output	Truth	Table
-------------------	--------	---------	--------	-------	-------

I/O7	I/O6	I/O0 to 5	Status
0	0	0	During internal operation
1	0	0	Abnormal end
1	1	0	Normal end
0	1	0	_

6.10.8 Programmer Mode Transition Time

Commands cannot be accepted during the oscillation stabilization period or the programmer mode setup period. After the programmer mode setup time, a transition is made to memory read mode.

Item	Symbol	Min	Мах	Unit	Notes
Oscillation stabilization time(crystal oscillator)	T _{osc1}	10	_	ms	Figure 6.20
Oscillation stabilization time(ceramic oscillator)	T _{osc1}	5		ms	
Programmer mode setup time	T _{bmv}	10		ms	
Vcc hold time	T_{dwn}	0		ms	



Figure 6.20 Oscillation Stabilization Time, Boot Program Transfer Time, and Power-Down Sequence

6.10.9 Notes on Memory Programming

- 1. When performing programming using programmer mode on a chip that has been programmed/erased in an on-board programming mode, auto-erasing is recommended before carrying out auto-programming.
- 2. The flash memory is initially in the erased state when the device is shipped by Renesas Technology. For other chips for which the erasure history is unknown, it is recommended that auto-erasing be executed to check and supplement the initialization (erase) level.



6.11 Power-Down States for Flash Memory

In user mode, the flash memory will operate in either of the following states:

• Normal operating mode

The flash memory can be read and written to at high speed.

• Power-down operating mode

The power supply circuit of the flash memory is partly halted and can be read under low power consumption.

• Standby mode

All flash memory circuits are halted.

Table 6.24 shows the correspondence between the operating modes of this LSI and the flash memory. In subactive mode, the flash memory can be set to operate in power-down mode with the PDWND bit in FLPWCR. When the flash memory returns to its normal operating state from power-down mode or standby mode, a period to stabilize the power supply circuits that were stopped is needed. When the flash memory returns to its normal operating state, bits STS2 to STS0 in SYSCR1 must be set to provide a wait time of at least 20 μ s, even when the external clock is being used.

Table 6.24 Flash Memory Operating States

	Flash Memory Operating State			
LSI Operating State	PDWND = 0 (Initial value)	PDWND = 1		
Active mode	Normal operating mode	Normal operating mode		
Subactive mode	Power-down mode	Normal operating mode		
Sleep mode	Normal operating mode	Normal operating mode		
Subsleep mode	Standby mode	Standby mode		
Standby mode	Standby mode	Standby mode		
Watch mode	Standby mode	Standby mode		



Section 7 RAM

7.1 Overview

The H8/3822R, H8/3823R, H8/38322, H8/38323, H8/38422, and H8/38423 have 1 Kbyte of highspeed static RAM on-chip, and the H8/3824R, H8/3824S, H8/38324, H8/38424, H8/3825R, H8/3825S, H8/38325, H8/38425, H8/3826R, H8/3826S, H8/38326, H8/38426, H8/3827R, H8/3827S, H8/38327, and H8/38427 have 2 Kbytes. The RAM is connected to the CPU by a 16bit data bus, allowing high-speed 2-state access for both byte data and word data.

7.1.1 Block Diagram

Figure 7.1 shows a block diagram of the on-chip RAM.



Figure 7.1 RAM Block Diagram (H8/3824R, H8/3824S, H8/38324, and H8/38424)



Section 8 I/O Ports

8.1 Overview

The H8/3827R Group, H8/3827S Group, and H8/38327 Group is provided with six 8-bit I/O ports, one 4-bit I/O port, one 3-bit I/O port, one 8-bit input-only port, and one 1-bit input-only port. Table 8.1 indicates the functions of each port.

Each port has of a port control register (PCR) that controls input and output, and a port data register (PDR) for storing output data. Input or output can be assigned to individual bits. See section 2.9.2, Notes on Bit Manipulation, for information on executing bit-manipulation instructions to write data in PCR or PDR.

Ports 5, 6, 7, 8, and A are also used as liquid crystal display segment and common pins, selectable in 8-bit units.

Block diagrams of each port are given in Appendix C, I/O Port Block Diagrams.

Port	Description	Pins	Other Functions	Function Switching Registers
Port 1	 8-bit I/O port MOS input pull-up option 	$\frac{P1_7 \text{ to } P1_5}{IRQ_3 \text{ to } IRQ_1}$ TMIF, TMIC	External interrupts 3 to 1 Timer event interrupts TMIF, TMIC	PMR1 TCRF, TMC
		P1 ₄ /IRQ ₄ /ADTRG	External interrupt 4 and A/D converter external trigger	PMR1, AMR
		P1 ₃ /TMIG	Timer G input capture input	PMR1
		P1 ₂ , P1 ₁ / TMOFH, TMOFL	Timer F output compare output	PMR1
		P1 ₀ /TMOW	Timer A clock output	PMR1

Table 8.1 Port Functions

Port	Description	Pins	Other Functions	Function Switching Registers
Port 3	 8-bit I/O port MOS input pull-up option Large-current port (H8/3827R Group, 	P3 ₇ /AEVL P3 ₆ /AEVH P3 ₅ /TXD ₃₁ P3 ₄ /RXD ₃₁ P3 ₃ /SCK ₃₁	SCI3-1 data output (TXD ₃₁), data input (RXD ₃₁), clock input/output (SCK ₃₁), and asynchronous counter event inputs AEVL, AEVH	PMR3 SCR31 SMR31
	(18/38327 Group and H8/38427 Group)	P3 ₂ /RESO ^{*1} P3 ₁ /UD/EXCL ^{*2} P3 ₀ /PWM	Reset output ^{*1} , timer C count-up/down select input, 14-bit PWM output, and external subclock input ^{*2}	PMR2 PMR3
Port 4	 1-bit input port 	P4 ₃ /IRQ ₀	External interrupt 0	PMR3
	• 3-bit I/O port	P4 ₂ /TXD ₃₂ P4 ₁ /RXD ₃₂ P4 ₀ /SCK ₃₂	SCI3-2 data output (TXD ₃₂), data input (RXD ₃₂), clock input/output (SCK ₃₂)	SCR32 SMR32
Port 5	 8-bit I/O port MOS input pull-up option 	$\frac{P5_7 \text{ to } P5_0}{WKP_7 \text{ to } WKP_0}$ SEG ₈ to SEG ₁	Wakeup input (\overline{WKP}_7 to \overline{WKP}_0), segment output (SEG ₈ to SEG ₁)	PMR5 LPCR
Port 6	 8-bit I/O port MOS input pull-up option 	P67 to P60/ SEG16 to SEG9	Segment output (SEG ₁₆ to SEG ₉)	LPCR
Port 7	• 8-bit I/O port	P77 to P70/ SEG24 to SEG17	Segment output (SEG ₂₄ to SEG ₁₇)	LPCR
Port 8	• 8-bit I/O port	P87/SEG ₃₂ /CL ₁ ^{*3} P86/SEG ₃₁ /CL ₂ ^{*3} P85/SEG ₃₀ /DO ^{*3} P84/SEG ₂₉ /M ^{*3} P83 to P80/ SEG ₂₈ to SEG ₂₅	Segment output (SEG ₃₂ to SEG ₂₅) Segment external expansion latch clock (CL ₁) ^{*3} , shift clock (CL ₂) ^{*3} , display data (DO) ^{*3} , alternation signal (M) ^{*3}	LPCR
Port A	4-bit I/O port	PA ₃ to PA ₀ / COM ₄ to COM ₁	Common output (COM ₄ to COM_1)	LPCR
Port B	8-bit input port	PB ₇ to PB ₀ / AN ₇ to AN ₀	A/D converter analog input	AMR

Notes: 1. The RESO function is not implemented in the H8/38327 Group and H8/38427 Group.

2. The EXCL function is only implemented in the H8/38327 Group and H8/38427 Group.

3. The external expansion function for LCD segments is not implemented in the H8/38327 Group and H8/38427 Group.

8.2 Port 1

8.2.1 Overview

Port 1 is a 8-bit I/O port. Figure 8.1 shows its pin configuration.





8.2.2 Register Configuration and Description

Table 8.2 shows the port 1 register configuration.

Table 8.2Port 1 Registers

Name	Abbr.	R/W	Initial Value	Address
Port data register 1	PDR1	R/W	H'00	H'FFD4
Port control register 1	PCR1	W	H'00	H'FFE4
Port pull-up control register 1	PUCR1	R/W	H'00	H'FFE0
Port mode register 1	PMR1	R/W	H'00	H'FFC8

1. Port Data Register 1 (PDR1)

Bit	7	6	5	4	3	2	1	0
	P17	P1 ₆	P1 ₅	P14	P1 3	P12	P1 ₁	P10
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

PDR1 is an 8-bit register that stores data for port 1 pins $P1_7$ to $P1_0$. If port 1 is read while PCR1 bits are set to 1, the values stored in PDR1 are read, regardless of the actual pin states. If port 1 is read while PCR1 bits are cleared to 0, the pin states are read.

Upon reset, PDR1 is initialized to H'00.

2. Port Control Register 1 (PCR1)

Bit	7	6	5	4	3	2	1	0
	PCR17	PCR1 ₆	PCR1 ₅	PCR1 ₄	PCR1 ₃	PCR1 ₂	PCR1 ₁	PCR10
Initial value	0	0	0	0	0	0	0	0
Read/Write	W	W	W	W	W	W	W	W

PCR1 is an 8-bit register for controlling whether each of the port 1 pins $P1_7$ to $P1_0$ functions as an input pin or output pin. Setting a PCR1 bit to 1 makes the corresponding pin an output pin, while clearing the bit to 0 makes the pin an input pin. The settings in PCR1 and in PDR1 are valid only when the corresponding pin is designated in PMR1 as a general I/O pin.

Upon reset, PCR1 is initialized to H'00.

PCR1 is a write-only register, which is always read as all 1s.



3. Port Pull-Up Control Register 1 (PUCR1)

Bit	7	6	5	4	3	2	1	0
	PUCR17	PUCR1 ₆	PUCR15	PUCR1 ₄	PUCR1 ₃	PUCR12	PUCR11	PUCR10
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

PUCR1 controls whether the MOS pull-up of each of the port 1 pins $P1_7$ to $P1_0$ is on or off. When a PCR1 bit is cleared to 0, setting the corresponding PUCR1 bit to 1 turns on the MOS pull-up for the corresponding pin, while clearing the bit to 0 turns off the MOS pull-up.

Upon reset, PUCR1 is initialized to H'00.

4. Port Mode Register 1 (PMR1)

Bit	7	6	5	4	3	2	1	0
	IRQ3	IRQ2	IRQ1	IRQ4	TMIG	TMOFH	TMOFL	TMOW
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

PMR1 is an 8-bit read/write register, controlling the selection of pin functions for port 1 pins.

Upon reset, PMR1 is initialized to H'00.

Bit 7: P1₇/IRQ₃/TMIF pin function switch (IRQ3)

This bit selects whether pin $P1_7/\overline{IRQ_3}/TMIF$ is used as $P1_7$ or as $\overline{IRQ_3}/TMIF$.

Bit 7 IRQ3	Description	
0	Functions as P1 ₇ I/O pin	(initial value)
1	Functions as IRQ ₃ /TMIF input pin	
Noto.	Rising or falling edge sensing can be designated for IRO ₂ TMIE	For details on TMIF

Note: Rising or falling edge sensing can be designated for IRQ₃, TMIF. For details on TMIF settings, see 3. Timer Control Register F (TCRF) in section 9.4.2.

Bit 6: $P1_6/\overline{IRQ}_2$ pin function switch (IRQ2)

This bit selects whether pin $P1_6/\overline{IRQ}_2$ is used as $P1_6$ or as \overline{IRQ}_2 .

Bit 6		
IRQ2	Description	
0	Functions as P1 ₆ I/O pin	(initial value)
1	Functions as \overline{IRQ}_2 input pin	
Mater	Distance of all the second sec	

Note: Rising or falling edge sensing can be designated for \overline{IRQ}_2 .

Bit 5: $P1_5/\overline{IRQ}_1/TMIC$ pin function switch (IRQ1)

This bit selects whether pin P1₅/ \overline{IRQ}_1 /TMIC is used as P1₅ or as \overline{IRQ}_1 /TMIC.

Bit 5 IRQ1	Description
0	Functions as P1 ₅ I/O pin (initial value)
1	Functions as IRQ ₁ /TMIC input pin
Note:	Rising or falling edge sensing can be designated for IRQ ₁ /TMIC.
	For details of TMIC pin setting, see 1. Timer mode register C (TMC) in section 9.3.2.

Bit 4: P1₄/IRQ₄/ADTRG pin function switch (IRQ4)

This bit selects whether pin $P1_4/\overline{IRQ_4}/\overline{ADTRG}$ is used as $P1_4$ or as $\overline{IRQ_4}/\overline{ADTRG}$.

Bit 4 IRQ4	Description
0	Functions as P1 ₄ I/O pin (initial value)
1	Functions as IRQ ₄ /ADTRG input pin
Mater	For details of ADTRO size anti-

Note: For details of ADTRG pin setting, see section 12.3.2, Start of A/D Conversion by External Trigger Input.



Bit 3: P1₃/TMIG pin function switch (TMIG)

This bit selects whether pin P1₃/TMIG is used as P1₃ or as TMIG.

Bit 3 TMIG	Description	
0	Functions as P1 ₃ I/O pin	(initial value)
1	Functions as TMIG input pin	

Bit 2: P1₂/TMOFH pin function switch (TMOFH)

This bit selects whether pin P1₂/TMOFH is used as P1₂ or as TMOFH.

Bit 2 TMOFH	Description	
0	Functions as P1 ₂ I/O pin	(initial value)
1	Functions as TMOFH output pin	

Bit 1: P1₁/TMOFL pin function switch (TMOFL)

This bit selects whether pin $P1_1/TMOFL$ is used as $P1_1$ or as TMOFL.

Bit 1 TMOFL	Description	
0	Functions as P1 ₁ I/O pin	(initial value)
1	Functions as TMOFL output pin	

Bit 0: P1₀/TMOW pin function switch (TMOW)

This bit selects whether pin $P1_0/TMOW$ is used as $P1_0$ or as TMOW.

Bit 0		
TMOW	Description	
0	Functions as P1 ₀ I/O pin	(initial value)
1	Functions as TMOW output pin	

8.2.3 Pin Functions

Table 8.3 shows the port 1 pin functions.

Table 8.3Port 1 Pin Functions

Pin	Pin Functions and Selection Method											
P17/IRQ3/TMIF	\overline{Q}_3 /TMIF The pin function depends on bit IRQ3 in PMR1, bits CKSL2 to CKSL0 in and bit PCR1 ₇ in PCR1.											
	IRQ ₃	0		1								
	PCR17	0	1	×	:							
	CKSL2 to CKSL0		*	Not 0**	0**							
	Pin function	P17 input pin	P17 output pin	IRQ₃ input pin	IRQ ₃ /TMIF input pin							
	Note: When this p to disable th	in is used as the e IRQ₃ interrupt		, clear bit IEN3 t	o 0 in IENR1							
P1 ₆ /IRQ ₂	The pin function de	epends on bits I	RQ2 in PMR1 a	nd bit PCR16 in	PCR1.							
	IRQ2	(0	1	1							
	PCR1 ₆	0 1 *		:								
	Pin function	P16 input pinP16 output pin \overline{IRQ}_2 input pin										
P1₅/IRQ₁ TMIC	The pin function de bit PCR1₅ in PCR1		Q1 in PMR1, bit	ts TMC2 to TMC	0 in TMC, and							
	IRQ1	(0	1								
	PCR1₅	0	1	×	:							
	TMC2 to TMC0	:	*	Not 111	111							
	IRQ₁ input pin	IRQ ₁ /TMIC input pin										
	•			, clear bit IEN1 t	Note: When this pin is used as the TMIC input pin, clear bit IEN1 to 0 in IENR1 to disable the IRQ ₁ interrupt.							

Pin Functions and	d Selection Me	thod						
The pin function depends on bit IRQ4 in PMR1, bit TRGE in AMR, and bit PCR1 $_4$ in PCR1.								
IRQ4		0		1				
PCR1 ₄	0	1	:	*				
TRGE	:	*	0	1				
Pin function	P14 input pin	P1 ₄ output pin	IRQ₄ input pin	IRQ₄/ADTRG input pin				
			oin, clear bit IEN	l4 to 0 in				
The pin function de	epends on bit T	MIG in PMR1 an	d bit PCR1₃ in F	PCR1.				
TMIG		0		1				
PCR1 ₃	0	1	*					
Pin function	P13 input pin	P13 output pin	TMIG input pin					
The pin function de	epends on bit TI	MOFH in PMR1	and bit PCR1 ₂ i	n PCR1.				
TMOFH	(0	1					
PCR1 ₂	0	1	*					
Pin function	P1 ₂ input pin	P12 output pin	TMOFH output pin					
The pin function de	epends on bit TI	MOFL in PMR1 a	and bit PCR1 ₁ ir	n PCR1.				
TMOFL		0		1				
PCR1 ₁	0	1	;	k				
Pin function	P1 ₁ input pin	P11 output pin	TMOFL output pin					
The pin function de	epends on bit T	MOW in PMR1 a	and bit PCR1 ₀ in	PCR1.				
TMOW		0	-	1				
PCR1 ₀	0	1	:	k				
Pin function	P1 ₀ input pin	P1 ₀ output pin	TMOW output pin					
	The pin function de in PCR1. IRQ4 PCR14 TRGE Pin function Note: When this p IENR1 to dia The pin function de TMIG PCR13 Pin function de TMOFH PCR12 Pin function The pin function de TMOFL PCR11 Pin function The pin function de TMOFL PCR11 Pin function	The pin function depends on bit IR in PCR1.IRQ4PCR140PCR140TRGEPin functionP14 input pinNote: When this pin is used as the IENR1 to disable the IRQ4 iThe pin function depends on bit TITMIG0PCR130Pin function depends on bit TIThe pin function depends on bit TITMOFHPCR120Pin functionP12 input pinThe pin function depends on bit TITMOFL0PCR110Pin functionP11 input pinThe pin function depends on bit TITMOFL0PCR110Pin functionP11 input pin	in PCR1. IRQ4 0 PCR14 0 1 TRGE * Pin function P14 input pin P14 output pin Note: When this pin is used as the ADTRG input pin IENR1 to disable the IRQ4 interrupt. The pin function depends on bit TMIG in PMR1 an 0 1 TMIG 0 1 PCR13 0 1 Pin function P13 input pin P13 output pin The pin function depends on bit TMOFH in PMR1 0 PCR12 0 1 PCR12 0 1 PCR12 0 1 TMOFH 0 1 PCR12 0 1 Pin function P12 input pin P12 output pin The pin function depends on bit TMOFL in PMR1 and the pin function depends on bit TMOFL in PMR1 and the pin function 1 PCR11 0 1 The pin function depends on bit TMOFL in pMR1 and the pin function 1 TMOFL 0 1 Pin function P11 input pin P11 output pin The pin function depends on bit TMOW in PMR1 and the pin function depends on b	The pin function depends on bit IRQ4 in PMR1, bit TRGE in AMR, in PCR1.IRQ40PCR140TRGE*0Pin functionP14 input pinP14 output pinIENR1 to disable the IRQ4 interrupt.The pin function depends on bit TMIG in PMR1 and bit PCR13 in FTMIG0PCR130PCR130PCR130Pin function depends on bit TMOFH in PMR1 and bit PCR12 in FThe pin function depends on bit TMOFH in PMR1 and bit PCR12 in FThe pin function depends on bit TMOFH in PMR1 and bit PCR12 in TMIG in FThe pin function depends on bit TMOFH in PMR1 and bit PCR12 in TMOFHThe pin function depends on bit TMOFH in PMR1 and bit PCR12 in TMOFHThe pin function depends on bit TMOFL in PMR1 and bit PCR11 in TMOFHThe pin function depends on bit TMOFL in PMR1 and bit PCR11 in TMOFL 0The pin function depends on bit TMOFL in PMR1 and bit PCR11 in TMOFL 0The pin function depends on bit TMOFL in PMR1 and bit PCR11 in TMOFL 0PCR110PCR110PCR110PCR110PCR10011TMOW011111111111111111111111111111111				

*: Don't care

8.2.4 Pin States

Table 8.4 shows the port 1 pin states in each operating mode.

Table 8.4 Port 1 Pin States

Pins	Reset	Sleep	Subsleep	Standby	Watch	Subactive	Active
P17/IRQ3/TMIF P16/IRQ2 P15/IRQ1/TMIC P14/IRQ4/ADTRG P13/TMIG P12/TMOFH P11/TMOFL P10/TMOW	High- impedance	Retains previous state	Retains previous state	High- impedance*		Functional	Functional
. -			han tha MC		n tha an a	hata	

Note: * A high-level signal is output when the MOS pull-up is in the on state.

8.2.5 MOS Input Pull-Up

Port 1 has a built-in MOS input pull-up function that can be controlled by software. When a PCR1 bit is cleared to 0, setting the corresponding PUCR1 bit to 1 turns on the MOS input pull-up for that pin. The MOS input pull-up function is in the off state after a reset.

PCR1 _n	0	0	1
PUCR1n	0	1	*
MOS input pull-up	Off	On	Off
			(n = 7 to 0)

(n = 7 to 0) *: Don't care



8.3 Port 3

8.3.1 Overview

Port 3 is a 8-bit I/O port, configured as shown in figure 8.2.

In the F-ZTAT version, the on-chip pull-up MOS for pin $P3_2$ is on during the reset period. It turns off and normal operation resumes after the reset is cleared. This should be considered when making connections to external circuitry. Note that in the mask ROM and ZTAT versions $P3_2$ continues to operate normally.



Figure 8.2 Port 3 Pin Configuration

8.3.2 Register Configuration and Description

Table 8.5 shows the port 3 register configuration.

Table 8.5Port 3 Registers

Name	Abbr.	R/W	Initial Value	Address
Port data register 3	PDR3	R/W	H'00	H'FFD6
Port control register 3	PCR3	W	H'00	H'FFE6
Port pull-up control register 3	PUCR3	R/W	H'00	H'FFE1
Port mode register 2	PMR2	R/W	H'58	H'FFC9
Port mode register 3	PMR3	R/W	H'04	H'FFCA

1. Port Data Register 3 (PDR3)

Bit	7	6	5	4	3	2	1	0
	P37	P3 ₆	P35	P34	P3 ₃	P32	P31	P30
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

PDR3 is an 8-bit register that stores data for port 3 pins $P3_7$ to $P3_0$. If port 3 is read while PCR3 bits are set to 1, the values stored in PDR3 are read, regardless of the actual pin states. If port 3 is read while PCR3 bits are cleared to 0, the pin states are read.

Upon reset, PDR3 is initialized to H'00.

2. Port Control Register 3 (PCR3)

Bit	7	6	5	4	3	2	1	0
	PCR37	PCR3 ₆	PCR3 ₅	PCR3 ₄	PCR3 ₃	PCR3 ₂	PCR3 ₁	PCR30
Initial value	0	0	0	0	0	0	0	0
Read/Write	W	W	W	W	W	W	W	W

PCR3 is an 8-bit register for controlling whether each of the port 3 pins $P3_7$ to $P3_0$ functions as an input pin or output pin. Setting a PCR3 bit to 1 makes the corresponding pin an output pin, while clearing the bit to 0 makes the pin an input pin. The settings in PCR3 and in PDR3 are valid only when the corresponding pin is designated in PMR3 as a general I/O pin.

Upon reset, PCR3 is initialized to H'00.

PCR3 is a write-only register, which is always read as all 1s.



3. Port Pull-Up Control Register 3 (PUCR3)

Bit	7	6	5	4	3	2	1	0
	PUCR37	PUCR3 ₆	PUCR35	PUCR3 ₄	PUCR33	PUCR3 ₂	PUCR31	PUCR30
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

PUCR3 controls whether the MOS pull-up of each of the port 3 pins $P3_7$ to $P3_0$ is on or off. When a PCR3 bit is cleared to 0, setting the corresponding PUCR3 bit to 1 turns on the MOS pull-up for the corresponding pin, while clearing the bit to 0 turns off the MOS pull-up.

Upon reset, PUCR3 is initialized to H'00.

4. Port Mode Register 3 (PMR3)

Bit	7	6	5	4	3	2	1	0
	AEVL	AEVH	WDCKS	NCS	IRQ0	RESO*	UD	PWM
Initial value	0	0	0	0	0	1	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Note: * The RESO bit is not implemented in the H8/38327 Group and H8/38427 Group.

PMR3 is an 8-bit read/write register, controlling the selection of pin functions for port 3 pins.

Upon reset, PMR3 is initialized to H'04.

Bit 7: P3₇/AEVL pin function switch (AEVL)

This bit selects whether pin P37/AEVL is used as P37 or as AEVL.

Bit 7		
AEVL	Description	
0	Functions as P3 ₇ I/O pin	(initial value)
1	Functions as AEVL input pin	

Bit 6: P3₆/AEVH pin function switch (AEVH)

This bit selects whether pin $P3_6/AEVH$ is used as $P3_6$ or as AEVH.

Bit 6 AEVH	Description	
0	Functions as P3 ₆ I/O pin	(initial value)
1	Functions as AEVH input pin	

Bit 5: Watchdog timer source clock select (WDCKS)

This bit selects the watchdog timer source clock.

Bit 5 WDCKS	Description	
0	φ/8192 selected	(initial value)
1	φw/32 selected	

Bit 4: TMIG noise canceler select (NCS)

This bit controls the noise canceler for the input capture input signal (TMIG).

Bit 4 NCS	Description	
0	Noise cancellation function not used	(initial value)
1	Noise cancellation function used	

Bit 3: $P4_3/\overline{IRQ}_0$ pin function switch (IRQ₀)

This bit selects whether pin P4₃/ \overline{IRQ}_0 is used as P4₃ or as \overline{IRQ}_0 .

Bit 3 IRQ₀	Description	
0	Functions as P4 ₃ input pin	(initial value)
1	Functions as \overline{IRQ}_0 input pin	

Bit 2: P3₂/RESO pin function switch (RESO)

This bit selects whether pin $P3_2/\overline{RESO}$ is used as $P3_2$ or as \overline{RESO} .

In the H8/38327 Group and H8/38427 Group these bits are reserved and cannot be written to.

Bit 2 RESO	Description	
0	Functions as $P3_2$ I/O pin	
1	Functions as RESO output pin	(initial value)

Bit 1: P3₁/UD pin function switch (SI1)

This bit selects whether pin $P3_1/UD$ is used as $P3_1$ or as UD.

Bit 1		
UD	Description	
0	Functions as P3 ₁ I/O pin	(initial value)
1	Functions as UD input pin	

Bit 0: P3₀/PWM pin function switch (PWM)

This bit selects whether pin P3₀/PWM is used as P3₀ or as PWM.

Bit 0 PWM	Description	
0	Functions as P3 ₀ I/O pin	(initial value)
1	Functions as PWM output pin	

5. Port Mode Register 2 (PMR2)

Bit	7	6	5	4	3	2	1	0	_
	EXCL	—	—	_	_	_	_	_	
Initial value	0	1	0	1	1	0	0	0	-
Read/Write	R/W	R	R/W	R	R	R/W	R/W	R/W	

PMR2 is an 8-bit read/write register that controls external clock input to pin P31.

Upon reset, PMR2 is initialized to H'58. The information on this register applies to the H8/38327 Group and H8/38427 Group.

Bit 7: P3₁/UD/EXCL pin function switch (EXCL)

This bit selects whether pin $P3_1/UD/EXCL$ is used as $P3_1/UD$ or as EXCL. When the pin is used as EXCL an external clock should be input to it. See section 4, Clock Pulse Generators, for a connection example.

Bit 7	-	
EXCL	Description	
0	Functions as P3 ₁ /UD I/O pin	(initial value)
1	Functions as EXCL input pin	

Bit 6: Reserved bit

Bit 6 is a reserved bit. It is always read as 1 and cannot be modified.

Bit 5: Reserved bit

Bit 5 is a readable/writable reserved bit.

Bits 4 and 3: Reserved bits

Bits 4 and 3 are reserved bits. They are always read as 1 and cannot be modified.

Bits 2 to 0: Reserved bits

Bits 2 to 0 are readable/writable reserved bits.



8.3.3 Pin Functions

Table 8.6 shows the port 3 pin functions.

Table 8.6Port 3 Pin Functions

Pin	Pin Functions and	d Selection Met	hod					
P37/AEVL	The pin function de	The pin function depends on bit SO1 in PMR3 and bit PCR37 in PCR3.						
	AEVL		0			1		
	PCR37	0		1		*		
	Pin function	P37 input p	in P37 ou	ıtput pin	A	EVL input pin		
P3 ₆ /AEVH	The pin function de	epends on bit AE	VH in PMR3 a	nd bit P(CR3 ₆ in	PCR3.		
	AEVH		0			1		
	PCR36	0		1		*		
	Pin function	P3 ₆ input p	in P3 ₆ ou	ıtput pin	AE	EVH input pin		
P3 ₅ /TXD ₃₁	The pin function de PCR3₅ in PCR3.	epends on bit TE	31 in SCR3-1, b	oit SPC3	1 in SP	CR, and bit		
	SPC31	0				1		
	TE ₃₁	0				1		
	PCR3₅	0		1		*		
	Pin function	P3₅ input p	in P3₅ οι	ıtput pin	TX	TXD_{31} output pin		
P3 ₄ /RXD ₃₁	The pin function de	The pin function depends on bit RE ₃₁ in SCR3-1 and bit PCR3₄ in PCR3.						
	RE ₃₁	0				1		
	PCR3 ₄	0		1		*		
	Pin function	P34 input pin P34 out		tput pin RX		CD31 input pin		
P3 ₃ /SCK ₃₁	The pin function depends on bits CKE311, CKE310, and SMR31 in SCR3-1 and bit PCR3 ₃ in PCR3.							
	CKE311		0			1		
	CKE310		0		1	*		
	COM3 ₁		0	1	*	*		
	PCR3 ₃	0	1	1 *		*		
	Pin function	P3 ₃ input pin	P33 output pir	-	output in	SCK ₃₁ input pin		

Pin	Pin Functions and	Selection Met	hod					
P3 ₂ /RESO	• H8/3827R Group	p and H8/38278	S Gro	up				
(H8/3827R,	The pin function	The pin function depends on bit RESO in PMR3 and bit PCR3 ₂ in PCR3.						
H8/3827S)	RESO		()			1	
	PCR3 ₂	0			1		*	
	Pin function	P3 ₂ input p	in	P3 ₂ out	tput pin	RE	SO output pin	
P3 ₂ (H8/38327,	• H8/38327 Group	o and H8/38427	Grou	qu				
H8/38427)	The pin function	depends on bit	PCR	32 in PCR	3.			
	PCR3 ₂	0		-	1]		
	Pin function	P32 input p	in	P3 ₂ out	tput pin			
P3 ₁ /UD (H8/3827R,	 H8/3827R Group and H8/3827S Group The pin function depends on bit UD in PMR3 and bit PCR3₁ in PCR3. 						n PCR3.	
H8/3827S)	UD	0		1		7		
	PCR3 ₁	0		1	*		_	
	Pin function	P31 input pin	n P3₁ output pin		UD input pin		_	
P31/UD/EXCL (H8/38327, H8/38427)	 H8/38327 Group The pin function PCR3₁ in PCR3 	depends on bit			2, bit UD in	PM	R3, and bit	
	EXCL			0			1	
	UD		0		1		*	
	PCR3 ₁	0		1	*		*	
	Pin function	P31 input pin	P31 (output pin	UD input	pin	EXCL input pin	
P3 ₀ /PWM	The pin function dep	pends on bit PV	/M in	PMR3 and	d bit PCR3	B ₀ in	PCR3.	
	PWM		()			1	
	PCR3 ₀	0		-	1		*	
	Pin function	P3 ₀ input p	in	P3 ₀ out	tput pin	P\	NM output pin	

*: Don't care



8.3.4 Pin States

Table 8.7 shows the port 3 pin states in each operating mode.

Pins	Reset	Sleep	Subsleep	Standby	Watch	Subactive	Active
P37/AEVL P36/AEVH P36/TXD31 P34/RXD31 P33/SCK31	High- impedance	Retains previous state	Retains previous state	High- impedance ^{*1}	Retains previous state	Functional	Functional
P3 ₂ /RESO ^{*2}	RESO output	_					
P32 ^{*4}	Pull-up MOS on	_					
P32 ^{*3} P31/UD ^{*2} P31/UD/EXCL ^{*3*4} P30/PWM	High- impedance	-					

Table 8.7Port 3 Pin States

Notes: 1. A high-level signal is output when the MOS pull-up is in the on state.

- 2. Applies to H8/3827R Group and H8/3827S Group.
- 3. Applies to the mask ROM version of the H8/38327 Group and H8/38427 Group.
- 4. Applies to the F-ZTAT version of the H8/38327 Group and H8/38427 Group.

8.3.5 MOS Input Pull-Up

Port 3 has a built-in MOS input pull-up function that can be controlled by software. When a PCR3 bit is cleared to 0, setting the corresponding PUCR3 bit to 1 turns on the MOS pull-up for that pin. The MOS pull-up function is in the off state after a reset.

PCR3n	0	0	1
PUCR3n	0	1	*
MOS input pull-up	Off	On	Off

(n = 7 to 0)

*: Don't care

8.4 Port 4

8.4.1 Overview

Port 4 is a 3-bit I/O port and 1-bit input port, configured as shown in figure 8.3.



Figure 8.3 Port 4 Pin Configuration

8.4.2 Register Configuration and Description

Table 8.8 shows the port 4 register configuration.

Table 8.8Port 4 Registers

Name	Abbr.	R/W	Initial Value	Address
Port data register 4	PDR4	R/W	H'F8	H'FFD7
Port control register 4	PCR4	W	H'F8	H'FFE7



1. Port Data Register 4 (PDR4)



PDR4 is an 8-bit register that stores data for port 4 pins $P4_2$ to $P4_0$. If port 4 is read while PCR4 bits are set to 1, the values stored in PDR4 are read, regardless of the actual pin states. If port 4 is read while PCR4 bits are cleared to 0, the pin states are read.

Upon reset, PDR4 is initialized to H'F8.

2. Port Control Register 4 (PCR4)



PCR4 is an 8-bit register for controlling whether each of port 4 pins $P4_2$ to $P4_0$ functions as an input pin or output pin. Setting a PCR4 bit to 1 makes the corresponding pin an output pin, while clearing the bit to 0 makes the pin an input pin. PCR4 and PDR4 settings are valid when the corresponding pins are designated for general-purpose input/output by SCR3-2.

Upon reset, PCR4 is initialized to H'F8.

PCR4 is a write-only register, which always reads all 1s.

8.4.3 Pin Functions

Table 8.9 shows the port 4 pin functions.

Table 8.9Port 4 Pin Functions

Pin	Pin Functions and Selection Method								
P4 ₃ /IRQ ₀	The pin function depends on bit IRQ0 in PMR3.								
	IRQ0		1						
	Pin function	P4 ₃ in		\overline{IRQ}_0 in	iput pin				
P4 ₂ /TXD ₃₂	The pin function de PCR4 ₂ in PCR4.	pends on bit TE	32 in SCR3-2, b	it SPC3	2 in SP	CR, and bit			
	SPC32		0			1			
	TE ₃₂		0			1			
	PCR4 ₂	0		1		*			
	Pin function	P4 ₂ input pin P4 ₂		tput pin T		XD ₃₂ output pin			
P41/RXD32	The pin function depends on bit RE ₃₂ in SCR3-2 and bit PCR4 ₁ in PCR4.								
	RE ₃₂				1				
	PCR41	0		1		*			
	Pin function	P4₁ input p	in P4 ₁ ou	P4 ₁ output pin R		XD ₃₂ input pin			
P40/SCK32	The pin function de SMR32, and bit PC		E321 and CKE	320 in S	CR3-2,	bit COM32 in			
	CKE321			1					
	CKE320		0		1	*			
	COM32		0	1	*	*			
	PCR4 ₀	0	1	*		*			
	Pin function	P4 ₀ input pin	P4 ₀ output pin	output pin SCK ₃₂ or pin		SCK ₃₂ input pin			

*: Don't care

8.4.4 Pin States

Table 8.10 shows the port 4 pin states in each operating mode.

Table 8.10Port 4 Pin States

Pins	Reset	Sleep	Subsleep	Standby	Watch	Subactive	Active
P4 ₃ /IRQ ₀ P4 ₂ /TXD ₃₂ P4 ₁ /RXD ₃₂ P4 ₀ /SCK ₃₂	High- impedance	Retains previous state		High- impedance		Functional	Functional

8.5 Port 5

8.5.1 Overview

Port 5 is an 8-bit I/O port, configured as shown in figure 8.4.



Figure 8.4 Port 5 Pin Configuration

8.5.2 Register Configuration and Description

Table 8.11 shows the port 5 register configuration.

Table 8.11 Port 5 Registers

Name	Abbr.	R/W	Initial Value	Address
Port data register 5	PDR5	R/W	H'00	H'FFD8
Port control register 5	PCR5	W	H'00	H'FFE8
Port pull-up control register 5	PUCR5	R/W	H'00	H'FFE2
Port mode register 5	PMR5	R/W	H'00	H'FFCC

1. Port Data Register 5 (PDR5)

Bit	7	6	5	4	3	2	1	0
	P57	P5 ₆	P5 ₅	P54	P53	P5 ₂	P51	P50
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

PDR5 is an 8-bit register that stores data for port 5 pins $P5_7$ to $P5_0$. If port 5 is read while PCR5 bits are set to 1, the values stored in PDR5 are read, regardless of the actual pin states. If port 5 is read while PCR5 bits are cleared to 0, the pin states are read.

Upon reset, PDR5 is initialized to H'00.

2. Port Control Register 5 (PCR5)

Bit	7	6	5	4	3	2	1	0
	PCR57	PCR5 ₆	PCR55	PCR5 ₄	PCR53	PCR5 ₂	PCR51	PCR50
Initial value	0	0	0	0	0	0	0	0
Read/Write	W	W	W	W	W	W	W	W

PCR5 is an 8-bit register for controlling whether each of the port 5 pins $P5_7$ to $P5_0$ functions as an input pin or output pin. Setting a PCR5 bit to 1 makes the corresponding pin an output pin, while clearing the bit to 0 makes the pin an input pin. PCR5 and PDR5 settings are valid when the corresponding pins are designated for general-purpose input/output by PMR5 and bits SGS3 to SGS0 in LPCR.

Upon reset, PCR5 is initialized to H'00.
PCR5 is a write-only register, which is always read as all 1s.

3. Port Pull-Up Control Register 5 (PUCR5)

Bit	7	6	5	4	3	2	1	0
	PUCR57	PUCR5 ₆	PUCR55	PUCR5 ₄	PUCR53	PUCR52	PUCR51	PUCR50
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

PUCR5 controls whether the MOS pull-up of each of port 5 pins $P5_7$ to $P5_0$ is on or off. When a PCR5 bit is cleared to 0, setting the corresponding PUCR5 bit to 1 turns on the MOS pull-up for the corresponding pin, while clearing the bit to 0 turns off the MOS pull-up.

Upon reset, PUCR5 is initialized to H'00.

4. Port Mode Register 5 (PMR5)

Bit	7	6	5	4	3	2	1	0
	WKP7	WKP ₆	WKP ₅	WKP ₄	WKP ₃	WKP ₂	WKP ₁	WKP ₀
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

PMR5 is an 8-bit read/write register, controlling the selection of pin functions for port 5 pins.

Upon reset, PMR5 is initialized to H'00.

Bit n: $P5_n/\overline{WKP}_n/SEG_{n+1}$ pin function switch (WKPn)

When pin P5n/WKPn/SEGn+1 is not used as SEG_{n+1} , these bits select whether the pin is used as P5n or WKP_n .

Bit n WKPn	Description	
0	Functions as P5n I/O pin	(initial value)
1	Functions as \overline{WKP}_n input pin	

(n = 7 to 0)

Note: For use as SEG_{n+1}, see section 13.2.1, LCD Port Control Register (LPCR).

Renesas

8.5.3 **Pin Functions**

Table 8.12 shows the port 5 pin functions.

Table 8.12 Port 5 Pin Functions

Pin **Pin Functions and Selection Method**

P57/WKP7/SEG8 The pin function depends on bit WKPn in PMR5, bit PCR5n in PCR5, and bits SGS3 to SGS0 in LPCR. to P5₀/WKP₀/SEG₁

(n = 7 to 0)

SGS3 to SGS0		1***		
WKPn	(0	1	*
PCR5 _n	0 1		*	*
Pin function	P5 _n input pin	P5 _n output pin	WKPn input pin	SEGn+1 output pin

*: Don't care

8.5.4 **Pin States**

Table 8.13 shows the port 5 pin states in each operating mode.

Table 8.13 Port 5 Pin States

Pins	Reset	Sleep	Subsleep	Standby	Watch	Subactive	Active
$P5_7/\overline{WKP}_7/$ SEG ₈ to $P5_0/$ \overline{WKP}_0/SEG_1	High- impedance			High- impedance [*]		Functional	Functional

Note: * A high-level signal is output when the MOS pull-up is in the on state.

8.5.5 MOS Input Pull-Up

Port 5 has a built-in MOS input pull-up function that can be controlled by software. When a PCR5 bit is cleared to 0, setting the corresponding PUCR5 bit to 1 turns on the MOS pull-up for that pin. The MOS pull-up function is in the off state after a reset.

PCR5n	0	0	1	
PUCR5n	0	1	*	
MOS input pull-up	Off	On	Off	
			(n = 7	7 to 0)
			*: Don'	t care

8.6 Port 6

8.6.1 Overview

Port 6 is an 8-bit I/O port. The port 6 pin configuration is shown in figure 8.5.



Figure 8.5 Port 6 Pin Configuration

8.6.2 Register Configuration and Description

Table 8.14 shows the port 6 register configuration.

Table 8.14Port 6 Registers

Name	Abbr.	R/W	Initial Value	Address
Port data register 6	PDR6	R/W	H'00	H'FFD9
Port control register 6	PCR6	W	H'00	H'FFE9
Port pull-up control register 6	PUCR6	R/W	H'00	H'FFE3

1. Port Data Register 6 (PDR6)

Bit	7	6	5	4	3	2	1	0
	P67	P6 ₆	P65	P64	P63	P62	P6 ₁	P60
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

PDR6 is an 8-bit register that stores data for port 6 pins P67 to P60.

If port 6 is read while PCR6 bits are set to 1, the values stored in PDR6 are read, regardless of the actual pin states. If port 6 is read while PCR6 bits are cleared to 0, the pin states are read.

Upon reset, PDR6 is initialized to H'00.

2. Port Control Register 6 (PCR6)

Bit	7	6	5	4	3	2	1	0
	PCR67	PCR6 ₆	PCR6 ₅	PCR6 ₄	PCR63	PCR6 ₂	PCR6 ₁	PCR60
Initial value	0	0	0	0	0	0	0	0
Read/Write	W	W	W	W	W	W	W	W

PCR6 is an 8-bit register for controlling whether each of the port 6 pins $P6_7$ to $P6_0$ functions as an input pin or output pin.

Setting a PCR6 bit to 1 makes the corresponding pin $(P6_7 \text{ to } P6_0)$ an output pin, while clearing the bit to 0 makes the pin an input pin. PCR6 and PDR6 settings are valid when the corresponding pins are designated for general-purpose input/output by bits SGS3 to SGS0 in LPCR.

Upon reset, PCR6 is initialized to H'00.

PCR6 is a write-only register, which always reads all 1s.

3. Port Pull-Up Control Register 6 (PUCR6)

Bit	7	6	5	4	3	2	1	0
	PUCR67	PUCR66	PUCR65	PUCR64	PUCR63	PUCR6 ₂	PUCR61	PUCR60
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

PUCR6 controls whether the MOS pull-up of each of the port 6 pins $P6_7$ to $P6_0$ is on or off. When a PCR6 bit is cleared to 0, setting the corresponding PUCR6 bit to 1 turns on the MOS pull-up for the corresponding pin, while clearing the bit to 0 turns off the MOS pull-up.

Upon reset, PUCR6 is initialized to H'00.

8.6.3 **Pin Functions**

Table 8.15 shows the port 6 pin functions.

Table 8.15 Port 6 Pin Functions

Pin	Pin Functions and Selection Method							
P6 ₇ /SEG ₁₆ to P6 ₀ /SEG ₉	The pin function depends on bit PCR6n in PCR6 and bits SGS3 to SGS0 in LPCR. (n = 7 to 0)							
	SEG3 to SEGS0	00**,	011**, 1***					
	PCR6 _n	0	1	*				
	Pin function	P6 _n input pin	P6 _n output pin	SEG _{n+9} output pin				

*: Don't care

8.6.4 Pin States

Table 8.16 shows the port 6 pin states in each operating mode.

Table 8.16 Port 6 Pin States

Pin	Reset	Sleep	Subsleep	Standby	Watch	Subactive	Active
P67/SEG16 to P60/SEG9	High- impedance		Retains previous state	High- impedance [*]		Functional	Functional

Note: * A high-level signal is output when the MOS pull-up is in the on state.

8.6.5 MOS Input Pull-Up

Port 6 has a built-in MOS pull-up function that can be controlled by software. When a PCR6 bit is cleared to 0, setting the corresponding PUCR6 bit to 1 turns on the MOS pull-up for that pin. The MOS pull-up function is in the off state after a reset.

PCR6n	0	0	1
PUCR6 _n	0	1	*
MOS input pull-up	Off	On	Off

(n = 7 to 0) *: Don't care



8.7 Port 7

8.7.1 Overview

Port 7 is a 8-bit I/O port, configured as shown in figure 8.6.





8.7.2 Register Configuration and Description

Table 8.17 shows the port 7 register configuration.

Table 8.17Port 7 Registers

Name	Abbr.	R/W	Initial Value	Address
Port data register 7	PDR7	R/W	H'00	H'FFDA
Port control register 7	PCR7	W	H'00	H'FFEA

1. Port Data Register 7 (PDR7)

Bit	7	6	5	4	3	2	1	0
	P7 ₇	P7 ₆	P75	P74	P73	P72	P7 ₁	P70
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

PDR7 is an 8-bit register that stores data for port 7 pins $P7_7$ to $P7_0$. If port 7 is read while PCR7 bits are set to 1, the values stored in PDR7 are read, regardless of the actual pin states. If port 7 is read while PCR7 bits are cleared to 0, the pin states are read.

Upon reset, PDR7 is initialized to H'00.

2. Port Control Register 7 (PCR7)

Bit	7	6	5	4	3	2	1	0
	PCR77	PCR76	PCR75	PCR74	PCR73	PCR72	PCR71	PCR70
Initial value	0	0	0	0	0	0	0	0
Read/Write	W	W	W	W	W	W	W	W

PCR7 is an 8-bit register for controlling whether each of the port 7 pins $P7_7$ to $P7_0$ functions as an input pin or output pin. Setting a PCR7 bit to 1 makes the corresponding pin an output pin, while clearing the bit to 0 makes the pin an input pin. PCR7 and PDR7 settings are valid when the corresponding pins are designated for general-purpose input/output by bits SGS3 to SGS0 in LPCR.

Upon reset, PCR7 is initialized to H'00.

PCR7 is a write-only register, which always reads as all 1s.



8.7.3 Pin Functions

Table 8.18 shows the port 7 pin functions.

Table 8.18Port 7 Pin Functions

Pin	Pin Functions and Selection Method							
P77/SEG24 to P70/SEG17	The pin function depends on bit PCR7 _n in PCR7 and bits SGS3 to SGS0 in LPCR. $(n = 7 \text{ to } 0)$							
	SEGS3 to SEGS0	00	01**, 1***					
	PCR7n	0	1	*				
	Pin function	P7 _n input pin P7 _n output pin		SEG_{n+17} output pin				
	·							

*: Don't care

8.7.4 Pin States

Table 8.19 shows the port 7 pin states in each operating mode.

Table 8.19Port 7 Pin States

Pins	Reset	Sleep	Subsleep	Standby	Watch	Subactive	Active
P7 ₇ /SEG ₂₄ to P7 ₀ /SEG ₁₇	High- impedance	Retains previous state		High- impedance		Functional	Functional

8.8 Port 8

8.8.1 Overview

Port 8 is an 8-bit I/O port configured as shown in figure 8.7.



Figure 8.7 Port 8 Pin Configuration

8.8.2 Register Configuration and Description

Table 8.20 shows the port 8 register configuration.

Table 8.20 Port 8 Registers

Name	Abbr.	R/W	Initial Value	Address
Port data register 8	PDR8	R/W	H'00	H'FFDB
Port control register 8	PCR8	W	H'00	H'FFEB

1. Port Data Register 8 (PDR8)

Bit	7	6	5	4	3	2	1	0
	P87	P8 ₆	P85	P84	P83	P82	P8 ₁	P8 ₀
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

PDR8 is an 8-bit register that stores data for port 8 pins $P8_7$ to $P8_0$. If port 8 is read while PCR8 bits are set to 1, the values stored in PDR8 are read, regardless of the actual pin states. If port 8 is read while PCR8 bits are cleared to 0, the pin states are read.

Upon reset, PDR8 is initialized to H'00.

2. Port Control Register 8 (PCR8)

Bit	7	6	5	4	3	2	1	0
	PCR87	PCR8 ₆	PCR85	PCR84	PCR83	PCR82	PCR81	PCR80
Initial value	0	0	0	0	0	0	0	0
Read/Write	W	W	W	W	W	W	W	W

PCR8 is an 8-bit register for controlling whether each of the port 8 pins $P8_7$ to $P8_0$ functions as an input or output pin. Setting a PCR8 bit to 1 makes the corresponding pin an output pin, while clearing the bit to 0 makes the pin an input pin. PCR8 and PDR8 settings are valid when the corresponding pins are designated for general-purpose input/output by bits SGS3 to SGS0 in LPCR.

Upon reset, PCR8 is initialized to H'00.

PCR8 is a write-only register, which is always read as all 1s.

Renesas

8.8.3 **Pin Functions**

Table 8.21 shows the port 8 pin functions. The SGX = 0 setting also functions on the H8/38327 and H8/38427.

Table 8.21 Port 8 Pin Functions

Pin	Pin Functions and	Selection Me	thod				
P87/SEG32/ CL1	The pin function de in LPCR.	pends on bit P	CR87 ir	n PCR8 a	nd bits SGX	and So	GS3 to SGS0
	SEGS3 to SEGS0	00)0*		001*, 01**,	1***	0000
	SGX	(0		0		1
	PCR87	0		1	*		*
	Pin function	P87 input pin	P87 0	utput pin	SEG ₃₂ outp	ut pin	CL1 output pin
P8 ₆ /SEG ₃₁ / CL ₂	The pin function de in LPCR.	pends on bit P	CR8 ₆ ir	ı PCR8 a	nd bits SGX	and S	GS3 to SGS0
	SEGS3 to SEGS0	00)0*		001*, 01**,	1***	0000
	SGX	(0		0		1
	PCR86	0		1	*		*
	Pin function	P86 input pin	P8 ₆ o	utput pin	SEG ₃₁ outp	ut pin	CL_2 output pin
P85/SEG30/ The pin function depends on bit PCR85 in PCR8 and bits SGX and SGS3 to in LPCR.							1
	SEGS3 to SEGS0	000*			001*, 01**,	1***	0000
	SGX		0		0		1
	PCR8₅	0		1	*		*
	Pin function	P85 input pin	P8 ₅ o	utput pin	SEG ₃₀ outp	ut pin	D0 output pin
P8 ₄ /SEG ₂₉ / M	The pin function de in LPCR.	pends on bit P	CR8₄ ir	n PCR8 a	nd bits SGX	and So	GS3 to SGS0
	SEGS3 to SEGS0	00)0*		001*, 01**,	1***	0000
	SGX	(C		0		1
	PCR84	0		1	*		*
	Pin function	P84 input pin	P84 0	utput pin	SEG ₂₉ outp	ut pin	M output pin
P83/SEG28 to P80/SEG25	The pin function de	pends on bit P	CR8 _n ir	ı PCR8 a	nd bits SGS3		SS0 in LPCR. (n = 3 to 0)
	SEGS3 to SEGS0		00	0*		001	*, 01**, 1***
	PCR8 _n	0			1		*
	Pin function	P8 _n input p	in	P8 _n o	utput pin	SEG	n+25 output pin
							*: Don't care

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8.8.4 Pin States

Table 8.22 shows the port 8 pin states in each operating mode.

Table 8.22 Port 8 Pin States

Pins	Reset	Sleep	Subsleep	Standby	Watch	Subactive	Active
P87/SEG ₃₂ /CL ₁ P86/SEG ₃₁ /CL ₂ P85/SEG ₃₀ /DO P84/SEG ₂₉ /M P83/SEG ₂₈ to P80/SEG ₂₅	High- impedance	Retains previous state	Retains previous state	High- impedance	Retains previous state	Functional	Functional

8.9 Port A

8.9.1 Overview

Port A is a 4-bit I/O port, configured as shown in figure 8.8.



Figure 8.8 Port A Pin Configuration

8.9.2 Register Configuration and Description

Table 8.23 shows the port A register configuration.

Table 8.23 Port A Registers

Name	Abbr.	R/W	Initial Value	Address
Port data register A	PDRA	R/W	H'F0	H'FFDD
Port control register A	PCRA	W	H'F0	H'FFED

1. Port Data Register A (PDRA)

Bit	7	6	5	4	3	2	1	0
	_	_	_	—	PA ₃	PA ₂	PA ₁	PA ₀
Initial value	1	1	1	1	0	0	0	0
Read/Write	—		—	—	R/W	R/W	R/W	R/W

PDRA is an 8-bit register that stores data for port A pins PA_3 to PA_0 . If port A is read while PCRA bits are set to 1, the values stored in PDRA are read, regardless of the actual pin states. If port A is read while PCRA bits are cleared to 0, the pin states are read.

Upon reset, PDRA is initialized to H'F0.

2. Port Control Register A (PCRA)

Bit	7	6	5	4	3	2	1	0
	—	—	_	_	PCRA ₃	PCRA ₂	PCRA ₁	PCRA ₀
Initial value	1	1	1	1	0	0	0	0
Read/Write	_	_	_	_	R/W	R/W	R/W	R/W

PCRA controls whether each of port A pins PA_3 to PA_0 functions as an input pin or output pin. Setting a PCRA bit to 1 makes the corresponding pin an output pin, while clearing the bit to 0 makes the pin an input pin. PCRA and PDRA settings are valid when the corresponding pins are designated for general-purpose input/output by LPCR.

Upon reset, PCRA is initialized to H'F0.

PCRA is a write-only register, which always reads all 1s.



8.9.3 Pin Functions

Table 8.24 shows the port A pin functions.

Table 8.24Port A Pin Functions

Pin	Pin Functions and	Selection Method					
PA ₃ /COM ₄	The pin function depends on bit PCRA ₃ in PCRA and bits SGS3 to SGS0.						
	SEGS3 to SEGS0	0000	0000	Not 0000			
	PCRA ₃	0	1	*			
	Pin function	PA ₃ input pin	PA ₃ output pin	COM ₄ output pin			
PA ₂ /COM ₃	The pin function dep	ends on bit PCRA ₂	in PCRA and bits SG	SS3 to SGS0.			
	SEGS3 to SEGS0	0000	0000	Not 0000			
	PCRA ₂	0	1	*			
	Pin function	PA ₂ input pin	PA ₂ output pin	COM ₃ output pin			
PA ₁ /COM ₂	The pin function dep	ends on bit PCRA ₁ i	in PCRA and bits SG	SS3 to SGS0.			
	SEGS3 to SEGS0	0000	0000	Not 0000			
	PCRA ₁	0	1	*			
	Pin function	PA1 input pin	PA ₁ output pin	COM ₂ output pin			
PA ₀ /COM ₁	The pin function dep	ends on bit PCRA ₀ i	in PCRA and bits SC	SS3 to SGS0.			
	SEGS3 to SEGS0	00	00	Not 0000			
	PCRA ₀	0	1	*			
	Pin function	PA ₀ input pin	PA ₀ output pin	COM ₁ output pin			
	1		1				

*: Don't care

8.9.4 Pin States

Table 8.25 shows the port A pin states in each operating mode.

Table 8.25 Port A Pin States

Pins	Reset	Sleep	Subsleep	Standby	Watch	Subactive	Active
PA ₃ /COM ₄ PA ₂ /COM ₃ PA ₁ /COM ₂ PA ₀ /COM ₁	High- impedance	Retains previous state		High- impedance		Functional	Functional

8.10 Port B

8.10.1 Overview

Port B is an 8-bit input-only port, configured as shown in figure 8.9.





8.10.2 Register Configuration and Description

Table 8.26 shows the port B register configuration.

Table 8.26Port B Register

Name	Abbr.	R/W	Address
Port data register B	PDRB	R	H'FFDE

Port Data Register B (PDRB)

Bit	7	6	5	4	3	2	1	0
	PB7	PB_6	PB_5	PB ₄	PB_3	PB ₂	PB ₁	PB ₀
Read/Write	R	R	R	R	R	R	R	R

Reading PDRB always gives the pin states. However, if a port B pin is selected as an analog input channel for the A/D converter by AMR bits CH3 to CH0, that pin reads 0 regardless of the input voltage.

8.11 Input/Output Data Inversion Function

8.11.1 Overview

With input pins \overline{WKP}_0 to \overline{WKP}_7 , RXD₃₁, and RXD₃₂, and output pins TXD₃₁ and TXD₃₂, the data can be handled in inverted form.



Figure 8.10 Input/Output Data Inversion Function

8.11.2 Register Configuration and Descriptions

Table 8.27 shows the registers used by the input/output data inversion function.

Table 8.27 Register Configuration

Name	Abbr.	R/W	Address
Serial port control register	SPCR	R/W	H'FF91

Serial Port Control Register (SPCR)

Bit	7	6	5	4	3	2	1	0
	_	—	SPC32	SPC31	SCINV3	SCINV2	SCINV1	SCINV0
Initial value	1	1	0	0	0	0	0	0
Read/Write	_	_	R/W	R/W	R/W	R/W	R/W	R/W

SPCR is an 8-bit readable/writable register that performs RXD₃₁, RXD₃₂, TXD₃₁, and TXD₃₂ pin input/output data inversion switching. SPCR is initialized to H'C0 by a reset.

Bits 7 and 6: Reserved bits

Bits 7 and 6 are reserved; they are always read as 1 and cannot be modified.

Bit 5: P4₂/TXD₃₂ pin function switch (SPC32)

This bit selects whether pin $P4_2/TXD_{32}$ is used as $P4_2$ or as TXD_{32} .

Bit 5 SPC32	Description	
0	Functions as P4 ₂ I/O pin	(initial value)
1	Functions as TXD ₃₂ output pin [*]	
Note: *	Set the TE bit in SCR3 after setting this bit to 1.	

Bit 4: P3₅/TXD₃₁ pin function switch (SPC31)

This bit selects whether pin $P3_5/TXD_{31}$ is used as $P3_5$ or as TXD_{31} .

Bit 4 SPC31	Description	
0	Functions as P3₅ I/O pin	(initial value)
1	Functions as TXD ₃₁ output pin*	
Note: *	Set the TE bit in SCR3 after setting this bit to 1.	

Bit 3: TXD₃₂ pin output data inversion switch

Bit 3 specifies whether or not TXD₃₂ pin output data is to be inverted.

Bit 3 SCINV3	Description	
0	TXD ₃₂ output data is not inverted	(initial value)
1	TXD ₃₂ output data is inverted	

Bit 2: RXD₃₂ pin input data inversion switch

Bit 2 specifies whether or not RXD₃₂ pin input data is to be inverted.

Bit 2 SCINV2	Description	
0	RXD ₃₂ input data is not inverted	(initial value)
1	RXD ₃₂ input data is inverted	

Bit 1: TXD₃₁ pin output data inversion switch

Bit 1 specifies whether or not TXD₃₁ pin output data is to be inverted.

Bit 1		
SCINV1	Description	
0	TXD ₃₁ output data is not inverted	(initial value)
1	TXD ₃₁ output data is inverted	

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Bit 0: RXD₃₁ pin input data inversion switch

Bit 0 specifies whether or not RXD_{31} pin input data is to be inverted.

Bit 0		
SCINV0	Description	
0	RXD ₃₁ input data is not inverted	(initial value)
1	RXD ₃₁ input data is inverted	

8.11.3 Note on Modification of Serial Port Control Register

When a serial port control register is modified, the data being input or output up to that point is inverted immediately after the modification, and an invalid data change is input or output. When modifying a serial port control register, do so in a state in which data changes are invalidated.

8.12 Application Note

8.12.1 The Management of the Un-Use Terminal

If an I/O pin not used by the user system is floating, pull it up or down.

- If an unused pin is an input pin, handle it in one of the following ways:
 - Pull it up to V_{CC} with an on-chip pull-up MOS.
 - Pull it up to V_{CC} with an external resistor of approximately 100 k Ω .
 - Pull it down to V_{SS} with an external resistor of approximately 100 k Ω .
 - For a pin also used by the A/D converter, pull it up to $\mathrm{AV}_{\mathrm{CC}}.$
- If an unused pin is an output pin, handle it in one of the following ways:
 - Set the output of the unused pin to high and pull it up to V_{CC} with an external resistor of approximately 100 k Ω .
 - Set the output of the unused pin to low and pull it down to V_{SS} with an external resistor of approximately 100 k Ω .



Section 9 Timers

9.1 Overview

This LSI provides six timers: timers A, C, F, G, and a watchdog timer, and an asynchronous event counter. The functions of these timers are outlined in table 9.1.

Table 9.1Timer Functions

Name	Functions	Internal Clock	Event Input Pin	Waveform Output Pin	Remarks
Timer A	8-bit interval timer	φ/8 to φ/8192	_	_	
	 Interval function 	(8 choices)			
	Time base	$\phi_W/128$ (choice of 4 overflow periods)	_		
	Clock output	 φ/4 to φ/32 φ_W, φ_W/4 to φ_W/32 (9 choices) 	_	TMOW	-
Timer C	8-bit timer	$\varphi/4$ to $\varphi/8192,\varphi_W/4$	TMIC	_	Up-count/down-
	 Interval function 	(7 choices)			count controllable by
	 Event counting function 				software or hardware
	 Up-count/down- count selectable 				
Timer F	16-bit timer	φ/4 to φ/32, φ _W /4	TMIF	TMOFL	
	Event counting function Also usable as two independent8- bit timers Output compare output function	(4 choices)		TMOFH	
Timer G	8-bit timer	φ/2 to φ/64, φ _W /4	TMIG	_	• Counter
	 Input capture function 	(4 choices)			clearing option Built-in capture
	 Interval function 				input signal noise canceler

Name	Functions	Internal Clock	Event Input Pin	Waveform Output Pin Remarks
Watchdog timer	Reset signal generated when8-bit counter overflows	φ/8192 φ _W /32	_	_
Asynchro-	16-bit counter	_	AEVL	
nous event counter	 Also usable as two independent 8-bit counters 		AEVH	
	 Counts events asynchronous to φ and φw 			

9.2 Timer A

9.2.1 Overview

Timer A is an 8-bit timer with interval timing and real-time clock time-base functions. The clock time-base function is available when a 32.768-kHz crystal oscillator is connected. A clock signal divided from 32.768 kHz, from 38.4 kHz (if a 38.4 kHz crystal oscillator is connected), or from the system clock, can be output at the TMOW pin.

1. Features

Features of timer A are given below.

- Choice of eight internal clock sources (φ/8192, φ/4096, φ/2048, φ/512, φ/256, φ/128, φ/32, φ/8).
- Choice of four overflow periods (1 s, 0.5 s, 0.25 s, 31.25 ms) when timer A is used as a clock time base (using a 32.768 kHz crystal oscillator).
- An interrupt is requested when the counter overflows.
- Any of nine clock signals can be output at the TMOW pin: 32.768 kHz divided by 32, 16, 8, or 4 (1 kHz, 2 kHz, 4 kHz, 8 kHz, 32,768 kHz) or 38.4 kHz divided by 32, 16, 8, or 4 (1.2 kHz, 2.4 kHz, 4.8 kHz, 9.6 kHz, 38.4 kHz), and the system clock divided by 32, 16, 8, or 4.
- Use of module standby mode enables this module to be placed in standby mode independently when not used.

2. Block Diagram

Figure 9.1 shows a block diagram of timer A.



Figure 9.1 Block Diagram of Timer A

3. Pin Configuration

Table 9.2 shows the timer A pin configuration.

Table 9.2Pin Configuration

Name	Abbr.	I/O	Function
Clock output	TMOW	Output	Output of waveform generated by timer A output circuit

4. Register Configuration

Table 9.3 shows the register configuration of timer A.

Table 9.3Timer A Registers

Name	Abbr.	R/W	Initial Value	Address
Timer mode register A	ТМА	R/W	H'10	H'FFB0
Timer counter A	TCA	R	H'00	H'FFB1
Clock stop register 1	CKSTPR1	R/W	H'FF	H'FFFA
Subclock output select register	CWOSR	R/W	H'FE	H'FF92

9.2.2 Register Descriptions

1. Timer Mode Register A (TMA)

Bit	7	6	5	4	3	2	1	0
	TMA7	TMA6	TMA5	_	ТМАЗ	TMA2	TMA1	TMA0
Initial value	0	0	0	1	0	0	0	0
Read/Write	R/W	R/W	R/W	_	R/W	R/W	R/W	R/W

TMA is an 8-bit read/write register for selecting the prescaler, input clock, and output clock.

Upon reset, TMA is initialized to H'10.



Bits 7 to 5: Clock output select (TMA7 to TMA5)

Bits 7 to 5 choose which of eight clock signals is output at the TMOW pin. The system clock divided by 32, 16, 8, or 4 can be output in active mode and sleep mode. A 32.768 kHz or 38.4 kHz signal divided by 32, 16, 8, or 4 can be output in active mode, sleep mode, and subactive mode. ϕ_w is output in all modes except the reset state.

CWOSR		TMA			
cwos	Bit 7 TMA7	Bit 6 TMA6	Bit 5 TMA5	 Clock Output	
0	0	0	0	φ/32	(initial value)
			1	φ/16	
		1	0	φ/8	
			1	φ/4	
	1	0	0	φ _w /32	
			1	φ _w /16	
		1	0	φ _w /8	
			1	φ _w /4	
1	*	*	*	φ _w	

*: Don't care

Bit 4: Reserved bit

Bit 4 is reserved; it is always read as 1, and cannot be modified.

Bits 3 to 0: Internal clock select (TMA3 to TMA0)

Bits 3 to 0 select the clock input to TCA. The selection is made as follows.

				Description	
Bit 3 TMA3	Bit 2 TMA2	Bit 1 TMA1	Bit 0 TMA0	Prescaler and Divider Ratio or Overflow Period	Function
0	0	0	0	PSS,	Interval timer
			1	PSS,	-
		1	0	PSS,	-
			1	PSS, φ/512	_
	1	0	0	PSS, ø/256	=
			1	PSS, ø/128	=
		1	0	PSS,	=
			1	PSS, φ/8	=
1	0	0	0	PSW, 1 s	Clock time base
			1	PSW, 0.5 s	[–] (when using _– 32.768 kHz)
		1	0	PSW, 0.25 s	- 32.700 KHZ)
			1	PSW, 0.03125 s	=
	1	0	0	PSW and TCA are reset	-
			1	_	
		1	0	_	
			1	_	



2. Timer Counter A (TCA)

Bit	7	6	5	4	3	2	1	0
	TCA7	TCA6	TCA5	TCA4	TCA3	TCA2	TCA1	TCA0
Initial value	0	0	0	0	0	0	0	0
Read/Write	R	R	R	R	R	R	R	R

TCA is an 8-bit read-only up-counter, which is incremented by internal clock input. The clock source for input to this counter is selected by bits TMA3 to TMA0 in timer mode register A (TMA). TCA values can be read by the CPU in active mode, but cannot be read in subactive mode. When TCA overflows, the IRRTA bit in interrupt request register 1 (IRR1) is set to 1.

TCA is cleared by setting bits TMA3 and TMA2 of TMA to 11.

Upon reset, TCA is initialized to H'00.

3. Clock Stop Register 1 (CKSTPR1)

Bit	7	6	5	4	3	2	1	0
	—	S31CKSTP	S32CKSTP	ADCKSTP	TGCKSTP	TFCKSTP	TCCKSTP	TACKSTP
Initial value	1	1	1	1	1	1	1	1
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

CKSTPR1 is an 8-bit read/write register that performs module standby mode control for peripheral modules. Only the bit relating to timer A is described here. For details of the other bits, see the sections on the relevant modules.

Bit 0: Timer A module standby mode control (TACKSTP)

Bit 0 controls setting and clearing of module standby mode for timer A.

TACKSTP Description

0	Timer A is set to module standby mode	
1	Timer A module standby mode is cleared	(initial value)

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4. Subclock Output Select Register (CWOSR)

Bit	7	6	5	4	3	2	1	0
	—	_	—	_	—	—	—	CWOS
Initial value	1	1	1	1	1	1	1	0
Read/Write	R	R	R	R	R	R	R	R/W

CWOSR is an 8-bit read/write register that selects the clock to be output from the TMOW pin.

CWOSR is initialized to H'FE by a reset.

Bits 7 to 1: Reserved bits

Bits 7 to 1 are reserved; they are always read as 1 and cannot be modified.

Bit 0: TMOW pin clock select (CWOS)

Bit 0 selects the clock to be output from the TMOW pin.

Bit 0 CWOS	Description	
0	Clock output from timer A is output (see TMA)	(initial value)
1	ϕ_w is output	



9.2.3 Timer Operation

1. Interval Timer Operation

When bit TMA3 in timer mode register A (TMA) is cleared to 0, timer A functions as an 8-bit interval timer.

Upon reset, TCA is cleared to H'00 and bit TMA3 is cleared to 0, so up-counting and interval timing resume immediately. The clock input to timer A is selected by bits TMA2 to TMA0 in TMA; any of eight internal clock signals output by prescaler S can be selected.

After the count value in TCA reaches H'FF, the next clock signal input causes timer A to overflow, setting bit IRRTA to 1 in interrupt request register 1 (IRR1). If IENTA = 1 in interrupt enable register 1 (IENR1), a CPU interrupt is requested.*

At overflow, TCA returns to H'00 and starts counting up again. In this mode timer A functions as an interval timer that generates an overflow output at intervals of 256 input clock pulses.

Note: * For details on interrupts, see section 3.3, Interrupts.

2. Real-Time Clock Time Base Operation

When bit TMA3 in TMA is set to 1, timer A functions as a real-time clock time base by counting clock signals output by prescaler W. The overflow period of timer A is set by bits TMA1 and TMA0 in TMA. A choice of four periods is available. In time base operation (TMA3 = 1), setting bit TMA2 to 1 clears both TCA and prescaler W to their initial values of H'00.

3. Clock Output

Setting bit TMOW in port mode register 1 (PMR1) to 1 causes a clock signal to be output at pin TMOW. Nine different clock output signals can be selected by means of bits TMA7 to TMA5 in TMA and bit CWOS in CWOSR. The system clock divided by 32, 16, 8, or 4 can be output in active mode and sleep mode. A 32.768 kHz or 38.4 kHz signal divided by 32, 16, 8, or 4 can be output in active mode, sleep mode, watch mode, subactive mode, and subsleep mode. The 32.768 kHz or 38.4 kHz or 38.4 kHz clock is output in all modes except the reset state.

Renesas

9.2.4 Timer A Operation States

Table 9.4 summarizes the timer A operation states.

Table 9.4Timer A Operation States

Oper	ation Mode	Reset	Active	Sleep	Watch	Sub- active	Sub- sleep	Standby	Module Standby
TCA	Interval	Reset	Functions	Functions	Halted	Halted	Halted	Halted	Halted
	Clock time base	Reset	Functions	Functions	Functions	Functions	Functions	Halted	Halted
TMA	CWOSR	Reset	Functions	Retained	Retained	Functions	Retained	Retained	Retained

Note: When the real-time clock time base function is selected as the internal clock of TCA in active mode or sleep mode, the internal clock is not synchronous with the system clock, so it is synchronized by a synchronizing circuit. This may result in a maximum error of 1/φ (s) in the count cycle.

9.2.5 Application Note

When bit 0 (TACKSTP) of the clock stop register 1 (CKSTPR1) is cleared to 0, bit 3 (TMA3) of the timer mode register A (TMA) cannot be rewritten.

Set bit 0 (TACKSTP) of the clock stop register 1 (CKSTPR1) to 1 before rewriting bit 3 (TMA3) of the timer mode register A (TMA).



9.3 Timer C

9.3.1 Overview

Timer C is an 8-bit timer that increments each time a clock pulse is input. This timer has two operation modes, interval and auto reload.

1. Features

Features of timer C are given below.

- Choice of seven internal clock sources (φ/8192, φ/2048, φ/512, φ/64, φ/16, φ/4, φw/4) or an external clock (can be used to count external events).
- An interrupt is requested when the counter overflows.
- Up/down-counter switching is possible by hardware or software.
- Subactive mode and subsleep mode operation is possible when $\phi w/4$ is selected as the internal clock, or when an external clock is selected.
- Use of module standby mode enables this module to be placed in standby mode independently when not used.

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2. Block Diagram

Figure 9.2 shows a block diagram of timer C.





3. Pin Configuration

Table 9.5 shows the timer C pin configuration.

Table 9.5Pin Configuration

Name	Abbr.	I/O	Function
Timer C event input	TMIC	Input	Input pin for event input to TCC
Timer C up/down-count selection	UD	Input	Timer C up/down select

4. Register Configuration

Table 9.6 shows the register configuration of timer C.

Table 9.6Timer C Registers

Name	Abbr.	R/W	Initial Value	Address
Timer mode register C	TMC	R/W	H'18	H'FFB4
Timer counter C	TCC	R	H'00	H'FFB5
Timer load register C	TLC	W	H'00	H'FFB5
Clock stop register 1	CKSTPR1	R/W	H'FF	H'FFFA

9.3.2 Register Descriptions

1. Timer Mode Register C (TMC)

Bit	7	6	5	4	3	2	1	0
	TMC7	TMC6	TMC5	—	_	TMC2	TMC1	TMC0
Initial value	0	0	0	1	1	0	0	0
Read/Write	R/W	R/W	R/W	_	_	R/W	R/W	R/W

TMC is an 8-bit read/write register for selecting the auto-reload function and input clock, and performing up/down-counter control.

Upon reset, TMC is initialized to H'18.

Bit 7: Auto-reload function select (TMC7)

Bit 7 selects whether timer C is used as an interval timer or auto-reload timer.

Bit 7		
TMC7	Description	
0	Interval timer function selected	(initial value)
1	Auto-reload function selected	

Bits 6 and 5: Counter up/down control (TMC6, TMC5)

Selects whether TCC up/down control is performed by hardware using UD pin input, or whether TCC functions as an up-counter or a down-counter.

Bit 6 TMC6	Bit 5 TMC5	Description	
0	0	TCC is an up-counter	(initial value)
0	1	TCC is a down-counter	
1	*	Hardware control by UD pin input UD pin input high: Down-counter UD pin input low: Up-counter	
			* Dault ann

*: Don't care

Bits 4 and 3: Reserved bits

Bits 4 and 3 are reserved; they are always read as 1 and cannot be modified.

Bits 2 to 0: Clock select (TMC2 to TMC0)

Bits 2 to 0 select the clock input to TCC. For external event counting, either the rising or falling edge can be selected.

Bit 2 TMC2	Bit 1 TMC1	Bit 0 TMC0	Description
0	0	0	Internal clock:
0	0	1	Internal clock:
0	1	0	Internal clock:
0	1	1	Internal clock: ø/64
1	0	0	Internal clock: ø/16
1	0	1	Internal clock: ø/4
1	1	0	Internal clock: øw/4
1	1	1	External event (TMIC): rising or falling edge*

Note: * The edge of the external event signal is selected by bit IEG1 in the IRQ edge select register (IEGR). See 1. IRQ edge select register (IEGR) in 3.3.2 for details. IRQ1 must be set to 1 in port mode register 1 (PMR1) before setting 111 in bits TMC2 to TMC0.

2. Timer Counter C (TCC)

Bit	7	6	5	4	3	2	1	0
	TCC7	TCC6	TCC5	TCC4	тссз	TCC2	TCC1	TCC0
Initial value	0	0	0	0	0	0	0	0
Read/Write	R	R	R	R	R	R	R	R

TCC is an 8-bit read-only up-counter, which is incremented by internal clock or external event input. The clock source for input to this counter is selected by bits TMC2 to TMC0 in timer mode register C (TMC). TCC values can be read by the CPU at any time.

When TCC overflows from H'FF to H'00 or to the value set in TLC, or underflows from H'00 to H'FF or to the value set in TLC, the IRRTC bit in IRR2 is set to 1.

TCC is allocated to the same address as TLC.

Upon reset, TCC is initialized to H'00.

3. Timer Load Register C (TLC)

Bit	7	6	5	4	3	2	1	0
	TLC7	TLC6	TLC5	TLC4	TLC3	TLC2	TLC1	TLC0
Initial value	0	0	0	0	0	0	0	0
Read/Write	W	W	W	W	W	W	W	W

TLC is an 8-bit write-only register for setting the reload value of timer counter C (TCC).

When a reload value is set in TLC, the same value is loaded into timer counter C as well, and TCC starts counting up from that value. When TCC overflows or underflows during operation in auto-reload mode, the TLC value is loaded into TCC. Accordingly, overflow/underflow periods can be set within the range of 1 to 256 input clocks.

The same address is allocated to TLC as to TCC.

Upon reset, TLC is initialized to H'00.

Renesas

4. Clock Stop Register 1 (CKSTPR1)

Bit	7	6	5	4	3	2	1	0
	—	S31CKSTP	S32CKSTP	ADCKSTP	TGCKSTP	TFCKSTP	TCCKSTP	TACKSTP
Initial value	1	1	1	1	1	1	1	1
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

CKSTPR1 is an 8-bit read/write register that performs module standby mode control for peripheral modules. Only the bit relating to timer C is described here. For details of the other bits, see the sections on the relevant modules.

Bit 1: Timer C module standby mode control (TCCKSTP)

Bit 1 controls setting and clearing of module standby mode for timer C.

TCCKSTP	Description	
0	Timer C is set to module standby mode	
1	Timer C module standby mode is cleared	(initial value)

9.3.3 Timer Operation

1. Interval Timer Operation

When bit TMC7 in timer mode register C (TMC) is cleared to 0, timer C functions as an 8-bit interval timer.

Upon reset, TCC is initialized to H'00 and TMC to H'18, so TCC continues up-counting as an interval up-counter without halting immediately after a reset. The timer C operating clock is selected from seven internal clock signals output by prescalers S and W, or an external clock input at pin TMIC. The selection is made by bits TMC2 to TMC0 in TMC.

TCC up/down-count control can be performed either by software or hardware. The selection is made by bits TMC6 and TMC5 in TMC.

After the count value in TCC reaches H'FF (H'00), the next clock input causes timer C to overflow (underflow), setting bit IRRTC to 1 in IRR2. If IENTC = 1 in interrupt enable register 2 (IENR2), a CPU interrupt is requested.

At overflow (underflow), TCC returns to H'00 (H'FF) and starts counting up (down) again.
During interval timer operation (TMC7 = 0), when a value is set in timer load register C (TLC), the same value is set in TCC.

Note: For details on interrupts, see section 3.3, Interrupts.

2. Auto-Reload Timer Operation

Setting bit TMC7 in TMC to 1 causes timer C to function as an 8-bit auto-reload timer. When a reload value is set in TLC, the same value is loaded into TCC, becoming the value from which TCC starts its count.

After the count value in TCC reaches H'FF (H'00), the next clock signal input causes timer C to overflow/underflow. The TLC value is then loaded into TCC, and the count continues from that value. The overflow/underflow period can be set within a range from 1 to 256 input clocks, depending on the TLC value.

The clock sources, up/down control, and interrupts in auto-reload mode are the same as in interval mode.

In auto-reload mode (TMC7 = 1), when a new value is set in TLC, the TLC value is also set in TCC.

3. Event Counter Operation

Timer C can operate as an event counter, counting rising or falling edges of an external event signal input at pin TMIC. External event counting is selected by setting bits TMC2 to TMC0 in timer mode register C to all 1s (111).

When timer C is used to count external event input, bit IRQ1 in PMR1 should be set to 1 and bit IEN1 in IENR1 cleared to 0 to disable interrupt IRQ_1 requests.

4. TCC Up/Down Control by Hardware

With timer C, TCC up/down control can be performed by UD pin input. When bit TMC6 is set to 1 in TMC, TCC functions as an up-counter when UD pin input is high, and as a down-counter when low.

When using UD pin input, set bit UD to 1 in PMR3.

9.3.4 Timer C Operation States

Table 9.7 summarizes the timer C operation states.

Table 9.7 Timer C Operation States

Opera	ation I	Mode	Reset	Active	Sleep	Watch	Sub- active	Sub-sleep	Standby	Module Standby
TCC	C Interval		Reset	Functions	Functions	Halted	Functions/ Halted*	Functions/ Halted*	Halted	Halted
	Auto	reload	Reset	Functions	Functions	Halted	Functions/ Halted*	Functions/ Halted*	Halted	Halted
TMC			Reset	Functions	Retained	Retained	Functions	Retained	Retained	Retained
Note: * When ϕ w/4 is selected as the TCC internal clock in active mode or sleep the system clock and internal clock are mutually asynchronous, synchron maintained by a synchronization circuit. This results in a maximum count 1/ ϕ (s). When the counter is operated in subactive mode or subsleep mode select ϕ w/4 as the internal clock or select an external clock. The counter operate on any other internal clock. If ϕ w/4 is selected as the internal clock counter when ϕ w/8 has been selected as subclock ϕ_{SUB} , the lower 2 bits of operate on the same cycle, and the operation of the least significant bit is the operation of the counter.					chronizatio count cycl p mode, e unter will r al clock fo bits of the	on is e error of ither not r the e counter				



9.3.5 Usage Note

Note the following regarding the operation of timer C.

(1) Counting errors caused by external event input

Timer counter errors may occur under the following conditions.

Conditions

• An external event (TMIC) is used in subsleep mode.

Symptom

• The counter increments or decrements twice for a single external event input.

Approximate rate of occurrence

The approximate rate of occurrence in cases where the external event input is not synchronized with internal operation is defined by the following equation.

Approximate rate of occurrence P = 30 ns / tsubcyc

For example, if tsubcyc = $61.06 \ \mu s$ (subclock $\phi w/2$), P = 0.0005 (0.05%). If 2,000 external event inputs occur, there is a likelihood that one of them will cause the counter to increment or decrement twice (+2 or -2).

The symptom described is caused by the internal circuit configuration of the device and therefore difficult to avoid. Therefore, it is not advisable to use the clock counter for applications requiring a high degree of accuracy.

9.4 Timer F

9.4.1 Overview

Timer F is a 16-bit timer with a built-in output compare function. As well as counting external events, timer F also provides for counter resetting, interrupt request generation, toggle output, etc., using compare match signals. Timer F can also be used as two independent 8-bit timers (timer FH and timer FL).

1. Features

Features of timer F are given below.

- Choice of four internal clock sources (φ/32, φ/16, φ/4, φw/4) or an external clock (can be used as an external event counter)
- TMOFH pin (TMOFL pin) toggle output provided using a single compare match signal (toggle output initial value can be set)
- Counter resetting by a compare match signal
- Two interrupt sources: one compare match, one overflow
- Can operate as two independent 8-bit timers (timer FH and timer FL) (in 8-bit mode).

		Timer FL
	Timer FH 8-Bit Timer [*]	8-Bit Timer/Event Counter
Internal clock	Choice of 4 (\$\phi/32, \$\phi/16, \$\phi/4, \$\phiw/4\$)	
Event input	—	TMIF pin
Toggle output	One compare match signal, output to TMOFH pin(initial value settable)	One compare match signal, output to TMOFL pin (initial value settable)
Counter reset	Counter can be reset by compare mat	ch signal
Interrupt sources	One compare match One overflow	

Note: * When timer F operates as a 16-bit timer, it operates on the timer FL overflow signal.

- Operation in watch mode, subactive mode, and subsleep mode
 When \$\phiw/4\$ is selected as the internal clock, timer F can operate in watch mode, subactive mode, and subsleep mode.
- Use of module standby mode enables this module to be placed in standby mode independently when not used.

2. Block Diagram

Figure 9.3 shows a block diagram of timer F.



Figure 9.3 Block Diagram of Timer F

3. Pin Configuration

Table 9.8 shows the timer F pin configuration.

Table 9.8Pin Configuration

Name	Abbr.	I/O	Function
Timer F event input	TMIF	Input	Event input pin for input to TCFL
Timer FH output	TMOFH	Output	Timer FH toggle output pin
Timer FL output	TMOFL	Output	Timer FL toggle output pin

4. Register Configuration

Table 9.9 shows the register configuration of timer F.

Table 9.9Timer F Registers

Name	Abbr.	R/W	Initial Value	Address
Timer control register F	TCRF	W	H'00	H'FFB6
Timer control/status register F	TCSRF	R/W	H'00	H'FFB7
8-bit timer counter FH	TCFH	R/W	H'00	H'FFB8
8-bit timer counter FL	TCFL	R/W	H'00	H'FFB9
Output compare register FH	OCRFH	R/W	H'FF	H'FFBA
Output compare register FL	OCRFL	R/W	H'FF	H'FFBB
Clock stop register 1	CKSTPR1	R/W	H'FF	H'FFFA



9.4.2 Register Descriptions

1. 16-bit Timer Counter (TCF) 8-bit Timer Counter (TCFH) 8-bit Timer Counter (TCFL)



TCF is a 16-bit read/write up-counter configured by cascaded connection of 8-bit timer counters TCFH and TCFL. In addition to the use of TCF as a 16-bit counter with TCFH as the upper 8 bits and TCFL as the lower 8 bits, TCFH and TCFL can also be used as independent 8-bit counters.

TCFH and TCFL can be read and written by the CPU, but when they are used in 16-bit mode, data transfer to and from the CPU is performed via a temporary register (TEMP). For details of TEMP, see section 9.4.3, CPU Interface.

TCFH and TCFL are each initialized to H'00 upon reset.

a. 16-bit mode (TCF)

When CKSH2 is cleared to 0 in TCRF, TCF operates as a 16-bit counter. The TCF input clock is selected by bits CKSL2 to CKSL0 in TCRF.

TCF can be cleared in the event of a compare match by means of CCLRH in TCSRF. When TCF overflows from H'FFFF to H'0000, OVFH is set to 1 in TCSRF. If OVIEH in TCSRF is 1 at this time, IRRTFH is set to 1 in IRR2, and if IENTFH in IENR2 is 1, an interrupt request is sent to the CPU.

b. 8-bit mode (TCFL/TCFH)

When CKSH2 is set to 1 in TCRF, TCFH and TCFL operate as two independent 8-bit counters. The TCFH (TCFL) input clock is selected by bits CKSH2 to CKSH0 (CKSL2 to CKSL0) in TCRF.

TCFH (TCFL) can be cleared in the event of a compare match by means of CCLRH (CCLRL) in TCSRF.

When TCFH (TCFL) overflows from H'FF to H'00, OVFH (OVFL) is set to 1 in TCSRF. If OVIEH (OVIEL) in TCSRF is 1 at this time, IRRTFH (IRRTFL) is set to 1 in IRR2, and if IENTFH (IENTFL) in IENR2 is 1, an interrupt request is sent to the CPU.

16-bit Output Compare Register (OCRF)
 8-bit Output Compare Register (OCRFH)
 8-bit Output Compare Register (OCRFL)



OCRF is a 16-bit read/write register composed of the two registers OCRFH and OCRFL. In addition to the use of OCRF as a 16-bit register with OCRFH as the upper 8 bits and OCRFL as the lower 8 bits, OCRFH and OCRFL can also be used as independent 8-bit registers.

OCRFH and OCRFL can be read and written by the CPU, but when they are used in 16-bit mode, data transfer to and from the CPU is performed via a temporary register (TEMP). For details of TEMP, see section 9.4.3, CPU Interface.

OCRFH and OCRFL are each initialized to H'FF upon reset.

a. 16-bit mode (OCRF)

When CKSH2 is cleared to 0 in TCRF, OCRF operates as a 16-bit register. OCRF contents are constantly compared with TCF, and when both values match, CMFH is set to 1 in TCSRF. At the same time, IRRTFH is set to 1 in IRR2. If IENTFH in IENR2 is 1 at this time, an interrupt request is sent to the CPU.

Toggle output can be provided from the TMOFH pin by means of compare matches, and the output level can be set (high or low) by means of TOLH in TCRF.

b. 8-bit mode (OCRFH/OCRFL)

When CKSH2 is set to 1 in TCRF, OCRFH and OCRFL operate as two independent 8-bit registers. OCRFH contents are compared with TCFH, and OCRFL contents are with TCFL. When the OCRFH (OCRFL) and TCFH (TCFL) values match, CMFH (CMFL) is set to 1 in TCSRF. At the same time, IRRTFH (IRRTFL) is set to 1 in IRR2. If IENTFH (IENTFL) in IENR2 is 1 at this time, an interrupt request is sent to the CPU.

Toggle output can be provided from the TMOFH pin (TMOFL pin) by means of compare matches, and the output level can be set (high or low) by means of TOLH (TOLL) in TCRF.

3. Timer Control Register F (TCRF)

Bit	7	6	5	4	3	2	1	0
	TOLH	CKSH2	CKSH1	CKSH0	TOLL	CKSL2	CKSL1	CKSL0
Initial value	0	0	0	0	0	0	0	0
Read/Write	W	W	W	W	W	W	W	W

TCRF is an 8-bit write-only register that switches between 16-bit mode and 8-bit mode, selects the input clock from among four internal clock sources or external event input, and sets the output level of the TMOFH and TMOFL pins.

TCRF is initialized to H'00 upon reset.

Bit 7: Toggle output level H (TOLH)

Bit 7 sets the TMOFH pin output level. The output level is effective immediately after this bit is written.

Bit 7 TOLH Description 0 Low level (initial value) 1 High level

Bits 6 to 4: Clock select H (CKSH2 to CKSH0)

Bits 6 to 4 select the clock input to TCFH from among four internal clock sources or TCFL overflow.

Bit 6 CKSH2	Bit 5 CKSH1	Bit 4 CKSH0	Description	
0	0	0	16-bit mode, counting on TCFL overflow signal	(initial value)
0	0	1	_	
0	1	0	_	
0	1	1	Use prohibited	
1	0	0	Internal clock: Counting on	
1	0	1	Internal clock: Counting on	
1	1	0	Internal clock: Counting on $\phi/4$	
1	1	1	Internal clock: Counting on ϕ w/4	

Bit 3: Toggle output level L (TOLL)

Bit 3 sets the TMOFL pin output level. The output level is effective immediately after this bit is written.

Bit 3 TOLL	Description	
0	Low level	(initial value)
1	High level	

Bits 2 to 0: Clock select L (CKSL2 to CKSL0)

Bits 2 to 0 select the clock input to TCFL from among four internal clock sources or external event input.

Bit 2 CKSL2	Bit 1 CKSL1	Bit 0 CKSL0	Description				
0	0	0	Counting on external event (TMIF) rising/falling edge*				
0	0	1	(initial value)				
0	1	0	—				
0	1	1	Use prohibited				
1	0	0	Internal clock: Counting on $\phi/32$				
1	0	1	Internal clock: Counting on $\phi/16$				
1	1	0	Internal clock: Counting on $\phi/4$				
1	1	1	Internal clock: Counting on ϕ w/4				
Note: *		External event edge selection is set by IEG3 in the IRQ edge select register (IEGR). For details, see 1. IRQ edge select register (IEGR) in section 3.3.2.					

Note that the timer F counter may increment if the setting of IRQ3 in port mode register 1 (PMR1) is changed from 0 to 1 while the TMIF pin is low in order to change the TMIF pin function.



4. Timer Control/Status Register F (TCSRF)

Bit	7	6	5	4	3	2	1	0
	OVFH	CMFH	OVIEH	CCLRH	OVFL	CMFL	OVIEL	CCLRL
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W*	R/W*	R/W	R/W	R/W*	R/W*	R/W	R/W

Note: * Bits 7, 6, 3, and 2 can only be written with 0, for flag clearing.

TCSRF is an 8-bit read/write register that performs counter clear selection, overflow flag setting, and compare match flag setting, and controls enabling of overflow interrupt requests.

TCSRF is initialized to H'00 upon reset.

Bit 7: Timer overflow flag H (OVFH)

Bit 7 is a status flag indicating that TCFH has overflowed from H'FF to H'00. This flag is set by hardware and cleared by software. It cannot be set by software.

Bit 7 OVFH	Description	
0	Clearing condition: After reading OVFH = 1, cleared by writing 0 to OVFH	(initial value)
1	Setting condition: Set when TCFH overflows from H'FF to H'00	

Bit 6: Compare match flag H (CMFH)

Bit 6 is a status flag indicating that TCFH has matched OCRFH. This flag is set by hardware and cleared by software. It cannot be set by software.

Bit 6 CMFH	Description	
0	Clearing condition: After reading CMFH = 1, cleared by writing 0 to CMFH	(initial value)
1	Setting condition: Set when the TCFH value matches the OCRFH value	

Bit 5: Timer overflow interrupt enable H (OVIEH)

Bit 5 selects enabling or disabling of interrupt generation when TCFH overflows.

Bit 5		
OVIEH	Description	
0	TCFH overflow interrupt request is disabled	(initial value)
1	TCFH overflow interrupt request is enabled	

Bit 4: Counter clear H (CCLRH)

In 16-bit mode, bit 4 selects whether TCF is cleared when TCF and OCRF match.

In 8-bit mode, bit 4 selects whether TCFH is cleared when TCFH and OCRFH match.

Bit 4		
CCLRH	Description	
0	16-bit mode: TCF clearing by compare match is disabled	
	8-bit mode: TCFH clearing by compare match is disabled	(initial value)
1	16-bit mode: TCF clearing by compare match is enabled	
	8-bit mode: TCFH clearing by compare match is enabled	

Bit 3: Timer overflow flag L (OVFL)

Bit 3 is a status flag indicating that TCFL has overflowed from H'FF to H'00. This flag is set by hardware and cleared by software. It cannot be set by software.

Bit 3 OVFL	Description	
0	Clearing condition:	(initial value)
	After reading OVFL = 1, cleared by writing 0 to OVFL	
1	Setting condition:	
	Set when TCFL overflows from H'FF to H'00	



Bit 2: Compare match flag L (CMFL)

Bit 2 is a status flag indicating that TCFL has matched OCRFL. This flag is set by hardware and cleared by software. It cannot be set by software.

Bit 2 CMFL	Description	
0	Clearing condition:	(initial value)
	After reading CMFL = 1, cleared by writing 0 to CMFL	
1	Setting condition:	
	Set when the TCFL value matches the OCRFL value	

Bit 1: Timer overflow interrupt enable L (OVIEL)

Bit 1 selects enabling or disabling of interrupt generation when TCFL overflows.

Bit 1 OVIEL	Description	
0	TCFL overflow interrupt request is disabled	(initial value)
1	TCFL overflow interrupt request is enabled	

Bit 0: Counter clear L (CCLRL)

Bit 0 selects whether TCFL is cleared when TCFL and OCRFL match.

Bit 0		
CCLRL	Description	
0	TCFL clearing by compare match is disabled	(initial value)
1	TCFL clearing by compare match is enabled	

5. Clock Stop Register 1 (CKSTPR1)

Bit	7	6	5	4	3	2	1	0
	—	S31CKSTP	S32CKSTP	ADCKSTP	TGCKSTP	TFCKSTP	TCCKSTP	TACKSTP
Initial value	1	1	1	1	1	1	1	1
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

CKSTPR1 is an 8-bit read/write register that performs module standby mode control for peripheral modules. Only the bit relating to timer F is described here. For details of the other bits, see the sections on the relevant modules.

Bit 2: Timer F module standby mode control (TFCKSTP)

Bit 2 controls setting and clearing of module standby mode for timer F.

TFCKSTP	Description	
0	Timer F is set to module standby mode	
1	Timer F module standby mode is cleared	(initial value)

9.4.3 CPU Interface

TCF and OCRF are 16-bit read/write registers, but the CPU is connected to the on-chip peripheral modules by an 8-bit data bus. When the CPU accesses these registers, it therefore uses an 8-bit temporary register (TEMP).

In 16-bit mode, TCF read/write access and OCRF write access must be performed 16 bits at a time (using two consecutive byte-size MOV instructions), and the upper byte must be accessed before the lower byte. Data will not be transferred correctly if only the upper byte or only the lower byte is accessed.

In 8-bit mode, there are no restrictions on the order of access.

1. Write Access

Write access to the upper byte results in transfer of the upper-byte write data to TEMP. Next, write access to the lower byte results in transfer of the data in TEMP to the upper register byte, and direct transfer of the lower-byte write data to the lower register byte.

Write to upper byte Module data bus Bus CPU interface (H'AA) TEMP (H'AA) TCFH TCFL () () Write to lower byte Module data bus Bus CPU interface (H'55) TEMP (H'AA) TCFH TCFL (H'AA) (H'55)

Figure 9.4 shows an example in which H'AA55 is written to TCF.

Figure 9.4 Write Access to TCR (CPU \rightarrow TCF)

2. Read Access

In access to TCF, when the upper byte is read the upper-byte data is transferred directly to the CPU and the lower-byte data is transferred to TEMP. Next, when the lower byte is read, the lower-byte data in TEMP is transferred to the CPU.

In access to OCRF, when the upper byte is read the upper-byte data is transferred directly to the CPU. When the lower byte is read, the lower-byte data is transferred directly to the CPU.

Figure 9.5 shows an example in which TCF is read when it contains H'AAFF.



Figure 9.5 Read Access to TCF (TCF \rightarrow CPU)

9.4.4 Operation

Timer F is a 16-bit counter that increments on each input clock pulse. The timer F value is constantly compared with the value set in output compare register F, and the counter can be cleared, an interrupt requested, or port output toggled, when the two values match. Timer F can also function as two independent 8-bit timers.

1. Timer F Operation

Timer F has two operating modes, 16-bit timer mode and 8-bit timer mode. The operation in each of these modes is described below.

a. Operation in 16-bit timer mode

When CKSH2 is cleared to 0 in timer control register F (TCRF), timer F operates as a 16-bit timer.

Following a reset, timer counter F (TCF) is initialized to H'0000, output compare register F (OCRF) to H'FFFF, and timer control register F (TCRF) and timer control/status register F (TCSRF) to H'00. The counter starts incrementing on external event (TMIF) input. The external event edge selection is set by IEG3 in the IRQ edge select register (IEGR).

The timer F operating clock can be selected from four internal clocks or an external clock by means of bits CKSL2 to CKSL0 in TCRF.

OCRF contents are constantly compared with TCF, and when both values match, CMFH is set to 1 in TCSRF. If IENTFH in IENR2 is 1 at this time, an interrupt request is sent to the CPU, and at the same time, TMOFH pin output is toggled. If CCLRH in TCSRF is 1, TCF is cleared. TMOFH pin output can also be set by TOLH in TCRF.

When TCF overflows from H'FFFF to H'0000, OVFH is set to 1 in TCSRF. If OVIEH in TCSRF and IENTFH in IENR2 are both 1, an interrupt request is sent to the CPU.

b. Operation in 8-bit timer mode

When CKSH2 is set to 1 in TCRF, TCF operates as two independent 8-bit timers, TCFH and TCFL. The TCFH/TCFL input clock is selected by CKSH2 to CKSH0/CKSL2 to CKSL0 in TCRF.

When the OCRFH/OCRFL and TCFH/TCFL values match, CMFH/CMFL is set to 1 in TCSRF. If IENTFH/IENTFL in IENR2 is 1, an interrupt request is sent to the CPU, and at the same time, TMOFH pin/TMOFL pin output is toggled. If CCLRH/CCLRL in TCSRF is 1, TCFH/TCFL is cleared. TMOFH pin/TMOFL pin output can also be set by TOLH/TOLL in TCRF.

When TCFH/TCFL overflows from H'FF to H'00, OVFH/OVFL is set to 1 in TCSRF. If OVIEH/OVIEL in TCSRF and IENTFH/IENTFL in IENR2 are both 1, an interrupt request is sent to the CPU.

2. TCF Increment Timing

TCF is incremented by clock input (internal clock or external event input).

a. Internal clock operation

Bits CKSH2 to CKSH0 or CKSL2 to CKSL0 in TCRF select one of four internal clock sources ($\phi/32$, $\phi/16$, $\phi/4$, or ϕ w/4) created by dividing the system clock (ϕ or ϕ w).

b. External event operation

External event input is selected by clearing CKSL2 to 0 in TCRF. TCF can increment on either the rising or falling edge of external event input. External event edge selection is set by IEG3 in the interrupt controller's IEGR register. An external event pulse width of at least 2 system clocks (ϕ) is necessary. Shorter pulses will not be counted correctly.

3. TMOFH/TMOFL Output Timing

In TMOFH/TMOFL output, the value set in TOLH/TOLL in TCRF is output. The output is toggled by the occurrence of a compare match. Figure 9.6 shows the output timing.



Figure 9.6 TMOFH/TMOFL Output Timing

4. TCF Clear Timing

TCF can be cleared by a compare match with OCRF.

5. Timer Overflow Flag (OVF) Set Timing

OVF is set to 1 when TCF overflows from H'FFFF to H'0000.

6. Compare Match Flag set Timing

The compare match flag (CMFH or CMFL) is set to 1 when the TCF and OCRF values match. The compare match signal is generated in the last state during which the values match (when TCF is updated from the matching value to a new value). When TCF matches OCRF, the compare match signal is not generated until the next counter clock.

7. Timer F Operation Modes

Timer F operation modes are shown in table 9.10.

Table 9.10	Timer	F Operation	Modes
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Operation Mode	Reset	Active	Sleep	Watch	Sub- active	Sub- sleep	Standby	Module Standby
TCF	Reset	Functions	Functions	Functions/ Halted*	Functions/ Halted*	Functions/ Halted*	Halted	Halted
OCRF	Reset	Functions	Held	Held	Functions	Held	Held	Held
TCRF	Reset	Functions	Held	Held	Functions	Held	Held	Held
TCSRF	Reset	Functions	Held	Held	Functions	Held	Held	Held

Note: * When $\phi_w/4$ is selected as the TCF internal clock in active mode or sleep mode, since the system clock and internal clock are mutually asynchronous, synchronization is maintained by a synchronization circuit. This results in a maximum count cycle error of $1/\phi$ (s). When the counter is operated in subactive mode, watch mode, or subsleep mode, $\phi_w/4$ must be selected as the internal clock. The counter will not operate if any other internal clock is selected.

9.4.5 Application Notes

The following types of contention and operation can occur when timer F is used.

1. 16-bit Timer Mode

In toggle output, TMOFH pin output is toggled when all 16 bits match and a compare match signal is generated. If a TCRF write by a MOV instruction and generation of the compare match signal occur simultaneously, TOLH data is output to the TMOFH pin as a result of the TCRF write. TMOFL pin output is unstable in 16-bit mode, and should not be used; the TMOFL pin should be used as a port pin.

If an OCRFL write and compare match signal generation occur simultaneously, the compare match signal is invalid. However, if the written data and the counter value match, a compare match signal will be generated at that point. As the compare match signal is output in synchronization with the TCFL clock, a compare match will not result in compare match signal generation if the clock is stopped.

Compare match flag CMFH is set when all 16 bits match and a compare match signal is generated. Compare match flag CMFL is set if the setting conditions for the lower 8 bits are satisfied.

When TCF overflows, OVFH is set. OVFL is set if the setting conditions are satisfied when the lower 8 bits overflow. If a TCFL write and overflow signal output occur simultaneously, the overflow signal is not output.

2. 8-bit Timer Mode

a. TCFH, OCRFH

In toggle output, TMOFH pin output is toggled when a compare match occurs. If a TCRF write by a MOV instruction and generation of the compare match signal occur simultaneously, TOLH data is output to the TMOFH pin as a result of the TCRF write.

If an OCRFH write and compare match signal generation occur simultaneously, the compare match signal is invalid. However, if the written data and the counter value match, a compare match signal will be generated at that point. The compare match signal is output in synchronization with the TCFH clock.

If a TCFH write and overflow signal output occur simultaneously, the overflow signal is not output.

b. TCFL, OCRFL

In toggle output, TMOFL pin output is toggled when a compare match occurs. If a TCRF write by a MOV instruction and generation of the compare match signal occur simultaneously, TOLL data is output to the TMOFL pin as a result of the TCRF write.

If an OCRFL write and compare match signal generation occur simultaneously, the compare match signal is invalid. However, if the written data and the counter value match, a compare match signal will be generated at that point. As the compare match signal is output in synchronization with the TCFL clock, a compare match will not result in compare match signal generation if the clock is stopped.

If a TCFL write and overflow signal output occur simultaneously, the overflow signal is not output.

3. Clear Timer FH, Timer FL Interrupt Request Flags (IRRTFH, IRRTFL), Timer Overflow Flags H, L (OVFH, OVFL) and Compare Match Flags H, L (CMFH, CMFL)

When $\phi w/4$ is selected as the internal clock, "Interrupt factor generation signal" will be operated with ϕw and the signal will be outputted with ϕw width. And, "Overflow signal" and "Compare match signal" are controlled with 2 cycles of ϕw signals. Those signals are outputted with 2 cycles width of ϕw (figure 9.7)

In active (high-speed, medium-speed) mode, even if you cleared interrupt request flag during the term of validity of "Interrupt factor generation signal", same interrupt request flag is set. (figure 9.7 (1)) And, you cannot be cleared timer overflow flag and compare match flag during the term of validity of "Overflow signal" and "Compare match signal".

For interrupt request flag is set right after interrupt request is cleared, interrupt process to one time timer FH, timer FL interrupt might be repeated. (figure 9.7 (2)) Therefore, to definitely clear interrupt request flag in active (high-speed, medium-speed) mode, clear should be processed after the time that calculated with below (1) formula. And, to definitely clear timer overflow flag and compare match flag, clear should be processed after read timer control status register F (TCSRF) after the time that calculated with below (1) formula. For ST of (1) formula, please substitute the longest number of execution states in used instruction. (10 states of RTE instruction when MULXU, DIVXU instruction is not used, 14 states when MULXU, DIVXU instruction is used) In subactive mode, there are not limitation for interrupt request flag, timer overflow flag, and compare match flag clear.

The term of validity of "Interrupt factor generation signal"

= 1 cycle of ϕw + waiting time for completion of executing instruction + interrupt time synchronized with $\phi = 1/\phi w + ST \times (1/\phi) + (2/\phi)$ (second).....(1)

ST: Executing number of execution states

Method 1 is recommended to operate for time efficiency.

Method 1

- 1. Prohibit interrupt in interrupt handling routine (set IENFH, IENFL to 0).
- 2. After program process returned normal handling, clear interrupt request flags (IRRTFH, IRRTFL) after more than that calculated with (1) formula.
- 3. After read timer control status register F (TCSRF), clear timer overflow flags (OVFH, OVFL) and compare match flags (CMFH, CMFL).
- 4. Operate interrupt permission (set IENFH, IENFL to 1).

Method 2

- 1. Set interrupt handling routine time to more than time that calculated with (1) formula.
- 2. Clear interrupt request flags (IRRTFH, IRRTFL) at the end of interrupt handling routine.
- 3. After read timer control status register F (TCSRF), clear timer overflow flags (OVFH, OVFL) and compare match flags (CMFH, CMFL).

All above attentions are also applied in 16-bit mode and 8-bit mode.



Figure 9.7 Clear Interrupt Request Flag when Interrupt Factor Generation Signal is Valid

4. Timer Counter (TCF) Read/Write

When $\phi w/4$ is selected as the internal clock in active (high-speed, medium-speed) mode, write on TCF is impossible. And, when read TCF, as the system clock and internal clock are mutually asynchronous, TCF synchronizes with synchronization circuit. This results in a maximum TCF read value error of ± 1 .

When read/write TCF in active (high-speed, medium-speed) mode is needed, please select internal clock except for ϕ w/4 before read/write.

In subactive mode, even $\phi w/4$ is selected as the internal clock, normal read/write TCF is possible.

9.5 Timer G

9.5.1 Overview

Timer G is an 8-bit timer with dedicated input capture functions for the rising/falling edges of pulses input from the input capture input pin (input capture input signal). High-frequency component noise in the input capture input signal can be eliminated by a noise canceler, enabling accurate measurement of the input capture input signal duty cycle. If input capture input is not set, timer G functions as an 8-bit interval timer.

1. Features

Features of timer G are given below.

- Choice of four internal clock sources ($\phi/64$, $\phi/32$, $\phi/2$, $\phi w/4$)
- Dedicated input capture functions for rising and falling edges
- Level detection at counter overflow

It is possible to detect whether overflow occurred when the input capture input signal was high or when it was low.

- Selection of whether or not the counter value is to be cleared at the input capture input signal rising edge, falling edge, or both edges
- Two interrupt sources: one input capture, one overflow. The input capture input signal rising or falling edge can be selected as the interrupt source.
- A built-in noise canceler eliminates high-frequency component noise in the input capture input signal.
- Watch mode, subactive mode and subsleep mode operation is possible when $\frac{\phi w}{4}$ is selected as the internal clock.
- Use of module standby mode enables this module to be placed in standby mode independently when not used.



2. Block Diagram

Figure 9.8 shows a block diagram of timer G.



Figure 9.8 Block Diagram of Timer G

3. Pin Configuration

Table 9.11 shows the timer G pin configuration.

Table 9.11Pin Configuration

Name	Abbr.	I/O	Function
Input capture input	TMIG	Input	Input capture input pin

4. Register Configuration

Table 9.12 shows the register configuration of timer G.

Table 9.12 Timer G Registers

Name	Abbr.	R/W	Initial Value	Address
Timer control register G	TMG	R/W	H'00	H'FFBC
Timer counter G	TCG	_	H'00	_
Input capture register GF	ICRGF	R	H'00	H'FFBD
Input capture register GR	ICRGR	R	H'00	H'FFBE
Clock stop register 1	CKSTPR1	R/W	H'FF	H'FFFA



9.5.2 Register Descriptions

1. Timer Counter (TCG)

Bit	7	6	5	4	3	2	1	0
	TCG7	TCG6	TCG5	TCG4	TCG3	TCG2	TCG1	TCG0
Initial value	0	0	0	0	0	0	0	0
Read/Write	_	_	_	_	_	_	_	_

TCG is an 8-bit up-counter which is incremented by clock input. The input clock is selected by bits CKS1 and CKS0 in TMG.

TMIG in PMR1 is set to 1 to operate TCG as an input capture timer, or cleared to 0 to operate TCG as an interval timer^{*}. In input capture timer operation, the TCG value can be cleared by the rising edge, falling edge, or both edges of the input capture input signal, according to the setting made in TMG.

When TCG overflows from H'FF to H'00, if OVIE in TMG is 1, IRRTG is set to 1 in IRR2, and if IENTG in IENR2 is 1, an interrupt request is sent to the CPU.

For details of the interrupt, see section 3.3, Interrupts.

TCG cannot be read or written by the CPU. It is initialized to H'00 upon reset.

Note: * An input capture signal may be generated when TMIG is modified.

2. Input Capture Register GF (ICRGF)

Bit	7	6	5	4	3	2	1	0
	ICRGF7	ICRGF6	ICRGF5	ICRGF4	ICRGF3	ICRGF2	ICRGF1	ICRGF0
Initial value	0	0	0	0	0	0	0	0
Read/Write	R	R	R	R	R	R	R	R

ICRGF is an 8-bit read-only register. When a falling edge of the input capture input signal is detected, the current TCG value is transferred to ICRGF. If IIEGS in TMG is 1 at this time, IRRTG is set to 1 in IRR2, and if IENTG in IENR2 is 1, an interrupt request is sent to the CPU.

For details of the interrupt, see section 3.3, Interrupts.

To ensure dependable input capture operation, the pulse width of the input capture input signal must be at least 2ϕ or $2\phi_{SUB}$ (when the noise canceler is not used).

ICRGF is initialized to H'00 upon reset.

3. Input Capture Register GR (ICRGR)

Bit	7	6	5	4	3	2	1	0
	ICRGR7	ICRGR6	ICRGR5	ICRGR4	ICRGR3	ICRGR2	ICRGR1	ICRGR0
Initial value	0	0	0	0	0	0	0	0
Read/Write	R	R	R	R	R	R	R	R

ICRGR is an 8-bit read-only register. When a rising edge of the input capture input signal is detected, the current TCG value is transferred to ICRGR. If IIEGS in TMG is 1 at this time, IRRTG is set to 1 in IRR2, and if IENTG in IENR2 is 1, an interrupt request is sent to the CPU.

For details of the interrupt, see section 3.3, Interrupts.

To ensure dependable input capture operation, the pulse width of the input capture input signal must be at least 2ϕ or $2\phi_{SUB}$ (when the noise canceler is not used).

ICRGR is initialized to H'00 upon reset.



4. Timer Mode Register G (TMG)

Bit:	7	6	5	4	3	2	1	0
	OVFH	OVFL	OVIE	IIEGS	CCLR1	CCLR0	CKS1	CKS0
Initial value:	0	0	0	0	0	0	0	0
Read/Write:	R/W*	R/W*	R/W	R/W	R/W	R/W	R/W	R/W

Note: * Bits 7 and 6 can only be written with 0, for flag clearing.

TMG is an 8-bit read/write register that performs TCG clock selection from four internal clock sources, counter clear selection, and edge selection for the input capture input signal interrupt request, controls enabling of overflow interrupt requests, and also contains the overflow flags.

TMG is initialized to H'00 upon reset.

Bit 7: Timer overflow flag H (OVFH)

Bit 7 is a status flag indicating that TCG has overflowed from H'FF to H'00 when the input capture input signal is high. This flag is set by hardware and cleared by software. It cannot be set by software.

Bit 7 OVFH	Description	
0	Clearing condition:	(initial value)
	After reading OVFH = 1, cleared by writing 0 to OVFH	
1	Setting condition:	
	Set when TCG overflows from H'FF to H'00	

Bit 6: Timer overflow flag L (OVFL)

Bit 6 is a status flag indicating that TCG has overflowed from H'FF to H'00 when the input capture input signal is low, or in interval operation. This flag is set by hardware and cleared by software. It cannot be set by software.

Bit 6 OVFL	Description	
0	Clearing condition:	(initial value)
	After reading OVFL = 1, cleared by writing 0 to OVFL	
1	Setting condition:	
	Set when TCG overflows from H'FF to H'00	

Bit 5: Timer overflow interrupt enable (OVIE)

Bit 5 selects enabling or disabling of interrupt generation when TCG overflows.

Bit 5 OVIE	Description	
0	TCG overflow interrupt request is disabled	(initial value)
1	TCG overflow interrupt request is enabled	

Bit 4: Input capture interrupt edge select (IIEGS)

Bit 4 selects the input capture input signal edge that generates an interrupt request.

Bit 4 IIEGS	Description	
0	Interrupt generated on rising edge of input capture input signal	(initial value)
1	Interrupt generated on falling edge of input capture input signal	

Bits 3 and 2: Counter clear 1 and 0 (CCLR1, CCLR0)

Bits 3 and 2 specify whether or not TCG is cleared by the rising edge, falling edge, or both edges of the input capture input signal.

Bit 3 CCLR1	Bit 2 CCLR0	Description	
0	0	TCG clearing is disabled	(initial value)
0	1	TCG cleared by falling edge of input capture input signal	
1	0	TCG cleared by rising edge of input capture input signal	
1	1	TCG cleared by both edges of input capture input signal	

Bits 1 and 0: Clock select (CKS1, CKS0)

Bit 1 CKS1	Bit 0 CKS0	Description	
0	0	Internal clock: Counting on	(initial value)
0	1	Internal clock: Counting on	
1	0	Internal clock: Counting on $\phi/2$	
1	1	Internal clock: Counting on $\phi w/4$	

Bits 1 and 0 select the clock input to TCG from among four internal clock sources.

5. Clock Stop Register 1 (CKSTPR1)

Bit	7	6	5	4	3	2	1	0
	—	S31CKSTP	S32CKSTP	ADCKSTP	TGCKSTP	TFCKSTP	TCCKSTP	TACKSTP
Initial value	1	1	1	1	1	1	1	1
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

CKSTPR1 is an 8-bit read/write register that performs module standby mode control for peripheral modules. Only the bit relating to timer G is described here. For details of the other bits, see the sections on the relevant modules.

Bit 3: Timer G module standby mode control (TGCKSTP)

Bit 3 controls setting and clearing of module standby mode for timer G.

IGCKSIP	Description	
0	Timer G is set to module standby mode	
1	Timer G module standby mode is cleared	(initial value)

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9.5.3 Noise Canceler

The noise canceler consists of a digital low-pass filter that eliminates high-frequency component noise from the pulses input from the input capture input pin. The noise canceler is set by NCS* in PMR3.



Figure 9.9 shows a block diagram of the noise canceler.

Figure 9.9 Noise Canceler Block Diagram

The noise canceler consists of five latch circuits connected in series and a match detector circuit. When the noise cancellation function is not used (NCS = 0), the system clock is selected as the sampling clock. When the noise cancellation function is used (NCS = 1), the sampling clock is the internal clock selected by CKS1 and CKS0 in TMG, the input capture input is sampled on the rising edge of this clock, and the data is judged to be correct when all the latch outputs match. If all the outputs do not match, the previous value is retained. After a reset, the noise canceler output is initialized when the falling edge of the input capture input signal has been sampled five times. Therefore, after making a setting for use of the noise cancellation function, a pulse with at least five times the width of the sampling clock is a dependable input capture signal. Even if noise cancellation is not used, an input capture input signal pulse width of at least 2ϕ or $2\phi_{SUB}$ is necessary to ensure that input capture operations are performed properly

Note: * An input capture signal may be generated when the NCS bit is modified.

Figure 9.10 shows an example of noise canceler timing.

In this example, high-level input of less than five times the width of the sampling clock at the input capture input pin is eliminated as noise.



Figure 9.10 Noise Canceler Timing (Example)

9.5.4 Operation

Timer G is an 8-bit timer with built-in input capture and interval functions.

1. Timer G Functions

Timer G is an 8-bit up-counter with two functions, an input capture timer function and an interval timer function.

The operation of these two functions is described below.

a. Input capture timer operation

When the TMIG bit is set to 1 in port mode register 1 (PMR1), timer G functions as an input capture timer^{*}.

In a reset, timer mode register G (TMG), timer counter G (TCG), input capture register GF (ICRGF), and input capture register GR (ICRGR) are all initialized to H'00.

Following a reset, TCG starts incrementing on the $\phi/64$ internal clock.

The input clock can be selected from four internal clock sources by bits CKS1 and CKS0 in TMG.

When a rising edge/falling edge is detected in the input capture signal input from the TMIG pin, the TCG value at that time is transferred to ICRGR/ICRGF. When the edge selected by IIEGS in TMG is input, IRRTG is set to 1 in IRR2, and if the IENTG bit in IENR2 is 1 at this time, an interrupt request is sent to the CPU. For details of the interrupt, see section 3.3, Interrupts.

TCG can be cleared by a rising edge, falling edge, or both edges of the input capture signal, according to the setting of bits CCLR1 and CCLR0 in TMG. If TCG overflows when the input capture signal is high, the OVFH bit is set in TMG; if TCG overflows when the input capture signal is low, the OVFL bit is set in TMG. If the OVIE bit in TMG is 1 when these bits are set, IRRTG is set to 1 in IRR2, and if the IENTG bit in IENR2 is 1, timer G sends an interrupt request to the CPU. For details of the interrupt, see section 3.3, Interrupts.

Timer G has a built-in noise canceler that enables high-frequency component noise to be eliminated from pulses input from the TMIG pin. For details, see section 9.5.3, Noise Canceler.

Note: * An input capture signal may be generated when TMIG is modified.



b. Interval timer operation

When the TMIG bit is cleared to 0 in PMR1, timer G functions as an interval timer. Following a reset, TCG starts incrementing on the $\phi/64$ internal clock. The input clock can be selected from four internal clock sources by bits CKS1 and CKS0 in TMG. TCG increments on the selected clock, and when it overflows from H'FF to H'00, the OVFL bit is set to 1 in TMG. If the OVIE bit in TMG is 1 at this time, IRRTG is set to 1 in IRR2, and if the IENTG bit in IENR2 is 1, timer G sends an interrupt request to the CPU. For details of the interrupt, see section 3.3, Interrupts.

2. Increment Timing

TCG is incremented by internal clock input. Bits CKS1 and CKS0 in TMG select one of four internal clock sources ($\phi/64$, $\phi/32$, $\phi/2$, or $\phi w/4$) created by dividing the system clock (ϕ) or watch clock (ϕw).

3. Input Capture Input Timing

a. Without noise cancellation function

For input capture input, dedicated input capture functions are provided for rising and falling edges.

Figure 9.11 shows the timing for rising/falling edge input capture input.



Figure 9.11 Input Capture Input Timing (without Noise Cancellation Function)

b. With noise cancellation function

When noise cancellation is performed on the input capture input, the passage of the input capture signal through the noise canceler results in a delay of five sampling clock cycles from the input capture input signal edge.

Figure 9.12 shows the timing in this case.

Input capture input signal	
Sampling clock	
Noise canceler output	
Input capture signal R	

Figure 9.12 Input Capture Input Timing (with Noise Cancellation Function)

4. Timing of Input Capture by Input Capture Input

Figure 9.13 shows the timing of input capture by input capture input



Figure 9.13 Timing of Input Capture by Input Capture Input


5. TGC Clear Timing

TCG can be cleared by the rising edge, falling edge, or both edges of the input capture input signal.

Figure 9.14 shows the timing for clearing by both edges.



Figure 9.14 TCG Clear Timing

6. Timer G Operation Modes

Timer G operation modes are shown in table 9.13.

Table 9.13 Timer G Operation Modes

Opera	ation Mode	Reset	Active	Sleep	Watch	Sub- active	Sub- sleep	Standby	Module Standby
TCG	Input capture	Reset	Functions*	Functions*	Functions/ halted [*]	Functions/ halted [*]	Functions/ halted [*]	Halted	Halted
	Interval	Reset	Functions*	Functions*	Functions/ halted*	Functions/ halted*	Functions/ halted*	Halted	Halted
ICRG	F	Reset	Functions*	Functions*	Functions/ halted*	Functions/ halted*	Functions/ halted*	Held	Held
ICRG	R	Reset	Functions*	Functions*	Functions halted*	Functions/ halted*	Functions/ halted*	Held	Held
TMG		Reset	Functions	Held	Held	Functions	Held	Held	Held

Note: * When φw/4 is selected as the TCG internal clock in active mode or sleep mode, since the system clock and internal clock are mutually asynchronous, synchronization is maintained by a synchronization circuit. This results in a maximum count cycle error of 1/φ (s). When φw/4 is selected as the TCG internal clock in watch mode, TCG and the noise canceler operate on the φw/4 internal clock without regard to the φ_{SUB} subclock (φw/8, φw/4, φw/2). Note that when another internal clock is selected, TCG and the noise canceler do not operate, and input of the input capture input signal does not result in input capture.

To be operated Timer G in subactive mode or subsleep mode, select ϕ w/4 for internal clock of TCG and also select ϕ w/2 for sub clock ϕ _{SUB}. When another internal clock is selected and when another sub clock (ϕ w/8, ϕ w/4) is selected, TCG and noise canceler do not operate.



9.5.5 Application Notes

1. Internal Clock Switching and TCG Operation

Depending on the timing, TCG may be incremented by a switch between difference internal clock sources. Table 9.14 shows the relation between internal clock switchover timing (by write to bits CKS1 and CKS0) and TCG operation.

When TCG is internally clocked, an increment pulse is generated on detection of the falling edge of an internal clock signal, which is divided from the system clock (ϕ) or subclock (ϕ w). For this reason, in a case like No. 3 in table 9.14 where the switch is from a high clock signal to a low clock signal, the switchover is seen as a falling edge, causing TCG to increment.

Table 9.14 Internal Clock Switching and TCG Operation





Note: * The switchover is seen as a falling edge, and TCG is incremented.



2. Notes on Port Mode Register Modification

The following points should be noted when a port mode register is modified to switch the input capture function or the input capture input noise canceler function.

• Switching input capture input pin function

Note that when the pin function is switched by modifying TMIG in port mode register 1 (PMR1), which performs input capture input pin control, an edge will be regarded as having been input at the pin even though no valid edge has actually been input. Input capture input signal input edges, and the conditions for their occurrence, are summarized in table 9.15.

Table 9.15 Input Capture Input Signal Input Edges Due to Input Capture Input Pin Switching, and Conditions for Their Occurrence

Input Edge	Conditions
Generation of rising edge	When TMIG is modified from 0 to 1 while the TMIG pin is high
	When NCS is modified from 0 to 1 while the TMIG pin is high, then TMIG is modified from 0 to 1 before the signal is sampled five times by the noise canceler
Generation of falling edge	When TMIG is modified from 1 to 0 while the TMIG pin is high
	When NCS is modified from 0 to 1 while the TMIG pin is low, then TMIG is modified from 0 to 1 before the signal is sampled five times by the noise canceler
	When NCS is modified from 0 to 1 while the TMIG pin is high, then TMIG is modified from 1 to 0 after the signal is sampled five times by the noise canceler
Note: When the P1 ₃ pin is not	set as an input capture input pin, the timer G input capture input

Input Capture Input Signal

Note: When the P1₃ pin is not set as an input capture input pin, the timer G input capture input signal is low.

Switching input capture input noise canceler function

When performing noise canceler function switching by modifying NCS in port mode register 3 (PMR3), which controls the input capture input noise canceler, TMIG should first be cleared to 0. Note that if NCS is modified without first clearing TMIG, an edge will be regarded as having been input at the pin even though no valid edge has actually been input. Input capture input signal input edges, and the conditions for their occurrence, are summarized in table 9.16.

Table 9.16 Input Capture Input Signal Input Edges Due to Noise Canceler Function Switching, and Conditions for Their Occurrence

Input Capture Input Signal Input Edge	Conditions
Generation of rising edge	When the TMIG pin level is switched from low to high while TMIG is set to 1, then NCS is modified from 0 to 1 before the signal is sampled five times by the noise canceler
Generation of falling edge	When the TMIG pin level is switched from high to low while TMIG is set to 1, then NCS is modified from 1 to 0 before the signal is sampled five times by the noise canceler

Input Capture Input Signal Input Edge
Generation of rising edge

When the pin function is switched and an edge is generated in the input capture input signal, if this edge matches the edge selected by the input capture interrupt select (IIEGS) bit, the interrupt request flag will be set to 1. The interrupt request flag should therefore be cleared to 0 before use. Figure 9.15 shows the procedure for port mode register manipulation and interrupt request flag clearing. When switching the pin function, set the interrupt-disabled state before manipulating the port mode register, then, after the port mode register operation has been performed, wait for the time required to confirm the input capture input signal as an input capture signal (at least two system clocks when the noise canceler is not used; at least five sampling clocks when the noise canceler is used), before clearing the interrupt enable flag to 0. There are two ways of preventing interrupt request flag setting when the pin function is switched: by controlling the pin level so that the conditions shown in tables 9.15 and 9.16 are not satisfied, or by setting the opposite of the generated edge in the IIEGS bit in TMG.





Figure 9.15 Port Mode Register Manipulation and Interrupt Enable Flag Clearing Procedure

9.5.6 Timer G Application Example

Using timer G, it is possible to measure the high and low widths of the input capture input signal as absolute values. For this purpose, CCLR1 and CCLR0 should both be set to 1 in TMG.

Figure 9.16 shows an example of the operation in this case.



Figure 9.16 Timer G Application Example

9.6 Watchdog Timer

9.6.1 Overview

The watchdog timer has an 8-bit counter that is incremented by an input clock. If a system runaway allows the counter value to overflow before being rewritten, the watchdog timer can reset the chip internally.

1. Features

Features of the watchdog timer are given below.

- Incremented by internal clock source ($\phi/8192$ or $\phi w/32$).
- A reset signal is generated when the counter overflows. The overflow period can be set from from 1 to 256 times 8192/φ or 32/φw (from approximately 4 ms to 1000 ms when φ = 2.00 MHz).
- Use of module standby mode enables this module to be placed in standby mode independently when not used.

2. Block Diagram

Figure 9.17 shows a block diagram of the watchdog timer.



Figure 9.17 Block Diagram of Watchdog Timer

3. Register Configuration

Table 9.17 shows the register configuration of the watchdog timer.

Table 9.17 Watchdog Timer Registers

Name	Abbr.	R/W	Initial Value	Address
Timer control/status register W	TCSRW	R/W	H'AA	H'FFB2
Timer counter W	TCW	R/W	H'00	H'FFB3
Clock stop register 2	CKSTP2	R/W	H'FF	H'FFFB
Port mode register 3	PMR3	R/W	H'00	H'FFCA

9.6.2 Register Descriptions

1. Timer Control/Status Register W (TCSRW)

Bit	7	6	5	4	3	2	1	0
	B6WI	TCWE	B4WI	TCSRWE	B2WI	WDON	B0WI	WRST
Initial value	1	0	1	0	1	0	1	0
Read/Write	R	R/(W)*	R	R/(W)*	R	R/(W)*	R	R/(W)*

Note: * Write is permitted only under certain conditions, which are given in the descriptions of the individual bits.

TCSRW is an 8-bit read/write register that controls write access to TCW and TCSRW itself, controls watchdog timer operations, and indicates operating status.

Bit 7: Bit 6 write inhibit (B6WI)

Bit 7 controls the writing of data to bit 6 in TCSRW.

Bit 7		
B6WI	Description	
0	Bit 6 is write-enabled	
1	Bit 6 is write-protected	(initial value)

This bit is always read as 1. Data written to this bit is not stored.

Bit 6: Timer counter W write enable (TCWE)

Bit 6 controls the writing of data to TCW.

Bit 6		
TCWE	Description	
0	Data cannot be written to TCW	(initial value)
1	Data can be written to TCW	

Bit 5: Bit 4 write inhibit (B4WI)

Bit 5 controls the writing of data to bit 4 in TCSRW.

Bit 5 B4WI	Description	
0	Bit 4 is write-enabled	
1	Bit 4 is write-protected	(initial value)

This bit is always read as 1. Data written to this bit is not stored.

Bit 4: Timer control/status register W write enable (TCSRWE)

Bit 4 controls the writing of data to TCSRW bits 2 and 0.

Bit 4		
TCSRWE	Description	
0	Data cannot be written to bits 2 and 0	(initial value)
1	Data can be written to bits 2 and 0	

Bit 3: Bit 2 write inhibit (B2WI)

Bit 3 controls the writing of data to bit 2 in TCSRW.

Bit 3 B2WI	Description	
0	Bit 2 is write-enabled	
1	Bit 2 is write-protected	(initial value)

This bit is always read as 1. Data written to this bit is not stored.

Bit 2: Watchdog timer on (WDON)

Bit 2 enables watchdog timer operation.

Bit 2 WDON	Description	
0	Watchdog timer operation is disabled	(initial value)
	Clearing condition:	
	Reset, or when TCSRWE = 1 and 0 is written in both B2WI and WDON	٨
1	Watchdog timer operation is enabled	
	Setting condition:	
	When TCSRWE = 1 and 0 is written in B2WI and 1 is written in WDON	l

Counting starts when this bit is set to 1, and stops when this bit is cleared to 0.

Bit 1: Bit 0 write inhibit (B0WI)

Bit 1 controls the writing of data to bit 0 in TCSRW.

Bit 1 B0WI	Description	
DUWI	Description	
0	Bit 0 is write-enabled	
1	Bit 0 is write-protected	(initial value)

This bit is always read as 1. Data written to this bit is not stored.

Bit 0: Watchdog timer reset (WRST)

Bit 0 indicates that TCW has overflowed, generating an internal reset signal. The internal reset signal generated by the overflow resets the entire chip. WRST is cleared to 0 by a reset from the $\overline{\text{RES}}$ pin, or when software writes 0.

Bit 0 WRST	Description
0	Clearing condition:
	Reset by RES pin
	When TCSRWE = 1, and 0 is written in both B0WI and WRST
1	Setting condition:
	When TCW overflows and an internal reset signal is generated

2. Timer Counter W (TCW)

Bit	7	6	5	4	3	2	1	0
	TCW7	TCW6	TCW5	TCW4	TCW3	TCW2	TCW1	TCW0
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W							

TCW is an 8-bit read/write up-counter, which is incremented by internal clock input. The input clock is $\phi/8192$ or $\phi w/32$. The TCW value can always be written or read by the CPU.

When TCW overflows from H'FF to H'00, an internal reset signal is generated and WRST is set to 1 in TCSRW. Upon reset, TCW is initialized to H'00.

3. Clock Stop Register 2 (CKSTPR2)

Bit	7	6	5	4	3	2	1	0
	_	—	—	—	AECKSTP	WDCKSTP	PWCKSTP	LDCKSTP
Initial value	1	1	1	1	1	1	1	1
Read/Write	—	—	—	—	R/W	R/W	R/W	R/W

CKSTPR2 is an 8-bit read/write register that performs module standby mode control for peripheral modules. Only the bit relating to the watchdog timer is described here. For details of the other bits, see the sections on the relevant modules.

Bit 2: Watchdog timer module standby mode control (WDCKSTP)

Bit 2 controls setting and clearing of module standby mode for the watchdog timer.

0	Watchdog timer is set to module standby mode	
1	Watchdog timer module standby mode is cleared	(initial value)
Note:	WDCKSTP is valid when the WDON bit is cleared to 0 in timer control/sta	atus register W
	(TCSRW). If WDCKSTP is set to 0 while WDON is set to 1 (during watch	ndog timer
	operation) 0 will be set in WDCKSTP but the watchdog timer will continu	e its watchdog

operation), 0 will be set in WDCKSTP but the watchdog timer will continue its watchdog function and will not enter module standby mode. When the watchdog function ends and WDON is cleared to 0 by software, the WDCKSTP setting will become valid and the watchdog timer will enter module standby mode.

4. Port Mode Register 3 (PMR3)

Bit	7	6	5	4	3	2	1	0
	AEVL	AEVH	WDCKS	NCS	IRQ0	RESO	UD	PWM
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

PMR3 is an 8-bit read/write register, mainly controlling the selection of pin functions for port 3 pins. Only the bit relating to the watchdog timer is described here. For details of the other bits, see section 8, I/O Ports.

Bit 5: Watchdog timer source clock select (WDCKS)

WDCKS	Description	
0	φ/8192 selected	(initial value)
1	φw/32 selected	

9.6.3 Timer Operation

The watchdog timer has an 8-bit counter (TCW) that is incremented by clock input (ϕ /8192 or ϕ w/32). The input clock is selected by bit WDCKS in port mode register 3 (PMR3): ϕ /8192 is selected when WDCKS is cleared to 0, and ϕ w/32 when set to 1. When TCSRWE = 1 in TCSRW, if 0 is written in B2WI and 1 is simultaneously written in WDON, TCW starts counting up. When the TCW count reaches H'FF, the next clock input causes the watchdog timer to overflow, and an internal reset signal is generated one reference clock (ϕ or ϕ _{SUB}) cycle later. The internal reset signal is output for 512 clock cycles of the ϕ _{OSC} clock. It is possible to write to TCW, causing TCW to count up from the written value. The overflow period can be set in the range from 1 to 256 input clocks, depending on the value written in TCW.

Figure 9.18 shows an example of watchdog timer operations.



Figure 9.18 Typical Watchdog Timer Operations (Example)

9.6.4 Watchdog Timer Operation States

Table 9.18 summarizes the watchdog timer operation states.

Table 9.18 Watchdog Timer Operation States

Operation Mode	Reset	Active	Sleep	Watch	Sub- active	Sub- sleep	Standby	Module Standby
TCW	Reset	Functions	Functions	Halted	Functions/ Halted*	Halted	Halted	Halted
TCSRW	Reset	Functions	Functions	Retained	Functions/ Halted [*]	Retained	Retained	Retained

Note: * Functions when $\phi w/32$ is selected as the input clock.

9.7 Asynchronous Event Counter (AEC)

9.7.1 Overview

The asynchronous event counter is incremented by external event clock input.

1. Features

Features of the asynchronous event counter are given below.

• Can count asynchronous events

Can count external events input asynchronously without regard to the operation of base clocks φ and $\varphi_{SUB}.$

The counter has a 16-bit configuration, enabling it to count up to $65536 (2^{16})$ events.

- Can also be used as two independent 8-bit event counter channels.
- Counter resetting and halting of the count-up function controllable by software
- Automatic interrupt generation on detection of event counter overflow
- Use of module standby mode enables this module to be placed in standby mode independently when not used.

2. Block Diagram

Figure 9.19 shows a block diagram of the asynchronous event counter.



Figure 9.19 Block Diagram of Asynchronous Event Counter

3. Pin Configuration

Table 9.19 shows the asynchronous event counter pin configuration.

Table 9.19 Pin Configuration

Name	Abbr.	I/O	Function
Asynchronous event input H	AEVH	Input	Event input pin for input to event counter H
Asynchronous event input L	AEVL	Input	Event input pin for input to event counter L

4. Register Configuration

Table 9.20 shows the register configuration of the asynchronous event counter.

Table 9.20 Asynchronous Event Counter Registers

Name	Abbr.	R/W	Initial Value	Address
Event counter control/status register	ECCSR	R/W	H'00	H'FF95
Event counter H	ECH	R	H'00	H'FF96
Event counter L	ECL	R	H'00	H'FF97
Clock stop register 2	CKSTP2	R/W	H'FF	H'FFFB

9.7.2 Register Descriptions

1. Event Counter Control/Status Register (ECCSR)

Bit	7	6	5	4	3	2	1	0
	OVH	OVL	—	CH2	CUEH	CUEL	CRCH	CRCL
Initial Value	0	0	0	0	0	0	0	0
Read/Write	R/W*	R/W*	R/W	R/W	R/W	R/W	R/W	R/W

Note: * Bits 7 and 6 can only be written with 0, for flag clearing.

ECCSR is an 8-bit read/write register that controls counter overflow detection, counter resetting, and halting of the count-up function.

ECCSR is initialized to H'00 upon reset.

Bit 7: Counter overflow flag H (OVH)

Bit 7 is a status flag indicating that ECH has overflowed from H'FF to H'00. This flag is set when ECH overflows. It is cleared by software but cannot be set by software. OVH is cleared by reading it when set to 1, then writing 0.

When ECH and ECL are used as a 16-bit event counter with CH2 cleared to 0, OVH functions as a status flag indicating that the 16-bit event counter has overflowed from H'FFFF to H'0000.

Bit 7		
OVH	Description	
0	ECH has not overflowed	(initial value)
	Clearing condition:	
	After reading OVH = 1, cleared by writing 0 to OVH	
1	ECH has overflowed	
	Setting condition:	
	Set when ECH overflows from H'FF to H'00	

Bit 6: Counter overflow flag L (OVL)

Bit 6 is a status flag indicating that ECL has overflowed from H'FF to H'00. This flag is set when ECL overflows. It is cleared by software but cannot be set by software. OVL is cleared by reading it when set to 1, then writing 0.

Bit 6		
OVL	Description	
0	ECL has not overflowed	(initial value)
	Clearing condition:	
	After reading OVL = 1, cleared by writing 0 to OVL	
1	ECL has overflowed	
	Setting condition:	
	Set when ECL overflows from H'FF to H'00 while CH2 is set to 1	

Bit 5: Reserved bit

Bit 5 is reserved; it can be read and written, and is initialized to 0 upon reset.

Bit 4: Channel select (CH2)

Bit 4 selects whether ECH and ECL are used as a single-channel 16-bit event counter or as two independent 8-bit event counter channels. When CH2 is cleared to 0, ECH and ECL function as a 16-bit event counter which is incremented each time an event clock is input to the AEVL pin as asynchronous event input. In this case, the overflow signal from ECL is selected as the ECH input clock. When CH2 is set to 1, ECH and ECL function as independent 8-bit event counters which are incremented each time an event clock is input to the AEVL pin, respectively, as asynchronous event input.

Bit 4 CH2	Description
0	ECH and ECL are used together as a single-channel 16-bit event counter (initial value)
1	ECH and ECL are used as two independent 8-bit event counter channels

Bit 3: Count-up enable H (CUEH)

Bit 3 enables event clock input to ECH. When 1 is written to this bit, event clock input is enabled and increments the counter. When 0 is written to this bit, event clock input is disabled and the ECH value is held. The AEVH pin or the ECL overflow signal can be selected as the event clock source by bit CH2.

Bit 3 CUEH	Description	
0	ECH event clock input is disabled	(initial value)
	ECH value is held	
1	ECH event clock input is enabled	

Bit 2: Count-up enable L (CUEL)

Bit 3 enables event clock input to ECL. When 1 is written to this bit, event clock input is enabled and increments the counter. When 0 is written to this bit, event clock input is disabled and the ECL value is held.

Bit 2 CUEL	Description	
0	ECL event clock input is disabled ECL value is held	(initial value)
1	ECL event clock input is enabled	

Bit 1: Counter reset control H (CRCH)

Bit 1 controls resetting of ECH. When this bit is cleared to 0, ECH is reset. When 1 is written to this bit, the counter reset is cleared and the ECH count-up function is enabled.

Bit 1 CRCH	Description	
0	ECH is reset	(initial value)
1	ECH reset is cleared and count-up function is enabled	

Bit 0: Counter reset control L (CRCL)

Bit 0 controls resetting of ECL. When this bit is cleared to 0, ECL is reset. When 1 is written to this bit, the counter reset is cleared and the ECL count-up function is enabled.

Bit 0		
CRCL	Description	
0	ECL is reset	(initial value)
1	ECL reset is cleared and count-up function is enabled	

2. Event Counter H (ECH)

Bit	7	6	5	4	3	2	1	0
	ECH7	ECH6	ECH5	ECH4	ECH3	ECH2	ECH1	ECH0
Initial Value	0	0	0	0	0	0	0	0
Read/Write	R	R	R	R	R	R	R	R

ECH is an 8-bit read-only up-counter that operates either as an independent 8-bit event counter or as the upper 8-bit up-counter of a 16-bit event counter configured in combination with ECL. Either the external asynchronous event AEVH pin or the overflow signal from lower 8-bit counter ECL can be selected as the input clock source by bit CH2. ECH can be cleared to H'00 by software, and is also initialized to H'00 upon reset.



3. Event Counter L (ECL)

ECL is an 8-bit read-only up-counter that operates either as an independent 8-bit event counter or as the lower 8-bit up-counter of a 16-bit event counter configured in combination with ECH. The event clock from the external asynchronous event AEVL pin is used as the input clock source. ECL can be cleared to H'00 by software, and is also initialized to H'00 upon reset.

Bit	7	6	5	4	3	2	1	0
	ECL7	ECL6	ECL5	ECL4	ECL3	ECL2	ECL1	ECL0
Initial Value	0	0	0	0	0	0	0	0
Read/Write	R	R	R	R	R	R	R	R

4. Clock Stop Register 2 (CKSTPR2)

Bit	7	6	5	4	3	2	1	0
	_		—	—	AECKSTP	WDCKSTP	PWCKSTP	LDCKSTP
Initial value	1	1	1	1	1	1	1	1
Read/Write	—	—	—	_	R/W	R/W	R/W	R/W

CKSTPR2 is an 8-bit read/write register that performs module standby mode control for peripheral modules. Only the bit relating to the asynchronous event counter is described here. For details of the other bits, see the sections on the relevant modules.

Bit 3: Asynchronous event counter module standby mode control (AECKSTP)

Bit 3 controls setting and clearing of module standby mode for the asynchronous event counter.

AECKSTP	Description	
0	Asynchronous event counter is set to module standby mode	
1	Asynchronous event counter module standby mode is cleared	(initial value)

9.7.3 Operation

1. 16-bit Event Counter Operation

When bit CH2 is cleared to 0 in ECCSR, ECH and ECL operate as a 16-bit event counter. Figure 9.20 shows an example of the software processing when ECH and ECL are used as a 16-bit event counter.



Figure 9.20 Example of Software Processing when Using ECH and ECL as 16-Bit Event Counter

As CH2 is cleared to 0 by a reset, ECH and ECL operate as a 16-bit event counter after a reset. They can also be used as a 16-bit event counter by carrying out the software processing shown in the example in figure 9.20. The operating clock source is asynchronous event input from the AEVL pin. When the next clock is input after the count value reaches H'FF in both ECH and ECL, ECH and ECL overflow from H'FFFF to H'0000, the OVH flag is set to 1 in ECCSR, the ECH and ECL count values each return to H'00, and counting up is restarted. When overflow occurs, the IRREC bit is set to 1 in IRR2. If the IENEC bit in IENR2 is 1 at this time, an interrupt request is sent to the CPU.

2. 8-bit Event Counter Operation

When bit CH2 is set to 1 in ECCSR, ECH and ECL operate as independent 8-bit event counters. Figure 9.21 shows an example of the software processing when ECH and ECL are used as 8-bit event counters.





Figure 9.21 Example of Software Processing when Using ECH and ECL as 8-Bit Event Counters

ECH and ECL can be used as 8-bit event counters by carrying out the software processing shown in the example in figure 9.20. The 8-bit event counter operating clock source is asynchronous event input from the AEVH pin for ECH, and asynchronous event input from the AEVL pin for ECL. When the next clock is input after the ECH count value reaches H'FF, ECH overflows, the OVH flag is set to 1 in ECCSR, the ECH count value returns to H'00, and counting up is restarted. Similarly, when the next clock is input after the ECL count value reaches H'FF, ECL overflows, the OVL flag is set to 1 in ECCSR, the ECL count value returns to H'00, and counting up is restarted. When overflow occurs, the IRREC bit is set to 1 in IRR2. If the IENEC bit in IENR2 is 1 at this time, an interrupt request is sent to the CPU.

9.7.4 Asynchronous Event Counter Operation Modes

Asynchronous event counter operation modes are shown in table 9.21.

Table 9.21	Asynchronous Event Counter Operation Modes
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Operation M	ode Reset	Active	Sleep	Watch	Sub- active	Sub- sleep	Standby	Module Standby
ECCSR	Reset	Functions	Functions	Held*	Functions	Functions	Held*	Held
ECH	Reset	Functions	Functions	Functions*	Functions	Functions	Functions*	Halted
ECL	Reset	Functions	Functions	Functions*	Functions	Functions	Functions*	Halted
Note: *	When an asynd	chronous e	external eve	ent is input	the count	er increme	ents but the	e counter

overflow H/L flags are not affected.

9.7.5 Application Notes

- 1. When reading the values in ECH and ECL, the correct value will not be returned if the event counter increments during the read operation. Therefore, if the counter is being used in the 8-bit mode, clear bits CUEH and CUEL in ECCSR to 0 before reading ECH or ECL. If the counter is being used in the 16-bit mode, clear CUEL only to 0 before reading ECH or ECL.
- 2. In the H8/3827R Group, if the internal power supply step-down circuit is not used, the maximum clock frequency to be input to the AEVH and AEVL pins is 16 MHz when Vcc = 4.5 to 5.5 V, 10 MHz when Vcc = 2.7 to 5.5 V, and 4 MHz when Vcc = 1.8 to 5.5 V. If the internal power step-down circuit is used, the maximum clock frequency to be input is 10 MHz when Vcc = 2.7 to 5.5 V, and 4 MHz when Vcc = 1.8 to 5.5 V. In the H8/3827S Group, the maximum clock frequency to be input is 10 MHz when Vcc = 1.8 to 3.6 V, and 4 MHz when Vcc = 2.7 to 3.6 V, and 4 MHz when Vcc = 1.8 to 3.6 V. In the H8/38327 Group and H8/38427 Group, the maximum clock frequency to be input is 16 MHz. In addition, ensure that the high and low widths of the clock are at least 32 ns. The duty cycle is immaterial.



Maximum AEVH/AEVL Pin Input Clock Frequency

Mode			Input Clock Frequency
16-bit mode			H8/3827R Group
8-bit mode	Active (high-speed), sleep (high-speed)		• Internal step-down circuit not used V_{CC} = 4.5 to 5.5 V/16 MHz V_{CC} = 2.7 to 5.5 V/10 MHz V_{CC} = 1.8 to 5.5 V/4 MHz • Internal step-down circuit used V_{CC} = 2.7 to 5.5 V/10 MHz V_{CC} = 1.8 to 5.5 V/4 MHz
			H8/3827S Group V _{CC} = 2.7 to 3.6 V/10 MHz V _{CC} = 1.8 to 3.6 V/4 MHz
			H8/38327 Group V _{CC} = 2.7 to 5.5 V/16 MHz
			H8/38427 Group V _{CC} = 4.5 to 5.5 V/16 MHz V _{CC} = 2.7 to 5.5 V/10 MHz
8-bit mode	Active (medium-speed), sleep (medium-speed)	(¢/16)	$2 \cdot f_{OSC}$
		(¢/32)	fosc
		(¢/64)	1/2 · fosc
	f _{OSC} = 1 MHz to 16 MHz	(¢/128)	$1/4 \cdot f_{OSC}$
8-bit mode	Watch, subactive, subsleep, standby	(¢w/2)	1000 kHz
		(¢w/4)	500 kHz
	φ _W = 32.768 kHz or 38.4 kHz	(¢w/8)	250 kHz

Mode

3. When AEC uses with 16-bit mode, set CUEH in ECCSR to "1" first, set CRCH in ECCSR to "1" second, or set both CUEH and CRCH to "1" at same time before clock entry. While AEC is operating on 16-bit mode, do not change CUEH. Otherwise, ECH will be miscounted up. Also, to reset the counter, clear CRCH and CRCL to 0 simultaneously or clear CRCL and CRCH to 0 sequentially, in that order.



Section 10 Serial Communication Interface

10.1 Overview

This LSI is provided with two serial communication interfaces, SCI3-1 and SCI3-2. These two SCIs have identical functions. In this manual, the generic term SCI3 is used to refer to both SCIs.

Serial communication interface 3 (SCI3) can carry out serial data communication in either asynchronous or synchronous mode. It is also provided with a multiprocessor communication function that enables serial data to be transferred among processors.

10.1.1 Features

Features of SCI3 are listed below.

- Choice of asynchronous or synchronous mode for serial data communication
 - Asynchronous mode

Serial data communication is performed asynchronously, with synchronization provided character by character. In this mode, serial data can be exchanged with standard asynchronous communication LSIs such as a Universal Asynchronous Receiver/Transmitter (UART) or Asynchronous Communication Interface Adapter (ACIA). A multiprocessor communication function is also provided, enabling serial data communication among processors.

There is a choice of 16 data transfer formats.

Data length	7, 8, 5 bits
Stop bit length	1 or 2 bits
Parity	Even, odd, or none
Multiprocessor bit	"1" or "0"
Receive error detection	Parity, overrun, and framing errors
Break detection	Break detected by reading the RXD_{3x} pin level directly when a framing error occurs

- Synchronous mode

Serial data communication is synchronized with a clock. In his mode, serial data can be exchanged with another LSI that has a synchronous communication function.

Data length	8 bits
Receive error detection	Overrun errors

• Full-duplex communication

Separate transmission and reception units are provided, enabling transmission and reception to be carried out simultaneously. The transmission and reception units are both double-buffered, allowing continuous transmission and reception.

- On-chip baud rate generator, allowing any desired bit rate to be selected
- Choice of an internal or external clock as the transmit/receive clock source
- Six interrupt sources: transmit end, transmit data empty, receive data full, overrun error, framing error, and parity error



10.1.2 Block Diagram

Figure 10.1 shows a block diagram of SCI3.





10.1.3 Pin Configuration

Table 10.1 shows the SCI3 pin configuration.

Table 10.1Pin Configuration

Name	Abbr.	I/O	Function
SCI3 clock	SCK _{3x}	I/O	SCI3 clock input/output
SCI3 receive data input	RXD _{3x}	Input	SCI3 receive data input
SCI3 transmit data output	TXD _{3x}	Output	SCI3 transmit data output

10.1.4 Register Configuration

Table 10.2 shows the SCI3 register configuration.

Table 10.2 Registers

Name	Abbr.	R/W	Initial Value	Address
Serial mode register	SMR	R/W	H'00	H'FFA8/FF98
Bit rate register	BRR	R/W	H'FF	H'FFA9/FF99
Serial control register 3	SCR3	R/W	H'00	H'FFAA/FF9A
Transmit data register	TDR	R/W	H'FF	H'FFAB/FF9B
Serial data register	SSR	R/W	H'84	H'FFAC/FF9C
Receive data register	RDR	R	H'00	H'FFAD/FF9D
Transmit shift register	TSR	Protected	—	—
Receive shift register	RSR	Protected	—	_
Bit rate counter	BRC	Protected	_	_
Clock stop register 1	CKSTPR1	R/W	H'FF	H'FFFA
Serial port control register	SPCR	R/W	H'C0	H'FF91



10.2 Register Descriptions

10.2.1 Receive Shift Register (RSR)

Bit	7	6	5	4	3	2	1	0
Read/Write	_	_	_	_	_	_	_	

RSR is a register used to receive serial data. Serial data input to RSR from the RXD_{3x} pin is set in the order in which it is received, starting from the LSB (bit 0), and converted to parallel data. When one byte of data is received, it is transferred to RDR automatically.

RSR cannot be read or written directly by the CPU.

10.2.2 Receive Data Register (RDR)

Bit	7	6	5	4	3	2	1	0
	RDR7	RDR6	RDR5	RDR4	RDR3	RDR2	RDR1	RDR0
Initial value	0	0	0	0	0	0	0	0
Read/Write	R	R	R	R	R	R	R	R

RDR is an 8-bit register that stores received serial data.

When reception of one byte of data is finished, the received data is transferred from RSR to RDR, and the receive operation is completed. RSR is then able to receive data. RSR and RDR are double-buffered, allowing consecutive receive operations.

RDR is a read-only register, and cannot be written by the CPU.

RDR is initialized to H'00 upon reset, and in standby, module standby or watch mode.

10.2.3 Transmit Shift Register (TSR)



TSR is a register used to transmit serial data. Transmit data is first transferred from TDR to TSR, and serial data transmission is carried out by sending the data to the TXD_{3x} pin in order, starting from the LSB (bit 0). When one byte of data is transmitted, the next byte of transmit data is transferred to TDR, and transmission started, automatically. Data transfer from TDR to TSR is not performed if no data has been written to TDR (if bit TDRE is set to 1 in the serial status register (SSR)).

TSR cannot be read or written directly by the CPU.

10.2.4 Transmit Data Register (TDR)

Bit	7	6	5	4	3	2	1	0
	TDR7	TDR6	TDR5	TDR4	TDR3	TDR2	TDR1	TDR0
Initial value	1	1	1	1	1	1	1	1
Read/Write	R/W							

TDR is an 8-bit register that stores transmit data. When TSR is found to be empty, the transmit data written in TDR is transferred to TSR, and serial data transmission is started. Continuous transmission is possible by writing the next transmit data to TDR during TSR serial data transmission.

TDR can be read or written by the CPU at any time.

TDR is initialized to H'FF upon reset, and in standby, module standby, or watch mode.



10.2.5	Serial Mode Register	(SMR)
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Bit	7	6	5	4	3	2	1	0
	СОМ	CHR	PE	PM	STOP	MP	CKS1	CKS0
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

SMR is an 8-bit register used to set the serial data transfer format and to select the clock source for the baud rate generator.

SMR can be read or written by the CPU at any time.

SMR is initialized to H'00 upon reset, and in standby, module standby, or watch mode.

Bit 7: Communication mode (COM)

Bit 7 selects whether SCI3 operates in asynchronous mode or synchronous mode.

Bit 7 COM	Description	
COW	Description	
0	Asynchronous mode	(initial value)
1	Synchronous mode	

Bit 6: Character length (CHR)

Bit 6 selects either 7 or 8 bits as the data length to be used in asynchronous mode. In synchronous mode the data length is always 8 bits, irrespective of the bit 6 setting.

Bit 6 CHR	Description	
0	8-bit data/5-bit data ^{*2} (initial v	alue)
1	7-bit data ^{*1} /5-bit data ^{*2}	
Notes:	: 1. When 7-bit data is selected, the MSB (bit 7) of TDR is not transmitted.	
	2. When 5 bit data is selected, set both DE and MD to 1. The three most significant k	aita

2. When 5-bit data is selected, set both PE and MP to 1. The three most significant bits (bits 7, 6, and 5) of TDR are not transmitted.

Bit 5: Parity enable (PE)

Bit 5 selects whether a parity bit is to be added during transmission and checked during reception in asynchronous mode. In synchronous mode parity bit addition and checking is not performed, irrespective of the bit 5 setting.

Bit 5		
PE	Description	
0	Parity bit addition and checking disabled ^{*2} (initial value)
1	Parity bit addition and checking enabled ^{*1*2}	
Notes: 1.	 When PE is set to 1, even or odd parity, as designated by bit PM, is added data before it is sent, and the received parity bit is checked against the pari designated by bit PM. 	
2.	2. For the case where 5-bit data is selected, see table 10.11.	

Bit 4: Parity mode (PM)

Bit 4 selects whether even or odd parity is to be used for parity addition and checking. The PM bit setting is only valid in asynchronous mode when bit PE is set to 1, enabling parity bit addition and checking. The PM bit setting is invalid in synchronous mode, and in asynchronous mode if parity bit addition and checking is disabled.

Bit 4		
РМ	Description	
0	Even parity ^{*1} (init	ial value)
1	Odd parity ^{*2}	
Notes: 7	 When even parity is selected, a parity bit is added in transmission so that the to number of 1 bits in the transmit data plus the parity bit is an even number; in re a check is carried out to confirm that the number of 1 bits in the receive data pl parity bit is an even number. 	eception,
2	2. When odd parity is selected, a parity bit is added in transmission so that the to	tal

2. When odd parity is selected, a parity bit is added in transmission so that the total number of 1 bits in the transmit data plus the parity bit is an odd number; in reception, a check is carried out to confirm that the number of 1 bits in the receive data plus the parity bit is an odd number.



Bit 3: Stop bit length (STOP)

Bit 3 selects 1 bit or 2 bits as the stop bit length is asynchronous mode. The STOP bit setting is only valid in asynchronous mode. When synchronous mode is selected the STOP bit setting is invalid since stop bits are not added.

Bit 3 STOP	Description				
0	1 stop bit ^{*1}	(initial value)			
1	2 stop bits ^{*2}				
Notes: 1. In transmission, a single 1 bit (stop bit) is added at the end of a transmit character.					

2. In transmission, two 1 bits (stop bits) are added at the end of a transmit character.

In reception, only the first of the received stop bits is checked, irrespective of the STOP bit setting. If the second stop bit is 1 it is treated as a stop bit, but if 0, it is treated as the start bit of the next transmit character.

Bit 2: Multiprocessor mode (MP)

Bit 2 enables or disables the multiprocessor communication function. When the multiprocessor communication function is disabled, the parity settings in the PE and PM bits are invalid. The MP bit setting is only valid in asynchronous mode. When synchronous mode is selected the MP bit should be set to 0. For details on the multiprocessor communication function, see section 10.3.4, Multiprocessor Communication Function.

Bit 2 MP		Description	
0		Multiprocessor communication function disabled*	(initial value)
1		Multiprocessor communication function enabled*	
Note:	*	For the case where 5-bit data is selected, see table 10.11.	

Bits 1 and 0: Clock select 1, 0 (CKS1, CKS0)

Bits 1 and 0 choose $\phi/64$, $\phi/16$, $\phi w/2$, or ϕ as the clock source for the baud rate generator.

For the relation between the clock source, bit rate register setting, and baud rate, see section 10.2.8, Bit rate register (BRR).

Bit 1	Bit 0					
CKS1	CKS0	Description				
0	0	φ clock	(initial value)			
0	1	ϕ w/2 clock ^{*1} / ϕ w clock ^{*2}				
1	0	φ/16 clock				
1	1	¢/64 clock				
Natas, 1	±/O ala	alt in active (madium analogical bigh analog) made and alage made				

Notes: 1. ϕ w/2 clock in active (medium-speed/high-speed) mode and sleep mode

φ w clock in subactive mode and subsleep mode
 In subactive or subsleep mode, SCI3 can be operated when CPU clock is φw/2 only.

10.2.6 Serial Control Register 3 (SCR3)

Bit	7	6	5	4	3	2	1	0
	TIE	RIE	TE	RE	MPIE	TEIE	CKE1	CKE0
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

SCR3 is an 8-bit register for selecting transmit or receive operation, the asynchronous mode clock output, interrupt request enabling or disabling, and the transmit/receive clock source.

SCR3 can be read or written by the CPU at any time.

SCR3 is initialized to H'00 upon reset, and in standby, module standby or watch mode.

Bit 7: Transmit interrupt enable (TIE)

Bit 7 selects enabling or disabling of the transmit data empty interrupt request (TXI) when transmit data is transferred from the transmit data register (TDR) to the transmit shift register (TSR), and bit TDRE in the serial status register (SSR) is set to 1.

TXI can be released by clearing bit TDRE or bit TIE to 0.
Bit 7 TIE	Description	
0	Transmit data empty interrupt request (TXI) disabled	(initial value)
1	Transmit data empty interrupt request (TXI) enabled	

Bit 6: Receive interrupt enable (RIE)

Bit 6 selects enabling or disabling of the receive data full interrupt request (RXI) and the receive error interrupt request (ERI) when receive data is transferred from the receive shift register (RSR) to the receive data register (RDR), and bit RDRF in the serial status register (SSR) is set to 1. There are three kinds of receive error: overrun, framing, and parity.

RXI can be released by clearing bit RDRF or the FER, PER, or OER error flag to 0, or by clearing bit RIE to 0.

Bit 6 RIE	Description	
0	Receive data full interrupt request (RXI) and receive error interrupt request (ERI) disabled	(initial value)
1	Receive data full interrupt request (RXI) and receive error interrupt request (ERI) enabled	

Bit 5: Transmit enable (TE)

Bit 5 selects enabling or disabling of the start of transmit operation.

Bit 5

TE	Description	
0	Transmit operation disabled ^{*1} (TXD pin is I/O port)	(initial value)
1	Transmit operation enabled ^{*2} (TXD pin is transmit data pin)	

Notes: 1. Bit TDRE in SSR is fixed at 1.

 When transmit data is written to TDR in this state, bit TDR in SSR is cleared to 0 and serial data transmission is started. Be sure to carry out serial mode register (SMR) settings, and setting of bit SPC31 or SPC32 in SPCR, to decide the transmission format before setting bit TE to 1.

Bit 4: Receive enable (RE)

Bit 4 selects enabling or disabling of the start of receive operation.

Bit 4	
RE	Description
0	Receive operation disabled ^{*1} (RXD pin is I/O port) (initial value)
1	Receive operation enabled ^{*2} (RXD pin is receive data pin)
Notes:	Note that the RDRF, FER, PER, and OER flags in SSR are not affected when bit RE is cleared to 0, and retain their previous state.
	In this state, serial data reception is started when a start bit is detected in asynchronous mode or serial clock input is detected in synchronous mode. Be sure to carry out serial mode register (SMR) settings to decide the reception format before setting bit RE to 1.

Bit 3: Multiprocessor interrupt enable (MPIE)

Bit 3 selects enabling or disabling of the multiprocessor interrupt request. The MPIE bit setting is only valid when asynchronous mode is selected and reception is carried out with bit MP in SMR set to 1. The MPIE bit setting is invalid when bit COM is set to 1 or bit MP is cleared to 0.

Bit 3 MPIE		Description			
0	Multiprocessor interrupt request disabled (normal receive operation) (initial value) Clearing condition: When data is received in which the multiprocessor bit is set to 1				
1		Multiprocessor interrupt request enabled*			
Note:	*	Receive data transfer from RSR to RDR, receive error detection, and setting of the RDRF, FER, and OER status flags in SSR is not performed. RXI, ERI, and setting of the RDRF, FER, and OER flags in SSR, are disabled until data with the multiprocessor bit set to 1 is received. When a receive character with the multiprocessor bit set to 1 is received, bit MPBR in SSR is set to 1, bit MPIE is automatically cleared to 0, and RXI and ERI requests (when bits TIE and RIE in serial control register 3 (SCR3) are set to 1) and setting of the RDRF, FER, and OER flags are enabled.			



Bit 2: Transmit end interrupt enable (TEIE)

Bit 2 selects enabling or disabling of the transmit end interrupt request (TEI) if there is no valid transmit data in TDR when MSB data is to be sent.

Bit 2 TEIE		Description	
0		Transmit end interrupt request (TEI) disabled	(initial value)
1		Transmit end interrupt request (TEI) enabled*	
Note:	*	TEI can be released by clearing bit TDRE to 0 and clearing bit T clearing bit TEIE to 0.	TEND to 0 in SSR, or by

Bits 1 and 0: Clock enable 1 and 0 (CKE1, CKE0)

Bits 1 and 0 select the clock source and enabling or disabling of clock output from the SCK_{3x} pin. The combination of CKE1 and CKE0 determines whether the SCK_{3x} pin functions as an I/O port, a clock output pin, or a clock input pin.

The CKE0 bit setting is only valid in case of internal clock operation (CKE1 = 0) in asynchronous mode. In synchronous mode, or when external clock operation is used (CKE1 = 1), bit CKE0 should be cleared to 0.

After setting bits CKE1 and CKE0, set the operating mode in the serial mode register (SMR).

For details on clock source selection, see table 10.9 in 10.3.1, Overview.

Bit 1	Bit 0	Description				
CKE1	CKE0	Communication Mode	Clock Source	SCK _{3x} Pin Function		
0	0	Asynchronous	Internal clock	I/O port ^{*1}		
		Synchronous	Internal clock	Serial clock output*1		
0	1	Asynchronous	Internal clock	Clock output*2		
		Synchronous	Reserved			
1	0	Asynchronous	External clock	Clock input ^{*3}		
		Synchronous	External clock	Serial clock input		
1	1	Asynchronous	Reserved			
		Synchronous	Reserved			

Notes: 1. Initial value

2. A clock with the same frequency as the bit rate is output.

3. Input a clock with a frequency 16 times the bit rate.

10.2.7 Serial Status Register (SSR)

Bit	7	6	5	4	3	2	1	0
	TDRE	RDRF	OER	FER	PER	TEND	MPBR	MPBT
Initial value	1	0	0	0	0	1	0	0
Read/Write	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R	R	R/W

Note: * Only a write of 0 for flag clearing is possible.

SSR is an 8-bit register containing status flags that indicate the operational status of SCI3, and multiprocessor bits.

SSR can be read or written by the CPU at any time, but only a write of 1 is possible to bits TDRE, RDRF, OER, PER, and FER. In order to clear these bits by writing 0, 1 must first be read.

Bits TEND and MPBR are read-only bits, and cannot be modified.

SSR is initialized to H'84 upon reset, and in standby, module standby, or watch mode.

Bit 7: Transmit data register empty (TDRE)

Bit 7 indicates that transmit data has been transferred from TDR to TSR.

Bit 7		
TDRE	Description	
0	Transmit data written in TDR has not been transferred to TSR	
	Clearing conditions:	
	After reading TDRE = 1, cleared by writing 0 to TDRE	
	When data is written to TDR by an instruction	
1	Transmit data has not been written to TDR, or transmit data written i transferred to TSR	n TDR has been
	Setting conditions:	
	When bit TE in SCR3 is cleared to 0	
	When data is transferred from TDR to TSR	(initial value)



Bit 6: Receive data register full (RDRF)

Bit 6 indicates that received data is stored in RDR.

Bit 6	
RDRF	Description
0	There is no receive data in RDR (initial value)
	Clearing conditions:
	After reading RDRF = 1, cleared by writing 0 to RDRF
	When RDR data is read by an instruction
1	There is receive data in RDR
	Setting condition:
	When reception ends normally and receive data is transferred from RSR to RDR
Note:	If an error is detected in the receive data, or if the RE bit in SCR3 has been cleared to 0, RDR and bit RDRF are not affected and retain their previous state. Note that if data reception is completed while bit RDRF is still set to 1, an overrun error

(OER) will result and the receive data will be lost.

Bit 5: Overrun error (OER)

Bit 5 indicates that an overrun error has occurred during reception.

Bit 5	
OER	Description
0	Reception in progress or completed ^{*1} (initial value)
	Clearing condition:
	After reading OER = 1, cleared by writing 0 to OER
1	An overrun error has occurred during reception *2
	Setting condition:
	When reception is completed with RDRF set to 1
Notes:	1. When bit RE in SCR3 is cleared to 0, bit OER is not affected and retains its previous

2. RDR retains the receive data it held before the overrun error occurred, and data

received after the error is lost. Reception cannot be continued with bit OER set to 1, and in synchronous mode, transmission cannot be continued either.

Bit 4: Framing error (FER)

Bit 4 indicates that a framing error has occurred during reception in asynchronous mode.

Bit 4			
FER		Description	
0		Reception in progress or completed ^{*1}	(initial value)
		Clearing condition:	
		After reading FER = 1, cleared by writing 0 to FER	
1		A framing error has occurred during reception	
		Setting condition:	
		When the stop bit at the end of the receive data is checked for a of reception, and the stop bit is 0^{*2}	value of 1 at the end
Notes:	1.	When bit RE in SCR3 is cleared to 0, bit FER is not affected and restate.	etains its previous
	2.	Note that, in 2-stop-bit mode, only the first stop bit is checked for a second stop bit is not checked. When a framing error occurs the re	

transferred to RDR but bit RDRF is not set. Reception cannot be continued with bit FER set to 1. In synchronous mode, neither transmission nor reception is possible when bit FER is set to 1.

Bit 3: Parity error (PER)

Bit 3 indicates that a parity error has occurred during reception with parity added in asynchronous mode.

Bit 3 PER	Description	
0	Reception in progress or completed*1	(initial value)
	Clearing condition:	
	After reading PER = 1, cleared by writing 0 to PER	
1	A parity error has occurred during reception*2	
	Setting condition:	
	When the number of 1 bits in the receive data plus parity bit does not parity designated by bit PM in the serial mode register (SMR)	match the
Notes: 1.	When bit RE in SCR3 is cleared to 0, bit PER is not affected and retains state.	its previous
2.	Receive data in which it a parity error has occurred is still transferred to RDRF is not set. Reception cannot be continued with bit PER set to 1. mode, neither transmission nor reception is possible when bit FER is set	In synchronous
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Bit 2: Transmit end (TEND)

Bit 2 indicates that bit TDRE is set to 1 when the last bit of a transmit character is sent.

Bit 2 is a read-only bit and cannot be modified.

Bit 2 TEND	Description	
0	Transmission in progress	
	Clearing conditions:	
	After reading TDRE = 1, cleared by writing 0 to TDRE	
	When data is written to TDR by an instruction	
1	Transmission ended (initial value	;)
	Setting conditions:	
	When bit TE in SCR3 is cleared to 0	
	When bit TDRE is set to 1 when the last bit of a transmit character is sent	

Bit 1: Multiprocessor bit receive (MPBR)

Bit 1 stores the multiprocessor bit in a receive character during multiprocessor format reception in asynchronous mode.

Bit 1 is a read-only bit and cannot be modified.

Bit 1 MPBR		Description	
0		Data in which the multiprocessor bit is 0 has been received st	(initial value)
1		Data in which the multiprocessor bit is 1 has been received	
Note:	*	When bit RE is cleared to 0 in SCR3 with the multiprocessor forma affected and retains its previous state.	at, bit MPBR is not

Bit 0: Multiprocessor bit transfer (MPBT)

Bit 0 stores the multiprocessor bit added to transmit data when transmitting in asynchronous mode. The bit MPBT setting is invalid when synchronous mode is selected, when the multiprocessor communication function is disabled, and when not transmitting.

Bit 0 MPBT	Description	
0	A 0 multiprocessor bit is transmitted	(initial value)
1	A 1 multiprocessor bit is transmitted	

10.2.8 Bit Rate Register (BRR)

Bit	7	6	5	4	3	2	1	0
	BRR7	BRR6	BRR5	BRR4	BRR3	BRR2	BRR1	BRR0
Initial value	1	1	1	1	1	1	1	1
Read/Write	R/W							

BRR is an 8-bit register that designates the transmit/receive bit rate in accordance with the baud rate generator operating clock selected by bits CKS1 and CKS0 of the serial mode register (SMR).

BRR can be read or written by the CPU at any time.

BRR is initialized to H'FF upon reset, and in standby, module standby, or watch mode.

Table 10.3 shows examples of BRR settings in asynchronous mode. The values shown are for active (high-speed) mode.



		OSC													
	32.8 kHz		38.4 kHz		2 MHz		2.4576 MHz			4 MHz					
Bit Rate (bit/s)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)	n	N	Error (%)
110	Ca	nnot be	e used,	_	_	_	_	_	_	2	21	-0.83	—	_	_
150		error ceeds 3	0/	0	3	0	2	12	0.16	3	3	0	2	25	0.16
200	- 670	ceus c	0 70	0	2	0	0	155	0.16	3	2	0	—	_	_
250	_			—	—	—	0	124	0	0	153	-0.26	0	249	0
300	_			0	1	0	0	103	0.16	3	1	0	2	12	0.16
600	_			0	0	0	0	51	0.16	3	0	0	0	103	0.16
1200	_			—	_	_	0	25	0.16	2	1	0	0	51	0.16
2400	_			—	—	—	0	12	0.16	2	0	0	0	25	0.16
4800	_			_	_	_	_	_	_	0	7	0	0	12	0.16
9600	_			—	—	—	_	—	_	0	3	0	—	—	_
19200	_			_	_	_	_	_	_	0	1	0	_	_	_
31250	_			_	_	_	0	0	0	_	_	_	0	1	0
38400	_			_		—	—	—	—	0	0	0		—	_

 Table 10.3
 Examples of BRR Settings for Various Bit Rates (Asynchronous Mode) (1)

			OSC								
		10 MI	Ηz	16 MHz							
Bit Rate (bit/s)	n	N	Error (%)	n	N	Error (%)					
110	2	88	-0.25	2	141	0.03					
150	2	64	0.16	2	103	0.16					
200	2	48	-0.35	2	77	0.16					
250	2	38	0.16	2	62	-0.79					
300	_	_	_	2	51	0.16					
600	—	—	—	2	25	0.16					
1200	0	129	0.16	0	207	0.16					
2400	0	64	0.16	0	103	0.16					
4800	—	_	—	0	51	0.16					
9600	—	—	—	0	25	0.16					
19200	—	—	—	0	12	0.16					
31250	0	4	0	0	7	0					
38400	—	—	—		—	—					

Table 10.3 Examples of BRR Settings for Various Bit Rates (Asynchronous Mode) (2)

Notes: 1. The setting should be made so that the error is not more than 1%.

2. The value set in BRR is given by the following equation:

$$N = \frac{OSC}{(64 \times 2^{2n} \times B)} - 1$$

where B: Bit rate (bit/s)

- N: Baud rate generator BRR setting $(0 \le N \le 255)$
- OSC: Value of ϕ_{OSC} (Hz)
- n: Baud rate generator input clock number (n = 0, 2, or 3)(The relation between n and the clock is shown in table 10.4.)
- 3. The error in table 10.3 is the value obtained from the following equation, rounded to two decimal places.

 $\text{Error (\%)} = \frac{\text{B (rate obtained from n, N, OSC)} - \text{R(bit rate in left-hand column in table 10.3.)}}{\text{R (bit rate in left-hand column in table 10.3.)}} \times 100$

		SMR Setting						
n	Clock	CKS1	CKS0					
0	φ	0	0					
0	$\phi_w/2^{*1}/\phi_w^{*2}$	0	1					
2	ф/16	1	0					
3	φ/64	1	1					

Table 10.4 Relation between n and Clock

Notes: 1. ϕ w/2 clock in active (medium-speed/high-speed) mode and sleep mode

φ w clock in subactive mode and subsleep mode
 In subactive or subsleep mode, SCI3 can be operated when CPU clock is φw/2 only.

Table 10.5 shows the maximum bit rate for each frequency. The values shown are for active (high-speed) mode.

		Setting	
Maximum Bit Rate (bit/s)	n	Ν	
600	0	0	
31250	0	0	
38400	0	0	
62500	0	0	
156250	0	0	
250000	0	0	
	600 31250 38400 62500 156250	600 0 31250 0 38400 0 62500 0 156250 0	Maximum Bit Rate (bit/s) n N 600 0 0 31250 0 0 38400 0 0 62500 0 0 156250 0 0

*: When SMR is set up to CKS1 = "0", CKS0 = "1".

Table 10.6 shows examples of BRR settings in synchronous mode. The values shown are for active (high-speed) mode.

							OS	C							
38.4 kHz				2 MHz			4 MHz			10 MHz			16 MHz		
n	Ν	Error	n	Ν	Error	n	Ν	Error	n	Ν	Error	n	Ν	Error	
0	23	0	_			_			_			_	_		
_	_	_	_	_	_	2	124	0	_	_	_	3	124	0	
2	0	0	_	_	_	_	_		_	_	_	_	_	_	
			_	_	_	_	_		_	_	_	2	249	0	
			0	249	0	_	_		_	_	_	2	124	0	
			0	99	0	0	199	0	—	_	—	2	49	0	
			0	49	0	0	99	0	0	249	0	2	24	0	
			0	24	0	0	49	0	0	124	0	0	199	0	
			0	9	0	0	19	0	0	49	0	0	79	0	
			0	4	0	0	9	0	0	24	0	0	39	0	
			_	_	—	0	4	0	_	_	_	0	19	0	
			0	0	0	0	1	0	0	4	0	0	7	0	
						0	0	0	_		_	0	3	0	
									_			0	1	0	
	n 0	n N 0 23	n N Error 0 23 0	N Error 0 23 0 2 0 0 2 0 0 2 0 0 0 2 0 0 0 0 4 0 0 0 4 0	N Error N 0 23 0 2 0 0 2 0 0 2 0 0 2 0 0 2 0 0 2 0 0 4 0 99 4 0 249 5 0 99 6 0 9 6 0 4 6 0 4	n N Error N Error 0 23 0 2 0 0 2 0 0 2 0 0 2 0 0 2 0 0 2 0 0 2 0 0 0 99 0 10 24 0 0 9 0 11 0 9 0 11 0 1 0	n N Error N Error $-$ 0 23 0 - - - - - - - 2 2 0 0 - - - 2 2 0 0 - - - - 2 0 0 - - - - - 2 0 0 -	2 $M HZ$ 2 $M HZ$ 4 $M HZ$ n N Error n N Error n N 0 23 0 </td <td>n N Error N Error N Error 0 23 0 23 0 2 124 0 2 0 0 2 124 0 2 0 0 2 0 0 2 0 0 -</td> <td>$38.4 \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$</td> <td>38.4 kHz 2 MHz 4 MHz 10 M n N Error n N Error n N Error n N Error n N M N N 0 23 0 </td> <td>$38.4 \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$</td> <td>$38.4 \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$</td> <td>$38.4 \ \text{kHz}$ $2 \ \text{MHz}$ $4 \ \text{MHz}$ $10 \ \text{Mz}$ $7 \ \text{m}$ 7 \ \text{m} $7 \ \text{m}$ <</td>	n N Error N Error N Error 0 23 0 23 0 2 124 0 2 0 0 2 124 0 2 0 0 2 0 0 2 0 0 -	$38.4 \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$	38.4 kHz 2 MHz 4 MHz 10 M n N Error n N Error n N Error n N Error n N M N N 0 23 0	$38.4 \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$	$38.4 \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$	$38.4 \ \text{kHz}$ $2 \ \text{MHz}$ $4 \ \text{MHz}$ $10 \ \text{Mz}$ $7 \ \text{m}$ 7 \ \text{m} $7 \ \text{m}$ <	

Table 10.6	Examples of BRR	Settings for	Various Bit Rates	(Synchronous Mode)
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Blank: Cannot be set.

-: A setting can be made, but an error will result.

Notes: The value set in BRR is given by the following equation:

$$N = \frac{OSC}{(8 \times 2^{2n} \times B)} - 1$$

where B: Bit rate (bit/s)

- N: Baud rate generator BRR setting $(0 \le N \le 255)$
- OSC: Value of ϕ_{OSC} (Hz)
- n: Baud rate generator input clock number (n = 0, 2, or 3)(The relation between n and the clock is shown in table 10.7.)

		SMR Setting			
n	Clock	CKS1	CKS0		
0	φ	0	0		
0	$\phi_w/2^{*1}/\phi_w^{*2}$	0	1		
2	φ/16	1	0		
3	φ/64	1	1		

Table 10.7 Relation between n and Clock

Notes: 1. ϕ w/2 clock in active (medium-speed/high-speed) mode and sleep mode

φw clock in subactive mode and subsleep mode
 In subactive or subsleep mode, SCI3 can be operated when CPU clock is φw/2 only.

10.2.9 Clock Stop Register 1 (CKSTPR1)

Bit	7	6	5	4	3	2	1	0
	—	S31CKSTP	S32CKSTP	ADCKSTP	TGCKSTP	TFCKSTP	TCCKSTP	TACKSTP
Initial value	1	1	1	1	1	1	1	1
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

CKSTPR1 is an 8-bit read/write register that performs module standby mode control for peripheral modules. Only the bits relating to SCI3 are described here. For details of the other bits, see the sections on the relevant modules.

Bit 6: SCI3-1 module standby mode control (S31CKSTP)

Bit 6 controls setting and clearing of module standby mode for SCI31.

S31CI	STP Description	
0	SCI3-1 is set to module standby mode	
1	SCI3-1 module standby mode is cleared	(initial value)
Note:	All SCI31 register is initialized in module standby mode.	

Bit 5: SCI3-2 module standby mode control (S32CKSTP)

Bit 5 controls setting and clearing of module standby mode for SCI32.

S32CK	STP Description	
0	SCI3-2 is set to module standby mode	
1	SCI3-2 module standby mode is cleared	(initial value)
Mater		

Note: All SCI32 register is initialized in module standby mode.

10.2.10 Serial Port Control Register (SPCR)

Bit	7	6	5	4	3	2	1	0
	_	_	SPC32	SPC31	SCINV3	SCINV2	SCINV1	SCINV0
Initial value	1	1	0	0	0	0	0	0
Read/Write	—	—	R/W	R/W	R/W	R/W	R/W	R/W

SPCR is an 8-bit readable/writable register that performs RXD₃₁, RXD₃₂, TXD₃₁, and TXD₃₂ pin input/output data inversion switching. SPCR is initialized to H'C0 by a reset.

Bits 7 to 6: Reserved bits

Bits 7 to 6 are reserved; they are always read as 1 and cannot be modified.

Bit 5: P4₂/TXD₃₂ pin function switch (SPC32)

This bit selects whether pin $P4_2/TXD_{32}$ is used as $P4_2$ or as TXD_{32} .

Bit 5 SPC32	Description	
0	Functions as P4 ₂ I/O pin	(initial value)
1	Functions as TXD ₃₂ output pin [*]	
Note: *	Set the TE bit in SCR3 after setting this bit to 1.	

Bit 4: P3₅/TXD₃₁ pin function switch (SPC31)

This bit selects whether pin $P3_5/TXD_{31}$ is used as $P3_5$ or as TXD_{31} .

Bit 4 SPC31	Description	
0	Functions as $P3_5$ I/O pin	(initial value)
1	Functions as TXD ₃₁ output pin*	
Note: *	Set the TE bit in SCR3 after setting this bit to 1.	

Bit 3: TXD₃₂ pin output data inversion switch

Bit 3 specifies whether or not TXD₃₂ pin output data is to be inverted.

Bit 3		
SCINV3	Description	
0	TXD ₃₂ output data is not inverted	(initial value)
1	TXD ₃₂ output data is inverted	

Bit 2: RXD₃₂ pin input data inversion switch

Bit 2 specifies whether or not RXD₃₂ pin input data is to be inverted.

Bit 2 SCINV2	Description	
0	RXD ₃₂ input data is not inverted	(initial value)
1	RXD ₃₂ input data is inverted	

Bit 1: TXD₃₁ pin output data inversion switch

Bit 1 specifies whether or not TXD₃₁ pin output data is to be inverted.

Bit 1 SCINV1	Description	
0	TXD ₃₁ output data is not inverted	(initial value)
1	TXD ₃₁ output data is inverted	

Bit 0: RXD₃₁ pin input data inversion switch

Bit 0 specifies whether or not RXD₃₁ pin input data is to be inverted.

Bit 0		
SCINV0	Description	
0	RXD ₃₁ input data is not inverted	(initial value)
1	RXD ₃₁ input data is inverted	

10.3 Operation

10.3.1 Overview

SCI3 can perform serial communication in two modes: asynchronous mode in which synchronization is provided character by character, and synchronous mode in which synchronization is provided by clock pulses. The serial mode register (SMR) is used to select asynchronous or synchronous mode and the data transfer format, as shown in table 10.8.

The clock source for SCI3 is determined by bit COM in SMR and bits CKE1 and CKE0 in SCR3, as shown in table 10.9.

1. Synchronous Mode

- Choice of 5-, 7-, or 8-bit data length
- Choice of parity addition, multiprocessor bit addition, and addition of 1 or 2 stop bits. (The combination of these parameters determines the data transfer format and the character length.)
- Framing error (FER), parity error (PER), overrun error (OER), and break detection during reception
- Choice of internal or external clock as the clock source

When internal clock is selected: SCI3 operates on the baud rate generator clock, and a clock with the same frequency as the bit rate can be output.

When external clock is selected: A clock with a frequency 16 times the bit rate must be input. (The on-chip baud rate generator is not used.)

2. Synchronous Mode

- Data transfer format: Fixed 8-bit data length
- Overrun error (OER) detection during reception
- Choice of internal or external clock as the clock source

When internal clock is selected: SCI3 operates on the baud rate generator clock, and a serial clock is output.

When external clock is selected: The on-chip baud rate generator is not used, and SCI3 operates on the input serial clock.



SMR						Data Transfer Format			
Bit 7 COM	Bit 6 CHR	Bit 2 MP	Bit 5 PE	Bit 3 STOP	Mode	Data Length	Multiprocessor Bit	Parity Bit	Stop Bit Length
0	0	0	0	0	Asynchronous	8-bit data	No	No	1 bit
				1	mode				2 bits
			1	0	-			Yes	1 bit
				1	-				2 bits
	1	-	0	0	-	7-bit data	-	No	1 bit
				1	-				2 bits
			1	0	-			Yes	1 bit
				1	-				2 bits
	0	1	0	0	-	8-bit data	Yes	No	1 bit
				1	-				2 bits
			1	0	-	5-bit data	No	-	1 bit
				1	-				2 bits
	1	-	0	0	-	7-bit data	Yes	-	1 bit
				1	-				2 bits
			1	0	-	5-bit data	No	Yes	1 bit
				1	-				2 bits
1	*	0	*	*	Synchronous mode	8-bit data	No	No	No

Table 10.8 SMR Settings and Corresponding Data Transfer Formats

*: Don't care

Table 10.9 SI	MR and SCR3 Settings and Clock Sourc	e Selection
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SMR	SCR3				
Bit 7	Bit 1	Bit 0	Transmit/Receive Clock		Transmit/Receive Clock
СОМ	CKE1	CKE0	Mode	Clock Source	SCK _{3x} Pin Function
0	0 0 0	0	Asynchronous mode	Internal	I/O port (SCK _{3x} pin not used)
1		1			Outputs clock with same frequency as bit rate
	1	0		External	Outputs clock with frequency 16 times bit rate
1	0 0 S	Synchronous	Internal	Outputs serial clock	
	1	0	mode	External	Inputs serial clock
0	1	1	Reserved (Do not specify these combinations)		
1	0	1	-		
1	1	1	-		



3. Interrupts and Continuous Transmission/Reception

SCI3 can carry out continuous reception using RXI and continuous transmission using TXI. These interrupts are shown in table 10.10.

Interrupt	Flags	Interrupt Request Conditions	Notes
RXI	RDRF RIE	When serial reception is performed normally and receive data is transferred from RSR to RDR, bit RDRF is set to 1, and if bit RIE is set to 1 at this time, RXI is enabled and an interrupt is requested. (See figure 10.2(a).)	The RXI interrupt routine reads the receive data transferred to RDR and clears bit RDRF to 0. Continuous reception can be performed by repeating the above operations until reception of the next RSR data is completed.
TXI	TDRE TIE	When TSR is found to be empty (on completion of the previous transmission) and the transmit data placed in TDR is transferred to TSR, bit TDRE is set to 1. If bit TIE is set to 1 at this time, TXI is enabled and an interrupt is requested. (See figure 10.2(b).)	The TXI interrupt routine writes the next transmit data to TDR and clears bit TDRE to 0. Continuous transmission can be performed by repeating the above operations until the data transferred to TSR has been transmitted.
TEI	TEND TEIE	When the last bit of the character in TSR is transmitted, if bit TDRE is set to 1, bit TEND is set to 1. If bit TEIE is set to 1 at this time, TEI is enabled and an interrupt is requested. (See figure 10.2(c).)	TEI indicates that the next transmit data has not been written to TDR when the last bit of the transmit character in TSR is sent.







Figure 10.2 (b) TDRE Setting and TXI Interrupt



Figure 10.2 (c) TEND Setting and TEI Interrupt

10.3.2 Operation in Asynchronous Mode

In asynchronous mode, serial communication is performed with synchronization provided character by character. A start bit indicating the start of communication and one or two stop bits indicating the end of communication are added to each character before it is sent.

SCI3 has separate transmission and reception units, allowing full-duplex communication. As the transmission and reception units are both double-buffered, data can be written during transmission and read during reception, making possible continuous transmission and reception.

1. Data Transfer Format

The general data transfer format in asynchronous communication is shown in figure 10.3.



Figure 10.3 Data Format in Asynchronous Communication

In asynchronous communication, the communication line is normally in the mark state (high level). SCI3 monitors the communication line and when it detects a space (low level), identifies this as a start bit and begins serial data communication.

One transfer data character consists of a start bit (low level), followed by transmit/receive data (LSB-first format, starting from the least significant bit), a parity bit (high or low level), and finally one or two stop bits (high level).

In asynchronous mode, synchronization is performed by the falling edge of the start bit during reception. The data is sampled on the 8th pulse of a clock with a frequency 16 times the bit period, so that the transfer data is latched at the center of each bit.

Table 10.11 shows the 16 data transfer formats that can be set in asynchronous mode. The format is selected by the settings in the serial mode register (SMR).

SMR			Serial Data Transfer Format and Frame Length		
CHR	PE	MP	STOP	1 2 3 4 5 6 7 8 9 10 11 12	
0	0	0	0	S 8-bit data STOP	
0	0	0	1	S 8-bit data STOP STOP	
0	0	1	0	S 8-bit data MPB STOP	
0	0	1	1	S 8-bit data MPB STOP STOP	
0	1	0	0	S 8-bit data P STOP	
0	1	0	1	S 8-bit data P STOP STOP	
0	1	1	0	S 5-bit data STOP	
0	1	1	1	S 5-bit data STOP STOP	
1	0	0	0	S 7-bit data STOP	
1	0	0	1	S 7-bit data STOP STOP	
1	0	1	0	S 7-bit data MPB STOP	
1	0	1	1	S 7-bit data MPB STOP STOP	
1	1	0	0	S 7-bit data P STOP	
1	1	0	1	S 7-bit data P STOP STOP	
1	1	1	0	S 5-bit data P STOP	
1	1	1	1	S 5-bit data P STOP STOP	

Table 10.11 Data Transfer Formats (Asynchronous Mode)

Legend:

S: Start bit

STOP: Stop bit

P: Parity bit

MPB: Multiprocessor bit

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2. Clock

Either an internal clock generated by the baud rate generator or an external clock input at the SCK_{3x} pin can be selected as the SCI3 transmit/receive clock. The selection is made by means of bit COM in SMR and bits SCE1 and CKE0 in SCR3. See table 10.9 for details on clock source selection.

When an external clock is input at the SCK_{3x} pin, the clock frequency should be 16 times the bit rate.

When SCI3 operates on an internal clock, the clock can be output at the SCK_{3x} pin. In this case the frequency of the output clock is the same as the bit rate, and the phase is such that the clock rises at the center of each bit of transmit/receive data, as shown in figure 10.4.



Figure 10.4 Phase Relationship between Output Clock and Transfer Data (Asynchronous Mode) (8-bit data, parity, 2 stop bits)

3. Data Transfer Operations

SCI3 initialization: Before data is transferred on SCI3, bits TE and RE in SCR3 must first be cleared to 0, and then SCI3 must be initialized as follows.

Note: If the operation mode or data transfer format is changed, bits TE and RE must first be cleared to 0.

When bit TE is cleared to 0, bit TDRE is set to 1.

Note that the RDRF, PER, FER, and OER flags and the contents of RDR are retained when RE is cleared to 0.

When an external clock is used in asynchronous mode, the clock should not be stopped during operation, including initialization. When an external clock is used in synchronous mode, the clock should not be supplied during operation, including initialization.

Figure 10.5 shows an example of a flowchart for initializing SCI3.



Figure 10.5 Example of SCI3 Initialization Flowchart

Transmitting: Figure 10.6 shows an example of a flowchart for data transmission. This procedure should be followed for data transmission after initializing SCI3.





SCI3 operates as follows when transmitting data.

SCI3 monitors bit TDRE in SSR, and when it is cleared to 0, recognizes that data has been written to TDR and transfers data from TDR to TSR. It then sets bit TDRE to 1 and starts transmitting. If bit TIE in SCR3 is set to 1 at this time, a TXI request is made.

Serial data is transmitted from the TXD3x pin using the relevant data transfer format in table 10.11. When the stop bit is sent, SCI3 checks bit TDRE. If bit TDRE is cleared to 0, SCI3 transfers data from TDR to TSR, and when the stop bit has been sent, starts transmission of the next frame. If bit TDRE is set to 1, bit TEND in SSR bit is set to 1 the mark state, in which 1s are transmitted, is established after the stop bit has been sent. If bit TEIE in SCR3 is set to 1 at this time, a TEI request is made.

Figure 10.12 shows an example of the operation when transmitting in asynchronous mode.



Figure 10.7 Example of Operation when Transmitting in Asynchronous Mode (8-bit data, parity, 1 stop bit)



Receiving: Figure 10.8 shows an example of a flowchart for data reception. This procedure should be followed for data reception after initializing SCI3.







Figure 10.8 Example of Data Reception Flowchart (Asynchronous Mode) (cont)



SCI3 operates as follows when receiving data.

SCI3 monitors the communication line, and when it detects a 0 start bit, performs internal synchronization and begins reception. Reception is carried out in accordance with the relevant data transfer format in table 10.11. The received data is first placed in RSR in LSB-to-MSB order, and then the parity bit and stop bit(s) are received. SCI3 then carries out the following checks.

• Parity check

SCI3 checks that the number of 1 bits in the receive data conforms to the parity (odd or even) set in bit PM in the serial mode register (SMR).

• Stop bit check

SCI3 checks that the stop bit is 1. If two stop bits are used, only the first is checked.

• Status check

SCI3 checks that bit RDRF is set to 0, indicating that the receive data can be transferred from RSR to RDR.

If no receive error is found in the above checks, bit RDRF is set to 1, and the receive data is stored in RDR. If bit RIE is set to 1 in SCR3, an RXI interrupt is requested. If the error checks identify a receive error, bit OER, PER, or FER is set to 1 depending on the kind of error. Bit RDRF retains its state prior to receiving the data. If bit RIE is set to 1 in SCR3, an ERI interrupt is requested.

Table 10.12 shows the conditions for detecting a receive error, and receive data processing.

Note: No further receive operations are possible while a receive error flag is set. Bits OER, FER, PER, and RDRF must therefore be cleared to 0 before resuming reception.

Receive Error	Abbr.	Detection Conditions	Receive Data Processing
Overrun error	OER	When the next date receive operation is completed while bit RDRF is still set to 1 in SSR	Receive data is not transferred from RSR to RDR
Framing error	FER	When the stop bit is 0	Receive data is transferred from RSR to RDR
Parity error	PER	When the parity (odd or even) set in SMR is different from that of the received data	Receive data is transferred from RSR to RDR

Table 10.12 Receive Error Detection Conditions and Receive Data Processing



Figure 10.9 shows an example of the operation when receiving in asynchronous mode.



10.3.3 Operation in Synchronous Mode

In synchronous mode, SCI3 transmits and receives data in synchronization with clock pulses. This mode is suitable for high-speed serial communication.

SCI3 has separate transmission and reception units, allowing full-duplex communication with a shared clock.

As the transmission and reception units are both double-buffered, data can be written during transmission and read during reception, making possible continuous transmission and reception.



1. Data Transfer Format



The general data transfer format in asynchronous communication is shown in figure 10.10.

Figure 10.10 Data Format in Synchronous Communication

In synchronous communication, data on the communication line is output from one falling edge of the serial clock until the next falling edge. Data confirmation is guaranteed at the rising edge of the serial clock.

One transfer data character begins with the LSB and ends with the MSB. After output of the MSB, the communication line retains the MSB state.

When receiving in synchronous mode, SCI3 latches receive data at the rising edge of the serial clock.

The data transfer format uses a fixed 8-bit data length.

Parity and multiprocessor bits cannot be added.

2. Clock

Either an internal clock generated by the baud rate generator or an external clock input at the SCK_{3x} pin can be selected as the SCI3 serial clock. The selection is made by means of bit COM in SMR and bits CKE1 and CKE0 in SCR3. See table 10.9 for details on clock source selection.

When SCI3 operates on an internal clock, the serial clock is output at the SCK_{3x} pin. Eight pulses of the serial clock are output in transmission or reception of one character, and when SCI3 is not transmitting or receiving, the clock is fixed at the high level.

3. Data Transfer Operations

SCI3 initialization: Data transfer on SCI3 first of all requires that SCI3 be initialized as described in 10.3.2.3. SCI3 initialization, and shown in figure 10.5.

Transmitting: Figure 10.11 shows an example of a flowchart for data transmission. This procedure should be followed for data transmission after initializing SCI3.





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SCI3 operates as follows when transmitting data.

SCI3 monitors bit TDRE in SSR, and when it is cleared to 0, recognizes that data has been written to TDR and transfers data from TDR to TSR. It then sets bit TDRE to 1 and starts transmitting. If bit TIE in SCR3 is set to 1 at this time, a TXI request is made.

When clock output mode is selected, SCI3 outputs 8 serial clock pulses. When an external clock is selected, data is output in synchronization with the input clock.

Serial data is transmitted from the TXD3x pin in order from the LSB (bit 0) to the MSB (bit 7). When the MSB (bit 7) is sent, checks bit TDRE. If bit TDRE is cleared to 0, SCI3 transfers data from TDR to TSR, and starts transmission of the next frame. If bit TDRE is set to 1, SCI3 sets bit TEND to 1 in SSR, and after sending the MSB (bit 7), retains the MSB state. If bit TEIE in SCR3 is set to 1 at this time, a TEI request is made.

After transmission ends, the SCK pin is fixed at the high level.

Note: Transmission is not possible if an error flag (OER, FER, or PER) that indicates the data reception status is set to 1. Check that these error flags are all cleared to 0 before a transmit operation.

Figure 10.12 shows an example of the operation when transmitting in synchronous mode.



Figure 10.12 Example of Operation when Transmitting in Synchronous Mode

Receiving: Figure 10.13 shows an example of a flowchart for data reception. This procedure should be followed for data reception after initializing SCI3.



Figure 10.13 Example of Data Reception Flowchart (Synchronous Mode)

SCI3 operates as follows when receiving data.

SCI3 performs internal synchronization and begins reception in synchronization with the serial clock input or output.

The received data is placed in RSR in LSB-to-MSB order.

After the data has been received, SCI3 checks that bit RDRF is set to 0, indicating that the receive data can be transferred from RSR to RDR.

If this check shows that there is no overrun error, bit RDRF is set to 1, and the receive data is stored in RDR. If bit RIE is set to 1 in SCR3, an RXI interrupt is requested. If the check identifies an overrun error, bit OER is set to 1.

Bit RDRF remains set to 1. If bit RIE is set to 1 in SCR3, an ERI interrupt is requested.

See table 10.12 for the conditions for detecting a receive error, and receive data processing.

Note: No further receive operations are possible while a receive error flag is set. Bits OER, FER, PER, and RDRF must therefore be cleared to 0 before resuming reception.

Figure 10.14 shows an example of the operation when receiving in synchronous mode.



Figure 10.14 Example of Operation when Receiving in Synchronous Mode

Simultaneous transmit/receive: Figure 10.15 shows an example of a flowchart for a simultaneous transmit/receive operation. This procedure should be followed for simultaneous transmission/reception after initializing SCI3.




- Notes: 1. When switching from transmission to simultaneous transmission/reception, check that SCI3 has finished transmitting and that bits TDRE and TEND are set to 1, clear bit TE to 0, and then set bits TE and RE to 1 simultaneously.
 - 2. When switching from reception to simultaneous transmission/reception, check that SCI3 has finished receiving, clear bit RE to 0, then check that bit RDRF and the error flags (OER, FER, and PER) are cleared to 0, and finally set bits TE and RE to 1 simultaneously.

10.3.4 Multiprocessor Communication Function

The multiprocessor communication function enables data to be exchanged among a number of processors on a shared communication line. Serial data communication is performed in asynchronous mode using the multiprocessor format (in which a multiprocessor bit is added to the transfer data).

In multiprocessor communication, each receiver is assigned its own ID code. The serial communication cycle consists of two cycles, an ID transmission cycle in which the receiver is specified, and a data transmission cycle in which the transfer data is sent to the specified receiver. These two cycles are differentiated by means of the multiprocessor bit, 1 indicating an ID transmission cycle, and 0, a data transmission cycle.

The sender first sends transfer data with a 1 multiprocessor bit added to the ID code of the receiver it wants to communicate with, and then sends transfer data with a 0 multiprocessor bit added to the transmit data. When a receiver receives transfer data with the multiprocessor bit set to 1, it compares the ID code with its own ID code, and if they are the same, receives the transfer data sent next. If the ID codes do not match, it skips the transfer data until data with the multiprocessor bit set to 1 is sent again.

In this way, a number of processors can exchange data among themselves.

Figure 10.16 shows an example of communication between processors using the multiprocessor format.



Figure 10.16 Example of Inter-Processor Communication Using Multiprocessor Format (Sending Data H'AA to Receiver A)

There is a choice of four data transfer formats. If a multiprocessor format is specified, the parity bit specification is invalid. See table 10.11 for details.

For details on the clock used in multiprocessor communication, see section 10.3.2, Operation in Asynchronous Mode.

Multiprocessor transmitting: Figure 10.17 shows an example of a flowchart for multiprocessor data transmission. This procedure should be followed for multiprocessor data transmission after initializing SCI3.





SCI3 operates as follows when transmitting data.

SCI3 monitors bit TDRE in SSR, and when it is cleared to 0, recognizes that data has been written to TDR and transfers data from TDR to TSR. It then sets bit TDRE to 1 and starts transmitting. If bit TIE in SCR3 is set to 1 at this time, a TXI request is made.

Serial data is transmitted from the TXD pin using the relevant data transfer format in table 10.11. When the stop bit is sent, SCI3 checks bit TDRE. If bit TDRE is cleared to 0, SCI3 transfers data from TDR to TSR, and when the stop bit has been sent, starts transmission of the next frame. If bit TDRE is set to 1 bit TEND in SSR bit is set to 1, the mark state, in which 1s are transmitted, is established after the stop bit has been sent. If bit TEIE in SCR3 is set to 1 at this time, a TEI request is made.

Figure 10.18 shows an example of the operation when transmitting using the multiprocessor format.



Figure 10.18 Example of Operation when Transmitting Using Multiprocessor Format (8-bit data, multiprocessor bit, 1 stop bit)

Multiprocessor receiving: Figure 10.19 shows an example of a flowchart for multiprocessor data reception. This procedure should be followed for multiprocessor data reception after initializing SCI3.





Figure 10.19 Example of Multiprocessor Data Reception Flowchart



Figure 10.19 Example of Multiprocessor Data Reception Flowchart (cont)

Figure 10.20 shows an example of the operation when receiving using the multiprocessor format.





Figure 10.20 Example of Operation when Receiving Using Multiprocessor Format (8-bit data, multiprocessor bit, 1 stop bit)

10.4 Interrupts

SCI3 can generate six kinds of interrupts: transmit end, transmit data empty, receive data full, and three receive error interrupts (overrun error, framing error, and parity error). These interrupts have the same vector address.

The various interrupt requests are shown in table 10.13.

Table 10.13 SCI3 Interrupt Requests

Interrupt Abbr.	Interrupt Request	Vector Address
RXI	Interrupt request initiated by receive data full flag (RDRF)	H'0022/H'0024
TXI	Interrupt request initiated by transmit data empty flag (TDRE)	_
TEI	Interrupt request initiated by transmit end flag (TEND)	_
ERI	Interrupt request initiated by receive error flag (OER, FER, PER)	_

Each interrupt request can be enabled or disabled by means of bits TIE and RIE in SCR3.

When bit TDRE is set to 1 in SSR, a TXI interrupt is requested. When bit TEND is set to 1 in SSR, a TEI interrupt is requested. These two interrupts are generated during transmission.

The initial value of bit TDRE in SSR is 1. Therefore, if the transmit data empty interrupt request (TXI) is enabled by setting bit TIE to 1 in SCR3 before transmit data is transferred to TDR, a TXI interrupt will be requested even if the transmit data is not ready.

Also, the initial value of bit TEND in SSR is 1. Therefore, if the transmit end interrupt request (TEI) is enabled by setting bit TEIE to 1 in SCR3 before transmit data is transferred to TDR, a TEI interrupt will be requested even if the transmit data has not been sent.

Effective use of these interrupt requests can be made by having processing that transfers transmit data to TDR carried out in the interrupt service routine.

To prevent the generation of these interrupt requests (TXI and TEI), on the other hand, the enable bits for these interrupt requests (bits TIE and TEIE) should be set to 1 after transmit data has been transferred to TDR.

When bit RDRF is set to 1 in SSR, an RXI interrupt is requested, and if any of bits OER, PER, and FER is set to 1, an ERI interrupt is requested. These two interrupt requests are generated during reception.

For further details, see section 3.3, Interrupts.

10.5 Application Notes

The following points should be noted when using SCI3.

1. Relation between Writes to TDR and Bit TDRE

Bit TDRE in the serial status register (SSR) is a status flag that indicates that data for serial transmission has not been prepared in TDR. When data is written to TDR, bit TDRE is cleared to 0 automatically. When SCI3 transfers data from TDR to TSR, bit TDRE is set to 1.

Data can be written to TDR irrespective of the state of bit TDRE, but if new data is written to TDR while bit TDRE is cleared to 0, the data previously stored in TDR will be lost of it has not yet been transferred to TSR. Accordingly, to ensure that serial transmission is performed dependably, you should first check that bit TDRE is set to 1, then write the transmit data to TDR once only (not two or more times).

2. Operation when a Number of Receive Errors Occur Simultaneously

If a number of receive errors are detected simultaneously, the status flags in SSR will be set to the states shown in table 10.14. If an overrun error is detected, data transfer from RSR to RDR will not be performed, and the receive data will be lost.

SS	SR Stat	us Flag	gs	Receive Data Transfer	
RDRF*	OER	FER	PER	$RSR \rightarrow RDR$	Receive Error Status
1	1	0	0	Х	Overrun error
0	0	1	0	0	Framing error
0	0	0	1	0	Parity error
1	1	1	0	Х	Overrun error + framing error
1	1	0	1	Х	Overrun error + parity error
0	0	1	1	0	Framing error + parity error
1	1	1	1	Х	Overrun error + framing error + parity error

Table 10.14 SSR Status Flag States and Receive Data Transfer

O : Receive data is transferred from RSR to RDR.

X : Receive data is not transferred from RSR to RDR.

Note: * Bit RDRF retains its state prior to data reception. However, note that if RDR is read after an overrun error has occurred in a frame because reading of the receive data in the previous frame was delayed, RDRF will be cleared to 0.

3. Break Detection and Processing

When a framing error is detected, a break can be detected by reading the value of the RXD_{3x} pin directly. In a break, the input from the RXD_{3x} pin becomes all 0s, with the result that bit FER is set and bit PER may also be set.

SCI3 continues the receive operation even after receiving a break. Note, therefore, that even though bit FER is cleared to 0 it will be set to 1 again.

4. Mark State and Break Detection

When bit TE is cleared to 0, the TXD_{3x} pin functions as an I/O port whose input/output direction and level are determined by PDR and PCR. This fact can be used to set the TXD_{3x} pin to the mark state, or to detect a break during transmission.

To keep the communication line in the mark state (1 state) until bit TE is set to 1, set PCR = 1 and PDR = 1. Since bit TE is cleared to 0 at this time, the TXD_{3x} pin functions as an I/O port and 1 is output.

To detect a break, clear bit TE to 0 after setting PCR = 1 and PDR = 0.

When bit TE is cleared to 0, the transmission unit is initialized regardless of the current transmission state, the TXD_{3x} pin functions as an I/O port, and 0 is output from the TXD_{3x} pin.

5. Receive Error Flags and Transmit Operation (Synchronous Mode Only)

When a receive error flag (OER, PER, or FER) is set to 1, transmission cannot be started even if bit TDRE is cleared to 0. The receive error flags must be cleared to 0 before starting transmission.

Note also that receive error flags cannot be cleared to 0 even if bit RE is cleared to 0.

6. Receive Data Sampling Timing and Receive Margin in Asynchronous Mode

In asynchronous mode, SCI3 operates on a basic clock with a frequency 16 times the transfer rate. When receiving, SCI3 performs internal synchronization by sampling the falling edge of the start bit with the basic clock. Receive data is latched internally at the 8th rising edge of the basic clock. This is illustrated in figure 10.21.





Figure 10.21 Receive Data Sampling Timing in Asynchronous Mode

Consequently, the receive margin in asynchronous mode can be expressed as shown in equation (1).

$$M = \{(0.5 - \frac{1}{2N}) - \frac{D - 0.5}{N} - (L - 0.5) F\} \times 100 [\%]$$
 Equation (1)

where M: Receive margin (%)

- N: Ratio of bit rate to clock (N = 16)
- D: Clock duty (D = 0.5 to 1.0)
- L: Frame length (L = 9 to 12)
- F: Absolute value of clock frequency deviation

Substituting 0 for F (absolute value of clock frequency deviation) and 0.5 for D (clock duty) in equation (1), a receive margin of 46.875% is given by equation (2).

When D = 0.5 and F = 0,

 $M = \{0.5 - \frac{1}{2 \times 16}\} \times 100 \,[\%]$ = 46.875% Equation (2)

However, this is only a computed value, and a margin of 20% to 30% should be allowed when carrying out system design.

7. Relation between RDR Reads and Bit RDRF

In a receive operation, SCI3 continually checks the RDRF flag. If bit RDRF is cleared to 0 when reception of one frame ends, normal data reception is completed. If bit RDRF is set to 1, this indicates that an overrun error has occurred.

When the contents of RDR are read, bit RDRF is cleared to 0 automatically. Therefore, if bit RDR is read more than once, the second and subsequent read operations will be performed while bit RDRF is cleared to 0. Note that, when an RDR read is performed while bit RDRF is cleared to 0, if the read operation coincides with completion of reception of a frame, the next frame of data may be read. This is illustrated in figure 10.22.



Figure 10.22 Relation between RDR Read Timing and Data

In this case, only a single RDR read operation (not two or more) should be performed after first checking that bit RDRF is set to 1. If two or more reads are performed, the data read the first time should be transferred to RAM, etc., and the RAM contents used. Also, ensure that there is sufficient margin in an RDR read operation before reception of the next frame is completed. To be precise in terms of timing, the RDR read should be completed before bit 7 is transferred in synchronous mode, or before the STOP bit is transferred in asynchronous mode.

8. Transmit and Receive Operations when Making a State Transition

Make sure that transmit and receive operations have completely finished before carrying out state transition processing.

9. Switching SCK_{3x} Function

If pin SCK_{3x} is used as a clock output pin by SCI3 in synchronous mode and is then switched to a general input/output pin (a pin with a different function), the pin outputs a low level signal for half a system clock (ϕ) cycle immediately after it is switched.

This can be prevented by either of the following methods according to the situation.

a. When an SCK_{3x} function is switched from clock output to non clock-output

When stopping data transfer, issue one instruction to clear bits TE and RE to 0 and to set bits CKE1 and CKE0 in SCR3 to 1 and 0, respectively. In this case, bit COM in SMR should be left 1. The above prevents SCK_{3x} from being used as a general input/output pin. To avoid an intermediate level of voltage from being applied to SCK_{3x} , the line connected to SCK_{3x} should be pulled up to the V_{CC} level via a resistor, or supplied with output from an external device.

- b. When an SCK_{3x} function is switched from clock output to general input/output When stopping data transfer,
 - (i) Issue one instruction to clear bits TE and RE to 0 and to set bits CKE1 and CKE0 in SCR3 to 1 and 0, respectively.
 - (ii) Clear bit COM in SMR to 0
 - (iii) Clear bits CKE1 and CKE0 in SCR3 to 0

Note that special care is also needed here to avoid an intermediate level of voltage from being applied to SCK_{3x} .

10. Setup at Subactive or Subsleep Mode

At subactive or subsleep mode, SCI3 becomes possible use only at CPU clock is $\phi w/2$.



Section 11 14-Bit PWM

11.1 Overview

This LSI is provided with a 14-bit PWM (pulse width modulator) on-chip, which can be used as a D/A converter by connecting a low-pass filter.

11.1.1 Features

Features of the 14-bit PWM are as follows.

• Choice of two conversion periods

Any of the following four conversion periods can be chosen:

- $131,072/\phi$, with a minimum modulation width of $8/\phi$ (PWCR1 = 1, PWCR0 = 1)
- $65,536/\phi$, with a minimum modulation width of $4/\phi$ (PWCR1 = 1, PWCR0 = 0)
- 32,768/ ϕ , with a minimum modulation width of 2/ ϕ (PWCR1 = 0, PWCR0 = 1)
- $16,384/\phi$, with a minimum modulation width of $1/\phi$ (PWCR1 = 0, PWCR0 = 0)
- Pulse division method for less ripple
- Use of module standby mode enables this module to be placed in standby mode independently when not used.

11.1.2 Block Diagram

Figure 11.1 shows a block diagram of the 14-bit PWM.



Figure 11.1 Block Diagram of the 14 Bit PWM

11.1.3 Pin Configuration

Table 11.1 shows the output pin assigned to the 14-bit PWM.

Table 11.1 Pin Configuration

Name	Abbr.	I/O	Function
PWM output pin	PWM	Output	Pulse-division PWM waveform output

11.1.4 Register Configuration

Table 11.2 shows the register configuration of the 14-bit PWM.

Table 11.2 Register Configuration

Name	Abbr.	R/W	Initial Value	Address
PWM control register	PWCR	W	H'FC	H'FFD0
PWM data register U	PWDRU	W	H'C0	H'FFD1
PWM data register L	PWDRL	W	H'00	H'FFD2
Clock stop register 2	CKSTPR2	R/W	H'FF	H'FFFB

11.2 Register Descriptions

11.2.1 PWM Control Register (PWCR)

Bit	7	6	5	4	3	2	1	0
	—	—	—	_	_	_	PWCR1	PWCR0
Initial value	1	1	1	1	1	1	0	0
Read/Write	_	_	_	_	_	_	W	W

PWCR is an 8-bit write-only register for input clock selection.

Upon reset, PWCR is initialized to H'FC.

Bits 7 to 2: Reserved bits

Bits 7 to 2 are reserved; they are always read as 1, and cannot be modified.

Bits 1 and 0: Clock select 1 and 0 (PWCR1, PWCR0)

Bits 1 and 0 select the clock supplied to the 14-bit PWM. These bits are write-only bits; they are always read as 1.

Bit 0 PWCR0	Description	
0	The input clock is $\phi/2$ (t $\phi^* = 2/\phi$) The conversion period is 16,384/ ϕ , with a minimum modulation width of 1/ ϕ	(initial value)
1	The input clock is $\phi/4$ (t $\phi^* = 4/\phi$) The conversion period is 32,768/ ϕ , with a minimum modulation width of 2/ ϕ	
0	The input clock is $\phi/8$ (t $\phi^* = 8/\phi$) The conversion period is 65,536/ ϕ , with a minimum modulation width of 4/ ϕ	
1	The input clock is $\phi/16$ (t ϕ^* = 16/ ϕ) The conversion period is 131,072/ ϕ , with a minimum modulation width of 8/ ϕ	
	PWCR0 0 1	PWCR0Description0The input clock is φ/2 (tφ* = 2/φ) The conversion period is 16,384/φ, with a minimum modulation width of 1/φ1The input clock is φ/4 (tφ* = 4/φ) The conversion period is 32,768/φ, with a minimum modulation width of 2/φ0The input clock is φ/8 (tφ* = 8/φ) The conversion period is 65,536/φ, with a minimum modulation width of 4/φ1The input clock is φ/16 (tφ* = 16/φ) The conversion period is 131,072/φ, with a minimum

Note: * Period of PWM input clock.

11.2.2 PWM Data Registers U and L (PWDRU, PWDRL)

PWDRU								
Bit	7	6	5	4	3	2	1	0
	_	_	PWDRU5	PWDRU4	PWDRU3	PWDRU2	PWDRU1	PWDRU0
Initial value	1	1	0	0	0	0	0	0
Read/Write	_	_	W	W	W	W	W	W
PWDRL								
Bit	7	6	5	4	3	2	1	0
	PWDRL7	PWDRL6	PWDRL5	PWDRL4	PWDRL3	PWDRL2	PWDRL1	PWDRL0
Initial value	0	0	0	0	0	0	0	0
Read/Write	W	W	W	W	W	W	W	W

PWDRU and PWDRL form a 14-bit write-only register, with the upper 6 bits assigned to PWDRU and the lower 8 bits to PWDRL. The value written to PWDRU and PWDRL gives the total high-level width of one PWM waveform cycle.

When 14-bit data is written to PWDRU and PWDRL, the register contents are latched in the PWM waveform generator, updating the PWM waveform generation data. The 14-bit data should always be written in the following sequence:

- 1. Write the lower 8 bits to PWDRL.
- 2. Write the upper 6 bits to PWDRU.

PWDRU and PWDRL are write-only registers. If they are read, all bits are read as 1.

Upon reset, PWDRU and PWDRL are initialized to H'C000.

11.2.3 Clock Stop Register 2 (CKSTPR2)

Bit	7	6	5	4	3	2	1	0
	_	_	_	_	AECKSTP	WDCKSTP	PWCKSTP	LDCKSTP
Initial value	1	1	1	1	1	1	1	1
Read/Write		_	_	—	R/W	R/W	R/W	R/W

CKSTPR2 is an 8-bit read/write register that performs module standby mode control for peripheral modules. Only the bit relating to the PWM is described here. For details of the other bits, see the sections on the relevant modules.

Bit 1: PWM module standby mode control (PWCKSTP)

Bit 1 controls setting and clearing of module standby mode for the PWM.

PWCKSTP	Description	
0	PWM is set to module standby mode	
1	PWM module standby mode is cleared	(initial value)

11.3 Operation

11.3.1 Operation

When using the 14-bit PWM, set the registers in the following sequence.

- 1. Set bit PWM in port mode register 3 (PMR3) to 1 so that pin P3₀/PWM is designated for PWM output.
- Set bits PWCR1 and PWCR0 in the PWM control register (PWCR) to select a conversion period of 131,072/\$\oplus\$ (PWCR1 = 1, PWCR0 = 1), 65,536/\$\oplus\$ (PWCR1 = 1, PWCR0 = 0), 32,768/\$\oplus\$ (PWCR1 = 0, PWCR0 = 1), or 16,384/\$\oplus\$ (PWCR1 = 0, PWCR0 = 0).
- 3. Set the output waveform data in PWM data registers U and L (PWDRU/L). Be sure to write in the correct sequence, first PWDRL then PWDRU. When data is written to PWDRU, the data in these registers will be latched in the PWM waveform generator, updating the PWM waveform generation in synchronization with internal signals.

One conversion period consists of 64 pulses, as shown in figure 11.2. The total of the high-level pulse widths during this period (T_H) corresponds to the data in PWDRU and PWDRL. This relation can be represented as follows.

 $T_{\rm H}$ = (data value in PWDRU and PWDRL + 64) × t_o/2

where t ϕ is the PWM input clock period: $2/\phi$ (PWCR = H'0), $4/\phi$ (PWCR = H'1), $8/\phi$ (PWCR = H'2), or $16/\phi$ (PWCR = H'3).

Example: Settings in order to obtain a conversion period of 32,768 µs:

When PWCR1 = 0 and PWCR0 = 0, the conversion period is $16,384/\phi$, so ϕ must be 0.5 MHz. In this case, tfn = 512 µs, with $1/\phi$ (resolution) = 2.0 µs.

When PWCR1 = 0 and PWCR0 = 1, the conversion period is $32,768/\phi$, so ϕ must be 1 MHz. In this case, tfn = 512 µs, with $2/\phi$ (resolution) = 2.0 µs.

When PWCR1 = 1 and PWCR0 = 0, the conversion period is $65,536/\phi$, so ϕ must be 2 MHz. In this case, tfn = 512 µs, with $4/\phi$ (resolution) = 2.0 µs.

Accordingly, for a conversion period of 32,768 $\mu s,$ the system clock frequency (ϕ) must be 0.5 MHz, 1 MHz, or 2 MHz.





11.3.2 PWM Operation Modes

PWM operation modes are shown in table 11.3.

Table 11.3	PWM Operation	on Modes
------------	---------------	----------

Operation Mode	Reset	Active	Sleep	Watch	Subactive	Subsleep	Standby	Module Standby
PWCR	Reset	Functions	Functions	Held	Held	Held	Held	Held
PWDRU	Reset	Functions	Functions	Held	Held	Held	Held	Held
PWDRL	Reset	Functions	Functions	Held	Held	Held	Held	Held



Section 12 A/D Converter

12.1 Overview

This LSI includes on-chip a resistance-ladder-based successive-approximation analog-to-digital converter, and can convert up to 8 channels of analog input.

12.1.1 Features

The A/D converter has the following features.

- 10-bit resolution
- Eight input channels
- Conversion time: approx. 12.4 µs per channel (at 5 MHz operation)
- Built-in sample-and-hold function
- Interrupt requested on completion of A/D conversion
- A/D conversion can be started by external trigger input
- Use of module standby mode enables this module to be placed in standby mode independently when not used.

12.1.2 Block Diagram

Figure 12.1 shows a block diagram of the A/D converter.



Figure 12.1 Block Diagram of the A/D Converter

12.1.3 Pin Configuration

Table 12.1 shows the A/D converter pin configuration.

Name	Abbr.	I/O	Function
Analog power supply	AV _{CC}	Input	Power supply and reference voltage of analog part
Analog ground	AV_{SS}	Input	Ground and reference voltage of analog part
Analog input 0	AN ₀	Input	Analog input channel 0
Analog input 1	AN ₁	Input	Analog input channel 1
Analog input 2	AN ₂	Input	Analog input channel 2
Analog input 3	AN ₃	Input	Analog input channel 3
Analog input 4	AN ₄	Input	Analog input channel 4
Analog input 5	AN ₅	Input	Analog input channel 5
Analog input 6	AN ₆	Input	Analog input channel 6
Analog input 7	AN ₇	Input	Analog input channel 7
External trigger input	ADTRG	Input	External trigger input for starting A/D conversion

Table 12.1Pin Configuration

12.1.4 Register Configuration

Table 12.2 shows the A/D converter register configuration.

Table 12.2 Register Configuration

Name	Abbr.	R/W	Initial Value	Address
A/D mode register	AMR	R/W	H'30	H'FFC6
A/D start register	ADSR	R/W	H'7F	H'FFC7
A/D result register H	ADRRH	R	Not fixed	H'FFC4
A/D result register L	ADRRL	R	Not fixed	H'FFC5
Clock stop register 1	CKSTPRT1	R/W	H'FF	H'FFFA

12.2 Register Descriptions

12.2.1 A/D Result Registers (ADRRH, ADRRL)



ADRRH and ADRRL together comprise a 16-bit read-only register for holding the results of analog-to-digital conversion. The upper 8 bits of the data are held in ADRRH, and the lower 2 bits in ADRRL.

ADRRH and ADRRL can be read by the CPU at any time, but the ADRRH and ADRRL values during A/D conversion are not fixed. After A/D conversion is complete, the conversion result is stored as 10-bit data, and this data is held until the next conversion operation starts.

ADRRH and ADRRL are not cleared on reset.

12.2.2 A/D Mode Register (AMR)

Bit	7	6	5	4	3	2	1	0
	CKS	TRGE	—	_	СНЗ	CH2	CH1	CH0
Initial value	0	0	1	1	0	0	0	0
Read/Write	R/W	R/W	_	_	R/W	R/W	R/W	R/W

AMR is an 8-bit read/write register for specifying the A/D conversion speed, external trigger option, and the analog input pins.

Upon reset, AMR is initialized to H'30.



Bit 7: Clock select (CKS)

Bit 7 sets the A/D conversion speed.

φ = 5 MHz
12.4 µs
_

Note: * For information on conversion time settings for which operation is guaranteed, see section 15, Electrical Characteristics.

Bit 6: External trigger select (TRGE)

Bit 6 enables or disables the start of A/D conversion by external trigger input.

Bit 6 TRGE		Description
0		Disables start of A/D conversion by external trigger (initial value)
1		Enables start of A/D conversion by rising or falling edge of external trigger at pin ADTRG*
Note:	*	The external trigger (ADTRG) edge is selected by bit IEG4 of IEGR. See 1. IRQ edge select register (IEGR) in section 3.3.2 for details.

Bits 5 and 4: Reserved bits

Bits 5 and 4 are reserved; they are always read as 1, and cannot be modified.

Bits 3 to 0: Channel select (CH3 to CH0)

Bits 3 to 0 select the analog input channel.

The channel selection should be made while bit ADSF is cleared to 0.

Bit 3 CH3	Bit 2 CH2	Bit 1 CH1	Bit 0 CH0	Analog Input Channel	
0	0	*	*	No channel selected	(initial value)
0	1	0	0	AN0	
0	1	0	1	AN1	
0	1	1	0	AN2	
0	1	1	1	AN3	
1	0	0	0	AN4	
1	0	0	1	AN5	
1	0	1	0	AN6	
1	0	1	1	AN7	
1	1	*	*	Setting prohibited	

Note: * Don't care

12.2.3 A/D Start Register (ADSR)

Bit	7	6	5	4	3	2	1	0
	ADSF	—			—	_		_
Initial value	0	1	1	1	1	1	1	1
Read/Write	R/W	_	_	_	_	_	_	_

The A/D start register (ADSR) is an 8-bit read/write register for starting and stopping A/D conversion.

A/D conversion is started by writing 1 to the A/D start flag (ADSF) or by input of the designated edge of the external trigger signal, which also sets ADSF to 1. When conversion is complete, the converted data is set in ADRRH and ADRRL, and at the same time ADSF is cleared to 0.



Bit 7: A/D start flag (ADSF)

Bit 7 controls and indicates the start and end of A/D conversion.

Bit 7 ADSF	Description	
0	Read: Indicates the completion of A/D conversion	(initial value)
	Write: Stops A/D conversion	
1	Read: Indicates A/D conversion in progress	
	Write: Starts A/D conversion	

Bits 6 to 0: Reserved bits

Bits 6 to 0 are reserved; they are always read as 1, and cannot be modified.

12.2.4 Clock Stop Register 1 (CKSTPR1)

Bit	7	6	5	4	3	2	1	0
	—	S31CKSTP	S32CKSTP	ADCKSTP	TGCKSTP	TFCKSTP	TCCKSTP	TACKSTP
Initial value	1	1	1	1	1	1	1	1
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

CKSTPR1 is an 8-bit read/write register that performs module standby mode control for peripheral modules. Only the bit relating to the A/D converter is described here. For details of the other bits, see the sections on the relevant modules.

Bit 4: A/D converter module standby mode control (ADCKSTP)

Bit 4 controls setting and clearing of module standby mode for the A/D converter.

ADCKSTP	Description	
0	A/D converter is set to module standby mode	
1	A/D converter module standby mode is cleared	(initial value)

12.3 Operation

12.3.1 A/D Conversion Operation

The A/D converter operates by successive approximations, and yields its conversion result as 10bit data.

A/D conversion begins when software sets the A/D start flag (bit ADSF) to 1. Bit ADSF keeps a value of 1 during A/D conversion, and is cleared to 0 automatically when conversion is complete.

The completion of conversion also sets bit IRRAD in interrupt request register 2 (IRR2) to 1. An A/D conversion end interrupt is requested if bit IENAD in interrupt enable register 2 (IENR2) is set to 1.

If the conversion time or input channel needs to be changed in the A/D mode register (AMR) during A/D conversion, bit ADSF should first be cleared to 0, stopping the conversion operation, in order to avoid malfunction.

12.3.2 Start of A/D Conversion by External Trigger Input

The A/D converter can be made to start A/D conversion by input of an external trigger signal. External trigger input is enabled at pin ADTRG when bit IRQ4 in PMR1 is set to 1 and bit TRGE in AMR is set to 1. Then when the input signal edge designated in bit IEG4 of interrupt edge select register (IEGR) is detected at pin ADTRG, bit ADSF in ADSR will be set to 1, starting A/D conversion.

Figure 12.2 shows the timing.



Figure 12.2 External Trigger Input Timing

12.3.3 A/D Converter Operation Modes

A/D converter operation modes are shown in table 12.3.

Table 12.3 A/D Converter Operation Modes

Operation Mode	Reset	Active	Sleep	Watch	Subactive	Subsleep	Standby	Module Standby
AMR	Reset	Functions	Functions	Held	Held	Held	Held	Held
ADSR	Reset	Functions	Functions	Held	Held	Held	Held	Held
ADRRH	Held*	Functions	Functions	Held	Held	Held	Held	Held
ADRRL	Held*	Functions	Functions	Held	Held	Held	Held	Held
Note: *	Undefine	ed in a powe	er-on reset.					

12.4 Interrupts

When A/D conversion ends (ADSF changes from 1 to 0), bit IRRAD in interrupt request register 2 (IRR2) is set to 1.

A/D conversion end interrupts can be enabled or disabled by means of bit IENAD in interrupt enable register 2 (IENR2).

For further details see section 3.3, Interrupts.

12.5 Typical Use

An example of how the A/D converter can be used is given below, using channel 1 (pin AN1) as the analog input channel. Figure 12.3 shows the operation timing.

- 1. Bits CH3 to CH0 of the A/D mode register (AMR) are set to 0101, making pin AN₁ the analog input channel. A/D interrupts are enabled by setting bit IENAD to 1, and A/D conversion is started by setting bit ADSF to 1.
- 2. When A/D conversion is complete, bit IRRAD is set to 1, and the A/D conversion result is stored is stored in ADRRH and ADRRL. At the same time ADSF is cleared to 0, and the A/D converter goes to the idle state.
- 3. Bit IENAD = 1, so an A/D conversion end interrupt is requested.
- 4. The A/D interrupt handling routine starts.
- 5. The A/D conversion result is read and processed.
- 6. The A/D interrupt handling routine ends.

If ADSF is set to 1 again afterward, A/D conversion starts and steps 2 to 6 take place.

Figures 12.4 and 12.5 show flow charts of procedures for using the A/D converter.





Figure 12.3 Typical A/D Converter Operation Timing



Figure 12.4 Flow Chart of Procedure for Using A/D Converter (Polling by Software)



Figure 12.5 Flow Chart of Procedure for Using A/D Converter (Interrupts Used)

12.6 Application Notes

12.6.1 Application Notes

- Data in ADRRH and ADRRL should be read only when the A/D start flag (ADSF) in the A/D start register (ADSR) is cleared to 0.
- Changing the digital input signal at an adjacent pin during A/D conversion may adversely affect conversion accuracy.
- When A/D conversion is started after clearing module standby mode, wait for 10ϕ clock cycles before starting.
- In active mode or sleep mode, analog power supply current (AI_{STOP1}) flows into the ladder resistance even when the A/D converter is not operating. Therefore, if the A/D converter is not used, it is recommended that AV_{CC} be connected to the system power supply and the ADCKSTP(A/D converter module standby mode control) bit be cleared to 0 in clock stop register 1 (CKSTPR1).

12.6.2 Permissible Signal Source Impedance

This LSI's analog input is designed such that conversion precision is guaranteed for an input signal for which the signal source impedance is 10 k Ω or less. This specification is provided to enable the A/D converter's sample-and-hold circuit input capacitance to be charged within the sampling time; if the sensor output impedance exceeds 10 k Ω , charging may be insufficient and it may not be possible to guarantee A/D conversion precision. However, a large capacitance provided externally, the input load will essentially comprise only the internal input resistance of 10 k Ω , and the signal source impedance is ignored. However, as a low-pass filter effect is obtained in this case, it may not be possible to follow an analog signal with a large differential coefficient (e.g., 5 mV/µs or greater) (see figure 12.6). When converting a high-speed analog signal, a low-impedance buffer should be inserted.


12.6.3 Influences on Absolute Precision

Adding capacitance results in coupling with GND, and therefore noise in GND may adversely affect absolute precision. Be sure to make the connection to an electrically stable GND.

Care is also required to ensure that filter circuits do not interfere with digital signals or act as antennas on the mounting board.



Figure 12.6 Analog Input Circuit Example



Section 13 LCD Controller/Driver

13.1 Overview

This LSI has an on-chip segment type LCD control circuit, LCD driver, and power supply circuit, enabling it to directly drive an LCD panel.

13.1.1 Features

1. Features

Features of the LCD controller/driver are given below.

• Display capacity

Duty Cycle	Internal Driver	Segment External Expansion Driver	
Static	32 seg	256 seg	
1/2	32 seg	128 seg	
1/3	32 seg	64 seg	
1/4	32 seg	64 seg	

- LCD RAM capacity 8 bits × 32 bytes (256 bits)
- Word access to LCD RAM
- All eight segment output pins can be used individually as port pins.
- Common output pins not used because of the duty cycle can be used for common doublebuffering (parallel connection).
- Display possible in operating modes other than standby mode
- Choice of 11 frame frequencies
- Built-in power supply split-resistance, supplying LCD drive power
- Use of module standby mode enables this module to be placed in standby mode independently when not used.
- A or B waveform selectable by software

13.1.2 Block Diagram

Figure 13.1 shows a block diagram of the LCD controller/driver.



Figure 13.1 Block Diagram of LCD Controller/Driver

13.1.3 Pin Configuration

Table 13.1 shows the LCD controller/driver pin configuration.

Table 13.1Pin Configuration

Name	Abbr.	I/O	Function
Segment output pins	SEG_{32} to SEG_1	Output	LCD segment drive pins All pins are multiplexed as port pins (setting programmable)
Common output pins	COM ₄ to COM ₁	Output	LCD common drive pins Pins can be used in parallel with static or 1/2 duty
Segment external expansion signal pins*	CL1	Output	Display data latch clock, multiplexed as SEG ₃₂
	CL ₂	Output	Display data shift clock, multiplexed as SEG ₃₁
	Μ	Output	LCD alternation signal, multiplexed as SEG ₂₉
	DO	Output	Serial display data, multiplexed as SEG ₃₀
LCD power supply pins	V ₀ , V ₁ , V ₂ , V ₃		Used when a bypass capacitor is connected externally, and when an external power supply circuit is used

Note: * The external expansion function for LCD segments is not implemented in the H8/38327 Group and H8/38427 Group.

13.1.4 Register Configuration

Table 13.2 shows the register configuration of the LCD controller/driver.

Table 13.2 LCD Controller/Driver Registers

Name	Abbr.	R/W	Initial Value	Address
LCD port control register	LPCR	R/W	H'00	H'FFC0
LCD control register	LCR	R/W	H'80	H'FFC1
LCD control register 2	LCR2	R/W	H'60	H'FFC2
LCD RAM	_	R/W	Undefined	H'F740, H'F75F
Clock stop register 2	CKSTPR2	R/W	H'FF	H'FFFB

13.2 Register Descriptions

Bit	7	6	5	4	3	2	1	0
	DTS1	DTS0	CMX	SGX	SGS3	SGS2	SGS1	SGS0
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

13.2.1 LCD Port Control Register (LPCR)

LPCR is an 8-bit read/write register which selects the duty cycle and LCD driver pin functions.

LPCR is initialized to H'00 upon reset.

Bits 7 to 5: Duty cycle select 1 and 0 (DTS1, DTS0), common function select (CMX)

The combination of DTS1 and DTS0 selects static, 1/2, 1/3, or 1/4 duty. CMX specifies whether or not the same waveform is to be output from multiple pins to increase the common drive power when not all common pins are used because of the duty setting.

Bit 7 DTS1	Bit 6 DTS0	Bit 5 CMX	Duty Cycle	Common Drivers	Notes
0	0	0	Static	COM ₁ (initial value)	Do not use COM_4 , COM_3 , and COM_2 .
		1		COM ₄ to COM ₁	COM ₄ , COM ₃ , and COM ₂ output the same waveform as COM ₁ .
0	1	0	1/2 duty	COM ₂ to COM ₁	Do not use COM ₄ and COM ₃ .
		1	_	COM ₄ to COM ₁	COM_4 outputs the same waveform as COM_3 , and COM_2 outputs the same waveform as COM_1 .
1	0	0	1/3 duty	COM ₃ to COM ₁	Do not use COM ₄ .
		1		COM ₄ to COM ₁	Do not use COM ₄ .
1	1	0	1/4 duty	COM ₄ to COM ₁	
		1			

Bit 4: Expansion signal select (SGX)

Bit 4 selects whether the SEG₃₂/CL₁, SEG₃₁/CL₂, SEG₃₀/DO, and SEG₂₉/M pins are used as segment pins (SEG₃₂ to SEG₂₉) or as segment external expansion pins (CL₁, CL₂, DO, and M).

In the H8/38327 Group and H8/38427 Group this bit should be left at its initial value and not written to. Changing the value of this bit may prevent the SEG/COM signal from operating normally.

Bit 4 SGX		Description	
0		Pins SEG ₃₂ to SEG ₂₉ *	(initial value)
1		Pins CL ₁ , CL ₂ , DO, M	
Note:	*	These pins function as ports whe	en the setting of SGS3 to SGS0 is 0000 or 0001.

Bits 3 to 0: Segment driver select 3 to 0 (SGS3 to SGS0)

Bits 3 to 0 select the segment drivers to be used. The SGX = 0 setting is selected on the H8/38327 and H8/38427.

					i uni				
Bit 4 SGX	Bit 3 SGS3	Bit 2 SGS2	Bit 1 SGS1	Bit 0 SGS0	SEG ₃₂ to SEG ₂₅	SEG ₂₄ to SEG ₁₇	SEG ₁₆ to SEG ₉	SEG ₈ to SEG ₁	Notes
0	0	0	0	0	Port	Port	Port	Port	(initial value)
	0	0	0	1	Port	Port	Port	Port	
	0	0	1	*	SEG	Port	Port	Port	
	0	1	0	*	SEG	SEG	Port	Port	
	0	1	1	*	SEG	SEG	SEG	Port	
	1	*	*	*	SEG	SEG	SEG	SEG	
1	0	0	0	0	Port ^{*1}	Port	Port	Port	
	*	*	*	*	Setting pro	ohibited			
-									

Function of Pins SEG₃₂ to SEG₁

*: Don't care

Note: 1. SEG₃₂ to SEG₂₉ are external expansion pins.

13.2.2 LCD Control Register (LCR)

Bit	7	6	5	4	3	2	1	0
	—	PSW	ACT	DISP	CKS3	CKS2	CKS1	CKS0
Initial value	1	0	0	0	0	0	0	0
Read/Write	_	R/W	R/W	R/W	R/W	R/W	R/W	R/W

LCR is an 8-bit read/write register which performs LCD drive power supply on/off control and display data control, and selects the frame frequency.

LCR is initialized to H'80 upon reset.

Bit 7: Reserved bit

Bit 7 is reserved; it is always read as 1 and cannot be modified.

Bit 6: LCD drive power supply on/off control (PSW)

Bit 6 can be used to turn the LCD drive power supply off when LCD display is not required in a power-down mode, or when an external power supply is used. When the ACT bit is cleared to 0, or in standby mode, the LCD drive power supply is turned off regardless of the setting of this bit.

Bit 6 PSW	Description	
0	LCD drive power supply off	(initial value)
1	LCD drive power supply on	

Bit 5: Display function activate (ACT)

Bit 5 specifies whether or not the LCD controller/driver is used. Clearing this bit to 0 halts operation of the LCD controller/driver. The LCD drive power supply is also turned off, regardless of the setting of the PSW bit. However, register contents are retained.

Bit 5 ACT	Description	
0	LCD controller/driver operation halted	(initial value)
1	LCD controller/driver operates	

Bit 4: Display data control (DISP)

Bit 4 specifies whether the LCD RAM contents are displayed or blank data is displayed regardless of the LCD RAM contents.

Bit 4 DISP	Description	
0	Blank data is displayed	(initial value)
1	LCD RAM data is display	

Bits 3 to 0: Frame frequency select 3 to 0 (CKS3 to CKS0)

Bits 3 to 0 select the operating clock and the frame frequency. In subactive mode, watch mode, and subsleep mode, the system clock (ϕ) is halted, and therefore display operations are not performed if one of the clocks from $\phi/2$ to $\phi/256$ is selected. If LCD display is required in these modes, ϕw , $\phi w/2$, or $\phi w/4$ must be selected as the operating clock.

Bit 3	Bit 2	Bit 1	Bit 0		Frame	e Frequency ^{*2}
CKS3	CKS2	CKS1	CKS0	Operating Clock	φ = 2 MHz	φ = 250 kHz ^{*1}
0	*	0	0	φw	128 Hz ^{*3} (initia	l value)
0	*	0	1	φw/2	64 Hz ^{*3}	
0	*	1	*	φw/4	32 Hz ^{*3}	
1	0	0	0	ф/2	—	244 Hz
1	0	0	1	ф/4	977 Hz	122 Hz
1	0	1	0	ф/8	488 Hz	61 Hz
1	0	1	1	ф/16	244 Hz	30.5 Hz
1	1	0	0	ф/32	122 Hz	_
1	1	0	1	ф/64	61 Hz	_
1	1	1	0	ф/128	30.5 Hz	_
1	1	1	1	ф/256	_	_

*: Don't care

Notes: 1. This is the frame frequency in active (medium-speed, ϕ osc/16) mode when ϕ = 2 MHz.

- 2. When 1/3 duty is selected, the frame frequency is 4/3 times the value shown.
- 3. This is the frame frequency when ϕw = 32.768 kHz.

13.2.3 LCD Control Register 2 (LCR2)

Bit	7	6	5	4	3	2	1	0
	LCDAB	—	—	_	CDS3	CDS2	CDS1	CDS0
Initial value	0	1	1	0	0	0	0	0
Read/Write	R/W	—	—	R/W	R/W	R/W	R/W	R/W

LCR2 is an 8-bit read/write register which controls switching between the A waveform and B waveform, and selects the duty cycle of the charge/discharge pulses which control disconnection of the power supply split-resistance from the power supply circuit.

LCR2 is initialized to H'60 upon reset.

Bit 7: A waveform/B waveform switching control (LCDAB)

Bit 7 specifies whether the A waveform or B waveform is used as the LCD drive waveform.

Bit 7		
LCDAB	Description	
0	Drive using A waveform	(initial value)
1	Drive using B waveform	

Bits 6 and 5: Reserved bits

Bits 6 and 5 are reserved; they are always read as 1 and cannot be modified.

Bit 4: Reserved bit

Bit 4 is reserved; it is always read as 0 and must not be written with 1.



Bit 3 CDS3	Bit 2 CDS2	Bit 1 CDS1	Bit 0 CDS0	Duty Cycle	Notes	
0	0	0	0	1	Fixed high	(initial value)
0	0	0	1	1/8		
0	0	1	0	2/8		
0	0	1	1	3/8		
0	1	0	0	4/8		
0	1	0	1	5/8		
0	1	1	0	6/8		
0	1	1	1	0	Fixed low	
1	0	*	*	1/16		
1	1	*	*	1/32		
						*: Don't coro

Bits 3 to 0: Charge/discharge pulse duty cycle select (CDS3 to CDS0)

*: Don't care

Bits 3 to 0 select the duty cycle while the power supply split-resistance is connected to the power supply circuit.

When a 0 duty cycle is selected, the power supply split-resistance is permanently disconnected from the power supply circuit, so power should be supplied to pins V_1 , V_2 , and V_3 by an external circuit.

Figure 13.2 shows the waveform of the charge/discharge pulses. The duty cycle is Tc/Tw.





13.2.4 Clock Stop Register 2 (CKSTPR2)



CKSTPR2 is an 8-bit read/write register that performs module standby mode control for peripheral modules. Only the bit relating to the LCD controller/driver is described here. For details of the other bits, see the sections on the relevant modules.

Bit 0: LCD controller/driver module standby mode control (LDCKSTP)

Bit 0 controls setting and clearing of module standby mode for the LCD controller/driver.

Bit 0 LDCKSTP	Description	
0	LCD controller/driver is set to module standby mode	
1	LCD controller/driver module standby mode is cleared	(initial value)



13.3 Operation

13.3.1 Settings Up to LCD Display

To perform LCD display, the hardware and software related items described below must first be determined.

1. Hardware Settings

a. Using 1/2 duty

When 1/2 duty is used, interconnect pins V_2 and V_3 as shown in figure 13.3.



Figure 13.3 Handling of LCD Drive Power Supply when Using 1/2 Duty

b. Large-panel display

As the impedance of the built-in power supply split-resistance is large, it may not be suitable for driving a large panel. If the display lacks sharpness when using a large panel, refer to section 13.3.6, Boosting the LCD Drive Power Supply. When static or 1/2 duty is selected, the common output drive capability can be increased. Set CMX to 1 when selecting the duty cycle. In this mode, with a static duty cycle pins COM₄ to COM₁ output the same waveform, and with 1/2 duty the COM₁ waveform is output from pins COM₂ and COM₁, and the COM₂ waveform is output from pins COM₄ and COM₃.

c. Luminance adjustment function (V_0 pin)

Connecting a resistance between the V_0 and V_1 pins enables the luminance to be adjusted. For details, see section 13.3.3, Luminance Adjustment Function (V_0 Pin).

d. LCD drive power supply setting

With the H8/3827R Group, there are two ways of providing LCD power: by using the on-chip power supply circuit, or by using an external circuit.

When the on-chip power supply circuit is used for the LCD drive power supply, the V_0 and V_1 pins should be interconnected externally, as shown in figure 13.4 (a).

When an external power supply circuit is used for the LCD drive power supply, connect the external power supply to the V_1 pin, and short the V_0 pin to V_{CC} externally, as shown in figure 13.4 (b).





e. Low-power-consumption LCD drive system

Use of a low-power-consumption LCD drive system enables the power consumption required for LCD drive to be optimized. For details, see section 13.3.4, Low-Power-Consumption LCD Drive System.

f. Segment external expansion

The number of segments can be increased by connecting an HD66100 externally. For details, see section 13.3.7, Connection to HD66100.



2. Software settings

a. Duty selection

Any of four duty cycles—static, 1/2 duty, 1/3 duty, or 1/4 duty—can be selected with bits DTS1 and DTS0.

b. Segment selection

The segment drivers to be used can be selected with bits SGS₃ to SGS₀.

c. Frame frequency selection

The frame frequency can be selected by setting bits CKS_3 to CKS_0 . The frame frequency should be selected in accordance with the LCD panel specification. For the clock selection method in watch mode, subactive mode, and subsleep mode, see section 13.3.5, Operation in Power-Down Modes.

d. A or B waveform selection

Either the A or B waveform can be selected as the LCD waveform to be used by means of LCDAB.

13.3.2 Relationship between LCD RAM and Display

The relationship between the LCD RAM and the display segments differs according to the duty cycle. LCD RAM maps for the different duty cycles when segment external expansion is not used are shown in figures 13.5 to 13.8, and LCD RAM maps when segment external expansion is used in figures 13.9 to 13.12.

After setting the registers required for display, data is written to the part corresponding to the duty using the same kind of instruction as for ordinary RAM, and display is started automatically when turned on. Word- or byte-access instructions can be used for RAM setting.

	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
H'F740	SEG ₂	SEG ₂	SEG ₂	SEG ₂	SEG1	SEG1	SEG1	SEG1
H'F74F	SEG ₃₂	SEG ₃₂	SEG ₃₂	SEG32	SEG31	SEG31	SEG31	SEG31
	+	+	+	+	+	+	+	
	COM ₄	COM ₃	COM ₂	COM ₁	COM ₄	COM ₃	COM ₂	COM ₁

Figure 13.5 LCD RAM Map when Not Using Segment External Expansion (1/4 Duty)



Figure 13.6 LCD RAM Map when Not Using Segment External Expansion (1/3 Duty)



Figure 13.7 LCD RAM Map when Not Using Segment External Expansion (1/2 Duty)



Figure 13.8 LCD RAM Map when Not Using Segment External Expansion (Static Mode)

	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	
H'F740	SEG ₂	SEG ₂	SEG ₂	SEG ₂	SEG1	SEG1	SEG1	SEG1	
									Expansion
									driver display space
H'F75F	SEG ₆₄	SEG ₆₄	SEG ₆₄	SEG ₆₄	SEG ₆₃	SEG ₆₃	SEG ₆₃	SEG ₆₃	
	+	+	*	*	*	+	+	*	
	COM ₄	COM ₃	COM ₂	COM ₁	COM ₄	COM ₃	COM ₁	COM ₁	

Figure 13.9 LCD RAM Map when Using Segment External Expansion (SGX = "1", SGS3 to SGS0 = "0000" 1/4 Duty)



Figure 13.10 LCD RAM Map when Using Segment External Expansion (SGX = "1", SGS3 to SGS0 = "0000" 1/3 Duty)



	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	
H'F740	SEG ₄	SEG ₄	SEG₃	SEG₃	SEG ₂	SEG ₂	SEG1	SEG1	
									Expansion
									driver display space
H'F75F	SEG ₁₂₈	SEG128	SEG127	SEG127	SEG ₁₂₆	SEG ₁₂₆	SEG ₁₂₅	SEG ₁₂₅	
	+	+	+	+	+	+	+	+	
	COM ₂	COM ₁	COM ₂	COM ₁	COM ₂	COM ₁	COM ₂	COM ₁	

Figure 13.11 LCD RAM Map when Using Segment External Expansion (SGX = "1", SGS3 to SGS0 = "0000" 1/2 Duty)

	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit0	
H'F740	SEG ₈	SEG7	SEG ₆	SEG₅	SEG ₄	SEG₃	SEG ₂	SEG1	
									 Expansion
									driver display space
H'F75F	SEG256	SEG255	SEG254	SEG253	SEG252	SEG ₂₅₁	SEG ₂₅₀	SEG249	
	∳ COM₁	∳ COM₁	∳ COM₁	∳ COM₁	∳ COM₁	∳ COM1	∳ COM₁	∳ COM₁	
				COM					

Figure 13.12 LCD RAM Map when Using Segment External Expansion (SGX = "1", SGS3 to SGS0 = "0000" Static)



13.3.3 Luminance Adjustment Function (V₀ Pin)

Figure 13.13 shows a detailed block diagram of the LCD drive power supply unit.

The voltage output to the V_0 pin is $V_{CC.}$ When either of these voltages is used directly as the LCD drive power supply, the V_0 and V_1 pins should be shorted. Also, connecting a variable resistance, R, between the V_0 and V_1 pins makes it possible to adjust the voltage applied to the V_1 pin, and so to provide luminance adjustment for the LCD panel.



Figure 13.13 LCD Drive Power Supply Unit

13.3.4 Low-Power-Consumption LCD Drive System

The use of the built-in split-resistance is normally the easiest method for implementing the LCD power supply circuit, but since the built-in resistance is fixed, a certain direct current flows constantly from the built-in resistance's V_{CC} to V_{SS} . As this current does not depend on the current dissipation of the LCD panel, if an LCD panel with a small current dissipation is used, a wasteful amount of power will be consumed. The H8/3827 Group is equipped with a function to minimize this waste of power. Use of this function makes it possible to achieve the optimum power supply circuit for the LCD panel's current dissipation.

1. Principles

- a. Capacitors are connected as external circuits to LCD power supply pins V1, V2, and V3, as shown in figure 13.14.
- b. The capacitors connected to V1, V2, and V3 are repeatedly charged and discharged in the cycle shown in figure 13.14, maintaining the potentials.
- c. At this time, the charged potential is a potential corresponding to the V1, V2, and V3 pins, respectively. (For example, with 1/3 bias drive, the charge for V2 is 2/3 that of V1, and that for V3 is 1/3 that of V1.)
- d. Power is supplied to the LCD panel by means of the charges accumulated in these capacitors.
- e. The capacitances and charging/discharging periods of these capacitors are therefore determined by the current dissipation of the LCD panel.
- f. The charging and discharging periods can be selected by software.

2. Example of Operation (with 1/3 bias drive)

- a. During charging period Tc in the figure, the potential is divided among pins V1, V2, and V3 by the built-in split-resistance (the potential of V2 being 2/3 that of V1, and that of V3 being 1/3 that of V1), as shown in figure 13.14, and external capacitors C1, C2, and C3 are charged. The LCD panel is continues to be driven during this time.
- b. In the following discharging period, Tdc, charging is halted and the charge accumulated in each capacitor is discharged, driving the LCD panel.
- c. At this time, a slight voltage drop occurs due to the discharging; optimum values must be selected for the charging period and the capacitor capacitances to ensure that this does not affect the driving of the LCD panel.
- d. In this way, the capacitors connected to V1, V2, and V3 are repeatedly charged and discharged in the cycle shown in figure 13.14, maintaining the potentials and continuously driving the LCD panel.

- e. As can be seen from the above description, the capacitances and charging/discharging periods of the capacitors are determined by the current dissipation of the LCD panel used. The charging/discharging periods can be selected with bits CDS3 to CDS0.
- f. The actual capacitor capacitances and charging/discharging periods must be determined experimentally in accordance with the current dissipation requirements of the LCD panel. An optimum current value can be selected, in contrast to the case in which a direct current flows constantly in the built-in split-resistance.



Figure 13.14 Example of Low-Power-Consumption LCD Drive Operation



Figure 13.15 Output Waveforms for Each Duty Cycle (A Waveform)



Figure 13.16 Output Waveforms for Each Duty Cycle (B Waveform)

Data		0	0	1	1
М		0	1	0	1
Static	Common output	V ₁	V _{SS}	V ₁	V _{SS}
	Segment output	V ₁	V _{SS}	V _{SS}	V ₁
1/2 duty	Common output	V ₂ , V ₃	V ₂ , V ₃	V ₁	V _{SS}
	Segment output	V ₁	V _{SS}	V _{SS}	V ₁
1/3 duty	Common output	V ₃	V ₂	V ₁	V _{SS}
	Segment output	V ₂	V ₃	V _{SS}	V ₁
1/4 duty	Common output	V ₃	V ₂	V ₁	V _{SS}
	Segment output	V ₂	V ₃	V _{SS}	V ₁

13.3.5 Operation in Power-Down Modes

In this LSI, the LCD controller/driver can be operated even in the power-down modes. The operating state of the LCD controller/driver in the power-down modes is summarized in table 13.4.

In subactive mode, watch mode, and subsleep mode, the system clock oscillator stops, and therefore, unless ϕw , $\phi w/2$, or $\phi w/4$ has been selected by bits CKS3 to CKS0, the clock will not be supplied and display will halt. Since there is a possibility that a direct current will be applied to the LCD panel in this case, it is essential to ensure that ϕw , $\phi w/2$, or $\phi w/4$ is selected. In active (medium-speed) mode, the system clock is switched, and therefore CKS3 to CKS0 must be modified to ensure that the frame frequency does not change.



Mode		Reset	Active	Sleep	Watch	Sub- active	Sub- sleep	Standby	Module Standby
Clock	φ	Runs	Runs	Runs	Stops	Stops	Stops	Stops	Stops ^{*4}
	φw	Runs	Runs	Runs	Runs	Runs	Runs	Stops ^{*1}	Stops*4
Display operation	ACT = "0"	Stops	Stops	Stops	Stops	Stops	Stops	Stops ^{*2}	Stops
	ACT = "1"	Stops	Functions	Functions	Functions *3	Functions *3	Functions *3	Stops ^{*2}	Stops

Table 13.4 Power-Down Modes and Display Operation

Notes: 1. The subclock oscillator does not stop, but clock supply is halted.

2. The LCD drive power supply is turned off regardless of the setting of the PSW bit.

- 3. Display operation is performed only if ϕw , $\phi w/2$, or $\phi w/4$ is selected as the operating clock.
- 4. The clock supplied to the LCD stops.

13.3.6 Boosting the LCD Drive Power Supply

When a large panel is driven, the on-chip power supply capacity may be insufficient. If the power supply capacity is insufficient when V_{CC} is used as the power supply, the power supply impedance must be reduced. This can be done by connecting bypass capacitors of around 0.1 to 0.3 μ F to pins V₁ to V₃, as shown in figure 13.17, or by adding a split-resistance externally.





13.3.7 Connection to HD66100

If the segments are to be expanded externally, an HD66100 should be connected. Connecting one HD66100 provides 80-segment expansion. When carrying out external expansion, select the external expansion signal function of pins SEG_{32} to SEG_{29} with the SGX bit in LPCR, and set bits SGS3 to SGS0 to 0000 or 0001. Data is output externally from SEG_1 of the LCD RAM. SEG_{28} to SEG_1 function as ports.

Figure 13.18 shows examples of connection to an HD66100. The output level is determined by a combination of the data and the M pin output, but these combinations differ from those in the HD66100. Table 13.3 shows the output levels of the LCD drive power supply, and figures 13.15 and 13.16 show the common and segment waveforms for each duty cycle.

When ACT is cleared to 0, operation stops with $CL_2 = 0$, $CL_1 = 0$, M = 0, and DO at the data value (1 or 0) being output at that instant. In standby mode, the expansion pins go to the high-impedance (floating) state.

When external expansion is implemented, the load in the LCD panel increases and the on-chip power supply may not provide sufficient current capacity. In this case, measures should be taken as described in section 13.3.6, Boosting the LCD Drive Power Supply.





Figure 13.18 Connection to HD66100



Section 14 Power Supply Circuit

14.1 Overview

H8/3827R Group, H8/38327 Group and H8/38427 Group incorporates an internal power supply step-down circuit. Use of this circuit enables the internal power supply to be fixed at a constant level of approximately 3.0 V to 3.2 V, independently of the voltage of the power supply connected to the external V_{cc} pin. As a result, the current consumed when an external power supply is used at 3.0 V or above can be held down to virtually the same low level as when used at approximately 3.0 V. If the external power supply is 3.0 V or below, the internal voltage will be practically the same as the external voltage. It is, of course, also possible to use the same level of external power supply voltage and internal power supply voltage without using the internal power supply stepdown circuit.

14.2 When Using Internal Power Supply Step-Down Circuit

Connect the external power supply to the V_{cc} pin, and connect a capacitance of approximately 0.1 μ F, in the case of the H8/3827R, or approximately 0.33 μ F, in the case of the H8/38327 or H8/38427, between CV_{cc} and V_{ss}, as shown in figure 14.1. The internal step-down circuit is made effective simply by adding this external circuit. In the external circuit interface, the external power supply voltage connected to V_{cc} and the GND potential connected to V_{ss} are the reference levels. For example, for port input/output levels, the V_{cc} level is the reference for the high level, and the V_{ss} level is that for the low level. The LCD power supply and A/D converter analog power supply are not affected by the internal step-down current.

In the H8/3827R Group the operating range differs depending on whether or not the internal stepdown circuit is used. For details, see section 15, Electrical Characteristics.



Figure 14.1 Power Supply Connection when Internal Step-Down Circuit is Used

14.3 When Not Using Internal Power Supply Step-Down Circuit

When the internal power supply step-down circuit is not used, connect the external power supply to the CV_{cc} pin and V_{cc} pin, as shown in figure 14.2. The external power supply is then input directly to the internal power supply. The permissible range for the power supply voltage is 1.8 V to 5.5 V for the H8/3827R Group and 2.7 V to 3.6 V for the H8/38327 Group and H8/38427 Group. Normally, however, the internal power supply step-down circuit should be used. Operation cannot be guaranteed if a voltage outside this range is input.



Figure 14.2 Power Supply Connection when Internal Step-Down Circuit is Not Used

14.4 H8/3827S Group

The H8/3827S Group has two V_{CC} pins, which should be interconnected externally.

14.5 Notes on Switching from the H8/3827R to the H8/38327 or H8/38427

Examine the following with regard to the power supply circuit.

- (1) If the internal power supply step-down circuit was used on the H8/3827R The stabilization capacitance value differs between the products. It is necessary to change the value from 0.1 μ F (H8/3827R) to 0.33 μ F (H8/38327 or H8/38427). Note that these values are rough guidelines and it is still necessary to confirm system operation.
- (2) If the internal power supply step-down circuit was not used on the H8/3827R Use of the internal power supply step-down circuit of the H8/38327 or H8/38427 is recommended. Furthermore, operation at a V_{CC} of 3.6 V or greater is not guaranteed if the internal power supply step-down circuit is not used. It is therefore necessary to change the CV_{CC} connection to use the internal power supply step-down circuit.

Section 15 Electrical Characteristics

15.1 H8/3827R Group Absolute Maximum Ratings (Regular Specifications)

Table 15.1 lists the absolute maximum ratings.

Table 15.1	Absolute Maximum Rating	ŞS
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Item		Symbol	Value	Unit	Notes
Power supply voltage		V_{CC} , CV_{CC}	-0.3 to +7.0	V	*1
Analog power supply voltage		AV _{CC}	-0.3 to +7.0	V	
Programming voltage		V _{PP}	–0.3 to +13.0	V	
Input voltage	Ports other than Port B	V _{in}	–0.3 to V _{CC} +0.3	V	
	Port B	AV _{in}	–0.3 to AV _{CC} +0.3	V	
Operating temperature		T _{opr}	–20 to +75 ^{*2}	°C	
Storage temperature		T _{stg}	–55 to +125	°C	

Notes: 1. Permanent damage may occur to the chip if maximum ratings are exceeded. Normal operation should be under the conditions specified in Electrical Characteristics. Exceeding these values can result in incorrect operation and reduced reliability.

2. The operating temperature is the temperature range in which power (voltage V_{CC} shown in "Electrical Characteristics") can be applied to the chip.

15.2 H8/3827R Group Electrical Characteristics (Regular Specifications)

15.2.1 Power Supply Voltage and Operating Range

The power supply voltage and operating range are indicated by the shaded region in the figures.

1. Power Supply Voltage and Oscillator Frequency Range



• Sleep (high-speed) mode

Internal power supply step-down circuit not used

Note: fosc is the oscillator frequency. When external clocks are used, fosc=1MHz is the minimum.



- Active (high-speed) mode
- Sleep (high-speed) mode
- Internal power supply step-down circuit used
- Note: fosc is the oscillator frequency. When external clocks are used, fosc=1MHz is the minimum.

All operating modes


2. Power Supply Voltage and Operating Frequency Range





Watch mode (except CPU)



3. Analog Power Supply Voltage and A/D Converter Operating Range



- Active (high-speed) mode
- Sleep (high-speed) mode
- Internal power supply step-down circuit not used and used



- Active (medium-speed) mode
- Sleep (medium-speed) mode
- Internal power supply step-down circuit not used



- Active (medium-speed) mode
- Sleep (medium-speed) mode
- Internal power supply step-down circuit used



15.2.2 DC Characteristics

Table 15.2 lists the DC characteristics.

Table 15.2 DC Characteristics

 $V_{CC} = 1.8 \text{ V}$ to 5.5 V, $AV_{CC} = 1.8 \text{ V}$ to 5.5 V, $V_{SS} = AV_{SS} = 0.0 \text{ V}$, $T_a = -20^{\circ}\text{C}$ to $+75^{\circ}\text{C}^{*4}$ (including subactive mode) unless otherwise indicated.

				Valu	es			
ltem	Symbol	Applicable Pins	Min	Тур	Max	Unit	Test Condition	Notes
Input high	V _{IH}	RES,	0.8 V _{CC}	_	Vcc + 0.3	V	$V_{\rm CC}$ = 4.0 V to 5.5 V	
voltage		$\label{eq:wkp_0} \begin{array}{l} WKP_0 \text{ to } WKP_7, \\ \overline{IRQ}_0 \text{ to } \overline{IRQ}_4, \\ AEVL, AEVH, \\ TMIC, TMIF, \\ TMIG \\ SCK_{31}, SCK_{32}, \\ \overline{ADTRG} \end{array}$	0.9 V _{CC}	_	V _{CC} + 0.3	_	Except the above	
		RXD ₃₁ , RXD ₃₂ ,	0.7 V _{CC}		V _{CC} + 0.3	V	V_{CC} = 4.0 V to 5.5 V	-
		UD	0.8 V _{CC}			Except the above	_	
		OSC ₁	0.8 V _{CC}	_	V _{CC} + 0.3	V	V_{CC} = 4.0 V to 5.5 V	-
			0.9 V _{CC}		V _{CC} + 0.3	_	Except the above	-
		X ₁	0.9 V _{CC}		V _{CC} + 0.3	V	$V_{\rm CC}$ = 1.8 V to 5.5 V	-
		P1 ₀ to P1 ₇ ,	0.7 V _{CC}		V _{CC} + 0.3	V	$V_{\rm CC}$ = 4.0 V to 5.5 V	-
		$\begin{array}{l} {\sf P3}_0 \mbox{ to } {\sf P3}_7, \\ {\sf P4}_0 \mbox{ to } {\sf P4}_3, \\ {\sf P5}_0 \mbox{ to } {\sf P5}_7, \\ {\sf P6}_0 \mbox{ to } {\sf P5}_7, \\ {\sf P7}_0 \mbox{ to } {\sf P6}_7, \\ {\sf P8}_0 \mbox{ to } {\sf P8}_7, \\ {\sf PA}_0 \mbox{ to } {\sf PA}_3 \end{array}$	0.8 V _{CC}	_	V _{CC} + 0.3	_	Except the above	
		PB ₀ to PB ₇	0.7 V _{CC}	_	AV_{CC} + 0.3	_	$V_{\rm CC}$ = 4.0 V to 5.5 V	_
			0.8 V _{CC}	_	AV_{CC} + 0.3		Except the above	

Note: Connect the TEST pin to V_{SS}.

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				Valu	es			
Item	Symbol	Applicable Pins	Min	Тур	Мах	Unit	Test Condition	Notes
Input low	V _{IL}	RES,	-0.3	_	0.2 V _{CC}	V	$V_{\rm CC}$ = 4.0 V to 5.5 V	
voltage		WKP ₀ to WKP ₇ , IRQ ₀ to IRQ ₄ , AEVL, AEVH, TMIC, TMIF, TMIG SCK ₃₁ , SCK ₃₂ , ADTRG	-0.3	_	0.1 V _{CC}		Except the above	-
		RXD ₃₁ , RXD ₃₂ ,	-0.3	—	0.3 V _{CC}	V	V_{CC} = 4.0 V to 5.5 V	-
		UD	-0.3	_	0.2 V _{CC}		Except the above	-
		OSC ₁	-0.3	_	0.2		When internal step- down circuit is used.	-
			-0.3	_	0.2 V _{CC}	V	$V_{\rm CC}$ = 4.0 V to 5.5 V	-
			-0.3	_	0.1 V _{CC}		Except the above	-
		X ₁	-0.3	_	0.1 V _{CC}	V	$V_{\rm CC}$ = 1.8 V to 5.5 V	-
		P1 ₀ to P1 ₇ ,	-0.3	_	0.3 V _{CC}	V	V_{CC} = 4.0 V to 5.5 V	-
		$\begin{array}{c} {\sf P3}_0 \mbox{ to } {\sf P3}_7, \\ {\sf P4}_0 \mbox{ to } {\sf P4}_3, \\ {\sf P5}_0 \mbox{ to } {\sf P5}_7, \\ {\sf P6}_0 \mbox{ to } {\sf P6}_7, \\ {\sf P7}_0 \mbox{ to } {\sf P7}_7, \\ {\sf P8}_0 \mbox{ to } {\sf P8}_7, \\ {\sf PA}_0 \mbox{ to } {\sf PA}_3, \\ {\sf PB}_0 \mbox{ to } {\sf PB}_7 \end{array}$	-0.3	_	0.2 V _{CC}		Except the above	
Output high voltage	V _{OH}	P1 ₀ to P1 ₇ , P3 ₀ to P3 ₇ ,	V _{CC} – 1.0	—	_	V	V_{CC} = 4.0 V to 5.5 V -I _{OH} = 1.0 mA	
		P4 ₀ to P4 ₂ , P5 ₀ to P5 ₇ , P6 ₀ to P6 ₇ ,	V _{CC} - 0.5	—	_		V_{CC} = 4.0 V to 5.5 V -I _{OH} = 0.5 mA	-
		$P7_0 \text{ to } P7_7,$ $P7_0 \text{ to } P7_7,$ $P8_0 \text{ to } P8_7,$ $PA_0 \text{ to } PA_3$	V _{CC} – 0.3	—	—		-I _{OH} = 0.1 mA	-

				Valu	es			
Item	Symbol	Applicable Pins	Min	Тур	Max	Unit	Test Condition	Notes
Output low voltage	V _{OL}	P1 ₀ to P1 ₇ , P4 ₀ to P4 ₂	_	—	0.6	V	V _{CC} = 4.0 V to 5.5 V I _{OL} = 1.6 mA	
			_	_	0.5		I _{OL} = 0.4 mA	-
		$\begin{array}{c} {\sf P5}_0 \text{ to } {\sf P5}_7, {\sf P6}_0 \\ {\sf to } {\sf P6}_7, {\sf P7}_0 \text{ to} \\ {\sf P7}_7, {\sf P8}_0 \text{ to } {\sf P8}_7, \\ {\sf PA}_0 \text{ to } {\sf PA}_3 \end{array}$	_	—	0.5		I _{OL} = 0.4 mA	-
		P3 ₀ to P3 ₇	_	-	1.5		V _{CC} = 4.0 V to 5.5 V I _{OL} = 10 mA	-
			_	—	0.6		V _{CC} = 4.0 V to 5.5 V I _{OL} = 1.6 mA	-
			_	—	0.5		I _{OL} = 0.4 mA	
Input/output	I _{IL}	RES, P4 ₃	_	—	20.0	μA	V _{IN} = 0.5 V to	*2
leakage current			_	_	1.0		$V_{CC} - 0.5 V$	*1
		$OSC_1, X_1,$ $P1_0$ to $P1_7,$ $P3_0$ to $P3_7,$ $P4_0$ to $P4_2,$ $P5_0$ to $P5_7,$ $P6_0$ to $P6_7,$ $P7_0$ to $P7_7,$ $P8_0$ to $P8_7,$ PA_0 to PA_3		_	1.0	μA	V _{IN} = 0.5 V to V _{CC} – 0.5 V	_
		PB ₀ to PB ₇	_	_	1.0		$V_{IN} = 0.5 V \text{ to}$ AV _{CC} - 0.5 V	-
Pull-up MOS	−l _p	P3 ₀ to P3 ₇ ,	50.0	_	300.0	μA	V _{CC} = 5 V, V _{IN} = 0 V	
current		P5 ₀ to P5 ₇ , P6 ₀ to P6 ₇	_	35.0	_		V _{CC} = 2.7 V, V _{IN} = 0 V	Reference value

				Valu	es			
ltem	Symbol	Applicable Pins	Min	Тур	Мах	Unit	Test Condition	Notes
Input capacitance	C _{IN}	All input pins except power supply, RES, P4 ₃ , PB ₀ to PB ₇	_		15.0	pF	f = 1MHz, $V_{IN} = 0 V,$ $T_a = 25^{\circ}C$	
		RES	_	_	80.0	_		*2
			—	_	15.0	_		*1
		P4 ₃	_	_	50.0	_		*2
			—	_	15.0	_		*1
		PB ₀ to PB ₇	_	_	15.0	_		
Active mode current	I _{OPE1}	V _{CC}	_	4.5	6.5	mA	Active (high-speed) mode $V_{CC} = 5 V$, $f_{OSC} = 10MHz$	*3 *5 *6
dissipation	I _{OPE2}	V _{CC}	—	1.3	2.0	mA		*3 *5 *6
Sleep mode current dissipation	I _{SLEEP}	V _{CC}	_	2.5	4.0	mA	V _{CC} =5 V, f _{OSC} =10MHz	*3 *5 *6
Subactive mode current dissipation	I _{SUB}	V _{cc}	_	15	30	μA	V_{CC} = 2.7 V, LCD on 32 kHz crystal oscillator ($\phi_{SUB}=\phi_w/2$)	*3 *5 *6
				8	_	μΑ	V_{CC} = 2.7 V, LCD on 32 kHz crystal oscillator ($\phi_{SUB} = \phi_w/8$)	*3 *5 Reference value *6
Subsleep mode current dissipation	I _{SUBSP}	V _{cc}	_	7.5	16	μA	V_{CC} = 2.7 V, LCD on 32 kHz crystal oscillator $(\phi_{SUB}=\phi_w/2)$	*3 *5 *6

Section 15 Electrical Characteristics

				Valu	es				
Item	Symbol	Applicable Pins	Min	Тур	Max	Unit	Test Condition	Notes	
Watch mode current dissipation	I _{WATCH}	V _{cc}	_	2.8	6	μA	V _{CC} = 2.7 V, 3 2 kHz crystal oscillator LCD not used	*3 *5 *6	
Standby mode current dissipation	I _{STBY}	V _{cc}	_	1.0	5.0	μA	32 kHz crystal oscillator not used	*3 *5	
RAM data retaining voltage	V _{RAM}	V _{CC}	1.5	_	_	V		*3 *5	
-	I _{OL}	Output pins except port 3	_	_	2.0	mA	$V_{\rm CC}$ = 4.0 V to 5.5 V		
		Port 3	_	—	10.0	_	$V_{\rm CC}$ = 4.0 V to 5.5 V		
(per pin)		All output pins	_	_	0.5	_			
Allowable output low	ΣI_{OL}	Output pins except port 3	_	_	40.0	mA	V_{CC} = 4.0 V to 5.5 V		
current (total)		Port 3	_	—	80.0	_	$V_{\rm CC}$ = 4.0 V to 5.5 V		
(total)		All output pins	_	_	20.0	_			
Allowable	–I _{ОН}	All output pins		_	2.0	mA	$V_{\rm CC}$ = 4.0 V to 5.5 V		
output high current (per pin)			_	_	0.2		Except the above		
Allowable	$\Sigma - I_{OH}$	All output pins	_	—	15.0	mA	V_{CC} = 4.0 V to 5.5 V		
output high current (total)	<i>—</i> •он <i>•</i>		-		_	10.0	_	Except the above	

lies to the Mask ROM products. Notes: T. Ap

2. Applies to the HD6473827R.

3. Pin states during current measurement.

	RES		Other	LCD Power	
Mode	Pin	Internal State	Pins	Supply	Oscillator Pins
Active (high-speed) mode (I _{OPE1})	V_{CC}	Only CPU operates	V _{CC}	Halted	System clock oscillator: crystal
Active (medium- speed) mode (I _{OPE2})					Subclock oscillator: Pin X ₁ = GND
Sleep mode	V_{CC}	Only timers operate	V_{CC}	Halted	_
Subactive mode	V_{CC}	Only CPU operates	V_{CC}	Halted	System clock oscillator:
Subsleep mode	V_{CC}	Only timers operate, CPU stops	V _{CC}	Halted	crystal Subclock oscillator:
Watch mode	V_{CC}	Only time base operates, CPU stops	V _{CC}	Halted	[–] crystal
Standby mode	V_{CC}	CPU and timers both stop	V _{CC}	Halted	System clock oscillator: crystal
					Subclock oscillator: Pin X ₁ = GND

- 4. The guaranteed temperature as an electrical characteristic for Die products is 75°C.
- 5. Excludes current in pull-up MOS transistors and output buffers.
- 6. When internal step-down circuit is used.



15.2.3 AC Characteristics

Table 15.3 lists the control signal timing, and tables 15.4 lists the serial interface timing.

Table 15.3 Control Signal Timing

 $V_{CC} = 1.8 \text{ V}$ to 5.5 V, $AV_{CC} = 1.8 \text{ V}$ to 5.5 V, $V_{SS} = AV_{SS} = 0.0 \text{ V}$, $T_a = -20^{\circ}\text{C}$ to $+75^{\circ}\text{C}^{*4}$ (including subactive mode) unless otherwise indicated.

		Applicable		Values	5			Reference
Item	Symbol	••	Min	Тур	Max	Unit	Test Condition	Figure
System clock	f _{OSC}	OSC_1, OSC_2	2	_	16	MHz	V_{CC} = 4.5 V to 5.5 V	*2
oscillation frequency			2	_	10	-	$V_{\rm CC}$ = 2.7 V to 5.5 V	
irequency			2	_	4	-	$V_{\rm CC}$ = 1.8 V to 5.5 V	
OSC clock (osc) cycle time	t _{osc}	OSC ₁ , OSC ₂	62.5	_	500 (1000)	ns	V_{CC} = 4.5 V to 5.5 V	Figure 15.1 *2*3
			100	_	500 (1000)	-	V _{CC} = 2.7 V to 5.5 V	Figure 15.1
			250	_	500 (1000)	-	V _{CC} = 1.8 V to 5.5 V	*3
System clock (t _{cyc}		2	_	128	t _{osc}		
cycle time			_	_	244.1	μs	-	
Subclock oscillation frequency	f _W	X ₁ , X ₂	—	32.768 or 38.4	_	kHz		
Watch clock (ϕ_W) cycle time	t _W	X ₁ , X ₂	_	30.5 or 26.0	—	μs		Figure 15.1
Subclock (ϕ_{SUB}) cycle time	t _{subcyc}		2	_	8	t _W		*1
Instruction cycle			2	_	—	t _{cyc}		
time						t _{subcyc}		
Oscillation stabilization time	t _{rc}	OSC ₁ , OSC ₂	_	20	45	μs	Figure 15.9 V _{CC} = 2.2 V to 5.5 V	Figure 15.9 *2
			_	0.1	8	ms	Figure 15.9 V _{CC} = 2.2 V to 5.5 V	Figure 15.9
			_	_	50	ms	Except the above	-

Section 15 Electrical Characteristics

		Applicable		Value	6			Reference
ltem	Symbol		Min	Тур	Мах	Unit	Test Condition	Figure
Oscillation stabilization time	t _{rc}	X ₁ , X ₂	_	_	2.0	S		
External clock high width	t _{CPH}	OSC ₁	25	_	_	ns	V_{CC} = 4.5 V to 5.5 V	Figure 15.1 *2
			40	_	_	_	V _{CC} = 2.7 V to 5.5 V	Figure 15.1
			100	_	_	_	$V_{\rm CC}$ = 1.8 V to 5.5 V	-
		X ₁	—	15.26 or 13.02	—	μs		-
External clock low width	t _{CPL}	OSC ₁	25	_	_	ns	$V_{\rm CC}$ = 4.5 V to 5.5 V	Figure 15.1 *2
			40	_	_	_	$V_{\rm CC}$ = 2.7 V to 5.5 V	Figure 15.1
			100	_	_	_	$V_{\rm CC}$ = 1.8 V to 5.5 V	-
		X ₁	_	15.26 or 13.02	_	μs		-
External clock rise time	t _{CPr}	OSC ₁	—	_	6	ns	V_{CC} = 4.5 V to 5.5 V	Figure 15.1 *2
			_	_	10	_	$V_{\rm CC}$ = 2.7 V to 5.5 V	Figure 15.1
			_	_	25		$V_{\rm CC}$ = 1.8 V to 5.5 V	-
		X ₁	—	—	55.0	ns		-
External clock fall time	t _{CPf}	OSC ₁	_		6	ns	$V_{\rm CC}$ = 4.5 V to 5.5 V	Figure 15.1 *2
			_	_	10	_	V _{CC} = 2.7 V to 5.5 V	Figure 15.1
			_		25	_	$V_{\rm CC}$ = 1.8 V to 5.5 V	-
		X ₁	—	_	55.0	ns		-
Pin RES low width	t _{REL}	RES	10	_	_	t _{cyc}		Figure 15.2

		Applicable		Values	\$			Reference
ltem	Symbol	••	Min	Тур	Max	Unit	Test Condition	Figure
Input pin high width	t _{iH}	$\label{eq:response} \begin{array}{c} \overline{IRQ}_0 \text{ to } \overline{IRQ}_4, \\ \overline{WKP}_0 \text{ to } \overline{WKP}_7 \\ \overline{ADTRG}, TMIC \\ TMIF, TMIG, \\ AEVL, AEVH \end{array}$	2	_		t _{cyc} t _{subcyc}		Figure 15.3
Input pin low width	t _{IL}	$\label{eq:response} \begin{array}{c} \overline{IRQ}_0 \text{ to } \overline{IRQ}_4, \\ \overline{WKP}_0 \text{ to } \overline{WKP}_7, \\ \overline{ADTRG}, \text{ TMIC}, \\ \overline{TMIF}, \overline{TMIG}, \\ AEVL, AEVH \end{array}$	2	_	_	t _{cyc} t _{subcyc}		Figure 15.3
UD pin minimum modulation width	t _{UDH} t _{UDL}	UD	4	—	_	t _{cyc} t _{subcyc}		Figure 15.4

Notes: 1. Selected with SA1 and SA0 of system clock control register 2 (SYSCR2).

- 2. Internal power supply step-down circuit not used
- 3. Figures in parentheses are the maximum t_{OSC} rate with external clock input.
- 4. The guaranteed temperature as an electrical characteristic for Die products is 75°C.

Table 15.4 Serial Interface (SCI3-1, SCI3-2) Timing

 $V_{CC} = 1.8 \text{ V}$ to 5.5 V, $AV_{CC} = 1.8 \text{ V}$ to 5.5 V, $V_{SS} = AV_{SS} = 0.0 \text{ V}$, $T_a = -20^{\circ}\text{C}$ to $+75^{\circ}\text{C}^{*2}$ (including subactive mode) unless otherwise indicated.

		Values						Reference
ltem		Symbol	Min	Тур	Мах	Unit	Test Conditions	Figure
Input clock	Asynchronous	t _{scyc}	4		—	$t_{\rm cyc}$ or		Figure 15.5
cycle	Synchronous		6		_	[–] t _{subcyc}		
Input clock pulse width		t _{SCKW}	0.4		0.6	t _{scyc}		Figure 15.5
Transmit dat	,	t _{TXD}			1	t _{cyc} or	V_{CC} = 4.0 V to 5.5 V	Figure 15.6
(synchronous	s)		_		1	[–] t _{subcyc}	Except the above	_
Receive data		t _{RXS}	200.0		_	ns	V_{CC} = 4.0 V to 5.5 V	Figure 15.6 *1
(synchronous)			400.0		_	_	Except the above	Figure 15.6
	Receive data hold time		200.0		—	ns	V_{CC} = 4.0 V to 5.5 V	Figure 15.6 *1
(synchronous	S)		400.0		_	_	Except the above	Figure 15.6

Notes: 1. When internal step-down circuit is not used.

2. The guaranteed temperature as an electrical characteristic for Die products is 75°C.

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15.2.4 A/D Converter Characteristics

Table 15.5 shows the A/D converter characteristics.

Table 15.5 A/D Converter Characteristics

 $V_{CC} = 1.8 \text{ V to } 5.5 \text{ V}, V_{SS} = AV_{SS} = 0.0 \text{ V}, T_a = -20^{\circ}\text{C to} +75^{\circ}\text{C}^{*6}$ (including subactive mode) unless otherwise indicated.

		Applicable		Va	lues			
Item	Symbol		Min	Тур	Max	Unit	Test Condition	Notes
Analog power supply voltage	AV_{CC}	AV_{CC}	1.8	_	5.5	V		*1
Analog input voltage	AV _{IN}	AN ₀ to AN ₇	- 0.3		AV _{CC} + 0.3	V		
Analog power	Al _{OPE}	AV _{CC}	_	_	1.5	mA	$AV_{CC} = 5 V$	
supply current	AI _{STOP1}	AV _{CC}	_	600		μA		*2
								Reference value
	AI _{STOP2}	AV _{CC}	_	_	5	μA		*3
Analog input capacitance	C _{AIN}	AN ₀ to AN ₇	_	_	15.0	рF		
Allowable signal source impedance	R _{AIN}		_	_	10.0	kΩ		
Resolution (data length)			—	—	10	bit		
Nonlinearity error			—	_	±2.5	LSB	AV _{CC} = 2.7 V to 5.5 V V _{CC} = 2.7 V to 5.5 V	*4
			_	_	±5.5	_	AV _{CC} = 2.0 V to 5.5 V V _{CC} = 2.0 V to 5.5 V	_
			_	_	±7.5	-	Except the above	*5
Quantization error			—	_	±0.5	LSB		

		Applicable Pins		Va	lues			Notes
Item	Symbol		Min	Тур	Max	Unit	Test Condition	
Absolute accuracy			_	_	±3.0	LSB	AV _{CC} = 3.0 V to 5.5 V V _{CC} = 3.0 V to 5.5 V	*4
			_	_	±6.0		AV_{CC} = 2.0 V to 5.5 V V _{CC} = 2.0 V to 5.5 V	_
			_	_	±8.0		Except the above	*5
Conversion time			12.4	_	124	μs	AV _{CC} = 2.7 V to 5.5 V V _{CC} = 2.7 V to 5.5 V	*4
			62	_	124		Except the above	_

Notes: 1. Set $AV_{CC} = V_{CC}$ when the A/D converter is not used.

2. Al_{STOP1} is the current in active and sleep modes while the A/D converter is idle.

3. AI_{STOP2} is the current at reset and in standby, watch, subactive, and subsleep modes while the A/D converter is idle.

4. When internal step-down circuit is not used.

5. Conversion time 62 µs

6. The guaranteed temperature as an electrical characteristic for Die products is 75°C.

15.2.5 LCD Characteristics

Table 15.6 shows the LCD characteristics.

Table 15.6 LCD Characteristics

 $V_{CC} = 1.8 \text{ V}$ to 5.5 V, $AV_{CC} = 1.8 \text{ V}$ to 5.5 V, $V_{SS} = AV_{SS} = 0.0 \text{ V}$, $T_a = -20^{\circ}\text{C}$ to $+75^{\circ}\text{C}^{*3}$ (including subactive mode) unless otherwise specified.

		Applicable	Test		Value	S		
ltem	Symbol	Pins	Conditions	Min	Тур	Max	Unit	Notes
Segment driver drop voltage	V _{DS}	SEG ₁ to SEG ₃₂	$I_D = 2 \ \mu A$ V ₁ = 2.7 to 5.5 V	_	_	0.6	V	*1
Common driver drop voltage	V _{DC}	COM ₁ to COM ₄	$I_D = 2 \ \mu A$ V ₁ = 2.7 to 5.5 V	—	—	0.3	V	*1
LCD power supply split-resistance	R _{LCD}		Between V_1 and V_{SS}	0.5	3.0	9.0	MΩ	
Liquid crystal display voltage	V _{LCD}	V ₁		2.2	_	5.5	V	*2

Notes: 1. The voltage drop from power supply pins V_1 , V_2 , V_3 , and V_{SS} to each segment pin or common pin.

2. When the liquid crystal display voltage is supplied from an external power source, ensure that the following relationship is maintained: $V_1 \ge V_2 \ge V_3 \ge V_{SS}$.

3. The guaranteed temperature as an electrical characteristic for Die products is 75°C.



Table 15.7 AC Characteristics for External Segment Expansion

 $V_{CC} = 1.8 \text{ V}$ to 5.5 V, $V_{SS} = 0.0 \text{ V}$, $T_a = -20^{\circ}\text{C}$ to $+75^{\circ}\text{C}^{*2}$ (including subactive mode) unless otherwise specified.

		Applicable	Test Values		5		Reference	
ltem	Symbol	Pins	Conditions	Min	Тур	Мах	Unit	Figure
Clock high width	t _{сwн}	CL ₁ , CL ₂	*1	800	_	_	ns	Figure 15.7
Clock low width	t _{CWL}	CL ₂	*1	800	_		ns	Figure 15.7
Clock setup time	t _{CSU}	CL ₁ , CL ₂	*1	500	_		ns	Figure 15.7
Data setup time	t _{su}	DO	*1	300	_	_	ns	Figure 15.7
Data hold time	t _{DH}	DO	*1	300	—	—	ns	Figure 15.7
M delay time	t _{DM}	М	*1	-1000	_	1000	ns	Figure 15.7
Clock rise and fall times	t _{CT}	CL ₁ , CL ₂		_	-	170	ns	Figure 15.7

Notes: 1. Value when the frame frequency is set to between 30.5 Hz and 488 Hz.

2. The guaranteed temperature as an electrical characteristic for Die products is 75°C.

15.3 H8/3827R Group Absolute Maximum Ratings (Wide-Range Specification)

Table 15.8 lists the absolute maximum ratings.

Table 15.8 Absolute Maximum Ratings

ltem		Symbol	Value	Unit
Power supply voltage		V_{CC} , CV_{CC}	-0.3 to +7.0	V
Analog power s	upply voltage	AV _{CC}	-0.3 to +7.0	V
Programming voltage		V _{PP}	–0.3 to +13.0	V
Input voltage	Ports other than Port B	Vin	–0.3 to V _{CC} +0.3	V
	Port B	AV _{in}	–0.3 to AV _{CC} +0.3	V
Operating temperature		T _{opr}	-40 to +85	°C
Storage temper	ature	T _{stg}	–55 to +125	°C

Note: Permanent damage may occur to the chip if maximum ratings are exceeded. Normal operation should be under the conditions specified in Electrical Characteristics. Exceeding these values can result in incorrect operation and reduced reliability.



15.4 H8/3827R Group Electrical Characteristics (Wide-Range Specification)

15.4.1 Power Supply Voltage and Operating Range

The power supply voltage and operating range are indicated by the shaded region in the figures.

1. Power Supply Voltage and Oscillator Frequency Range





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2. Power Supply Voltage and Operating Frequency Range





Watch mode (except CPU)

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3. Analog Power Supply Voltage and A/D Converter Operating Range



- Active (high-speed) mode
- Sleep (high-speed) mode
- Internal power supply step-down circuit not used and used



- Active (medium-speed) mode
- Sleep (medium-speed) mode
- Internal power supply step-down circuit not used



- Active (medium-speed) mode
- Sleep (medium-speed) mode
- Internal power supply step-down circuit used

15.4.2 DC Characteristics

Table 15.9 lists the DC characteristics.

Table 15.9 DC Characteristics

 $V_{CC} = 1.8 \text{ V}$ to 5.5 V, $AV_{CC} = 1.8 \text{ V}$ to 5.5 V, $V_{SS} = AV_{SS} = 0.0 \text{ V}$, $T_a = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$ (including subactive mode) unless otherwise indicated.

				Valu	es			
Item	Symbol	Applicable Pins	Min	Тур	Мах	Unit	Test Condition	Notes
Input high	V _{IH}	RES,	0.8 V _{CC}	_	Vcc + 0.3	V	$V_{\rm CC}$ = 4.0 V to 5.5 V	
voltage		$\label{eq:wkp_0} \begin{array}{l} \mbox{WKP}_0 \mbox{ to } \mbox{WKP}_7, \\ \hline \mbox{IRQ}_0 \mbox{ to } \mbox{IRQ}_4, \\ \mbox{AEVL}, \mbox{ AEVH}, \\ \mbox{TMIC}, \mbox{TMIF}, \\ \hline \mbox{TMIG} \\ \mbox{SCK}_{31}, \mbox{SCK}_{32}, \\ \hline \mbox{ADTRG} \end{array}$	0.9 V _{CC}	_	V _{CC} + 0.3		Except the above	
		RXD ₃₁ , RXD ₃₂ ,	$0.7 V_{CC}$	—	V _{CC} + 0.3	V	V_{CC} = 4.0 V to 5.5 V	
	UD	UD	0.8 V _{CC}	—	V _{CC} + 0.3	_	Except the above	
		OSC ₁	$0.8 V_{CC}$	—	V _{CC} + 0.3	V	V_{CC} = 4.0 V to 5.5 V	
			$0.9 V_{CC}$	—	V _{CC} + 0.3		Except the above	
		X ₁	$0.9 V_{CC}$	—	V _{CC} + 0.3	V	V_{CC} = 1.8 V to 5.5 V	
		P1 ₀ to P1 ₇ ,	0.7 V _{CC}	—	V _{CC} + 0.3	V	V_{CC} = 4.0 V to 5.5 V	
		P3 ₀ to P3 ₇ , P4 ₀ to P4 ₃ , P5 ₀ to P5 ₇ , P6 ₀ to P6 ₇ , P7 ₀ to P7 ₇ , P8 ₀ to P8 ₇ , PA ₀ to PA ₃	0.8 V _{CC}	_	V _{CC} + 0.3	_	Except the above	
		PB ₀ to PB ₇	$0.7 V_{CC}$	—	AV _{CC} + 0.3		$V_{\rm CC}$ = 4.0 V to 5.5 V	
			0.8 V _{CC}	_	AV _{CC} + 0.3		Except the above	

Note: Connect the TEST pin to V_{SS}.

				Values				
Item	Symbol	Applicable Pins	Min	Тур	Max	Unit	Test Condition	Notes
Input low	V _{IL}	RES,	-0.3	_	0.2 V _{CC}	V	V_{CC} = 4.0 V to 5.5 V	
voltage		$\label{eq:wkp_0} \begin{array}{l} \overline{WKP}_0 \text{ to } \overline{WKP}_7, \\ \overline{IRQ}_0 \text{ to } \overline{IRQ}_4, \\ AEVL, AEVH, \\ TMIC, TMIF, \\ TMIG \\ SCK_{31}, SCK_{32}, \\ \overline{ADTRG} \end{array}$	-0.3	_	0.1 V _{CC}	_	Except the above	-
		RXD ₃₁ , RXD ₃₂ ,	-0.3	—	0.3 V _{CC}	V	V_{CC} = 4.0 V to 5.5 V	-
		UD	-0.3	_	$0.2 V_{CC}$		Except the above	
		OSC ₁	-0.3	_	0.2		When internal step- down circuit is used.	
			-0.3	—	0.2 V _{CC}	V	$V_{\rm CC}$ = 4.0 V to 5.5 V	-
			-0.3	—	0.1 V _{CC}	_	Except the above	-
		X ₁	-0.3	—	0.1 V _{CC}	V	$V_{\rm CC}$ = 1.8 V to 5.5 V	-
		P1 ₀ to P1 ₇ ,	-0.3	—	0.3 V _{CC}	V	V_{CC} = 4.0 V to 5.5 V	-
		$\begin{array}{c} {\sf P3}_0 \mbox{ to } {\sf P3}_7, \\ {\sf P4}_0 \mbox{ to } {\sf P4}_3, \\ {\sf P5}_0 \mbox{ to } {\sf P5}_7, \\ {\sf P6}_0 \mbox{ to } {\sf P6}_7, \\ {\sf P7}_0 \mbox{ to } {\sf P7}_7, \\ {\sf P8}_0 \mbox{ to } {\sf P8}_7, \\ {\sf P4}_0 \mbox{ to } {\sf P4}_3, \\ {\sf PB}_0 \mbox{ to } {\sf P8}_7 \end{array}$	-0.3	_	0.2 V _{CC}		Except the above	
Output high voltage	V _{OH}	$P1_0$ to $P1_7$, $P3_0$ to $P3_7$,	V _{CC} – 1.0	_	_	V	V_{CC} = 4.0 V to 5.5 V -I _{OH} = 1.0 mA	
		$P4_0$ to $P4_2$, $P5_0$ to $P5_7$, $P6_0$ to $P6_7$,	V _{CC} – 0.5	—	_		V _{CC} = 4.0 V to 5.5 V -I _{OH} = 0.5 mA	-
		P_{0}^{0} to P_{7}^{0} , P_{1}^{0} to P_{7}^{0} , P_{1}^{0} to P_{1}^{0} , P_{1}^{0} to P_{1}^{0} , P_{2}^{0} to P_{3}^{0}	V _{CC} - 0.3	_	_	_	-I _{OH} = 0.1 mA	-

				Value	es			
ltem	Symbol	Applicable Pins	Min	Тур	Max	Unit	Test Condition	Notes
Output low voltage	V _{OL}	P1 ₀ to P1 ₇ , P4 ₀ to P4 ₂	_	_	0.6	V	V _{CC} = 4.0 V to 5.5 V I _{OL} = 1.6 mA	
			_	—	0.5		I _{OL} = 0.4 mA	-
		$\begin{array}{c} {\sf P5}_0 \text{ to } {\sf P5}_7, {\sf P6}_0 \\ {\sf to } {\sf P6}_7, {\sf P7}_0 \text{ to} \\ {\sf P7}_7, {\sf P8}_0 \text{ to } {\sf P8}_7, \\ {\sf PA}_0 \text{ to } {\sf PA}_3 \end{array}$	—	_	0.5	_	I _{OL} = 0.4 mA	-
		P3 ₀ to P3 ₇	_	_	1.5		V_{CC} = 4.0 V to 5.5 V I _{OL} = 10 mA	-
			_	_	0.6		V_{CC} = 4.0 V to 5.5 V I_{OL} = 1.6 mA	-
			_	—	0.5		I _{OL} = 0.4 mA	
Input/output	I _{IL}	RES, P4 ₃	_	_	20.0	μA	V _{IN} = 0.5 V to	*2
leakage current			_	_	1.0		$V_{CC} - 0.5 V$	*1
Current		$\begin{array}{c} OSC_1, X_1, \\ P1_0 \ to \ P1_7, \\ P3_0 \ to \ P3_7, \\ P4_0 \ to \ P4_2, \\ P5_0 \ to \ P5_7, \\ P6_0 \ to \ P6_7, \\ P7_0 \ to \ P7_7, \\ P8_0 \ to \ P8_7, \\ PA_0 \ to \ PA_3 \end{array}$	_	-	1.0	μΑ	V _{IN} = 0.5 V to V _{CC} – 0.5 V	
		PB ₀ to PB ₇	_	—	1.0		$V_{IN} = 0.5 V$ to AV _{CC} - 0.5 V	
Pull-up MOS	-I _p	P1 ₀ to P1 ₇ , P3 ₀ to P3 ₇ ,	50.0	_	300.0	μA	V _{CC} = 5 V, V _{IN} = 0 V	
current		P5 ₀ to P5 ₇ , P6 ₀ to P6 ₇	_	35.0	_		V _{CC} = 2.7 V, V _{IN} = 0 V	Reference value

Section 15 Electrical Characteristics

				Valu	Values			
Item	Symbol	Applicable Pins	Min	Тур	Max	Unit	Test Condition	Notes
Input capacitance	C _{IN}	All input pins except power supply, RES, P4 ₃ , PB ₀ to PB ₇	_	_	15.0	pF	f = 1MHz, $V_{IN} = 0 V,$ $T_a = 25^{\circ}C$	
		RES	_	_	80.0	_		*2
			_	_	15.0	_		*1
		P4 ₃	_	—	50.0			*2
				_	15.0			*1
		PB ₀ to PB ₇	_	_	15.0			
Active mode current	I _{OPE1}	V _{CC}	—	4.5	6.5	mA	Active (high-speed) mode $V_{CC} = 5 V$, $f_{OSC} = 10MHz$	*3 *4 *5
dissipation	I _{OPE2}	V _{CC}		1.3	2.0	mA	Active (medium- speed) mode $V_{CC} = 5 V$, $f_{OSC} = 10MHz$ Divided by 128	*3 *4 *5
Sleep mode current dissipation	I _{SLEEP}	V _{CC}	_	2.5	4.0	mA	V _{CC} =5 V, f _{OSC} =10MHz	*3 *4 *5
Subactive mode current dissipation	I _{SUB}	V _{cc}	_	15	30	μA	V_{CC} = 2.7 V, LCD on 32 kHz crystal oscillator ($\phi_{SUB}=\phi_w/2$)	*3 *4 *5
				8	_	μA	V_{CC} = 2.7 V, LCD on 32 kHz crystal oscillator ($\phi_{SUB}=\phi_w/8$)	*3 *4 Reference value *5
Subsleep mode current dissipation	I _{SUBSP}	V _{cc}	—	7.5	16	μA	V_{CC} = 2.7 V, LCD on 32 kHz crystal oscillator ($\phi_{SUB}=\phi_w/2$)	*3 *4 *5

				Valu	es			
ltem	Symbol	Applicable Pins	Min	Тур	Max	Unit	Test Condition	Notes
Watch mode current dissipation	I _{WATCH}	V _{CC}	_	2.8	6	μA	V _{CC} = 2.7 V 3 2 kHz crystal oscillator LCD not used	*3 *4 *5
Standby mode current dissipation	I _{STBY}	V _{cc}	_	1.0	5.0	μA	32 kHz crystal oscillator not used	*3 *4
RAM data retaining voltage	V _{RAM}	V _{CC}	1.5	_	_	V		*3 *4
Allowable I _{OL} output low		Output pins except port 3	_	—	2.0	mA	$V_{\rm CC}$ = 4.0 V to 5.5 V	
current (per pin)		Port 3	—	—	10.0		$V_{\rm CC}$ = 4.0 V to 5.5 V	
(per pin)		All output pins		—	0.5			
Allowable output low	ΣI_{OL}	Output pins except port 3	_	—	40.0	mA	V_{CC} = 4.0 V to 5.5 V	
current (total)		Port 3		_	80.0		$V_{\rm CC}$ = 4.0 V to 5.5 V	
(iotal)		All output pins	—	—	20.0			
Allowable	–I _{OH}	All output pins	—	_	2.0	mA	$V_{\rm CC}$ = 4.0 V to 5.5 V	
output high current (per pin)			_	_	0.2		Except the above	
Allowable	$\Sigma - I_{OH}$	All output pins	_	_	15.0	mA	$V_{\rm CC}$ = 4.0 V to 5.5 V	
output high current (total)			_	—	10.0	_	Except the above	

Section 15 Electrical Characteristics

2. Applies to the HD6473827R.

Mode	RES Pin	Internal State	Other Pins	LCD Power Supply	Oscillator Pins
Active (high-speed) mode (I _{OPE1})	V_{CC}	Only CPU operates	V _{CC}	Halted	System clock oscillator: crystal
Active (medium- speed) mode (I _{OPE2})					Subclock oscillator: Pin X ₁ = GND
Sleep mode	V_{CC}	Only timers operate	V_{CC}	Halted	_
Subactive mode	V_{CC}	Only CPU operates	V_{CC}	Halted	System clock oscillator:
Subsleep mode	V_{CC}	Only timers operate, CPU stops	V _{CC}	Halted	crystal Subclock oscillator:
Watch mode	V_{CC}	Only time base operates, CPU stops	V_{CC}	Halted	[–] crystal
Standby mode	V_{CC}	CPU and timers both stop	V _{CC}	Halted	System clock oscillator: crystal
					Subclock oscillator: Pin X ₁ = GND

3. Pin states during current measurement.

4. Excludes current in pull-up MOS transistors and output buffers.

5. When internal step-down circuit is used.

15.4.3 AC Characteristics

Table 15.10 lists the control signal timing, and tables 15.11 lists the serial interface timing.

Table 15.10 Control Signal Timing

 $V_{CC} = 1.8 \text{ V}$ to 5.5 V, $AV_{CC} = 1.8 \text{ V}$ to 5.5 V, $V_{SS} = AV_{SS} = 0.0 \text{ V}$, $T_a = -40^{\circ}\text{C}$ to +85°C (including subactive mode) unless otherwise indicated.

		Applicable		Values	6			Reference
Item	Symbol	••	Min	Тур	Max	Unit	Test Condition	Figure
System clock	f _{OSC}	OSC_1, OSC_2	2	_	16	MHz	V_{CC} = 4.5 V to 5.5 V	*2
oscillation frequency			2		10	-	$V_{\rm CC}$ = 2.7 V to 5.5 V	
nequency			2		4	=	$V_{\rm CC}$ = 1.8 V to 5.5 V	-
OSC clock (ϕ_{OSC}) cycle time	tosc	OSC ₁ , OSC ₂	62.5	_	500 (1000)	ns	V_{CC} = 4.5 V to 5.5 V	Figure 15.1 *2*3
			100	_	500 (1000)	_	V _{CC} = 2.7 V to 5.5 V	Figure 15.1
			250	_	500 (1000)	-	$V_{\rm CC}$ = 1.8 V to 5.5 V	*3
System clock (t _{cyc}		2	_	128	t _{osc}		
cycle time			_		244.1	μs	-	
Subclock oscillation frequency	f _W	X ₁ , X ₂	—	32.768 or 38.4	_	kHz		
Watch clock (ϕ_W) cycle time	t _W	X ₁ , X ₂	_	30.5 or 26.0	_	μs		Figure 15.1
Subclock (ϕ_{SUB}) cycle time	t _{subcyc}		2	_	8	t _W		*1
Instruction cycle time			2	_	—	t _{cyc} t _{subcyc}		
Oscillation stabilization time	t _{rc}	OSC ₁ , OSC ₂	_	20	45	μs	Figure 15.9 V _{CC} = 2.2 V to 5.5 V	Figure 15.9 *2
			_	0.1	8	ms	Figure 15.9 V _{CC} = 2.2 V to 5.5 V	Figure 15.9
			_	—	50	ms	Except the above	-

		Applicable		Values	5			Reference
Item	Symbol		Min	Тур	Мах	Unit	Test Condition	Figure
Oscillation stabilization time	t _{rc}	X ₁ , X ₂	_	_	2.0	S		
External clock high width	t _{CPH}	OSC ₁	25	_	_	ns	V_{CC} = 4.5 V to 5.5 V	Figure 15.1 *2
			40	_	_	_	V _{CC} = 2.7 V to 5.5 V	Figure 15.1
			100	_	_	_	V _{CC} = 1.8 V to 5.5 V	_
		X ₁	_	15.26 or 13.02	—	μs		-
External clock low width	t _{CPL}	OSC ₁	25	_	_	ns	$V_{\rm CC}$ = 4.5 V to 5.5 V	Figure 15.1 *2
			40	_	_	_	V _{CC} = 2.7 V to 5.5 V	Figure 15.1
			100	_	_	_	V_{CC} = 1.8 V to 5.5 V	-
		X ₁	_	15.26 or 13.02	_	μs		-
External clock rise time	t _{CPr}	OSC ₁	_	_	6	ns	$V_{\rm CC}$ = 4.5 V to 5.5 V	Figure 15.1 *2
			_		10	_	V _{CC} = 2.7 V to 5.5 V	Figure 15.1
			_		25	_	$V_{\rm CC}$ = 1.8 V to 5.5 V	-
		X ₁	_		55.0	ns		-
External clock fall time	t _{CPf}	OSC ₁	_	_	6	ns	$V_{\rm CC}$ = 4.5 V to 5.5 V	Figure 15.1 *2
			_	_	10	_	V _{CC} = 2.7 V to 5.5 V	Figure 15.1
			_	_	25	_	V _{CC} = 1.8 V to 5.5 V	_
		X ₁	_	_	55.0	ns		-
$Pin\ \overline{RES}\ low\ width$	t _{REL}	RES	10	_	_	t _{cyc}		Figure 15.2

Section 15 Electrical Characteristics

		Applicable		Values	5			Reference
Item	Symbol	••	Min	Тур	Мах	Unit	Test Condition	Figure
Input pin high width	t _{iH}	$\label{eq:response} \begin{array}{c} \overline{IRQ}_0 \text{ to } \overline{IRQ}_4, \\ \overline{WKP}_0 \text{ to } \overline{WKP}_7 \\ \overline{ADTRG}, TMIC \\ TMIF, TMIG, \\ AEVL, AEVH \end{array}$	2	_	_	t _{cyc} t _{subcyc}		Figure 15.3
Input pin low width	t _{IL}	$\label{eq:response} \begin{array}{c} \overline{IRQ}_0 \text{ to } \overline{IRQ}_4, \\ \overline{WKP}_0 \text{ to } \overline{WKP}_7, \\ \overline{ADTRG}, TMIC, \\ \overline{TMIF}, TMIG, \\ AEVL, AEVH \end{array}$	2	_	_	t _{cyc} t _{subcyc}		Figure 15.3
UD pin minimum modulation width	t _{UDH} t _{UDL}	UD	4	_	_	t _{cyc} t _{subcyc}		Figure 15.4

Notes: 1. Selected with SA1 and SA0 of system clock control register 2 (SYSCR2).

- 2. Internal power supply step-down circuit not used
- 3. Figures in parentheses are the maximum $t_{\mbox{\scriptsize OSC}}$ rate with external clock input.

Table 15.11 Serial Interface (SCI3-1, SCI3-2) Timing

 $V_{CC} = 1.8$ V to 5.5 V, $AV_{CC} = 1.8$ V to 5.5 V, $V_{SS} = AV_{SS} = 0.0$ V, $T_a = -40^{\circ}$ C to +85°C unless otherwise indicated.

				Values	6			Reference
Item		Symbol	Min	Тур	Мах	Unit	Test Conditions	Figure
Input clock	Asynchronous	t _{scyc}	4	_	_	t _{cyc} or		Figure 15.5
cycle	Synchronous		6		_	t _{subcyc}		
Input clock pulse width		t _{SCKW}	0.4		0.6	t _{scyc}		Figure 15.5
Transmit data delay time		t _{TXD}			1	t _{cyc} or	V_{CC} = 4.0 V to 5.5 V	Figure 15.6
(synchronous	s)		_	_	1	t _{subcyc}	Except the above	_
Receive data setup time		t _{RXS}	200.0	_	—	ns	V_{CC} = 4.0 V to 5.5 V	Figure 15.6*
(synchronous)			400.0	_	_	_	Except the above	Figure 15.6
Receive data hold time (synchronous)		t _{RXH}	200.0	_	_	ns	V_{CC} = 4.0 V to 5.5 V	Figure 15.6*
			400.0			_	Except the above	Figure 15.6

Note: * When internal step-down circuit is not used.

15.4.4 A/D Converter Characteristics

Table 15.12 shows the A/D converter characteristics of the H8/3827R.

Table 15.12 A/D Converter Characteristics

 $V_{CC} = 1.8$ V to 5.5 V, $V_{SS} = AV_{SS} = 0.0$ V, $T_a = -40^{\circ}$ C to $+85^{\circ}$ C unless otherwise indicated.

		Applicable		Va	lues			
ltem	Symbol		Min	Тур	Max	Unit	Test Condition	Notes
Analog power supply voltage	AV_{CC}	AV_{CC}	1.8	_	5.5	V		*1
Analog input voltage	AV _{IN}	AN ₀ to AN ₇	- 0.3	_	AV _{CC} + 0.3	V		
Analog power	Al _{OPE}	AV _{CC}	_	—	1.5	mA	$AV_{CC} = 5 V$	
supply current	AI _{STOP1}	AV _{CC}	_	600	_	μA		*2
								Reference value
	AI _{STOP2}	AV _{CC}	_	_	5	μA		*3
Analog input capacitance	C _{AIN}	AN ₀ to AN ₇	_	_	15.0	pF		
Allowable signal source impedance	R _{AIN}		_	_	10.0	kΩ		
Resolution (data length)			—	—	10	bit		
Nonlinearity error			—	_	±2.5	LSB	AV _{CC} = 2.7 V to 5.5 V V _{CC} = 2.7 V to 5.5 V	*4
			_	_	±5.5	_	AV _{CC} = 2.0 V to 5.5 V V _{CC} = 2.0 V to 5.5 V	_
			_	—	±7.5	_	Except the above	*5
Quantization error			_	—	±0.5	LSB		

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		Applicable	Values					
Item	Symbol	••	Min	Тур	Max	Unit	Test Condition	Notes
Absolute accuracy			_	_	±3.0	LSB	AV _{CC} = 2.7 V to 5.5 V V _{CC} = 2.7 V to 5.5 V	*4
			_	_	±6.0		AV _{CC} = 2.0 V to 5.5 V V _{CC} = 2.0 V to 5.5 V	_
			_	_	±8.0		Except the above	*5
Conversion time			12.4	_	124	μs	AV _{CC} = 2.7 V to 5.5 V V _{CC} = 2.7 V to 5.5 V	*4
			62	_	124		Except the above	-

Notes: 1. Set $AV_{CC} = V_{CC}$ when the A/D converter is not used.

2. Al_{STOP1} is the current in active and sleep modes while the A/D converter is idle.

3. Al_{STOP2} is the current at reset and in standby, watch, subactive, and subsleep modes while the A/D converter is idle.

4. When internal step-down circuit is not used.

5. Conversion time 62 μ s



15.4.5 LCD Characteristics

Table 15.13 shows the LCD characteristics.

Table 15.13 LCD Characteristics

 $V_{CC} = 1.8 \text{ V}$ to 5.5 V, $AV_{CC} = 1.8 \text{ V}$ to 5.5 V, $V_{SS} = AV_{SS} = 0.0 \text{ V}$, $T_a = -40^{\circ}\text{C}$ to +85°C (including subactive mode) unless otherwise specified.

		Applicable	Test		Value	S		
ltem	Symbol	Pins	Conditions	Min	Тур	Max	Unit	Notes
Segment driver drop voltage	V _{DS}	SEG ₁ to SEG ₃₂	$I_D = 2 \ \mu A$ V ₁ = 2.7 to 5.5 V	_	_	0.6	V	*1
Common driver drop voltage	V _{DC}	COM ₁ to COM ₄	$I_D = 2 \ \mu A$ V ₁ = 2.7 to 5.5 V	—	—	0.3	V	*1
LCD power supply split-resistance	R _{LCD}		Between V_1 and V_{SS}	0.5	3.0	9.0	MΩ	
Liquid crystal display voltage	V _{LCD}	V ₁		2.2	—	5.5	V	*2

Notes: 1. The voltage drop from power supply pins V₁, V₂, V₃, and V_{SS} to each segment pin or common pin.

2. When the liquid crystal display voltage is supplied from an external power source, ensure that the following relationship is maintained: $V_1 \ge V_2 \ge V_3 \ge V_{SS}$.

Table 15.14 AC Characteristics for External Segment Expansion

 V_{CC} = 1.8 V to 5.5 V, V_{SS} = 0.0 V, T_a = -40°C to +85°C (including subactive mode) unless otherwise specified.

		Applicable	Test	•	Values	5		Reference
ltem	Symbol	Pins	Conditions	Min	Тур	Мах	Unit	Figure
Clock high width	t _{сwн}	CL ₁ , CL ₂	*	800	_	_	ns	Figure 15.7
Clock low width	t _{CWL}	CL ₂	*	800	_		ns	Figure 15.7
Clock setup time	t _{csu}	CL ₁ , CL ₂	*	500	_		ns	Figure 15.7
Data setup time	t _{su}	DO	*	300	_	_	ns	Figure 15.7
Data hold time	t _{DH}	DO	*	300			ns	Figure 15.7
M delay time	t _{DM}	М	*	-1000	_	1000	ns	Figure 15.7
Clock rise and fall times	t _{C⊺}	CL ₁ , CL ₂		_	_	170	ns	Figure 15.7

Note: * Value when the frame frequency is set to between 30.5 Hz and 488 Hz.



15.5 H8/3827S Group Absolute Maximum Ratings

Table 15.15 lists the absolute maximum ratings.

Table 15.15 A	bsolute Maximum	Ratings
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ltem		Symbol	Value	Unit	Notes
Power supply vo	Itage	V _{CC}	–0.3 to +4.3	V	*1
Analog power su	ipply voltage	AV _{CC}	–0.3 to +4.3	V	
Input voltage	Ports other than Port B	V _{in}	–0.3 to V _{CC} +0.3	V	_
	Port B	AV _{in}	–0.3 to AV _{CC} +0.3	V	
Operating temperature		T _{opr}	–20 to +75 (Regular specifications)	°C	
			-40 to +85 (wide-range specifications)		
			+75 (products shipped as chips) ^{*2}	-	
Storage tempera	iture	T _{stg}	–55 to +125	°C	

Notes: 1. Permanent damage may occur to the chip if maximum ratings are exceeded. Normal operation should be under the conditions specified in Electrical Characteristics. Exceeding these values can result in incorrect operation and reduced reliability.

2. Power may be applied when the temperature is between –20 and –75°C.

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15.6 H8/3827S Group Electrical Characteristics

15.6.1 Power Supply Voltage and Operating Range

The power supply voltage and operating range are indicated by the shaded region in the figures.

1. Power Supply Voltage and Oscillator Frequency Range



Note: fosc is the oscillator frequency. When external clocks are used, fosc=1MHz is the minimum.



2. Power Supply Voltage and Operating Frequency Range



Note: Figures in parentheses are the minimum operating frequency of a case external clocks are used. When using an oscillator, the minimum operating frequency is \u03c6=15.625kHz.

3. Analog Power Supply Voltage and A/D Converter Operating Range



15.6.2 DC Characteristics

Table 15.16 lists the DC characteristics of the H8/3827S Group.

Table 15.16 DC Characteristics

				Values				
Item	Symbol	Applicable Pins	Min	Тур	Max	Unit	Test Condition	Notes
Input high voltage	V _{IH}	$\label{eq:response} \begin{array}{l} \overline{\text{RES}}, \\ \overline{\text{WKP}}_0 \text{ to } \overline{\text{WKP}}_7, \\ \overline{\text{IRQ}}_0 \text{ to } \overline{\text{IRQ}}_4, \\ AEVL, AEVH, \\ TMIC, TMIF, \\ TMIG \\ SCK_{31}, SCK_{32}, \\ \overline{\text{ADTRG}} \end{array}$	0.9 V _{CC}		V _{CC} + 0.3	V		_
		RXD ₃₁ , RXD ₃₂ , UD	0.8 V _{CC}	_	V _{CC} + 0.3	V		_
		OSC ₁	0.9 V _{CC}	_	V _{CC} + 0.3	V		
		X ₁	0.9 V _{CC}	_	V _{CC} + 0.3	V		_
		$\begin{array}{c} P1_0 \ \text{to} \ P1_7, \\ P3_0 \ \text{to} \ P3_7, \\ P4_0 \ \text{to} \ P4_3, \\ P5_0 \ \text{to} \ P5_7, \\ P6_0 \ \text{to} \ P6_7, \\ P7_0 \ \text{to} \ P7_7, \\ P8_0 \ \text{to} \ P8_7, \\ PA_0 \ \text{to} \ PA_3 \end{array}$	0.8 V _{CC}	_	V _{CC} + 0.3	V		-
		PB ₀ to PB ₇	0.8 V _{CC}	_	AV_{CC} + 0.3			_

Note: Connect the TEST pin to V_{SS} .
				Value	es			
Item	Symbol	Applicable Pins	Min	Тур	Max	Unit	Test Condition	Notes
Input low voltage	V _{IL}	$\label{eq:response} \begin{array}{l} \overline{\text{RES}}, \\ \overline{\text{WKP}}_0 \text{ to } \overline{\text{WKP}}_7, \\ \overline{\text{IRQ}}_0 \text{ to } \overline{\text{IRQ}}_4, \\ AEVL, AEVH, \\ TMIC, TMIF, \\ TMIG \\ \underline{\text{SCK}}_{31}, \text{SCK}_{32}, \\ \overline{\text{ADTRG}} \end{array}$	-0.3	_	0.1 V _{CC}	V		
		RXD ₃₁ , RXD ₃₂ , UD	-0.3	—	0.2 V _{CC}	V		_
		OSC ₁	-0.3	_	0.1 V _{CC}	V		
		X ₁	-0.3	—	0.1 V _{CC}	V		
		$\begin{array}{c} P1_0 \mbox{ to } P1_7, \\ P3_0 \mbox{ to } P3_7, \\ P4_0 \mbox{ to } P4_3, \\ P5_0 \mbox{ to } P5_7, \\ P6_0 \mbox{ to } P6_7, \\ P7_0 \mbox{ to } P7_7, \\ P8_0 \mbox{ to } P8_7, \\ PA_0 \mbox{ to } PA_3, \\ PB_0 \mbox{ to } PB_7 \end{array}$	-0.3	_	0.2 V _{CC}	V		_
Output high voltage	V _{OH}	$\begin{array}{c} {\sf P1}_0 \mbox{ to } {\sf P1}_7, \\ {\sf P3}_0 \mbox{ to } {\sf P3}_7, \\ {\sf P4}_0 \mbox{ to } {\sf P4}_2, \\ {\sf P5}_0 \mbox{ to } {\sf P5}_7, \\ {\sf P6}_0 \mbox{ to } {\sf P5}_7, \\ {\sf P7}_0 \mbox{ to } {\sf P7}_7, \\ {\sf P8}_0 \mbox{ to } {\sf P8}_7, \\ {\sf PA}_0 \mbox{ to } {\sf PA}_3 \end{array}$	V _{CC} – 0.3	_	_	V	–I _{OH} = 0.1 mA	

				Valu	es			
Item	Symbol	Applicable Pins	Min	Тур	Max	Unit	Test Condition	Notes
Output low voltage	V _{OL}	P1 ₀ to P1 ₇ , P4 ₀ to P4 ₂	_	_	0.5	V	I _{OL} = 0.4 mA	
		$\begin{array}{c} {\sf P5}_0 \text{ to } {\sf P5}_7, {\sf P6}_0 \\ {\sf to } {\sf P6}_7, {\sf P7}_0 \text{ to} \\ {\sf P7}_7, {\sf P8}_0 \text{ to } {\sf P8}_7, \\ {\sf PA}_0 \text{ to } {\sf PA}_3 \end{array}$	_	_	0.5		I _{OL} = 0.4 mA	
		P3 ₀ to P3 ₇	_	_	0.5		I _{OL} = 0.4 mA	
Input/output leakage current	I _{IL}	$\label{eq:response} \begin{array}{c} \overline{\text{RES}}, \mbox{ OSC}_1, \mbox{ X}_1, \\ \mbox{ P1}_0 \mbox{ to P1}_7, \\ \mbox{ P3}_0 \mbox{ to P3}_7, \\ \mbox{ P4}_0 \mbox{ to P4}_3, \\ \mbox{ P5}_0 \mbox{ to P5}_7, \\ \mbox{ P6}_0 \mbox{ to P6}_7, \\ \mbox{ P7}_0 \mbox{ to P7}_7, \\ \mbox{ P8}_0 \mbox{ to P8}_7, \\ \mbox{ PA}_0 \mbox{ to PA}_3 \end{array}$	_	_	1.0	μA	$V_{IN} = 0.5 V \text{ to}$ $V_{CC} - 0.5 V$	
		PB ₀ to PB ₇	—	—	1.0		$V_{IN} = 0.5 V$ to AV _{CC} - 0.5 V	
Pull-up MOS current	-Ip	P1 ₀ to P1 ₇ , P3 ₀ to P3 ₇ , P5 ₀ to P5 ₇ , P6 ₀ to P6 ₇	10.0	_	300.0	μA	V _{CC} = 3 V, V _{IN} = 0 V	



				Valu	es			
ltem	Symbol	Applicable Pins	Min	Тур	Max	Unit	Test Condition	Notes
Input capacitance	C _{IN}	All input pins except power supply	_	_	15.0	pF	f = 1MHz, $V_{IN} = 0 V,$ $T_a = 25^{\circ}C$	
Active mode current dissipation	I _{OPE1}	V _{CC}	_	0.4	*3	mA	Active (high-speed) mode $V_{CC} = 1.8 V$, $f_{OSC} = 2 MHz$	*1 *2
			_	1.4	*3		Active (high-speed) mode V _{CC} = 3 V, f _{OSC} = 4 MHz	_
			_	3.5	5.5		Active (high-speed) mode V_{CC} = 3 V, f_{OSC} = 10 MHz	_
	I _{OPE2}	V _{cc}	_	0.1	*3		Active (medium-speed) mode $V_{CC} = 1.8 V$, $f_{OSC} = 2 MHz$ $\phi_{OSC}/128$	_
			_	0.3	*3		Active (medium-speed) mode $V_{CC} = 3 V$, $f_{OSC} = 4 MHz$ $\phi_{OSC}/128$	_
			_	0.7	1.6		Active (medium-speed) mode $V_{CC} = 3 V$, $f_{OSC} = 10 MHz$ $\phi_{OSC}/128$	-
Sleep mode current	I _{SLEEP}	SLEEP V _{CC} –	—	0.2	*3	mA	V_{CC} = 1.8 V, f_{OSC} = 2 MHz	*1 *2
dissipation			_	0.6	*3		V_{CC} = 3 V, f_{OSC} = 4 MHz	-
			—	1.4	2.9		V _{CC} = 3 V, f _{OSC} = 10 MHz	_

				v	alues			
Item	Symbol	Applicable Pins	Min	Тур	Мах	Unit	_ Test Condition	Notes
Subactive mode current dissipation	I _{SUB}	V _{CC}		8	*3	μA	V_{CC} = 1.8 V, LCD on 32 kHz crystal oscillator ($\phi_{SUB} = \phi_W/2$)	*1 *2
			_	4	*3		$V_{CC} = 2.7 \text{ V},$ LCD on 32 kHz crystal oscillator $(\phi_{SUB} = \phi_W/8)$	-
			_	14	*3		V_{CC} = 2.7 V, LCD on 32 kHz crystal oscillator ($\phi_{SUB} = \phi_W/2$)	-
Subsleep mode current dissipation	I _{SUBSP}	V _{CC}	_	5.0	12	μA	V_{CC} = 2.7 V, LCD on 32 kHz crystal oscillator ($\phi_{SUB}=\phi_w/2$)	*1 *2
	I _{WATCH}	NATCH V _{CC}	_	1.4	*3	μA	V_{CC} = 1.8 V, Ta = 25°C 32 kHz crystal oscillator LCD not used	*1 *2
			_	2.2	*3		V_{CC} = 2.7 V, Ta = 25°C 32 kHz crystal oscillator LCD not used	-
			_	2.8	6		V _{CC} = 2.7 V, 32 kHz crystal oscillator LCD not used	-
Standby mode current dissipation	I _{STBY}	V _{cc}	_	0.3	*3	μA	32 kHz crystal oscillator not used V_{CC} = 1.8 V, Ta = 25°C	*1 *2
			_	0.5	*3		$\label{eq:scalar} \begin{array}{l} 32 \text{ kHz crystal oscillator} \\ \text{not used} \\ V_{\text{CC}} = 2.7 \text{ V}, \\ \text{Ta} = 25^{\circ}\text{C} \end{array}$	-
			_	1	5		Except the above	-
RAM data retaining voltage	V _{RAM}	V _{CC}	1.5	_	_	V		

				V	alues			
Item	Symbol	Applicable Pins	Min	Тур	Мах	Unit	Test Condition	Notes
Allowable output low current (per pin)	I _{OL}	All output pins	_		0.5	mA		
Allowable output low current (total)	ΣI_{OL}	All output pins	_	_	20.0	mA		
Allowable output high current (per pin)	–I _{OH}	All output pins	_	_	0.2	mA		
Allowable output high current (total)	$\Sigma - I_{OH}$	All output pins	_	_	10.0	mA		

Notes: 1. Pin states during current measurement.

Mode	RES Pin	Internal State	Other Pins	LCD Power Supply	Oscillator Pins
Active (high-speed) mode (I _{OPE1})	V_{CC}	Only CPU operates	V _{CC}	Halted	System clock oscillator: crystal
Active (medium- speed) mode (I _{OPE2})	_				Subclock oscillator: Pin X1 = GND
Sleep mode	V_{CC}	Only timers operate	V_{CC}	Halted	_
Subactive mode	V_{CC}	Only CPU operates	V_{CC}	Halted	System clock oscillator:
Subsleep mode	V_{CC}	Only timers operate, CPU stops	V _{CC}	Halted	crystal Subclock oscillator:
Watch mode	V_{CC}	Only time base operates, CPU stops	V _{CC}	Halted	[–] crystal
Standby mode	V_{CC}	CPU and timers both stop	V _{CC}	Halted	System clock oscillator: crystal
					Subclock oscillator: Pin X ₁ = GND

2. Excludes current in pull-up MOS transistors and output buffers.

3. The maximum current consumption value (standard) is $1.1 \times typ$.

15.6.3 AC Characteristics

Table 15.17 lists the control signal timing, and tables 15.18 lists the serial interface timing of the H8/3827S.

Table 15.17 Control Signal Timing

		Applicable		Values	;			Reference
Item	Symbol	••	Min	Тур	Max	Unit	Test Condition	Figure
System clock	f _{OSC}	OSC_1, OSC_2	2	_	10	MHz	$V_{\rm CC}$ = 2.7 V to 3.6 V	
oscillation frequency			2	—	4	_	V _{CC} = 1.8 V to 3.6 V	_
OSC clock (\u00f6osc) cycle time	t _{osc}	OSC ₁ , OSC ₂	100	_	500 (1000)	ns	V_{CC} = 2.7 V to 3.6 V	Figure 15.1
			250	_	500 (1000)	_	V _{CC} = 1.8 V to 3.6 V	*2
System clock (t _{cyc}		2		128	t _{osc}		
cycle time			_	_	128	μs	-	
Subclock oscillation frequency	f_W	X ₁ , X ₂	—	32.768 or 38.4	—	kHz		
Watch clock (ϕ_W) cycle time	t _W	X ₁ , X ₂	—	30.5 or 26.0	_	μs		Figure 15.1
Subclock (ϕ_{SUB}) cycle time	t _{subcyc}		2	_	8	t _W		*1
Instruction cycle			2			t _{cyc}		
time						t _{subcyc}		



		Applicable		Values				Reference
Item	Symbol		Min	Тур	Max	Unit	Test Condition	Figure
Oscillation stabilization time	t _{rc}	OSC ₁ , OSC ₂	_	20	45	μs	Ceramic Oscillator Parameters V _{CC} = 2.2 V to 3.6 V	Figure 15.9
			_	80	_		Ceramic Oscillator Parameters Except the above	-
			_	0.8	2	ms	Crystal Oscillator Parameters V _{CC} = 2.7 V to 3.6 V	_
			_	1.2	3		Crystal Oscillator Parameters V_{CC} = 2.2 V to 3.6 V	_
			_	4.0	—		Crystal Oscillator Parameters Except the above	_
			_	_	50		Except the above	-
		X1, X2	_	_	2	S	$V_{\rm CC}$ = 2.2 V to 3.6 V	_
			_	4	_		Except the above	_
External clock high	t _{CPH}	OSC ₁	40	_	_	ns	$V_{\rm CC}$ = 2.7 V to 3.6 V	Figure 15.1
width			100	_	—		$V_{\rm CC}$ = 1.8 V to 3.6 V	_
		X ₁	—	15.26 or 13.02	_	μs		
External clock low	t _{CPL}	OSC ₁	40	—	_	ns	V_{CC} = 2.7 V to 3.6 V	Figure 15.1
width			100	_	—		$V_{\rm CC}$ = 1.8 V to 3.6 V	
		X ₁	—	15.26 or 13.02	—	μs		
External clock rise	t _{CPr}	OSC ₁	—	—	10	ns	$V_{\rm CC}$ = 2.7 V to 3.6 V	Figure 15.1
time			—	_	25		$V_{\rm CC}$ = 1.8 V to 3.6 V	
		X ₁	_	_	55.0			_
External clock fall	t _{CPf}	OSC ₁	_	_	10	ns	$V_{\rm CC}$ = 2.7 V to 3.6 V	Figure 15.1
time			_		25		$V_{\rm CC}$ = 1.8 V to 3.6 V	_
		X ₁	_	_	55.0			
Pin RES low width	t _{REL}	RES	10	_	—	t _{cyc}		Figure 15.2

		Applicable		Values	5		Reference
Item	Symbol	••	Min Typ Max		Мах	Unit Test Condition	Figure
Input pin high width	t _{iH}	$\label{eq:response} \begin{array}{c} \overline{IRQ}_0 \ \text{to} \ \overline{IRQ}_4, \\ \overline{WKP}_0 \ \text{to} \\ \overline{WKP}_7 \\ \overline{ADTRG}, \\ TMIC \ TMIF, \\ TMIG, \ AEVL, \\ AEVH \end{array}$	2	_	_	t _{cyc} t _{subcyc}	Figure 15.3
Input pin low width	t _{IL}	$\label{eq:response} \begin{array}{ c c c c } \hline IRQ_0 \ to \ \overline{IRQ}_4, \\ \hline WKP_0 \ to \\ \hline WKP_7, \\ \hline ADTRG, \\ TMIC, TMIF, \\ TMIG, AEVL, \\ AEVH \\ \end{array}$	2			t _{cyc} t _{subcyc}	Figure 15.3
UD pin minimum modulation width	t _{UDH} t _{UDL}	UD	4	—	—	t _{cyc} t _{subcyc}	Figure 15.4

Notes: 1. Selected with SA1 and SA0 of system clock control register 2 (SYSCR2).

2. Figures in parentheses are the maximum t_{OSC} rate with external clock input.

Table 15.18 Serial Interface (SCI3-1, SCI3-2) Timing

				Values	5			Reference
Item		Symbol	Min	Тур	Мах	Unit	Test Conditions	Figure
Input clock	Asynchronous	t _{scyc}	4	_	_	t _{cyc} or		Figure 15.5
cycle	Synchronous		6		—	t _{subcyc}		
Input clock pulse width		t _{SCKW}	0.4	_	0.6	t _{scyc}		Figure 15.5
Transmit dat (synchronou	,	t _{TXD}	_		1	t _{cyc} or t _{subcyc}		Figure 15.6
Receive data setup time (synchronous)		t _{RXS}	400.0	—	_	ns		Figure 15.6
Receive data hold time (synchronous)		t _{RXH}	400.0	_	_	ns		Figure 15.6

15.6.4 A/D Converter Characteristics

Table 15.19 shows the A/D converter characteristics.

Table 15.19 A/D Converter Characteristics

		Applicable		Va	lues			
Item	Symbol	••	Min	Тур	Max	Unit	Test Condition	Notes
Analog power supply voltage	AV_{CC}	AV _{CC}	1.8	_	3.6	V		*1
Analog input voltage	AV _{IN}	AN ₀ to AN ₇	- 0.3	_	AV _{CC} + 0.3	V		
Analog power	Al _{OPE}	AV _{CC}	—	_	1.2	mA	AV _{CC} = 3.0 V	
supply current	AI _{STOP1}	AV _{CC}	_	600	_	μA		*2 Reference value
	AI _{STOP2}	AV _{CC}	—	_	5	μA		*3
Analog input capacitance	C _{AIN}	AN ₀ to AN ₇	_	_	15.0	pF		
Allowable signal source impedance	R _{AIN}			_	10.0	kΩ		
Resolution (data length)			_	_	10	bit		
Nonlinearity error			—	_	±3.5	LSB	AV _{CC} = 2.7 V to 3.6 V V _{CC} = 2.7 V to 3.6 V	
			_	_	±5.5	_	AV _{CC} = 2.0 V to 3.6 V V _{CC} = 2.0 V to 3.6 V	_
			_	_	±7.5	_	Except the above	*4
Quantization error			_	_	±0.5	LSB		

		Applicable		Val	lues			
Item	Symbol	••	Min	Тур	Max	Unit	Test Condition	Notes
Absolute accuracy			_	±2	±4	LSB	AV _{CC} = 2.7 V to 3.6 V V _{CC} = 2.7 V to 3.6 V	
			_	±2.5	±6		AV _{CC} = 2.0 V to 3.6 V V _{CC} = 2.0 V to 3.6 V	_
			_	±3	±8		Except the above	*4
Conversion time			12.4	_	124	μs	AV _{CC} = 2.7 V to 3.6 V V _{CC} = 2.7 V to 3.6 V	
			62	—	124		Except the above	_

Notes: 1. Set $AV_{CC} = V_{CC}$ when the A/D converter is not used.

2. AI_{STOP1} is the current in active and sleep modes while the A/D converter is idle.

3. Al_{STOP2} is the current at reset and in standby, watch, subactive, and subsleep modes while the A/D converter is idle.

4. Conversion time 62 μs



15.6.5 LCD Characteristics

Table 15.20 shows the LCD characteristics.

Table 15.20 LCD Characteristics

		Applicable	Test		Va	lues		
ltem	Symbol	Pins	Conditions	Min	Тур	Max	Unit	Notes
Segment driver drop voltage	V _{DS}	SEG ₁ to SEG ₃₂	I _D = 2 μA V ₁ = 2.7 to 3.6 V	_	_	0.6	V	*1
Common driver drop voltage	V _{DC}	COM ₁ to COM ₄	$I_D = 2 \ \mu A$ V ₁ = 2.7 to 3.6 V	—	_	0.3	V	*1
LCD power supply split-resistance	R _{LCD}		Between V_1 and V_{SS}	1.5	3.5	7	MΩ	
Liquid crystal display voltage	V _{LCD}	V ₁		2.2	—	3.6	V	*2

Notes: 1. The voltage drop from power supply pins V_1 , V_2 , V_3 , and V_{SS} to each segment pin or common pin.

2. When the liquid crystal display voltage is supplied from an external power source, ensure that the following relationship is maintained: $V_1 \ge V_2 \ge V_3 \ge V_{SS}$.

Table 15.21 AC Characteristics for External Segment Expansion

		Applicable	Test	Values				Reference
ltem	Symbol	Pins	Conditions	Min	Тур	Max	Unit	Figure
Clock high width	t _{CWH}	CL ₁ , CL ₂	*	800.0	_	_	ns	Figure 15.7
Clock low width	t _{CWL}	CL ₂	*	800.0	_	_	ns	Figure 15.7
Clock setup time	t _{csu}	CL ₁ , CL ₂	*	500.0	_	_	ns	Figure 15.7
Data setup time	t _{su}	DO	*	300.0	_	_	ns	Figure 15.7
Data hold time	t _{DH}	DO	*	300.0	_	_	ns	Figure 15.7
M delay time	t _{DM}	М		-1000.0	_	1000.0	ns	Figure 15.7
Clock rise and fall times	t _{CT}	CL ₁ , CL ₂		_	—	170.0	ns	Figure 15.7

Note: * Value when the frame frequency is set to between 30.5 Hz and 488 Hz.

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15.7 Absolute Maximum Ratings of H8/38327 Group and H8/38427 Group

Table 15.22 lists the absolute maximum ratings.

Table 15.22 Absolute Maximum Ratings

Item		Symbol	Value	Unit	Note
Power supply vol	tage	V _{CC}	–0.3 to +7.0	V	*1
		CV _{CC}	–0.3 to +4.3	V	
Analog power su	pply voltage	AV _{CC}	–0.3 to +7.0	V	
Input voltage	Other than port B	Vin	–0.3 to V _{CC} +0.3	V	
	Port B	AV _{in}	–0.3 to AV _{CC} +0.3	V	
Operating tempe	rature	T _{opr}	–20 to +75 ^{*2} (regular specifications)	°C	
			-40 to +85 ^{*2} (wide-range temperature specifications)	_	
			+75 ^{*3} (chip shipment specifications)	_	
Storage tempera	ture	T _{stg}	–55 to +125	°C	

Notes: 1. Permanent damage may result if maximum ratings are exceeded. Normal operation should be under the conditions specified in Electrical Characteristics. Exceeding these values can result in incorrect operation and reduced reliability.

2. The operating temperature ranges from –20°C to +75°C when programming or erasing the flash memory.

3. The temperature range in which power may be applied to the device is -20°C to +75°C.

15.8 Electrical Characteristics of H8/38327 Group and H8/38427 Group

15.8.1 Power Supply Voltage and Operating Ranges

The power supply voltage and operating ranges (shaded portions) are shown below.

1. Power Supply Voltage and Oscillation Frequency Range



Note: fosc is the oscillator frequency. When an external clock is used 1 MHz is the minimum fosc value.

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2. Power Supply Voltage and Operating Frequency Range





3. Analog Power Supply Voltage and A/D Converter Operating Range



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15.8.2 DC Characteristics

Table 15.23 lists the DC characteristics.

Table 15.23DC Characteristics

 $V_{CC} = 2.7 \text{ V}$ to 5.5 V, $AV_{CC} = 2.7 \text{ V}$ to 5.5 V, $V_{SS} = AV_{SS} = 0.0 \text{ V}$, unless otherwise specified

				Valu	es			
Item	Symbol	Applicable Pins	Min	Тур	Мах	Unit	Test Condition	Notes
Input high voltage	1 0	$\label{eq:response} \begin{array}{l} \overline{\text{RES}},\\ \overline{\text{WKP}}_0 \text{ to } \overline{\text{WKP}}_7,\\ \overline{\text{IRQ}}_0 \text{ to } \overline{\text{IRQ}}_4, \end{array}$	$V_{CC} \times 0.8$	_	V _{CC} + 0.3	V	V_{CC} = 4.0 V to 5.5 V	
	AEVL, AEVH, TMIC, TMIF, TMIG, ADTRG, SCK ₃₁ , SCK ₃₂	$V_{CC} \times 0.9$	_	V _{CC} + 0.3	_	Other than above		
		RXD ₃₁ , RXD ₃₂ ,	$V_{CC}\!\times\!0.7$	_	V _{CC} + 0.3	V	$V_{\rm CC}$ = 4.0 V to 5.5 V	
	UD	$V_{CC}\!\times\!0.8$		V _{CC} + 0.3	_	Other than above		
		OSC ₁	$V_{CC}\!\times\!0.8$		V _{CC} + 0.3	V	$V_{\rm CC}$ = 4.0 V to 5.5 V	
			$V_{CC}\!\times\!0.9$		V _{CC} + 0.3	_	Other than above	
		$P1_0$ to $P1_7$, $P3_0$ to $P3_7$, $P4_0$ to $P4_3$,	V _{CC} ×0.7	_	V _{CC} + 0.3	V	V_{CC} = 4.0 V to 5.5 V	
		P5 ₀ to P5 ₇ , P6 ₀ to P6 ₇ , P7 ₀ to P7 ₇ , P8 ₀ to P8 ₇ , PA ₀ to PA ₃	V _{CC} ×0.8	_	V _{CC} + 0.3	_	Other than above	
		PB ₀ to PB ₇	$V_{CC}\!\times\!0.7$	—	AV _{CC} + 0.3	V	$V_{\rm CC}$ = 4.0 V to 5.5 V	
			$V_{CC}\!\times\!0.8$	—	AV_{CC} + 0.3	-	Other than above	
		EXCL	$V_{CC}\!\times\!0.9$	_	V _{CC} + 0.3	V		

Note: Connect the TEST pin to V_{SS} .

				Valu	es			
ltem	Symbol	Applicable Pins	Min	Тур	Max	Unit	Test Condition	Notes
Input low voltage	•	$\label{eq:response} \begin{array}{l} \overline{\text{RES}},\\ \overline{\text{WKP}}_0 \text{ to } \overline{\text{WKP}}_7,\\ \overline{\text{IRQ}}_0 \text{ to } \overline{\text{IRQ}}_4,\\ \text{AEVL, AEVH,} \end{array}$	- 0.3	_	$V_{CC} \times 0.2$	V	V _{CC} = 4.0 V to 5.5 V	
	TMIC, TMIF, TMIG, ADTRG, SCK ₃₁ , SCK ₃₂	- 0.3	_	$V_{CC} imes 0.1$		Other than above	-	
		RXD ₃₁ , RXD ₃₂ ,	- 0.3	_	$V_{CC} \times 0.3$	V	$V_{\rm CC}$ = 4.0 V to 5.5 V	
		UD	- 0.3	_	$V_{CC} \times 0.2$	_	Other than above	-
		OSC ₁	- 0.3	_	$V_{CC} \times 0.2$	V	$V_{\rm CC}$ = 4.0 V to 5.5 V	
			- 0.3	—	$V_{CC} \times 0.1$	_	Other than above	-
		EXCL	- 0.3	_	0.1 V _{CC}	V		
		$P1_0$ to $P1_7$ $P3_0$ to $P3_7$, $P4_0$ to $P4_3$,	- 0.3	_	$V_{CC} \times 0.3$	V	V_{CC} = 4.0 V to 5.5 V	
		$P5_0$ to $P5_7$, $P6_0$ to $P6_7$, $P7_0$ to $P7_7$, $P8_0$ to $P8_7$, PA_0 to PA_3 , PB_0 to PB_7	- 0.3	_	$V_{CC} \times 0.2$	_	Other than above	_
Output high	V _{OH}	P1 ₀ to P1 ₇ P3 ₀ to P3 ₇ , P4 ₀ to P4 ₂ ,	V _{CC} – 1.0	—	_	V	V _{CC} = 4.0 V to 5.5 V -I _{OH} = 1.0 mA	
voltage	voltage	$P_{0} = 0 P_{7}$ $P_{0} = 0 P_{7}$ $P_{0} = 0 P_{7}$ $P_{0} = 0 P_{7}$	V _{CC} – 0.5	_	_		V_{CC} = 4.0 V to 5.5 V -I _{OH} = 0.5 mA	-
		P_0 to P_7 , P_0 to P_7 , P_0 to P_3	V _{CC} – 0.3	—	_		–I _{OH} = 0.1 mA	-

Section 15 Electrical Characteristics	acteristics
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				Value	S			
Item	Symbol	Applicable Pins	Min	Тур	Max	Unit	Test Condition	Notes
Output low	V _{OL}	P1 ₀ to P1 ₇ ,	_	_	0.6	V	$V_{\rm CC}$ = 4.0 V to 5.5 V	
voltage		P4 ₀ to P4 ₂ , P5 ₀ to P5 ₇ , P6 ₀ to P6 ₇ ,					I _{OL} = 1.6 mA	
		P_{0}^{-} to P_{7}^{-} , P_{0}^{-} to P_{7}^{-} , P_{0}^{-} to P_{0}^{-} , P_{0}^{-} to P_{0}^{-}	_	_	0.5		I _{OL} = 0.4 mA	-
		P3 ₀ to P3 ₇	_	_	1.0		V_{CC} = 4.0 V to 5.5 V	-
							I _{OL} = 10 mA	
			_	_	0.6		V_{CC} = 4.0 V to 5.5 V	-
							I _{OL} = 1.6 mA	
			_	—	0.5		I _{OL} = 0.4 mA	-
Input/ output leakage current	11_	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$			1.0	μA	V _{IN} = 0.5 V to V _{CC} – 0.5 V	_
		PB ₀ to PB ₇	—	—	1.0		V_{IN} = 0.5 V to AV _{CC} - 0.5 V	
Pull-up MOS	-Ip	P1 ₀ to P1 ₇ , P3 ₀ to P3 ₇ ,	20	_	200	μA	V _{CC} = 5.0 V, V _{IN} = 0.0 V	
current		$P5_0$ to $P5_7$, $P6_0$ to $P6_7$	_	40	_		V _{CC} = 2.7 V, V _{IN} = 0.0 V	Refer- ence value
Input capaci- tance	C _{in}	All input pins except power supply pin	_	_	15.0	pF	f = 1 MHz, V _{IN} = 0.0 V, T _a = 25°C	

				Value	S			
ltem	Symbol	Applicable Pins	Min	Тур	Мах	Unit	Test Condition	Notes
Active mode current consump- tion	I _{OPE1}	V _{CC}		0.8	_	mA	Active (high-speed) mode V_{CC} = 2.7 V, f_{OSC} = 2 MHz	*1 *3 *4 Approx. max. value = $1.1 \times$ Typ.
			_	1.2	_	_		*2 *3 *4 Approx. max. value = $1.1 \times$ Typ.
			_	1.0	_		Active (high-speed) mode V _{CC} = 5 V, f _{OSC} = 2 MHz	*1 *3 *4 Approx. max. value = 1.1 × Typ.
			_	1.5	_	_		*2 *3 *4 Approx. max. value = $1.1 \times$ Typ.
			_	2.0	_	_	Active (high-speed) mode $V_{CC} = 5 V$, $f_{OSC} = 4 MHz$	*1 *3 *4 Approx. max. value = $1.1 \times$ Typ.
			_	2.4	_			*2 *3 *4
			_	4.0	7.0		Active (high-speed)	*1 *3 *4
			_	4.9	7.0		mode V _{CC} = 5 V, f _{OSC} = 10 MHz	*2 *3 *4

				Value	S			
ltem	Symbol	Applicable Pins	Min	Тур	Мах	Unit	Test Condition	Notes
Active mode current consump- tion	I _{OPE2}	V _{CC}	_	0.4	_	mA	Active (medium- speed) mode $V_{CC} = 2.7 V$, $f_{OSC} = 2 MHz$, $\phi_{OSC}/128$	*1 *3 *4 Approx. max. value = 1.1 × Typ.
			_	0.7	_			*2 *3 *4 Approx. max. value = $1.1 \times$ Typ.
			_	0.5	_		Active (medium- speed) mode $V_{CC} = 5 V$, $f_{OSC} = 2 MHz$, $\phi_{OSC}/128$	*1 *3 *4 Approx. max. value = $1.1 \times$ Typ.
			—	1.0	—			*2 *3 *4 Approx. max. value = $1.1 \times$ Typ.
			_	0.8	—		Active (medium- speed) mode $V_{CC} = 5 V$, $f_{OSC} = 4 MHz$, $\phi_{OSC}/128$	*1 *3 *4 Approx. max. value = 1.1 × Typ.
			_	1.2	_			*2 *3 *4
			_	1.2	3.0		Active (medium-	*1 *3 *4
			_	1.7	3.0		speed) mode $V_{CC} = 5 V$, $f_{OSC} = 10 MHz$, $\phi_{OSC}/128$	*2 *3 *4



				Value	s			
ltem	Symbol	Applicable Pins	Min	Тур	Мах	Unit	Test Condition	Notes
Sleep mode current consump- tion	I _{SLEEP}	V _{CC}	_	0.5	_	mA	V _{CC} = 2.7 V, f _{OSC} = 2 MHz	*1 *3 *4 Approx. max. value = 1.1 × Typ.
			_	0.8	_			*2 *3 *4
								Approx. max. value = 1.1 × Typ.
			_	0.7	_		V _{CC} = 5 V,	*1 *3 *4
							f _{OSC} = 2 MHz	Approx. max. value = 1.1 × Typ.
			—	1.2	—			*2 *3 *4
								Approx. max. value = 1.1 × Typ.
			_	1.1	_		V _{CC} = 5 V, f _{OSC} = 4 MHz	*1*3*4 Approx. max. value = 1.1 × Typ.
			_	1.6	_			*2 *3 *4
			_	1.9	5.0		V _{CC} = 5 V,	*1 *3 *4
			—	2.6	5.0		f _{OSC} = 10 MHz	*2 *3 *4
Subactive	leun	V _{CC}	_	12	_	μA	V _{CC} = 2.7 V,	*1 *3 *4
mode current	1308	•00		12		μ, τ	LCD on, 32-kHz crystal	Reference value
consump- tion			_	15	_		resonator used (φ _{SUB} = φ _W /8)	*2 *3 *4 Reference value
			_	18	50		V _{CC} = 2.7 V,	*1 *3 *4
			_	30	50	_	LCD on,	*2 *3 *4
							32-kHz crystal resonator used $(\phi_{SUB} = \phi_W/2)$	

				Value	S			
Item	Symbol	Applicable Pins	Min	Тур	Мах	Unit	Test Condition	Notes
Subsleep mode current consump- tion	I _{SUBSP}	V _{CC}	_	3.8	16	μΑ	V_{CC} = 2.7 V, LCD on, 32-kHz crystal resonator used ($\phi_{SUB} = \phi_W/2$)	*3 *4
Watch mode current	Iwatch	V _{CC}	_	1.8	_	μA	V_{CC} = 2.7 V, T _a = 25°C, 32-kHz crystal	*1 *3 *4 Reference value
consump- tion			_	1.8	_		resonator used, LCD not used	*2 *3 *4 Reference value
			_	3.0	6.0		V _{CC} = 2.7 V, 32-kHz crystal resonator used, LCD not used	*3 *4
Standby I _{STB} mode current consump-	I _{STBY}	Vcc	_	0.3	_	μA	V_{CC} = 2.7 V, T_a = 25°C, 32-kHz crystal resonator not used	*1 *3 *4 Reference value
tion			_	0.3	_		V_{CC} = 2.7 V, T_a = 25°C, 32-kHz crystal resonator not used	*2 *3 *4 Reference value
			_	0.4	_		V_{CC} = 5.0 V, T_a = 25°C, 32-kHz crystal resonator not used	*1 *3 *4 Reference value
			_	0.5	_			*2 *3 *4 Reference value
			_	1.0	5.0		32-kHz crystal resonator not used	*3 *4
RAM data retaining voltage	V _{RAM}	V _{CC}	2.0	_	_	V		*5
Allowable output low	IOL	Output pins except port 3	-	—	2.0	mA	V_{CC} = 4.0 V to 5.5 V	
current (per pin)		Port 3	_	_	10.0	_	V_{CC} = 4.0 V to 5.5 V	_
(hei hiii)		All output pins	—	_	0.5			_
Allowable output low	ΣI_{OL}	Output pins except port 3	—	—	40.0	mA	V_{CC} = 4.0 V to 5.5 V	
current (total)		Port 3	—	_	80.0	_	V_{CC} = 4.0 V to 5.5 V	_
/		All output pins	_	_	20.0	-		

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				Value	S			
Item	Symbol	Applicable Pins	Min	Тур	Мах	Unit	Test Condition	Notes
Allowable	–I _{OH}	All output pins	_	_	2.0	mA	V_{CC} = 4.0 V to 5.5 V	
output high current (per pin)			_	_	0.2		Other than above	
Allowable	Σ –I _{OH}	All output pins	_	_	15.0	mA	V_{CC} = 4.0 V to 5.5 V	
output high current (total)			_	_	10.0		Other than above	_

Notes: Connect the TEST pin to V_{SS} .

- 1. Applies to the mask-ROM version.
- 2. Applies to the F-ZTAT version.
- 3. Pin states when current consumption is measured

Mode	RES Pin	Internal State	Other Pins	LCD Power Supply	Oscillator Pins
Active (high-speed) mode (I _{OPE1})	Vcc	Only CPU operates	Vcc	Stops	System clock: crystal resonator
Active (medium- speed) mode (I _{OPE2})					Subclock: Pin X ₁ = GND
Sleep mode	V _{CC}	Only all on-chip timers operate	V _{CC}	Stops	-
Subactive mode	V_{CC}	Only CPU operates	V _{CC}	Stops	System clock:
Subsleep mode	V _{CC}	Only all on-chip timers operate	V _{CC}	Stops	crystal resonator Subclock:
		CPU stops			crystal resonator
Watch mode	V _{CC}	Only clock time base operates	V _{CC}	Stops	-
		CPU stops			
Standby mode	V _{CC}	CPU and timers both stop	V _{CC}	Stops	System clock: crystal resonator
					Subclock: Pin X ₁ = GND

4. Except current which flows to the pull-up MOS or output buffer

5. Voltage maintained in standby mode

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15.8.3 AC Characteristics

Table 15.24 lists the control signal timing and table 15.25 lists the serial interface timing.

Table 15.24 Control Signal Timing

 $V_{CC} = 2.7 \text{ V}$ to 5.5 V, $AV_{CC} = 2.7 \text{ V}$ to 5.5 V, $V_{SS} = AV_{SS} = 0.0 \text{ V}$, unless otherwise specified

		Applicable		Values	6			Reference
Item	Symbol	Pins	Min	Тур	Max	Unit	Test Condition	Figure
System clock	fosc	OSC ₁ ,	2.0	_	16.0	MHz		*3
oscillation frequency		OSC ₂	2.0	_	16.0	_	V_{CC} = 4.5 to 5.5 V	*4
nequency			2.0	_	10.0	-	$V_{\rm CC}$ = 2.7 to 5.5 V	_
OSC clock (ϕ_{OSC}) cycle time	tosc	OSC ₁ , OSC ₂	62.5	—	500 (1000)	ns		Figure 15.1 ^{*2 *3}
			62.5	—	500 (1000)	_	$V_{\rm CC}$ = 4.5 to 5.5 V	Figure 15.1 ^{*2 *4}
			100	—	500 (1000)	_	$V_{\rm CC}$ = 2.7 to 5.5 V	_
System clock (t _{cyc}		2		128	tosc		
cycle time			_		128	μs	-	
Subclock oscillation frequency	f₩	X ₁ , X ₂ , EXCL	_	32.768 or 38.4	_	kHz		
Watch clock (ϕ_W) cycle time	tw	X ₁ , X ₂ , EXCL	_	30.5 or 26.0	_	μs		Figure 15.1
Subclock (ϕ_{SUB}) cycle time	t _{subcyc}		2	—	4	t _W		*1
Instruction cycle time			2	—	—	t _{cyc} t _{subcyc}		
Oscillation stabilization time	t _{rc}	OSC ₁ , OSC ₂	—	20	45	μs	Ceramic resonator (V_{CC} = 3.0 to 5.5 V)	Figure 15.10
			—	80	—	_	Ceramic resonator other than above	_
			_	0.8	2	ms	Crystal resonator	_
			_		50	-	Other than above	
	t _{rc}	X ₁ , X ₂	_	_	2.0	S		

		Applicable		Values				Reference
Item	Symbol	Pins	Min	Тур	Мах	Unit	Test Condition	Figure
External clock high width	t _{CPH}	OSC ₁	25	_	—	ns		Figure 15.1 ^{*3}
			25	_	—	_	$V_{\rm CC}$ = 4.5 to 5.5 V	Figure
			40	_	—	_	$V_{\rm CC}$ = 2.7 to 5.5 V	15.1 ^{*4}
		EXCL	_	15.26 or 13.02	_	μs		Figure 15.1
External clock low width	t _{CPL}	OSC1	25	_	—	ns		Figure 15.1 ^{*3}
			25	_	_		$V_{\rm CC}$ = 4.5 to 5.5 V	Figure
			40	_	_		$V_{\rm CC}$ = 2.7 to 5.5 V	15.1 ^{*4}
		EXCL	_	15.26 or 13.02	—	μs		Figure 15.1
External clock rise time	t _{CPr}	OSC ₁	—	_	6	ns		Figure 15.1 ^{*3}
			_	_	6		$V_{\rm CC}$ = 4.5 to 5.5 V	Figure
			_	_	10		$V_{\rm CC}$ = 2.7 to 5.5 V	15.1 ^{*4}
		EXCL	—	_	55.0			Figure 15.1
External clock fall time	t _{CPf}	OSC ₁	—	_	6	ns		Figure 15.1 ^{*3}
			—	_	6		$V_{\rm CC}$ = 4.5 to 5.5 V	Figure
			—	_	10	_	$V_{\rm CC}$ = 2.7 to 5.5 V	15.1 ^{*4}
		EXCL	—	_	55.0			Figure 15.1
RES pin low width	t _{REL}	RES	10	_	—	t _{cyc}		Figure 15.2
Input pin high width	t _{iH}	$\label{eq:response} \begin{array}{c} \overline{IRQ}_0 \text{ to } \overline{IRQ}_4,\\ \overline{WKP}_0 \text{ to }\\ \overline{WKP}_7,\\ \overline{ADTRG},\\ TMIC, TMIF,\\ TMIG \end{array}$	2	_	_	t _{cyc} t _{subcyc}	_	Figure 15.3
		AEVL, AEVH	32	—	—	ns		

		Applicable		Value	s			Reference
Item	Symbol	Pins	Min	Тур	Max	Unit	Test Condition	Figure
Input pin low width	t _{IL}	$\label{eq:constraint} \begin{array}{c} \overline{IRQ}_0 \text{ to } \overline{IRQ}_4, \\ \overline{WKP}_0 \text{ to } \\ \overline{WKP}_7, \\ \overline{ADTRG}, \\ TMIC, TMIF, \\ TMIG \end{array}$	2	_	_	t _{cyc} t _{subcyc}		Figure 15.3
		AEVL, AEVH	32	_	—	ns	_	
UD pin minimum	t _{UDH}	UD	4	_		t _{cyc}		Figure 15.4
transition width	t _{UDL}					t _{subcyc}		

Notes: 1. Determined by the SA1 and SA0 bits in the system control register 2 (SYSCR2).

2. The figure in parentheses () indicates the maximum fosc value when an external clock is used.

- 3. Also applies to H8/38327 Group.
- 4. Also applies to H8/38427 Group.

Table 15.25 Serial Interface (SCI3) Timing

 $V_{CC} = 2.7 \text{ V}$ to 5.5 V, $AV_{CC} = 2.7 \text{ V}$ to 5.5 V, $V_{SS} = AV_{SS} = 0.0 \text{ V}$, unless otherwise specified

				Values	5		Test	Reference
Item		Symbol	Min	Тур	Мах	Unit	Condition	Figure
Input clock	Asynchronous	t _{scyc}	4	_	_	$t_{\text{cyc}} \ \text{or}$		Figure 15.5
cycle	Clocked synchronous	=	6	_	_	t _{subcyc}		
Input clock	pulse width	t _{SCKW}	0.4	—	0.6	t _{scyc}		Figure 15.5
Transmit da (clocked sy	ata delay time nchronous)	t _{TXD}	_	_	1	t _{cyc} or t _{subcyc}		Figure 15.6
Receive dat (clocked system)	ta setup time nchronous)	t _{RXS}	200	—	_	ns		Figure 15.6
Receive dat (clocked system)		t _{RXH}	200	_	_	ns		Figure 15.6



15.8.4 A/D Converter Characteristics

Table 15.26 shows the A/D converter characteristics.

Table 15.26 A/D Converter Characteristics

 $V_{CC} = 2.7 \text{ V}$ to 5.5 V, $AV_{CC} = 2.7 \text{ V}$ to 5.5 V, $V_{SS} = AV_{SS} = 0.0 \text{ V}$, unless otherwise specified

		Applicable		Valu	les		Test	Reference
Item	Symbol	Pins	Min	Тур	Мах	Unit	Condition	Figure
Analog power supply voltage	AV_{CC}	AV _{CC}	2.7	_	5.5	V		*1
Analog input voltage	AV _{IN}	AN₀ to AN₃	- 0.3	_	AV _{CC} + 0.3	V		
Analog power supply	Alope	AV _{CC}	—	—	1.5	mA	AV _{CC} = 5.0 V	
current	AI _{STOP1}	AV _{CC}	—	600	_	μA		*2 Reference value
	AI _{STOP2}	AV _{CC}	_	—	5.0	μA		*3
Analog input capacitance	C _{AIN}	AN ₀ to AN ₇	_	_	15.0	pF		
Allowable signal source impedance	R _{AIN}		_	_	10.0	kΩ		
Resolution (data length)			—	—	10	bit		
Nonlinearity error			—	—	±3.5	LSB	AV _{CC} = 4.0 V to 5.5 V	
			—	—	±7.5	-	AV _{cc} = 2.7 V to 5.5 V	-
Quantization error			—	—	±0.5	LSB		
Absolute accuracy			—	±2.0	±4.0	LSB	AV _{CC} = 4.0 V to 5.5 V	
			—	±2.0	±8.0	-	AV _{cc} = 2.7 V to 5.5 V	-
Conversion time			7.8	_	124	μs		*4
			12.4	_	124	-		*5

Notes: 1. Set $AV_{CC} = V_{CC}$ when the A/D converter is not used.

2. AI_{STOP1} is the current in active and sleep modes while the A/D converter is idle.

- 3. AI_{STOP2} is the current at reset and in standby, watch, subactive, and subsleep modes while the A/D converter is idle.
- 4. Also applies to H8/38327 Group.
- 5. Also applies to H8/38427 Group.

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15.8.5 LCD Characteristics

Table 15.27 shows the LCD characteristics.

Table 15.27 LCD Characteristics

 $V_{CC} = 2.7$ V to 5.5 V, $AV_{CC} = 2.7$ V to 5.5 V, $V_{SS} = AV_{SS} = 0.0$ V, unless otherwise specified

		Applicable		Value	s			Reference
Item	Symbol	Pins	Min	Тур	Мах	Unit	Test Condition	Figure
Segment driver step-down voltage	V _{DS}	SEG ₁ to SEG ₃₂	_	_	0.6	V	I _D = 2 μA V1 = 2.7 V to 5.5 V	*1
Common driver step-down voltage	V _{DC}	COM_1 to COM_4	_	_	0.3	V	I _D = 2 μA V1 = 2.7 V to 5.5 V	*1
LCD power supply split-resistance	R_{LCD}		1.5	3.0	7.0	MΩ	Between V1 and V_{SS}	
Liquid crystal display voltage	V _{LCD}	V ₁	2.7	—	5.5	V		*2

Notes: 1. The voltage step-down from power supply pins V1, V2, V3, and V_{SS} to each segment pin or common pin.

2. When the liquid crystal display voltage is supplied from an external power supply, ensure that the following relationship is maintained: $V1 \ge V2 \ge V3 \ge V_{SS}$.



15.8.6 Flash Memory Characteristics

Table 15.28 Flash Memory Characteristics

Condition: $AV_{CC} = 2.7 V$ to 5.5 V, $V_{SS} = AV_{SS} = 0.0 V$, $V_{CC} = 2.7 V$ to 5.5 V (range of operating voltage when reading), $V_{CC} = 3.0 V$ to 5.5 V (range of operating voltage when programming/erasing), $T_a = -20^{\circ}C$ to $+75^{\circ}C$ (range of operating temperature when programming/erasing: product with regular specifications, product with wide-range temperature specifications)

				Values			Test
Item		Symbol	Min	Тур	Max	Unit	Conditions
Programming t	ime ^{*1*2*4}	t₽	_	7	200	ms/128 bytes	
Erase time ^{*1*3}	*5	t _E	_	100	1200	ms/block	
Reprogrammin	g count	N _{WEC}	1000 ^{*8}	10000 ^{*9}	_	times	
Data retain per	iod	t _{DRP}	10 ^{*10}	_	_	year	
Programming	Wait time after SWE-bit setting ^{*1}	x	1	_	_	μs	
	Wait time after PSU-bit setting ^{*1}	У	50	—	_	μs	
	Wait time after	z1	28	30	32	μs	$1 \le n \le 6$
	P-bit setting ^{*1*4}	z2	198	200	202	μs	$7 \le n \le 1000$
		z3	8	10	12	μs	Additional programming
	Wait time after P-bit clear ^{*1}	α	5	—	_	μs	
	Wait time after PSU-bit clear ^{*1}	β	5	—	_	μs	
	Wait time after PV-bit setting ^{*1}	γ	4	_	_	μs	
	Wait time after dummy write ^{*1}	ε	2	_	_	μs	
	Wait time after PV-bit clear ^{*1}	η	2	_	—	μs	
	Wait time after SWE-bit clear ^{*1}	θ	100		—	μs	
	Maximum programming count ^{*1*4*5}	Ν	—	—	1000	times	

				Value	s		Test
Item		Symbol	Min	Тур	Мах	Unit	Conditions
Erase	Wait time after SWE-bit setting ^{*1}	х	1	_	_	μs	
	Wait time after ESU-bit setting ^{*1}	у	100	_	_	μs	
	Wait time after E-bit setting ^{*1*6}	Z	10	_	100	ms	
	Wait time after E-bit clear ^{*1}	α	10	_	_	μs	
	Wait time after ESU-bit clear ^{*1}	β	10	_	_	μs	
	Wait time after EV-bit setting ^{*1}	γ	20	_	_	μs	
	Wait time after dummy write ^{*1}	ε	2	_	_	μs	
	Wait time after EV-bit clear ^{*1}	η	4	_	_	μs	
	Wait time after SWE-bit clear ^{*1}	θ	100	_	_	μs	
	Maximum erase count*1*6*7	Ν	_	_	120	times	

- 2. Programming time per 128 bytes (Shows the total period for which the P bit in FLMCR1 is set. It does not include the programming verification time.)
- 3. Block erase time (Shows the total period for which the E bit in FLMCR1 is set. It does not include the erase verification time.)
- 4. Maximum programming time (t_P (max)) t_P (max) = Wait time after P-bit setting (z) × maximum number of writes (N)
- 5. The maximum number of writes (N) should be set according to the actual set value of z1, z2, and z3 to allow programming within the maximum programming time (t_P (max)).

The wait time after P-bit setting (z1 and z2) should be alternated according to the number of writes (n) as follows:

$$1 \le n \le 6$$
 $z1 = 30 \ \mu s$

$$7 \le n \le 1000$$
 z2 = 200 µs

6. Maximum erase time (t_E (max))

 t_E (max) = Wait time after E-bit setting (z) × maximum erase count (N)

- 7. The maximum number of erases (N) should be set according to the actual set value of z to allow erasing within the maximum erase time (t_E (max)).
- 8. This minimum value guarantees all characteristics after reprogramming (the guaranteed range is from 1 to the minimum value).
- 9. Reference value when the temperature is 25°C (normally reprogramming will be performed by this count).
- 10. This is a data retain characteristic when reprogramming is performed within the specification range including this minimum value.



15.9 Operation Timing

Figures 15.1 to 15.7 show timing diagrams.







Figure 15.2 **RES** Low Width



Figure 15.3 Input Timing

Renesas



Figure 15.4 UD Pin Minimum Modulation Width Timing



Figure 15.5 SCK3 Input Clock Timing





Figure 15.6 SCI3 Synchronous Mode Input/Output Timing



Figure 15.7 Segment Expansion Signal Timing



15.10 Output Load Circuit





15.11 Resonator



Figure 15.9 Resonator Equivalent Circuit

Resonating Frequency	Manufacturer	Model	C ₁ , C ₂
4 MHz	Nihon Denpa Kogyo	NR-18	$12 pF \pm 20\%$
10 MHz			
	Manufacturer	Model	C ₁ , C ₂
	Manufacturer MURATA	Model CSTCC2M00G53-B0	C ₁ , C ₂ 15pF ± 20%
Resonating Frequency			·
Resonating Frequency		CSTCC2M00G53-B0	15pF ± 20%
Resonating Frequency 2 MHz		CSTCC2M00G53-B0 CSTCC2M00G56-B0	15pF ± 20% 47pF ± 20%
		CSTCC2M00G53-B0 CSTCC2M00G56-B0 CSTLS4M00G53-B0	15pF ± 20% 47pF ± 20% 15pF ± 20%

Figure 15.10 Resonator Equivalent Circuit

15.12 Usage Note

Each of the products covered in this manual satisfy the electrical characteristics indicated. However, the actual electrical characteristics, operating margin and noise margin may differ from the indicated values due to differences in the manufacturing process, built-in ROM, layout pattern and other factors.

If a system evaluation test is conducted with the ZTAT or F-ZTAT version, when switching to a mask ROM version, perform the same evaluation test with the mask ROM version.


Appendix A CPU Instruction Set

A.1 Instructions

Operation Notation

Rd8/16	General register (destination) (8 or 16 bits)
Rs8/16	General register (source) (8 or 16 bits)
Rn8/16	General register (8 or 16 bits)
CCR	Condition code register
N	N (negative) flag in CCR
Z	Z (zero) flag in CCR
V	V (overflow) flag in CCR
С	C (carry) flag in CCR
PC	Program counter
SP	Stack pointer
#xx: 3/8/16	Immediate data (3, 8, or 16 bits)
d: 8/16	Displacement (8 or 16 bits)
@aa: 8/16	Absolute address (8 or 16 bits)
+	Addition
-	Subtraction
×	Multiplication
÷	Division
^	Logical AND
V	Logical OR
\oplus	Exclusive logical OR
\rightarrow	Move
_	Logical complement

Condition Code Notation

Symbol

\$	Modified according to the instruction result
*	Not fixed (value not guaranteed)
0	Always cleared to 0
_	Not affected by the instruction execution result

Table A.1 lists the H8/300L CPU instruction set.

Table A.1Instruction Set

			In						ode 1 (b		s)							
	Operand Size		#xx: 8/16		@Rn	@(d:16, Rn)	@-Rn/@Rn+	@aa: 8/16	@(d:8, PC)	@aa	mplied	с	ond	ditio	on (Coc	le	of States
Mnemonic	ŏ	Operation	¥	Rn	0	0	0	0	0	0	<u></u>	T	н	Ν	z	v	С	° Ž
MOV.B #xx:8, Rd	В	$\text{\#xx:8} \rightarrow \text{Rd8}$	2									_	—	\updownarrow	\updownarrow	0	—	2
MOV.B Rs, Rd	В	$Rs8 \rightarrow Rd8$		2								_	—	\updownarrow	\updownarrow	0	—	2
MOV.B @Rs, Rd	В	$@Rs16 \to Rd8$			2							—	—	\updownarrow	\updownarrow	0	—	4
MOV.B @(d:16, Rs), Rd	В	$@(d:16, Rs16) \rightarrow Rd8$				4						—	—	\updownarrow	\Rightarrow	0	—	6
MOV.B @Rs+, Rd	В	$\begin{array}{l} @Rs16 \rightarrow Rd8 \\ Rs16+1 \rightarrow Rs16 \end{array}$					2						_	€	€	0		6
MOV.B @aa:8, Rd	В	@aa:8 → Rd8						2				—	—	↕	\updownarrow	0	—	4
MOV.B @aa:16, Rd	В	@aa:16 \rightarrow Rd8						4				_	_	€	\updownarrow	0	—	6
MOV.B Rs, @Rd	В	$Rs8 \rightarrow @Rd16$			2							_	_	\uparrow	\updownarrow	0	_	4
MOV.B Rs, @(d:16, Rd)	В	$Rs8 \rightarrow @(d:16, Rd16)$				4						—	—	↕	\updownarrow	0	—	6
MOV.B Rs, @-Rd	В	$ \begin{array}{l} \text{Rd16-1} \rightarrow \text{Rd16} \\ \text{Rs8} \rightarrow @\text{Rd16} \end{array} $					2					_	_	\$	↕	0		6
MOV.B Rs, @aa:8	В	$Rs8 \rightarrow @aa:8$						2				_	_	↕	\updownarrow	0	—	4
MOV.B Rs, @aa:16	В	$Rs8 \rightarrow @aa:16$						4				_	—	€	\updownarrow	0	—	6
MOV.W #xx:16, Rd	W	#xx:16 → Rd	4									—	_	↕	\updownarrow	0	—	4
MOV.W Rs, Rd	W	$Rs16 \rightarrow Rd16$		2								_	_	€	\updownarrow	0	—	2
MOV.W @Rs, Rd	W	$@Rs16 \to Rd16$			2							—	—	\updownarrow	\updownarrow	0	—	4
MOV.W @(d:16, Rs), Rd	W	$@(\texttt{d:16}, \texttt{Rs16}) \rightarrow \texttt{Rd16}$				4						_	_	\updownarrow	\updownarrow	0	—	6
MOV.W @Rs+, Rd	W	$\begin{array}{l} @Rs16 \rightarrow Rd16 \\ Rs16+2 \rightarrow Rs16 \end{array}$					2					—	_	⊅	€	0		6
MOV.W @aa:16, Rd	W	@aa:16 \rightarrow Rd16						4				_	_	\updownarrow	\updownarrow	0	_	6
MOV.W Rs, @Rd	W	$Rs16 \to @Rd16$			2							—	—	\updownarrow	\Rightarrow	0	—	4
MOV.W Rs, @(d:16, Rd)	W	$Rs16 \to @(d:16, Rd16)$				4						_	_	\updownarrow	\Rightarrow	0		6
MOV.W Rs, @-Rd	W	$\begin{array}{l} \text{Rd162} \rightarrow \text{Rd16} \\ \text{Rs16} \rightarrow @\text{Rd16} \end{array}$					2						_	\Rightarrow	\Leftrightarrow	0		6
MOV.W Rs, @aa:16	W	$\text{Rs16} \rightarrow @\text{aa:16}$						4				—	—	\updownarrow	\updownarrow	0	—	6
POP Rd	W	$\begin{array}{l} @SP \to Rd16 \\ SP+2 \to SP \end{array}$					2					_	_	↕	\Leftrightarrow	0	_	6
PUSH Rs	W	$\begin{array}{l} SP-2 \to SP \\ Rs16 \to @ SP \end{array}$					2					_	_	\$	\$	0		6

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			In			res on					s)							
	Operand Size		c: 8/16		Rn	@(d:16, Rn)	@-Rn/@Rn+	@aa: 8/16	@(d:8, PC)	@aa	Implied	с	ond	ditie	on (Cod	le	. of States
Mnemonic	do	Operation	:xx#	Rn	@Rn	0	9	0	0	0	Ē	I	н	Ν	z	v	С	So.
ADD.B #xx:8, Rd	В	$Rd8\text{+}\#xx:8\toRd8$	2									_	\updownarrow	\updownarrow	\$	\updownarrow	\updownarrow	2
ADD.B Rs, Rd	В	$Rd8\text{+}Rs8\toRd8$		2								—	\updownarrow	\updownarrow	\Rightarrow	\updownarrow	\Leftrightarrow	2
ADD.W Rs, Rd	W	$\rm Rd16\text{+}Rs16 \rightarrow \rm Rd16$		2								—	(1)	\updownarrow	\updownarrow	\updownarrow	\Leftrightarrow	2
ADDX.B #xx:8, Rd	В	$Rd8\text{+}\texttt{\#xx:8}\text{+}C\toRd8$	2									—	\updownarrow	\updownarrow	(2)	\updownarrow	\leftrightarrow	2
ADDX.B Rs, Rd	В	$Rd8\text{+}Rs8\text{+}C\rightarrowRd8$		2								—	\updownarrow	\updownarrow	(2)	\updownarrow	\updownarrow	2
ADDS.W #1, Rd	W	$Rd16+1 \rightarrow Rd16$		2								_	_	—	_	—	_	2
ADDS.W #2, Rd	W	$Rd16+2 \rightarrow Rd16$		2								—	—	—	_	—		2
INC.B Rd	В	$Rd8+1 \rightarrow Rd8$		2								—	—	\updownarrow	\updownarrow	\updownarrow	—	2
DAA.B Rd	в	Rd8 decimal adjust \rightarrow Rd8		2								—	*	\updownarrow	\updownarrow	*	(3)	2
SUB.B Rs, Rd	В	$Rd8Rs8\toRd8$		2								—	\updownarrow	\updownarrow	\updownarrow	\updownarrow	\updownarrow	2
SUB.W Rs, Rd	W	$Rd16Rs16 \rightarrow Rd16$		2								_	(1)	\updownarrow	\$	\updownarrow	\updownarrow	2
SUBX.B #xx:8, Rd	В	$Rd8\text{-}\#xx:8\text{-}C\toRd8$	2									_	€	\updownarrow	(2)	\updownarrow	\updownarrow	2
SUBX.B Rs, Rd	В	$Rd8Rs8C\toRd8$		2								—	\updownarrow	\updownarrow	(2)	\updownarrow	\updownarrow	2
SUBS.W #1, Rd	W	$Rd16-1 \rightarrow Rd16$		2								—	_	—	_	—	_	2
SUBS.W #2, Rd	W	$Rd16-2 \rightarrow Rd16$		2								_	—	—	_	—		2
DEC.B Rd	В	$Rd8-1 \rightarrow Rd8$		2								—	—	\updownarrow	\$	\updownarrow	_	2
DAS.B Rd	В	Rd8 decimal adjust \rightarrow Rd8		2								—	*	\updownarrow	\$	*	_	2
NEG.B Rd	В	$0-Rd \rightarrow Rd$		2								_	\updownarrow	\updownarrow	\updownarrow	\updownarrow	\updownarrow	2
CMP.B #xx:8, Rd	В	Rd8–#xx:8	2									_	↕	\updownarrow	€	\updownarrow	\updownarrow	2
CMP.B Rs, Rd	В	Rd8–Rs8		2									↕	\updownarrow	\$	\updownarrow	↕	2
CMP.W Rs, Rd	W	Rd16–Rs16		2								_	(1)	\updownarrow	↕	\updownarrow	\updownarrow	2

			In					g M ngth			s)							
	Operand Size		#xx: 8/16		@Rn	@(d:16, Rn)	@-Rn/@Rn+	@ aa: 8/16	@(d:8, PC)	@ @aa	Implied	с	one	ditio	on (Coc	le	. of States
Mnemonic	ð	Operation	¢#	Rn	0	0	9	0	0	0	<u></u>	I	н	Ν	z	۷	С	Š
MULXU.B Rs, Rd	В	$\text{Rd8}\times\text{Rs8}\rightarrow\text{Rd16}$		2								—	—	_	—	—	—	14
DIVXU.B Rs, Rd	В	$Rd16 \div Rs8 \rightarrow Rd16$ (RdH: remainder, RdL: quotient)		2											(6)	_		14
AND.B #xx:8, Rd	В	$Rd8 \land \#xx: 8 \rightarrow Rd8$	2									_	_	\$	↕	0		2
AND.B Rs, Rd	В	$Rd8 \land Rs8 \rightarrow Rd8$		2								_	_	↕	↕	0		2
OR.B #xx:8, Rd	В	$Rd8 \lor \#xx: 8 \rightarrow Rd8$	2									_	_	↕	\updownarrow	0		2
OR.B Rs, Rd	В	$Rd8 \lor Rs8 \rightarrow Rd8$		2								_	_	↕	↕	0		2
XOR.B #xx:8, Rd	В	$Rd8 \oplus \#xx: 8 \rightarrow Rd8$	2									—	—	\updownarrow	\updownarrow	0		2
XOR.B Rs, Rd	В	$Rd8{\oplus}Rs8 \to Rd8$		2								_	_	\updownarrow	\updownarrow	0		2
NOT.B Rd	в	$\overline{Rd}\toRd$		2								_	—	\updownarrow	\updownarrow	0		2
SHAL.B Rd	В			2										\$	\$	€	\$	2
SHAR.B Rd	В			2										\$	\Leftrightarrow	0	\$	2
SHLL.B Rd	В			2									_	↔	\leftrightarrow	0	\$	2
SHLR.B Rd	В	$0 \rightarrow \boxed[b_7 \\ b_0 $		2										0	↔	0	\$	2
ROTXL.B Rd	В	C b7 b0		2										↔	\leftrightarrow	0	\$	2
ROTXR.B Rd	В	b ₇ b ₀ C		2										\$	↔	0	\$	2

			In	A stru			sin Ler	•			s)							
	Operand Size		#xx: 8/16		@Rn	@(d:16, Rn)	@-Rn/@Rn+	@aa: 8/16	@(d:8, PC)	@aa	mplied	С	one	ditio	on (Coc	le	. of States
Mnemonic	g	Operation	¥	Rn	9	0	9	0	0	0	Ĩ	I	н	Ν	z	v	С	°.
ROTL.B Rd	В			2									_	\$	\$	0	\$	2
ROTR.B Rd	В	▶		2										\$	\$	0	\$	2
BSET #xx:3, Rd	В	(#xx:3 of Rd8) ← 1		2								_		_	_		—	2
BSET #xx:3, @Rd	В	(#xx:3 of @Rd16) ← 1			4							—	—	—	—	—	—	8
BSET #xx:3, @aa:8	В	(#xx:3 of @aa:8) ← 1						4				_	_	_	_	—	—	8
BSET Rn, Rd	В	(Rn8 of Rd8) ← 1		2										_	_		—	2
BSET Rn, @Rd	В	(Rn8 of @Rd16) ← 1			4							—	—	—	—	—	—	8
BSET Rn, @aa:8	В	(Rn8 of @aa:8) ← 1						4				—	_	_	_	_	—	8
BCLR #xx:3, Rd	В	(#xx:3 of Rd8) ← 0		2										_	_		—	2
BCLR #xx:3, @Rd	В	(#xx:3 of @Rd16) ← 0			4							—	—	_	—	—	—	8
BCLR #xx:3, @aa:8	В	(#xx:3 of @aa:8) ← 0						4				—	_	_	—	_	—	8
BCLR Rn, Rd	В	(Rn8 of Rd8) ← 0		2								_	_	_	_	_	-	2
BCLR Rn, @Rd	В	(Rn8 of @Rd16) ← 0			4							—	—	_	—	—	—	8
BCLR Rn, @aa:8	В	(Rn8 of @aa:8) ← 0						4				—	—	_	—	—	—	8
BNOT #xx:3, Rd	В	$(\frac{\#xx:3}{(\#xx:3 \text{ of } Rd8)} \leftarrow \\ (\frac{\#xx:3}{(\#xx:3 \text{ of } Rd8)}) $		2									_	_	_	_	-	2
BNOT #xx:3, @Rd	В	$(\overset{\text{(\#xx:3)}}{\text{(\#xx:3)}} \overset{\text{of}}{\text{of}} \overset{\text{@Rd16})}{\text{@Rd16}}) \leftarrow$			4								_		_	_	-	8
BNOT #xx:3, @aa:8	В	$(\#xx:3 \text{ of } @aa:8) \leftarrow \\ (\#xx:3 \text{ of } @aa:8)$						4					_	_	_	-	_	8
BNOT Rn, Rd	В	$(\frac{\text{Rn8 of } \text{Rd8}}{(\overline{\text{Rn8 of } \text{Rd8}})} \leftarrow$		2									_	_	_	-	_	2
BNOT Rn, @Rd	В	$(\frac{\text{Rn8 of } @\text{Rd16})}{(\overline{\text{Rn8 of } @\text{Rd16}})} \leftarrow$			4								_		_	_	_	8
BNOT Rn, @aa:8	В	$(\frac{\text{Rn8 of }@aa:8)}{(\overline{\text{Rn8 of }@aa:8)}} \leftarrow$						4					_				_	8

			In				sing Ler				s)							
	Operand Size		#xx: 8/16	c	@Rn	@(d:16, Rn)	@-Rn/@Rn+	@aa: 8/16	@(d:8, PC)) @aa	mplied	-				Cod		No. of States
Mnemonic	-	Operation	#	Rn	ø	ø	ø	ø	ø	0	5	I	н	Ν	Z	V	С	
BTST #xx:3, Rd	В	$(\#xx:3 \text{ of } Rd8) \rightarrow Z$		2								-	-	_	\$	_	-	2
BTST #xx:3, @Rd	В	$(\#xx:3 \text{ of } @Rd16) \rightarrow Z$			4							-	-	—	\$	_	-	6
BTST #xx:3, @aa:8	В	$(\#xx:3 \text{ of } @aa:8) \rightarrow Z$						4				_	—	_	\$	_	—	6
BTST Rn, Rd	В	(Rn8 of Rd8) \rightarrow Z		2								-	-	—	↕	_		2
BTST Rn, @Rd	В	$(\overline{\text{Rn8 of } @\text{Rd16}}) \rightarrow \text{Z}$			4							_	_	_	↕	_	_	6
BTST Rn, @aa:8	В	$(\overline{\text{Rn8}} \ \overline{\text{of}} \ \overline{\text{@aa:8}}) \rightarrow \text{Z}$						4				_	—	_	↕	_	_	6
BLD #xx:3, Rd	В	(#xx:3 of Rd8) \rightarrow C		2								-	—	—	—	_	\updownarrow	2
BLD #xx:3, @Rd	В	(#xx:3 of @Rd16) \rightarrow C			4							_	_	_	_	_	\updownarrow	6
BLD #xx:3, @aa:8	В	(#xx:3 of @aa:8) \rightarrow C						4				-	—	—	—	_	\updownarrow	6
BILD #xx:3, Rd	В	$(\overline{\#xx:3} \text{ of } \overline{Rd8}) \to C$		2								—	—	—	—	—	\updownarrow	2
BILD #xx:3, @Rd	В	$(\overline{\#xx:3} \text{ of } \overline{@Rd16}) \rightarrow C$			4							_	_	_	_	_	\updownarrow	6
BILD #xx:3, @aa:8	В	$(\overline{\#xx:3} \text{ of } \overline{@aa:8}) \rightarrow C$						4				_	_	_	—	_	\updownarrow	6
BST #xx:3, Rd	В	$C \rightarrow (\#xx:3 \text{ of } Rd8)$		2								_	_	—	—	—		2
BST #xx:3, @Rd	В	$C \rightarrow (\#xx:3 \text{ of } @Rd16)$			4							_	—	—	—	_	—	8
BST #xx:3, @aa:8	в	$C \rightarrow (\#xx:3 \text{ of } @aa:8)$						4				—	—	—	—	_		8
BIST #xx:3, Rd	В	$\overline{C} \rightarrow$ (#xx:3 of Rd8)		2								_	_	_	_	—		2
BIST #xx:3, @Rd	В	$\overline{C} \rightarrow$ (#xx:3 of @Rd16)			4							—	—	_	_	_		8
BIST #xx:3, @aa:8	В	$\overline{C} \rightarrow$ (#xx:3 of @aa:8)						4				_	_	_	_	_	—	8
BAND #xx:3, Rd	В	$C {\wedge} (\#xx{:}3 \text{ of } Rd8) \to C$		2								_	—	—	—	—	\updownarrow	2
BAND #xx:3, @Rd	В	$C {\wedge} (\#xx:3 \text{ of } @ Rd16) \to C$			4							_	—	_	_	_	\updownarrow	6
BAND #xx:3, @aa:8	В	$C {\scriptstyle \land} (\#xx:3 \text{ of } @aa:8) \rightarrow C$						4				—	—	—	—	_	\updownarrow	6
BIAND #xx:3, Rd	В	$C {\wedge} (\overline{\#xx:3} \ \overline{of} \ \overline{Rd8}) \to C$		2								_	—	—	—	—	\updownarrow	2
BIAND #xx:3, @Rd	В	$C {\wedge} (\overline{\#xx:3} \ \overline{of} \ \overline{@ Rd16}) \to C$			4							—	—	—	—	—	\updownarrow	6
BIAND #xx:3, @aa:8	В	$C {\wedge} (\overline{\#xx:3} \ \overline{of} \ \overline{@aa:8}) \to C$						4				—	—	_	_	—	\updownarrow	6
BOR #xx:3, Rd	В	$C{\scriptstyle\lor}(\text{\#xx:3 of Rd8})\rightarrow C$		2								_	_	_	_	—	\leftrightarrow	2
BOR #xx:3, @Rd	в	$C{\scriptstyle\lor}(\#xx{:}3\text{ of }@Rd16)\rightarrow C$			4							_	_	_	_	_	\updownarrow	6
BOR #xx:3, @aa:8	в	$C \lor (\#xx:3 \text{ of } @aa:8) \rightarrow C$						4				_	_	_	_	_	\updownarrow	6
BIOR #xx:3, Rd	в	$C{\scriptstyle\lor}(\overline{\#xx:3}\ \overline{of}\ \overline{Rd8})\rightarrow C$		2								_	_	_		—	\updownarrow	2
BIOR #xx:3, @Rd	в	$C {\scriptstyle \lor} (\overline{\#xx:3} \ \overline{of} \ \overline{@Rd16}) \rightarrow C$			4							—	_	_	_	—	\updownarrow	6

				In				sino Ler				s)							
	Operand Size		Branching	c: 8/16	Rn	۲n	@(d:16, Rn)	@-Rn/@Rn+	@aa: 8/16	@(d:8, PC)	@aa	Implied	С	one	ditio	on (Cod	le	. of States
Mnemonic	ő	Operation	Condition	:xx#	Rn	0	0	9	0	0	0	Ē	I	Н	Ν	z	v	С	Ň
BIOR #xx:3, @aa:8	В	C∨(#xx:3 of	$\overline{@aa:8}) \rightarrow C$						4				_	_	—	—	-	\updownarrow	6
BXOR #xx:3, Rd	В	C⊕(#xx:3 of	f Rd8) \rightarrow C		2								_	_	—	—	-	\updownarrow	2
BXOR #xx:3, @Rd	В	C⊕(#xx:3 of	f @Rd16) \rightarrow C			4							—	_	—	—	_	\updownarrow	6
BXOR #xx:3, @aa:8	в	C⊕(#xx:3 of	f @aa:8) \rightarrow C						4				—	_	—	—	_	\updownarrow	6
BIXOR #xx:3, Rd	В	C⊕(#xx:3 of	$\overline{f} \ \overline{Rd8}) \to C$		2								_	_	—	—	_	\updownarrow	2
BIXOR #xx:3, @Rd	В	C⊕(#xx:3 of	$\overline{f} \otimes Rd16) \rightarrow C$			4							_	_	—	—	-	\updownarrow	6
BIXOR #xx:3, @aa:8	В	C⊕(#xx:3 of	$\overline{f} @aa:8) \rightarrow C$						4				_	_	—	—	-	\updownarrow	6
BRA d:8 (BT d:8)	—	$PC \gets PC\text{+}c$	d:8							2			_	_	—	—	-	—	4
BRN d:8 (BF d:8)	_	$PC \leftarrow PC + 2$	2							2			_	_	_			_	4
BHI d:8	_	lf	$C \lor Z = 0$							2			_	_	_	_	—	_	4
BLS d:8	_	condition is true	C ∨ Z = 1							2			_	_	_	_	—	—	4
BCC d:8 (BHS d:8)	_	then	C = 0							2			_	_	_		-	_	4
BCS d:8 (BLO d:8)	_	PC ←	C = 1							2			_	_	_		-	_	4
BNE d:8	_	PC+d:8 else next;	Z = 0							2			_	_	_	_	—	_	4
BEQ d:8	_		Z = 1							2			_	_	_	_	—	—	4
BVC d:8	_		V = 0							2			_	_	_	_	—		4
BVS d:8	_		V = 1							2			_	_	_	_	—	_	4
BPL d:8	_		N = 0							2			_	_	_			_	4
BMI d:8	_		N = 1							2			_	_	_	_	—	—	4
BGE d:8	_		N⊕V = 0							2			_	_	_	_	—	—	4
BLT d:8	_		N⊕V = 1							2			_	_	_	_	—	_	4
BGT d:8	_		Z ∨ (N⊕V) = 0							2			_	_	_	_	—	_	4
BLE d:8	_		Z ∨ (N⊕V) = 1							2			_	_	_	_	—	—	4
JMP @Rn	_	$PC \leftarrow Rn16$	3			2							_	_	_	_	—	_	4
JMP @aa:16	_	$PC \leftarrow aa:16$	6						4				_				—	_	6
JMP @@aa:8	_	PC ← @aa	:8								2		_			_	—	_	8
BSR d:8		$\begin{array}{c} SP-2 \rightarrow SP \\ PC \rightarrow @SP \\ PC \leftarrow PC+c \end{array}$)							2								_	6

			In				sing Ler				s)							
Mnemonic	Operand Size	Operation	#xx: 8/16	Rn	@Rn	@(d:16, Rn)	@-Rn/@Rn+	@aa: 8/16	@(d:8, PC)	@ @aa	Implied	C	on	<u> </u>	on (Coc	le C	No. of States
JSR @Rn	—	$\begin{array}{c} SP-2 \rightarrow SP \\ PC \rightarrow @SP \\ PC \leftarrow Rn16 \end{array}$			2							_	_		_	-		6
JSR @aa:16	_	$\begin{array}{l} SP-2 \rightarrow SP \\ PC \rightarrow @SP \\ PC \leftarrow aa:16 \end{array}$						4							_	_		8
JSR @@aa:8		$\begin{array}{c} SP-2 \to SP \\ PC \to @ SP \\ PC \leftarrow @ aa:8 \end{array}$								2				_	_			8
RTS	_	$\begin{array}{l} PC \leftarrow @SP \\ SP+2 \rightarrow SP \end{array}$									2	—	_	—	—	-	-	8
RTE	_	$CCR \leftarrow @SP$ $SP+2 \rightarrow SP$ $PC \leftarrow @SP$ $SP+2 \rightarrow SP$									2	\$	\$	\$	\$	\$	\$	10
SLEEP		Transit to sleep mode.									2	_	_	_	_	—	—	2
LDC #xx:8, CCR	В	#xx:8 → CCR	2									\$	\$	\$	\$	\$	\$	2
LDC Rs, CCR	В	$Rs8 \rightarrow CCR$		2								\$	\$	\$	\$	\$	\$	2
STC CCR, Rd	В	$CCR \rightarrow Rd8$		2								_	—		_	—	—	2
ANDC #xx:8, CCR	В	$CCR_{\wedge}\#xx:8 \rightarrow CCR$	2									\$	\$	\$	\$	\updownarrow	\$	2
ORC #xx:8, CCR	В	$CCR \lor \#xx:8 \rightarrow CCR$	2									\$	\$	\$	\$	\$	\$	2
XORC #xx:8, CCR	В	$CCR \oplus \#xx: 8 \rightarrow CCR$	2									\$	\$	\$	\$	\$	\$	2
NOP	_	$PC \gets PC+2$									2	_	—		_	—	—	2
EEPMOV		if R4L \neq 0 Repeat @R5 \rightarrow @R6 R5+1 \rightarrow R5 R6+1 \rightarrow R6 R4L-1 \rightarrow R4L Until R4L=0 else next;									4							(4)

Notes: (1) Set to 1 when there is a carry or borrow from bit 11; otherwise cleared to 0.

- (2) If the result is zero, the previous value of the flag is retained; otherwise the flag is cleared to 0.
- (3) Set to 1 if decimal adjustment produces a carry; otherwise retains value prior to arithmetic operation.
- (4) The number of states required for execution is 4n + 9 in the H8/3827R Group and 4n + 8 in the H8/3827S Group, H8/38327 Group and H8/38427 Group (n = value of R4L).
- (5) Set to 1 if the divisor is negative; otherwise cleared to 0.
- (6) Set to 1 if the divisor is zero; otherwise cleared to 0.



A.2 Operation Code Map

Table A.2 is an operation code map. It shows the operation codes contained in the first byte of the instruction code (bits 15 to 8 of the first instruction word).



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	G			В			su								
ш	ADDX	SUBX		BGT	JSR		Bit-manipulation instructions								
۵	MOV	CMP		ВLТ			manipulatio								
U	MO	Ö		BGE		*NON	Bit-								
в	ADDS	SUBS		BMI		W	EEPMOV								
A	INC	DEC		BPL	AML										
6	ADD	SUB		BVS			MOV								
8	AC		MOV	BVC				ADD	ADDX	CMP	SUBX	OR	XOR	AND	MOV
7	LDC	NOT	Ň	BEQ		BST BIST	BLD	AI	AD	ō	SL	0	X	AI	ž
9	ANDC	AND		BNE	RTE		BIAND								
5	XORC	XOR		BCS	BSR		BXOR E BIXOR								
4	ORC	OR		BCC	RTS		BOR BIOR								
3	LDC	ROTXR		BLS		1010	מוס								
2		ROTXL		BHI			BCLK								
۲	e.	SHLR		BRN	DIVXU		BNUI								
0	٩	SHLL		BRA	MULXU	H L C	BOEL								
≥ /															

Note: * The PUSH and POP instructions are identical in machine language to MOV instructions.

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Table A.2 **Operation Code Map**

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ო 4 2

2

Low

High

0

DAA DAS

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A.3 Number of Execution States

The tables here can be used to calculate the number of states required for instruction execution. Table A.4 indicates the number of states required for each cycle (instruction fetch, read/write, etc.), and table A.3 indicates the number of cycles of each type occurring in each instruction. The total number of states required for execution of an instruction can be calculated from these two tables as follows:

Execution states = $I \times S_I + J \times S_J + K \times S_K + L \times S_L + M \times S_M + N \times S_N$

Examples: When instruction is fetched from on-chip ROM, and an on-chip RAM is accessed.

BSET #0, @FF00 From table A.4: I = L = 2, J = K = M = N = 0From table A.3: $S_I = 2$, $S_L = 2$ Number of states required for execution = $2 \times 2 + 2 \times 2 = 8$ When instruction is fetched from on-chip ROM, branch address is read from on-chip ROM, and on-chip RAM is used for stack area.

JSR @@ 30 From table A.4: I = 2, J = K = 1, L = M = N = 0From table A.3: $S_I = S_J = S_K = 2$ Number of states required for execution $= 2 \times 2 + 1 \times 2 + 1 \times 2 = 8$

Table A.3 Number of Cycles in Each Instruction

Execution Status			Access Location
(Instruction Cycle)		On-Chip Memory	On-Chip Peripheral Module
Instruction fetch	Sı	2	_
Branch address read	SJ		
Stack operation	Sĸ		
Byte data access	SL		2 or 3*
Word data access	S _M		_
Internal operation	S _N	1	
Note: * Depends on v	which on-cl	hin module is accessed	See section 2.9.1 Notes on Data

Note: * Depends on which on-chip module is accessed. See section 2.9.1, Notes on Data Access for details.

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Table A.4 Number of Cycles in Each Instruction

In a far	Maamaaia	Instruction Fetch	Addr. Read		Byte Data Access	Word Data Access	Internal Operation
Instruction	Mnemonic	1	J	К	L	М	N
ADD	ADD.B #xx:8, Rd	1					
	ADD.B Rs, Rd	1					
	ADD.W Rs, Rd	1					
ADDS	ADDS.W #1, Rd	1					
	ADDS.W #2, Rd	1					
ADDX	ADDX.B #xx:8, Rd	1					
	ADDX.B Rs, Rd	1					
AND	AND.B #xx:8, Rd	1					
	AND.B Rs, Rd	1					
ANDC	ANDC #xx:8, CCR	1					
BAND	BAND #xx:3, Rd	1					
	BAND #xx:3, @Rd	2			1		
	BAND #xx:3, @aa:8	2			1		
Bcc	BRA d:8 (BT d:8)	2					
	BRN d:8 (BF d:8)	2					
	BHI d:8	2					
	BLS d:8	2					
	BCC d:8 (BHS d:8)	2					
	BCS d:8 (BLO d:8)	2					
	BNE d:8	2					
	BEQ d:8	2					
	BVC d:8	2					
	BVS d:8	2					
	BPL d:8	2					
	BMI d:8	2					
	BGE d:8	2					
	BLT d:8	2					
	BGT d:8	2					
	BLE d:8	2					
BCLR	BCLR #xx:3, Rd	1					
	BCLR #xx:3, @Rd	2			2		
	BCLR #xx:3, @aa:8	2			2		
	BCLR Rn, Rd	1					
	BCLR Rn, @Rd	2			2		
	BCLR Rn, @aa:8	2			2		
BIAND	BIAND #xx:3, Rd	1					
2000	BIAND #xx:3, @Rd	2			1		
	BIAND #xx:3, @aa:8	2			1		

Instruction	Mnemonic	Instruction Fetch I	Branch Addr. Read J	Stack Operation K	Byte Data Access L	Word Data Access M	Internal Operation N
BILD	BILD #xx:3, Rd	1	-		-		
DIED	BILD #xx:3, @Rd	2			1		
	BILD #xx:3, @aa:8	2			1		
BIOR	BIOR #xx:3, Rd	1			1		
BIOK	BIOR #xx:3, @Rd	2			1		
	BIOR #xx:3, @aa:8	2			1		
BIST	BIST #xx:3, Rd	1			1		
DIGT	BIST #xx:3, @Rd	2			2		
	BIST #xx:3, @aa:8	2			2		
BIXOR	BIXOR #xx:3, Rd	1			2		
BIXOR	BIXOR #xx:3, @Rd	2			1		
	BIXOR #xx:3, @Rd BIXOR #xx:3, @aa:8	2			1		
BLD	BLD #xx:3, Rd	1			1		
DLD	BLD #xx:3, @Rd	2			1		
	BLD #xx:3, @aa:8	2			1		
BNOT	BNOT #xx:3, Rd	1			1		
DINOT	BNOT #xx:3, @Rd	2			2		
	BNOT #xx:3, @aa:8	2			2		
	BNOT Rn, Rd	1			2		
	BNOT Rn, @Rd	2			2		
	BNOT Rn, @aa:8	2			2		
BOR	BOR #xx:3, Rd	1			2		
Don	BOR #xx:3, @Rd	2			1		
	BOR #xx:3, @aa:8	2			1		
BSET	BSET #xx:3, Rd	1			•		
DOLI	BSET #xx:3, @Rd	2			2		
	BSET #xx:3, @aa:8	2			2		
	BSET Rn, Rd	1			-		
	BSET Rn, @Rd	2			2		
	BSET Rn, @aa:8	2			2		
BSR	BSR d:8	2		1	-		
BST	BST #xx:3, Rd	1					
-0.	BST #xx:3, @Rd	2			2		
	BST #xx:3, @aa:8	2			2		
BTST	BTST #xx:3, Rd	1			-		
2101	BTST #xx:3, @Rd	2			1		
	BTST #xx:3, @aa:8	2			1		
	BTST Rn, Rd	1					
	BTST Rn, @Rd	2			1		

Appendix A CPU Instruction Set

		Instruction Fetch	Addr. Read		Byte Data Access	Word Data Access	Internal Operation
Instruction	Mnemonic	I	J	К	L	Μ	N
BTST	BTST Rn, @aa:8	2			1		
BXOR	BXOR #xx:3, Rd	1					
	BXOR #xx:3, @Rd	2			1		
	BXOR #xx:3, @aa:8	2			1		
CMP	CMP. B #xx:8, Rd	1					
	CMP. B Rs, Rd	1					
	CMP.W Rs, Rd	1					
DAA	DAA.B Rd	1					
DAS	DAS.B Rd	1					
DEC	DEC.B Rd	1					
DIVXU	DIVXU.B Rs, Rd	1					12
EEPMOV	EEPMOV	2			2n+2 ^{*1}		1 ^{*2}
INC	INC.B Rd	1					
JMP	JMP @Rn	2					
	JMP @aa:16	2					2
	JMP @@aa:8	2	1				2
JSR	JSR @Rn	2		1			
	JSR @aa:16	2		1			2
	JSR @@aa:8	2	1	1			
LDC	LDC #xx:8, CCR	1					
	LDC Rs, CCR	1					
MOV	MOV.B #xx:8, Rd	1					
	MOV.B Rs, Rd	1					
	MOV.B @Rs, Rd	1			1		
	MOV.B @(d:16, Rs), Rd	2			1		
	MOV.B @Rs+, Rd	1			1		2
	MOV.B @aa:8, Rd	1			1		
	MOV.B @aa:16, Rd	2			1		
	MOV.B Rs, @Rd	1			1		
	MOV.B Rs, @(d:16, Rd)	2			1		
	MOV.B Rs, @-Rd	1			1		2
	MOV.B Rs, @aa:8	1			1		
	MOV.B Rs, @aa:16	2			1		
	MOV.W #xx:16, Rd	2					
	MOV.W Rs, Rd	1					
	MOV.W @Rs, Rd	1				1	
	MOV.W @(d:16, Rs), Rd	2				1	
	MOV.W @Rs+, Rd	1				1	2
	MOV.W @aa:16, Rd	2				1	

Instruction	Mnemonic	Instruction Fetch I	Branch Addr. Read J	Stack Operation K	Byte Data Access L	Word Data Access M	Internal Operation N
MOV	MOV.W Rs, @Rd	1				1	
	MOV.W Rs, @(d:16, Rd)	2				1	
	MOV.W Rs, @-Rd	1				1	2
	MOV.W Rs, @aa:16	2				1	
MULXU	MULXU.B Rs, Rd	1					12
NEG	NEG.B Rd	1					
NOP	NOP	1					
NOT	NOT.B Rd	1					
OR	OR.B #xx:8, Rd	1					
	OR.B Rs, Rd	1					
ORC	ORC #xx:8, CCR	1					
ROTL	ROTL.B Rd	1					
ROTR	ROTR.B Rd	1					
ROTXL	ROTXL.B Rd	1					
ROTXR	ROTXR.B Rd	1					
RTE	RTE	2		2			2
RTS	RTS	2		1			2
SHAL	SHAL.B Rd	1					
SHAR	SHAR.B Rd	1					
SHLL	SHLL.B Rd	1					
SHLR	SHLR.B Rd	1					
SLEEP	SLEEP	1					
STC	STC CCR, Rd	1					
SUB	SUB.B Rs, Rd	1					
	SUB.W Rs, Rd	1					
SUBS	SUBS.W #1, Rd	1					
	SUBS.W #2, Rd	1					
POP	POP Rd	1		1			2
PUSH	PUSH Rs	1		1			2
SUBX	SUBX.B #xx:8, Rd	1					
	SUBX.B Rs, Rd	1					
XOR	XOR.B #xx:8, Rd	1					
	XOR.B Rs, Rd	1					
XORC	XORC #xx:8, CCR	1					

Notes: 1. n: Initial value in R4L. The source and destination operands are accessed n + 1 times each.

2. 1 in the H8/3827R Group and 0 in the H8/3827S Group, H8/38327 Group, and H8/38427 Group.

Appendix B Internal I/O Registers

B.1 Addresses

Upper Address: H'F0

Lower	Register		Bit Names									
Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Module Name		
H'20	FLMCR1	—	SWE	ESU	PSU	EV	PV	E	Р	ROM		
H'21	FLMCR2	FLER	_	_	_	_	_	_	_	-		
H'22	FLPWCR	PDWND	_	_	_	_	_	_	_	-		
H'23	EBR	EB7	EB6	EB5	EB4	EB3	EB2	EB1	EB0	-		
H'24										=		
H'25										-		
H'26										-		
H'27										-		
H'28										-		
H'29										-		
H'2A										-		
H'2B	FENR	FLSHE	_	_	_	_	_	_	_	-		
H'2C										=		
H'2D										-		
H'2E										-		
H'2F										_		



Lower	Register	ster Bit Names								Module
Address		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Name
H'90	WEGR	WKEGS7	WKEGS6	WKEGS5	WKEGS4	WKEGS3	WKEGS2	WKEGS1	WKEGS0	System control
H'91	SPCR	_	_	SPC32	SPC31	SCINV3	SCINV2	SCINV1	SCINV0	SCI
H'92	CWOSR	_	_	_	_	_	_	_	CWOS	Timer A
H'93										
H'94										-
H'95	ECCSR	OVH	OVL	_	CH2	CUEH	CUEL	CRCH	CRCL	Asynchro-
H'96	ECH	ECH7	ECH6	ECH5	ECH4	ECH3	ECH2	ECH1	ECH0	 nous ever counter
H'97	ECL	ECL7	ECL6	ECL5	ECL4	ECL3	ECL2	ECL1	ECL0	
H'98	SMR31	COM31	CHR31	PE31	PM31	STOP31	MP31	CKS311	CKS310	SCI31
H'99	BRR31	BRR317	BRR316	BRR315	BRR314	BRR313	BRR312	BRR311	BRR310	-
H'9A	SCR31	TIE31	RIE31	TE31	RE31	MPIE31	TEIE31	CKE31	CKE310	=
H'9B	TDR31	TDR317	TDR316	TDR315	TDR314	TDR313	TDR312	TDR311	TDR310	-
H'9C	SSR31	TDRE31	RDRF31	OER31	FER31	PER31	TEND31	MPBR31	MPBT31	_
H'9D	RDR31	RDR317	RDR316	RDR315	RDR314	RDR313	RDR312	RDR311	RDR310	_
H'9E										_
H'9F										_
H'A0										
H'A1										_
H'A2										=
H'A3										_
H'A4										-
H'A5										_
H'A6										-
H'A7										-
H'A8	SMR32	COM32	CHR32	PE32	PM32	STOP32	MP32	CKS321	CKS320	SCI32
H'A9	BRR32	BRR327	BRR326	BRR325	BRR324	BR323	BRR322	BRR321	BRR320	-
H'AA	SCR32	TIE32	RIE32	TE32	RE32	MPIE32	TEIE32	CKE321	CKE320	-
H'AB	TDR32	TDR327	TDR326	TDR325	TDR324	TDR323	TDR322	TDR321	TDR320	-
H'AC	SSR32	TDRE32	RDRF32	OER32	FER32	PER32	TEND32	MPBR32	MPBT32	-
H'AD	RDR32	RDR327	RDR326	RDR325	RDR324	RDR323	RDR322	RDR321	RDR320	-
H'AE										-
H'AF										-
H'B0	TMA	TMA7	TMA6	TMA5	_	TMA3	TMA2	TMA1	TMA0	Timer A

Lower	Register	Bit Names										
Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Name		
H'B1	TCA	TCA7	TCA6	TCA5	TCA4	TCA3	TCA2	TCA1	TCA0	Timer A		
H'B2	TCSRW	B6WI	TCWE	B4WI	TCSRWE	B2WI	WDON	BOW1	WRST	Watchdog		
H'B3	TCW	TCW7	TCW6	TCW5	TCW4	TCW3	TCW2	TCW1	TCWO	timer		
H'B4	TMC	TMC7	TMC6	TMC5	_	_	TMC2	TMC1	TMC0	Timer C		
H'B5	TCC/TLC	TCC/ TLC7	TCC6/ TLC6	TCC5/ TLC5	TCC4/ TLC4	TCC3/ TLC3	TCC2/ TLC2	TCC1/ TLC1	TCC0/ TLC0	_		
H'B6	TCRF	TOLH	CKSH2	CKSH1	CKSH0	TOLL	CKSL2	CKSL1	CKSL0	Timer F		
H'B7	TCSRF	OVFH	CMFH	OVIEH	CCLRH	OVFL	CMFL	OVIEL	CCLRL	-		
H'B8	TCFH	TCFH7	TCFH6	TCFH5	TCFH4	TCFH3	TCFH2	TCFH1	TCFH0	-		
H'B9	TCFL	TCFL7	TCFL6	TCFL5	TCFL4	TCFL3	TCFL2	TCFL1	TCFL0	-		
H'BA	OCRFH	OCRFH7	OCRFH6	OCRFH5	OCRFH4	OCRFH3	OCRFH2	OCRFH1	OCRFH0	-		
H'BB	OCRFL	OCRFL7	OCRFL6	OCRFL5	OCRFL4	OCRFL3	OCRFL2	OCRFL1	OCRFL0	-		
H'BC	TMG	OVFH	OVFL	OVIE	IIEGS	CCLR1	CCLR0	CKS1	CKS0	Timer G		
H'BD	ICRGF	ICRGF7	ICRGF6	ICRGF5	ICRGF4	ICRGF3	ICRGF2	ICRGF1	ICRGFO	-		
H'BE	ICRGR	ICRGR7	ICRGR6	ICRGR5	ICRGR4	ICRGR3	ICRGR2	ICRGR1	ICRGRO	-		
H'BF										-		
H'C0	LPCR	DTS1	DTS0	CMX	SGX	SGS3	SGS2	SGS1	SGS0	LCD		
H'C1	LCR	_	PSW	ACT	DISP	CKS3	CKS2	CKS1	CKS0	controller		
H'C2	LCR2	LCDAB	_	_	_	CDS3	CDS2	CDS1	CDS0	driver		
H'C3										-		
H'C4	ADRRH	ADR9	ADR8	ADR7	ADR6	ADR5	ADR4	ADR3	ADR2	A/D		
H'C5	ADRRL	ADR1	ADR0	_	_	_	_		_	converter		
H'C6	AMR	CKS	TRGE	_	_	CH3	CH2	CH1	CH0	-		
H'C7	ADSR	ADSF	_	_	_	_	_	_	_	-		
H'C8	PMR1	IRQ3	IRQ2	IRQ1	IRQ4	TMIG	TMOFH	TMOFL	TMOW	I/O port		
H'C9	PMR2	EXCL	_	_	_	_	_	_	_	=		
H'CA	PMR3	AEVL	AEVH	WDCKS	NCS	IRQ0	RESO	UD	PWM	=		
H'CB										-		
H'CC	PMR5	WKP7	WKP6	WKP5	WKP4	WKP3	WKP2	WKP1	WKP0	=		
H'CD										-		
H'CE										-		
H'CF										-		
H'D0	PWCR	_	_	_	_	_	_	PWCR1	PWCR0	Bit 14		
H'D1	PWDRU	_	_	PWDRU5	PWDRU4	PWDRU3	PWDRU2	PWDRU1	PWDRU0	PWM		
H'D2	PWDRL	PWDRL7	PWDRL6	PWDRL5	PWDRL4	PWDRL3	PWDRL2	PWDRL1	PWDRL0	-		
H'D3												
H'D4	PDR1	P17	P16	P15	P14	P13	P12	P11	P10	I/O Port		

Lower	Register	Bit Names									
Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Name	
H'D5										I/O Por	
H'D6	PDR3	P37	P36	P35	P34	P33	P32	P31	P30	_	
H'D7	PDR4	—	—		—	P43	P42	P41	P40	_	
H'D8	PDR5	P57	P56	P55	P54	P53	P52	P51	P50		
H'D9	PDR6	P67	P66	P65	P64	P63	P62	P61	P60		
H'DA	PDR7	P77	P76	P75	P74	P73	P72	P71	P70		
H'DB	PDR8	P87	P86	P85	P84	P83	P82	P81	P80		
H'DC											
H'DD	PDRA	_	_		_	PA3	PA2	PA1	PA0	_	
H'DE	PDRB	PB7	PB6	PB5	PB4	PB3	PB2	PB1	PB0	-	
H'DF											
H'E0	PUCR1	PUCR17	PUCR16	PUCR15	PUCR14	PUCR13	PUCR12	PUCR11	PUCR10	I/O Por	
H'E1	PUCR3	PUCR37	PUCR36	PUCR35	PUCR34	PUCR33	PUCR32	PUCR31	PUCR30	-	
H'E2	PUCR5	PUCR57	PUCR56	PUCR55	PUCR54	PUCR53	PUCR52	PUCR51	PUCR50		
H'E3	PUCR6	PUCR67	PUCR66	PUCR65	PUCR64	PUCR63	PUCR62	PUCR61	PUCR60	_	
H'E4	PCR1	PCR17	PCR16	PCR15	PCR14	PCR13	PCR12	PCR11	PCR10	-	
H'E5										-	
H'E6	PCR3	PCR37	PCR36	PCR35	PCR34	PCR33	PCR32	PCR31	PCR30	_	
H'E7	PCR4	_	_	_	_	_	PCR42	PCR41	PCR40	-	
H'E8	PCR5	PCR57	PCR56	PCR55	PCR54	PCR53	PCR52	PCR51	PCR50	-	
H'E9	PCR6	PCR67	PCR66	PCR65	PCR64	PCR63	PCR62	PCR61	PCR60	_	
H'EA	PCR7	PCR77	PCR76	PCR75	PCR74	PCR73	PCR72	PCR71	PCR70	-	
H'EB	PCR8	PCR87	PCR86	PCR85	PCR84	PCR83	PCR82	PCR81	PCR80	-	
H'EC										-	
H'ED	PCRA	_	_	_	_	PCRA3	PCRA2	PCRA1	PCRA0		
H'EE										-	
H'EF											
H'F0	SYSCR1	SSBY	STS2	STS1	STS0	LSON	_	MA1	MA0	System	
H'F1	SYSCR2	—	_	_	NESEL	DTON	MSON	SA1	SA0	control	
H'F2	IEGR	_	_		IEG4	IEG3	IEG2	IEG1	IEG0		
H'F3	IENR1	IENTA	_	IENWP	IEN4	IEN3	IEN2	IEN1	IEN0	-	
H'F4	IENR2	IENDT	IENAD	_	IENTG	IENTFH	IENTFL	IENTC	IENEC	-	
H'F5										-	
H'F6	IRR1	IRRTA	_	_	IRRI4	IRRI3	IRRI2	IRRI1	IRRI0	-	
H'F7	IRRI2	IRRDT	IRRAD	_	IRRTG	IRRTFH	IRRTFL	IRRTC	IRREC	_	
H'F8										_	

Lower	Register Bit Names										
Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Name	
H'F9	IWPR	IWPF7	IWPF6	IWPF5	IWPF4	IWPF3	IWPF2	IWPF1	IWPF0	System	
H'FA	CKSTPR1	_	S31CKST P	S32CKST P	ADCKSTP	TGCKSTP	TFCKSTP	TCCKSTP	TACKSTP	control	
H'FB	CKSTPR2	_	_	_	_	AECKSTP	WDCKST P	PWCKSTP	LDCKSTP	-	
H'FC											
H'FD											
H'FE											
H'FF											

Legend:

SCI: Serial Communication Interface



B.2 Functions



*: Don't care

FLMCR1—Flash Memory Control Register 1





1 Writing/erasing enabled







FLPWCR—Fla	ash Memo	ry Power	Register	H']	F022	Flash Memory		
Bit	7	6	5	4	3	2	1	0
	PDWND		_			_	_	_
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	—	—	—	—	—	—	—
	Power-	down Dis	sable					
		ien the sy flash mei						
		,	stem trans mory chan	· · ·				

EBR—Erase B	lock Regi	ister			H	F023	F	Flash Memory			
Bit	7	6	5	4	3	2	1	0	_		
	EB7	EB6	EB5	EB4	EB3	EB2	EB1	EB0			
Initial value	0	0	0	0	0	0	0	0	,		
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W			
			Blocks 7 0 When	to 0 a block of	EB7 to El	B0 is not s	elected (ii	nitial value	:)		
			1 When	a block of	EB7 to El	B0 is seleo	cted				
Note: Set the bit of EBR to H'00 when erasing.											
FENR Flash M	lemory E	nable Reg	gister	H'	F02B	F	ash Mem	ory			

Bit	7	6	5	4	3	2	1	0				
	FLSHE	—		—		—		_				
Initial value	0	0	0	0	0	0	0	0				
Read/Write	R/W Flash I	 Memory C	 Control Re	 gister En	able	_	—	_				
	0 The flash memory control register cannot be accessed											
	1 Th	e flash me	emory cont	trol registe	r can be a	accessed						



WEGR—Wake	up Edge S	Select Reg		Н'9	0	Sys	System control	
Bit	7	6	5	4	3	2	1	0
	WKEGS7	WKEGS6	WKEGS5	WKEGS4	WKEGS3	WKEGS2	WKEGS1	WKEGS0
Initial value	0	0	0	0	0	0		
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
		WK	Pn edge sel	ected				
		0	falling edge			_		
		1	rising edge	detected				
					(n = 0 to	7)		



P42/TXD32pin function switch

0	Function as P4 ₂ I/O pin
1	Function as TXD ₃₂ output pin



ECCSR—Event Counter Control/Status Register



AEC



1 ECH has overflowed

Note: * Only a write of 0 for flag clearing is possible.



ECH—Event C	ounter H				AEC				
Bit	7	6	5	4	3	2	1	0	_
	ECH7	ECH6	ECH5	ECH4	ECH3	ECH2	ECH1	ECH0	
Initial value	0	0	0	0	0	0	0	0	
Read/Write	R	R	R	R	R	R	R	R	
Count value									

Note: ECH and ECL can also be used as the upper and lower halves, respectively, of a 16-bit event counter (EC).

ECL—Event C		AEC							
Bit	7	6	5	4	3	2	1	0	_
	ECL7	ECL6	ECL5	ECL4	ECL3	ECL2	ECL1	ECL0	
Initial value	0	0	0	0	0	0	0	0	_
Read/Write	R	R	R	R	R	R	R	R	
				Count	t value				

Note: ECH and ECL can also be used as the upper and lower halves, respectively, of a 16-bit event counter (EC).



- 0 Asynchronous mode
- 1 Synchronous mode

BRR31—Bit Ra	ate Regist	er31			Н'99				
Bit	7	6	5	4	3	2	1	0	-
	BRR317	BRR316	BRR315	BRR314	BRR313	BRR312	BRR311	BRR310	
Initial value	1	1	1	1	1	1	1	1	
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	
Serial transmit/receive bit rate									

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CR31—Serial Control Register 31						1	Н'9А				
Bit			7	6	6	5	4	3	2	1	0
			TIE31	RIE	31	TE31	RE31	MPIE31	TEIE31	CKE311	CKE310
Initial v	/alue	l	0	()	0	0	0	0	0	0
Read/\	Nrite		R/W	R/	W	R/W	R/W	R/W	R/W	R/W	R/W
			Clock e	enable -							
			Bit 1	Bit 0				Description			
			CKE311	CKE310	Cor	nmunication	Mode	Clock Source	SCK3	Pin Function	
			0	0	Asynchronous					ort	
						chronous		Internal clock		clock output output	
			0	1		nchronous		Internal clock Reserved (Do	20)		
			1	0	Asynchronous Synchronous Asynchronous			External clock	Clock		511)
								External clock Serial clock input			
			1	1				Reserved (Do not specify this combination)			
					Syr	chronous		Reserved (Do	not specify th	nis combinatio	on)
				smit end smit end	interro interro	upt request (upt request (1				
		0	Multiproo [Clearing When da	cessor in condition ata is rec	terrup n] eived	t request disa in which the	multiproces	nal receive ope ssor bit is set to	,		
	1 Multiprocessor interrupt request enabled The receive interrupt request (RXI), receive error interrupt request (ERI), and setting of the RDRF, FER, and OER flags in the serial status register (SSR), are disabled until data with the multiprocessor bit set to 1 is received.										
	Re	ceiv	e enable								
	0	F	Receive ope	eration di	sable	d (RXD pin is	s I/O port)				
	1	F	Receive ope	eration er	nableo	I (RXD pin is	receive da	ta pin)			
]	Fransm	nit e	nable								
	0 T	rans	smit operati	ion disab	led (T	XD pin is trai	nsmit data	pin)			
	1 T	rans	smit operati	on enab	ed (T	XD pin is trar	nsmit data j	oin)			
Rec	eive in	nterr	upt enable	•							
0	Rece	eive	data full int	errupt re	quest	(RXI) and re	ceive error	interrupt requ	est (ERI) disa	abled	
1	Rece	eive	data full int	errupt re	quest	(RXI) and re	ceive error	interrupt requ	est (ERI) ena	bled	
			ot enable								
0 T	ransmi	it da	ta empty in	terrupt re	quest	(TXI) disable	ed				

1 Transmit data empty interrupt request (TXI) enabled

TDR31—Trans	mit Data	Register 3	31		SCI31				
Bit	7	6	5	4	3	2	1	0	
	TDR317	TDR316	TDR315	TDR314	TDR313	TDR312	TDR311	TDR310	
Initial value	1	1	1	1	1	1	1	1	J
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	

Data for transfer to TSR



Note: * Only a write of 0 for flag clearing is possible.



RDR31—Recei	ve Data R	egister 31			H'9D				
Bit	7	6	5	4	3	2	1	0	_
	RDR317	RDR316	RDR315	RDR314	RDR313	RDR312	RDR311	RDR310	
Initial value	0	0	0	0	0	0	0	0	
Read/Write	R	R	R	R	R	R	R	R	
Serial receiving data are stored									

SMR32—Serial Mode Register 32





1 Synchronous mode
BRR32—Bit R	ate Regist	er 32			SCI32				
Bit	7	6	5	4	3	2	1	0	_
	BRR327	BRR326	BRR325	BRR324	BRR323	BRR322	BRR321	BRR3120	
Initial value	1	1	1	1	1	1	1	1	
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	
			• ·		, . <u>.</u>				

Serial transmit/receive bit rate

Bit

SCR32—Serial Control Register 32

7

TIE32

Transmit data empty interrupt request (TXI) disabled Transmit data empty interrupt request (TXI) enabled

Transmit interrupt enable

0

1

Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/\	N R/W	R/W	R/W	R/W	R/W	R/W
]							
	Clock	enable –						
	Bit 1	Bit 0		[Description			
		1 CKE320	Communication		ock Source	SCK3	Pin Function	
	0	0	Asynchronous Synchronous	In	ternal clock ternal clock	I/O po		
	0	1	Asynchronous	In	ternal clock	Clock	output	_
	1	0	Synchronous Asynchronous	E	eserved (Do r xternal clock	Clock	input	on)
		1	Synchronous Asynchronous		xternal clock eserved (Do r		clock input	n)
			Synchronous	R	eserved (Do r	not specify th	nis combinatio	n)
			rupt enable	FEI) disabled				
			interrupt request (,				
	Multiprocess			,				
	Clearin	a conditio	errupt request disa n] eived in which the r			,		
	1 Multipro The rece RDRF, F	cessor int eive interr FER, and	errupt request ena upt request (RXI), OER flags in the s r bit set to 1 is reco	bled receive error erial status re	interrupt requ	ıest (ERI), a		
Rec	eive enable							
0	Receive op	eration dis	sabled (RXD pin is	I/O port)				
1	Receive op	eration en	abled (RXD pin is	receive data	pin)			
Transm	it enable							
0 T	ransmit operat	ion disabl	ed (TXD pin is trar	nsmit data pir	ו)			
1 T	ransmit operat	ion enable	ed (TXD pin is trar	ismit data pin)			
Receive in	terrupt enable	9						
0 Rece	eive data full in	terrupt red	quest (RXI) and re	ceive error in	terrupt reque	st (ERI) disa	abled	
1 Rece	eive data full in	terrupt red	quest (RXI) and re	ceive error in	terrupt reque	st (ERI) ena	bled	

5

TE32

6

RIE32

4

3

H'AA 2

RE32 MPIE32 TEIE32 CKE321 CKE320

0

1

TDR32—Trans	TDR32—Transmit Data Register 32				H'AB				
Bit	7	6	5	4	3	2	1	0	_
	TDR327	TDR326	TDR325	TDR324	TDR323	TDR322	TDR321	TDR320	
Initial value	1	1	1	1	1	1	1	1	J
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	

Data for transfer to TSR



Note: * Only a write of 0 for flag clearing is possible.



RDR32—Recei	ve Data R	egister 32	2		H'AD				SCI32	
Bit	7	6	5	4	3	2	1	0		
	RDR327	RDR326	RDR325	RDR324	RDR323	RDR322	RDR321	RDR320	1	
Initial value	0	0	0	0	0	0	0	0		
Read/Write	R	R	R	R	R	R	R	R		
		Serial receiving data are stored								

TMA—Timer Mode Register A

H'B0

Bit	7	6	5	4	3	2	1	0
	TMA7	TMA6	TMA5	—	ТМАЗ	TMA2	TMA1	TMA0
Initial value	0	0	0	1	0	0	0	0
Read/Write	R/W	R/W	R/W	_	R/W	R/W	R/W	R/W

Γ

TMA3	TMA2	TMA1	тмао	Prescaler a or Overflow	and Divider Ratio	Function
0	0	0	0	PSS	φ/8192	Interval
			1	PSS	ф/4096	timer
		1	0	PSS	ф/2048	-
			1	PSS	ф/512	-
	1	0	0	PSS	ф/256	
			1	PSS	ф/128	
		1	0	PSS	ф/32	
			1	PSS	ф/8	
1	0	0	0	PSW	1 s	Time
			1	PSW	0.5 s	base
		1	0	PSW	0.25 s	(when using
			1	PSW	0.03125 s	32.768 kHz)
	1	0	0	PSW and T	CA are reset	
			1			
		1	0			
			1			

Clock output select*

0	0	0	ф/32				
		1	ф/16				
	1	0	ф/8				
		1	ф/4				
1	0	0	φ _W /32				
		1	φ _W /16				
	1	0	φ _W /8				
		1	φ _W /4				
			/ I I				

Note: * Values when the CWOS bit in CWOSR is cleared to 0. When the CWOS bit is set to 1, ϕ_W is output regardless of the value of bits TMA7 to TMA5.

TCA—Timer C	Counter A				Timer A				
Bit	7	6	5	4	3	2	1	0	_
	TCA7	TCA6	TCA5	TCA4	TCA3	TCA2	TCA1	TCA0	
Initial value	0	0	0	0	0	0	0	0	-
Read/Write	R	R	R	R	R	R	R	R	
	Count value								





TCW—Timer	Counter '	W				H'I	33	Wat	Watchdog timer		
Bit	7	6	5	4		3	2	1	0		
	TCW7	TCW6	TCW5	TCW4	Т	CW3	TCW2	TCW1	TCW0		
Initial value	0	0	0	0		0	0	0	0		
Read/Write	R/W	R/W	R/W	R/W	F	R/W	R/W	R/W	R/W		
				Cou	 nt val	ue					
TMC—Timer I	Mode Reg	gister C				H'l	84		Timer (2	
Bit	7	6	5	4	:	3	2	1	0		
	TMC7	TMC6	TMC5	_	-	_	TMC2	TMC1	TMC0		
Initial value	0	0	0	1		1 (0	0		
Read/Write	R/W	R/W	R/W	—	-	_	R/W	R/W	R/W		
				Cloc	k se	ect					
				0	0 0	Inter	nal clock:	ф/8192			
					0 1		nal clock:				
					1 0		nal clock:	•			
					1 1 0 0		nal clock: nal clock:				
					0 0		nal clock:				
					1 0		nal clock:	1			
	$\begin{array}{c c c c c c c c c c c c c c c c c c c $							Counting			
	с	ounter up/	/down co	ntrol							
			is an up-								
	() 1 TCC	is a dowr	n-counter							
		UDp	oin input h	trol of TC high: Down ow: Up-co	n-cou	nter	operation	by UD pir	n input		

Auto-reload function select

- 0 Interval timer function selected
- 1 Auto-reload function selected

* : Don't care

TCC—Timer Counter C					H'B5				
7	6	5	4	3	2	1	0	_	
TCC7	TCC6	TCC5	TCC4	тссз	TCC2	TCC1	тссо		
0	0	0	0	0	0	0	0	_	
R	R	R	R	R	R	R	R		
			Count	t value					
	7 TCC7 0	7 6 TCC7 TCC6 0 0	7 6 5 TCC7 TCC6 TCC5 0 0 0	7 6 5 4 TCC7 TCC6 TCC5 TCC4 0 0 0 0 R R R R	7 6 5 4 3 TCC7 TCC6 TCC5 TCC4 TCC3 0 0 0 0 0	7 6 5 4 3 2 TCC7 TCC6 TCC5 TCC4 TCC3 TCC2 0 0 0 0 0 0 0 R R R R R R R	7 6 5 4 3 2 1 TCC7 TCC6 TCC5 TCC4 TCC3 TCC2 TCC1 0 0 0 0 0 0 0 0 R R R R R R R	7 6 5 4 3 2 1 0 TCC7 TCC6 TCC5 TCC4 TCC3 TCC2 TCC1 TCC0 0 0 0 0 0 0 0 0 0 R R R R R R R R	

Note: TCC is assigned to the same address as TLC. In a read, the TCC value is read.

TLC—Timer I	load Regis	ster C				Timer	С		
Bit	7	6	5	4	3	2	1	0	
	TLC7	TLC6	TLC5	TLC4	TLC3	TLC2	TLC1	TLC0	
Initial value	0	0	0	0	0	0	0	0	
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	
				Reloa	d value				

Note: TLC is assigned to the same address as TCC. In a write, the TLC value is written.









Bit	7	6	5	4	3	2	1	0
	OVFH	CMFH	OVIEH	CCLRH	OVFL	CMFL	OVIEL	CCLRL
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/(W)*	R/(W)*	R/W	R/W	R/(W)*	R/(W)*	R/W	R/W
Read/Write	R/(W)*	R/(W)* Counter cl 0 TCF 1 TCFL ov 0 TCFL ov 1 TCFL	R/W ear L L clearing by cr L clearing by cr interrupt enaterrupt erflow interrupt erflow interrupt ag L ndition] g CMFL = 1, clearer dition] vFL = 1, clearer overflows from learing by comp learing by comp learing by comp learing by comp	R/W ompare match is ompare match is on the theorem is disat request is enable eared by writing natches the OC ad by writing 0 to h H'FF to H'00 pare match is di pare match is di pare match is er pare match is er	R/(W)* R/(W) s disabled disabled oto CMFL oto CMFL oto CMFL sabled sabled sabled sabled	-	-	-
	1 TCFH ov	verflow interrup	t request is ena	bled				
Com	pare match fla	ag H						
0	[Clearing con After reading	ndition] g CMFH = 1, cle	eared by writing	0 to CMFH				
1	[Setting cond Set when the	dition] e TCFH value r	natches the OC	RFH value				
Timer o	verflow flag H							
	Clearing condit	ion] /FH = 1, cleare	d by writing 0 t	o OVFH				
	Setting condition Set when TCFH	on] I overflows from	H'FF to H'00					
Note: * B	Bits 7, 6, 3, and	2 can only be v	ritten with 0, fo	or flag clearing.				



TCFH—8-Bit T	Timer Cou	inter FH			Timer	·F			
Bit	7	6	5	4	3	2	1	0	
	TCFH7	TCFH6	TCFH5	TCFH4	TCFH3	TCFH2	TCFH1	TCFH0	
Initial value	0	0	0	0	0	0	0	0	
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	
				Count	t value				

Note: TCFH and TCFL can also be used as the upper and lower halves, respectively, of a 16-bit event counter (TCF).

TCFL—8-Bit	Fimer Cou	nter FL			Timer			
Bit	7	6	5	4	3	2	1	0
	TCFL7	TCFL6	TCFL5	TCFL4	TCFL3	TCFL2	TCFL1	TCFL0
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
				Coun	t value			

Note: TCFH and TCFL can also be used as the upper and lower halves, respectively, of a 16-bit event counter (TCF).

OCRFH—Out	out Comp	are Regis	ter FH		H'E	BA		Timer	F
Bit	7	6	5	4	3	2	1	0	
	OCRFH7	OCRFH6	OCRFH5	OCRFH4	OCRFH3	OCRFH2	OCRFH1	OCRFH0	
Initial value	1	1	1	1	1	1	1	1	
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	

Note: ECH and ECL can also be used as the upper and lower halves, respectively, of a 16-bit output compare register (OCRF).

OCRFL—Out	out Compa	are Regist	er FL		H'BB				
Bit	7	6	5	4	3	2	1	0	
	OCRFL7	OCRFL6	OCRFL5	OCRFL4	OCRFL3	OCRFL2	OCRFL1	OCRFL0	
Initial value	1	1	1	1	1	1	1	1	
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	

Note: ECH and ECL can also be used as the upper and lower halves, respectively, of a 16-bit output compare register (OCRF).



TMG—Timer Mode Register G

H'BC

Timer G



0	[Clearing condition] After reading OVFH = 1, cleared by writing 0 to OVFH
1	[Setting condition] Set when TCG overflows from H'FF to H'00

Note: * Bits 7 and 6 can only be written with 0, for flag clearing.

ICRGF—Inpu	t Capture	Register	GF		H'BD				
Bit	7	6	5	4	3	2	1	0	
	ICRGF7	ICRGF6	ICRGF5	ICRGF4	ICRGF3	ICRGF2	ICRGF1	ICRGF0	
Initial value	0	0	0	0	0	0	0	0	
Read/Write	R	R	R	R	R	R	R	R	
ICRGR—Inpu	t Capture	Register	GR		Timer				
Bit	7	6	5	4	3	2	1	0	
2	ICRGR7	-		-	-	ICRGR2	ICRGR1		
Initial value	0	0	0	0	0	0	0	0	
Read/Write	R	R	R	R	R	R	R	R	

Stores TCG value at rising edge of input capture signal



LPCR—LCD Port Control Register

H'C0

LCD controller/driver

Bit	7	6	5	4	3	2	1	0
	DTS1	DTS0	CMX	SGX	SGS3	SGS2	SGS1	SGS0
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

Bit 4	Bit 3	Bit 2	Bit 1	Bit 0			F	unction of	Pins SEG ₃	32 to SEG1			
SGX	SGS3	SGS2	SGS1	SGS0	SEG ₃₂ to SEG ₂₉	SEG ₂₈ to SEG ₂₅	SEG ₂₄ to SEG ₂₁	SEG ₂₀ to SEG ₁₇	SEG ₁₆ to SEG ₁₃	SEG ₁₂ to SEG ₉	SEG ₈ to SEG₅	SEG ₄ to SEG ₁	Notes
0	0	0	0	0	Port	Port	Port	Port	Port	Port	Port	Port	(Initial val
	0	0	0	1	Port	Port	Port	Port	Port	Port	Port	Port	
	0	0	1	*	SEG	SEG	Port	Port	Port	Port	Port	Port	1
	0	1	0	*	SEG	SEG	SEG	SEG	Port	Port	Port	Port	1
	0	1	1	*	SEG	SEG	SEG	SEG	SEG	SEG	Port	Port	1
	1	*	*	*	SEG	SEG	SEG	SEG	SEG	SEG	SEG	SEG	1
1	0	0	0	0	Port*	Port	Port	Port	Port	Port	Port	Port	
	*	*	*	*			U	se prohibit	ed				

Bit 4	Description	
SGX	Description	
0	Pins SEG ₃₂ to SEG ₂₉ *	(Initial value)
1	Pins CL ₁ , CL ₂ , DO, M	

Note: * These pins function as ports when the setting of SGS3 to SGS0 is 0000 or 0001. In the case of the H8/38327 Group and H8/38427 Group the initial values of these bits must not be changed.

Duty select, common function select

Bit 7	Bit 6	Bit 5	Durte Curala	D. D.	Notes
DTS1	DTS0	CMX	Duty Cycle	Common Drivers	Notes
0	0	0	Static	COM ₁	
		1	Static	COM ₄ to COM ₁	COM ₄ to COM ₂ output the same waveform as COM ₁
0	1	0	1/2 duty	COM ₂ to COM ₁	
		1	1/2 duty	COM ₄ to COM ₁	COM_4 outputs the same waveform as COM_3 and COM_2 outputs the same waveform as COM_1
1	0	0	1/3 duty	COM ₃ to COM ₁	
		1	1/3 duty	COM ₄ to COM ₁	COM ₄ outputs a non-selected waveform
1	1	0	1/4 dutv	COM ₄ to COM ₁	_
		1	1/4 duty		

LCR—LCD Control Register

H'C1 LCD controller/driver

Bit	7	6	5	4	3		2	1		0
	_	PSW	ACT	DISP	СК	S3	CKS2	CK	S1 (CKS0
Initial value	1	0	0	0	0		0	0		0
Read/Write	_	R/W	R/W	R/W	R/\	N	R/W	R/\	N	R/W
					_		freque]
						Bit 3	Bit 2	Bit 1	Bit 0	Operating Clock
							CKS2		CKS0	
					-	0	*	0	0	¢w
					\vdash	0	*	0	1	φ _W /2 φ _W /4
					F	0	0	0	0	ψ _W /4 φ/2
					F	1	0	0	1	φ/2 φ/4
						1	0	1	0	φ/ 4 φ/8
					F	1	0	1	1	¢/16
						1	1	0	0	¢/32
					F	1	1	0	1	φ/64
						1	1	1	0	φ/128
						1	1	1	1	ф/256
				Display	data	contre	- I			* : Don't care
							splayed	1		
							is displ			
						Tuata		aycu		
			Display f	unction a	ctivate	е				
				controller/			tion hal	ted		
			1 LCD	controller/	driver	operat	tes			

LCD drive power supply on/off control

0	LCD drive power supply off
0	LOD drive neuron europhy off

1 LCD drive power supply on

LCD

H'C2

Bit 7 6 5 4 3 2 1 0 LCDAB CDS3 CDS2 CDS1 CDS0 ____ _ ____ Initial value 0 1 1 0 0 0 0 0 Read/Write R/W R/W R/W R/W R/W R/W ____ _ Charge/discharge pulse duty cycle select Bit 3 Bit 2 Bit 1 Bit 0 Duty Cycle CDS3 CDS2 CDS1 CDS0 0 0 0 0 1 0 0 0 1 1/8 0 0 1 0 2/8 0 0 1 1 3/8 0 1 0 0 4/8 0 1 0 1 5/8 0 1 1 0 6/8 0 1 0 1 1 * * 1/16 1 0 1 1 * * 1/32 * : Don't care A waveform/B waveform switching control Drive using A waveform 0 1 Drive using B waveform

LCR2—LCD Control Register 2

ADRRH—A/D ADRRL—A/D		0			H'C4 H'C5			A/D converter				
ADRRH												
Bit	7	6	5	4	3	2	1	0				
	ADR9	ADR8	ADR7	ADR6	ADR5	ADR4	ADR3	ADR2				
Initial value	Not fixed	Not fixed	Not fixed	Not fixed	Not fixed	Not fixed	Not fixed	Not fixed				
Read/Write	R	R	R	R	R	R	R	R				
		A/D conversion result										
ADRRL												
Bit	7	6	5	4	3	2	1	0				
	ADR1	ADR0		_	_		_	_				
Initial value	Not fixed	Not fixed	_	_	_							
Read/Write	R	R	—	—	—	—	—					
			.14									

A/D conversion result



AMR—A/D Mode Register H'C6 A/D converter Bit 7 6 3 2 5 4 1 0 CKS TRGE СНЗ CH2 CH1 CH0 Initial value 0 0 1 1 0 0 0 0 Read/Write R/W R/W R/W R/W R/W R/W **Channel select** Bit 3 Bit 2 Bit 1 Bit 0 CH3 Analog Input Channel CH2 CH1 CH0 0 0 * * No channel selected 1 0 0 AN₀ AN₁ 1 1 0 AN_2 1 AN_3 1 0 0 0 AN₄ AN₅ 1 1 0 AN_6 1 AN₇ Setting prohibited 1 1 * * * : Don't care External trigger select Disables start of A/D conversion by external trigger 0 1 Enables start of A/D conversion by rising or falling edge of external trigger at pin ADTRG

Clock select

Bit 7		Conversion Time				
CKS	Conversion Period	$\phi = 1 \text{ MHz}$	$\phi = 5 \text{ MHz}$			
0	62/ 	62 µs	12.4 µs			
1	31/ф	31 µs	—			

ADSR—A/D Sta	art Reg	gister				H'(C 7	A/D converter		
Bit	7		6	5	4	3	2	1	0	_
	ADSI	= _	_	_	_		_	_	_	
Initial value	0		1	1	1	1	1	1	1	-
Read/Write	R/W		_		—	—	—	—	—	
	A/C	status Read		ates comp	pletion of A	VD conve	rsion			
		Write		s A/D con						
	1	Read	Indic	ates A/D o	conversion	in progre	SS			
		Write	Star	ts A/D con	version					



PMR1—Port Mode Register 1

H'C8

I/O port



- 0 Functions as P1₇ I/O pin
- 1 Functions as IRQ₃/TMIF input pin



Note: The information on this register applies to the H8/38327 Group and H8/38427 Group.



PMR3—Port Mode Register 3

H'CA

I/O port



Note: * In the H8/38327 Group and H8/38427 Group this bit is reserved and cannot be written to.



Appendix B In	ternal I/O F	Registers						
PMR5—Port	Mode Regi	ster 5			H'O	CC		I/O port
Bit	7	6	5	4	3	2	1	0
	WKP ₇	WKP ₆	WKP ₅	WKP ₄	WKP ₃	WKP ₂	WKP ₁	WKP ₀
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
				P	∣ ₽5 _n /WKP _n /	/SEG _n +1 j	oin functi	on switch
						ns as P5 _n		
				1		ns as WK		in
							(n = 7	to 0)
PWCR—PWN	A Control	Register			H'I	D0		14-bit PWM
		0						
Bit	7	6	5	4	3	2	1	0
	—	—	—	—	—	—	PWCR1	PWCR0
Initial value	1	1	1	1	1	1	0	0
Read/Write	—	_	—	—	_	—	W	W
Cle	ock select							
0			$\frac{1}{2} (t\phi^* = 2)$					
			iod is 16,3 /4 (top* = 4/		a minimur	n modulat	ion width (of 1/ø
			iod is 32,7		a minimur	n modulat	ion width o	of 2/ø
1	The input	clock is ϕ	$/8 (t\phi^* = 8/$	/φ)				
			iod is 65,5		a minimur	n modulat	ion width o	of 4/ø
			$^{\prime}16 (t\phi^* = ^{\prime})$	1.7			بلامص ببادانه	of 0/h
	I ne conv	ersion per	iod is 131,	$072/\phi$, with	i a minimu	im modula	alion wiath	ι υι δ/φ

Note: * to: Period of PWM input clock

								U
PWDRU—PW	M Data R	egister U	ſ		H']	D1		14-bit PWM
Bit	7	6	5	4	3	2	1	0
	_		PWDRU5	PWDRU4	PWDRU	PWDRU2	PWDUR [,]	1PWDRU0
Initial value	1	1	0	0	0	0	0	0
Read/Write	_	_	W	W	W	W	W	W
			Uppe	r 6 bits of	data for g	enerating	PWM way	veform
PWDRL—PW	M Data R	egister L			H']	D2		14-bit PWM
Bit	7	6	5	4	3	2	1	0
	PWDRL7	PWDRL	6 PWDRL5	PWDRL4	PWDRL3	PWDRL2	PWDRL1	PWDRL0
Initial value	0	0	0	0	0	0	0	0
Read/Write	W	W	W	W	W	W	W	W
PDR1—Port D	ata Regist	er 1			H']	D4		I/O ports
Bit	7	6	5	4	3	2	1	0
DI	P1 ₇	P1 ₆	P1 ₅	P1 ₄	P1 ₃	P1 ₂	P11	P1 ₀
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W						
		1011	10,00	1011		1011	1011	
				Data for	port 1 pins	3		
PDR3—Port D	ata Regist	er 3			H']	D6		I/O ports
Bit	7	6	5	4	3	2	1	0
	P3 ₇	P3 ₆	P3 ₅	P3 ₄	P3 ₃	P32	P3 ₁	P3 ₀
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W						
				Data for p	port 3 pins	3		



PDR8—Port Da	ata Regist	er 8			H'I)B		I/O ports
Bit	7	6	5	4	3	2	1	0
	P87	P8 ₆	P8 ₅	P8 ₄	P8 ₃	P8 ₂	P8 ₁	P8 ₀
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W							
				Data for p	oort 8 pins			
PDRA—Port D	ata Regis	ter A			H'I	DD		I/O ports
Bit	7	6	5	4	3	2	1	0
				_	PA_3	PA ₂	PA ₁	PA ₀
Initial value	1	1	1	1	0	0	0	0
Read/Write	—	—	—	—	R/W	R/W	R/W	R/W
						Data for	port A pin	s
PDRB—Port D	ata Regist	ter B			H'I	DE		I/O ports
Bit	7	6	5	4	3	2	1	0
	PB ₇	PB_6	PB_5	PB ₄	PB_3	PB ₂	PB ₁	PB ₀
Read/Write	R	R	R	R	R	R	R	R
				Data for p	ort B pins			

PUCR1—Port	Pull-Up C	ontrol Re	gister 1		H'I	EO		I/O port
Bit	7	6	5	4	3	2	1	0
	PUCR17	PUCR1 ₆	PUCR15	PUCR1 ₄	PUCR1 ₃	PUCR12	PUCR11	PUCR10
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
				ull-up MO				
				IP MOS is				
				IP MOS is				
		Note:	when th	e PCRTS	pecificatio	n is u. (inp	out port sp	ecification)
PUCR3—Port	Pull-Up C	ontrol Re	gister 3		H'I	E1		I/O port
Bit	7	6	5	4	3	2	1	0
	PUCR37	PUCR3 ₆	PUCR35	PUCR3 ₄	PUCR3 ₃	PUCR3 ₂	PUCR3 ₁	PUCR30
Initial value	0	0	0	0	0	0	0	0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
		0 Ir 1 Ir	nput pull-u nput pull-u	III-up MO Ip MOS is Ip MOS is e PCR3 sp	off on	n is 0. (Inp	ut port spe	ecification)
PUCR5—Port	Pull-Up C	ontrol Re	gister 5		H'I	E 2		I/O port
Bit	7	6	5	4	3	2	1	0
Bit	7 PUCR5 ₇				3 PUCR5 ₃		1 PUCR5 ₁	
Bit Initial value				4 PUCR5 ₄ 0				
	PUCR57	PUCR5 ₆	PUCR5 ₅	PUCR5 ₄	PUCR53	PUCR5 ₂	PUCR51	PUCR50

I/O ports

H'E3

Bit	7	6	5	4	3	2	1	0		
	PUCR67		PUCR65		PUCR63		PUCR61	PUCR60		
Initial value	0	0	0	0	0	0	0	0		
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W		
		Port	6 input pu	III-up MO	S control					
		0 li	nput pull-u	p MOS is	off					
		1 li	nput pull-u	p MOS is	on					
		Note:	When the	e PCR6 sp	pecification	n is 0. (Inp	ut port spe	ecification)		
PCR1—Port Co	ontrol Reg	gister 1			H'H	24		I/O por		
Bit	7	6	5	4	3	2	1	0		
	PCR17	PCR1 ₆	PCR1 ₅	PCR1 ₄	PCR1 ₃	PCR1 ₂	PCR1 ₁	PCR10		
Initial value	0	0	0	0	0	0	0	0		
Read/Write	W	W	W	W	W	W	W	W		
				Б	ort 1 inpu	t/output s	alact			
						-				
				1	- · ·					
						<u>.</u>				
PCR3—Port Co	ontrol Reg	gister 3			H'H	26		I/O por		
Bit	7	6	5	4	3	2	1	0		
	PCR37	PCR3 ₆	PCR3 ₅	PCR3 ₄	PCR3 ₃	PCR3 ₂	PCR3 ₁	PCR30		
Initial value	0	0	0	0	0	0	0	0		
Read/Write	W	W	W	W	W	W	W	W		
				Р	ort 3 inpu	t/output s	elect			
		0 Input pin								
				() Input pi	n				

PUCR6—Port Pull-Up Control Register 6







0	 When a SLEEP instruction is executed in active mode, a transition is made to sleep mode 	
	• When a SLEEP instruction is executed in subactive mode, a transition is made to subsleep mode	
1	 When a SLEEP instruction is executed in active mode, a transition is made to standby mode or watch mode 	
	• When a SLEEP instruction is executed in subactive mode, a transition is made to watch mode	



Noise elimination sampling frequency select

0	Sampling rate is $\phi_{OSC}/16$	
1	Sampling rate is $\phi_{OSC}/4$	

Renesas



1 Rising edge of \overline{IRQ}_4 pin and \overline{ADTRG} pin is detected




System control







Direct transition interrupt enable

- 0 Disables direct transition interrupt requests
- 1 Enables direct transition interrupt requests



System control

H'F6

inter interrupt nequest negister i									
Bit	7	6	5	4	3	2	1	0	
	IRRTA		_	IRRI4	IRRI3	IRRI2	IRRI1	IRRI0	
Initial value	0	0	1	0	0	0	0	0	
Read/Write	R/(W)*	R/(W)*	_	R/(W)*	R/(W)*	R/(W)*	R/(W)*	R/(W)*	
			IF O	[Clearin	g conditio	n] it is cleare		g 0	
			1	When p		designate gnated sig	gnal edge i	s input	
								(n = 4 to 0))
Timer A interrupt request flag									

0	[Clearing condition] When IRRTA = 1, it is cleared by writing 0
1	[Setting condition] When the timer A counter value overflows (from H'FF to H'00)

Note: * Bits 7 and 4 to 0 can only be written with 0, for flag clearing.

IRR1—Interrupt Request Register 1

IRR2—Interrupt Request Register 2

Bit 7 6 5 4 3 2 1 0 IRRDT IRRAD IRRTG IRRTFH IRRTFL IRRTC IRREC Initial value 0 0 0 0 0 0 0 0 Read/Write R/(W)* R/(W)* R/W R/(W)* R/(W)* R/(W)* R/(W)* R/(W)* Asynchronous event counter interrupt request flag 0 [Clearing condition] When IRREC = 1, it is cleared by writing 0 [Setting condition] 1 When the asynchronous event counter value overflows Timer C interrupt request flag 0 [Clearing condition] When IRRTC = 1, it is cleared by writing 0 1 [Setting condition] When the timer C counter value overflows (from H'FF to H'00) or underflows (from H'00 to H'FF) Timer FL interrupt request flag [Clearing condition] 0 When IRRTFL = 1, it is cleared by writing 0 1 [Setting condition] When counter FL and output compare register FL match in 8-bit timer mode Timer FH interrupt request flag [Clearing condition] 0 When IRRTFH = 1, it is cleared by writing 0 [Setting condition] 1 When counter FH and output compare register FH match in 8-bit timer mode, or when 16-bit counters FL and FH and output compare registers FL and FH match in 16-bit timer mode Timer G interrupt request flag [Clearing condition] When IRRTG = 1, it is cleared by writing 0 0 1 [Setting condition] When the TMIG pin is designated for TMIG input and the designated signal edge is input A/D converter interrupt request flag 0 [Clearing condition] When IRRAD = 1, it is cleared by writing 0 [Setting condition] 1 When the A/D converter completes conversion and ADSF is reset Direct transition interrupt request flag [Clearing condition] When IRRDT = 1, it is cleared by writing 0 [Setting condition]

Note: * Bits 7, 6 and 4 to 0 can only be written with 0, for flag clearing.

When a SLEEP instruction is executed while DTON is

set to 1, and a direct transition is made

0

1



System control

H'F7

IWPR—Wakeup Interrupt Request Register

System control

7	6	5	4	3	2	1	0
IWPF7	IWPF6	IWPF5	IWPF4	IWPF3	IWPF2	IWPF1	IWPF0
0	0	0	0	0	0	0	0
R/(W)*							
	0	0 0	0 0 0				

Wakeup interrupt request register

0	[Clearing condition] When IWPFn = 1, it is cleared by writing 0
1	[Setting condition] When pin \overline{WKPn} is designated for wakeup input and a falling edge is input at that pin

(n = 7 to 0)

Note: * All bits can only be written with 0, for flag clearing.









Asynchronous event counter module standby mode control

0	Asynchronous event counter is set to module standby mode
---	--

1 Asynchronous event counter module standby mode is cleared

Appendix C I/O Port Block Diagrams

C.1 Block Diagrams of Port 1



Figure C.1 (a) Port 1 Block Diagram (Pins P1₇ to P1₄)



Figure C.1 (b) Port 1 Block Diagram (Pin P1₃)



Figure C.1 (c) Port 1 Block Diagram (Pin P1₂, P1₁)





Figure C.1 (d) Port 1 Block Diagram (Pin P1₀)

C.2 Block Diagrams of Port 3



Figure C.2 (a) Port 3 Block Diagram (Pin P37 to P36)





Figure C.2 (b) Port 3 Block Diagram (Pin P3₅)



Figure C.2 (c) Port 3 Block Diagram (Pin P3₄)



Figure C.2 (d) Port 3 Block Diagram (Pin P3₃)



Figure C.2 (e-1) Port 3 Block Diagram (Pin P3₂, H8/3827R Group and H8/3827S Group)





Figure C.2 (e-2) Port 3 Block Diagram (Pin P3₂ in the Mask ROM Version of the H8/38327 Group and H8/38427 Group)



Figure C.2 (e-3) Port 3 Block Diagram (Pin P3₂ in the F-ZTAT Version of the H8/38327 Group and H8/38427 Group)





Figure C.2 (f-1) Port 3 Block Diagram (Pin P3₁, H8/3827R Group and H8/3827S Group)



Figure C.2 (f-2) Port 3 Block Diagram (Pin P3₁, H8/38327 Group and H8/38427 Group)





Figure C.2 (g) Port 3 Block Diagram (Pin P3₀)

C.3 Block Diagrams of Port 4



Figure C.3 (a) Port 4 Block Diagram (Pin P4₃)





Figure C.3 (b) Port 4 Block Diagram (Pin P4₂)



Figure C.3 (c) Port 4 Block Diagram (Pin P4₁)



Figure C.3 (d) Port 4 Block Diagram (Pin P4₀)

C.4 Block Diagram of Port 5



Figure C.4 Port 5 Block Diagram



C.5 Block Diagram of Port 6



Figure C.5 Port 6 Block Diagram

C.6 Block Diagram of Port 7



Figure C.6 Port 7 Block Diagram



C.7 Block Diagrams of Port 8



Figure C.7 Port 8 Block Diagram

C.8 Block Diagram of Port A



Figure C.8 Port A Block Diagram



C.9 Block Diagram of Port B



Figure C.9 Port B Block Diagram



Appendix D Port States in the Different Processing States

Table D.1	Port States	Overview

Port	Reset	Sleep	Subsleep	Standby	Watch	Subactive	Active
P1 ₇ to P1 ₀	High impedance	Retained	Retained	High impedance ^{*1}	Retained	Functions	Functions
P3 ₇ to P3 ₀	High impedance ^{*2}	Retained	Retained	High impedance ^{*1}	Retained	Functions	Functions
P4 ₃ to P4 ₀	High impedance	Retained	Retained	High impedance	Retained	Functions	Functions
P5 ₇ to P5 ₀	High impedance	Retained	Retained	High impedance ^{*1}	Retained	Functions	Functions
P67 to P60	High impedance	Retained	Retained	High impedance	Retained	Functions	Functions
P7 ₇ to P7 ₀	High impedance	Retained	Retained	High impedance	Retained	Functions	Functions
P87 to P80	High impedance	Retained	Retained	High impedance	Retained	Functions	Functions
PA ₃ to PA ₀	High impedance	Retained	Retained	High impedance	Retained	Functions	Functions
PB ₇ to PB ₀	High impedance	High impedance	High impedance	High impedance	High impedance	High impedance	High impedance

Notes: 1. High level output when MOS pull-up is in on state.

 Reset output from P3₂ pin only (H8/3827R Group and H8/3827S Group). On-chip pull-up MOS turns on for pin P3₂ only (F-ZTAT Version of the H8/38327 Group and H8/38427 Group).

Appendix E List of Product Codes

Table E.1 H8/3827R Group, H8/3827S Group, and H8/38327 Group Product Code Lineup

Product Ty	/pe			Product Code	Mark Code	Package (Package Code)
H8/3827R	H8/3822R	Mask	Regular products	HD6433822RH	HD6433822R(***)H	80-pin QFP (FP-80A)
Group		ROM versions		HD6433822RF	HD6433822R(***)F	80-pin QFP (FP-80B)
		Versions		HD6433822RW	HD6433822R(***)W	80-pin TQFP (TFP-80C)
				HCD6433822R	_	Die
			Wide-range	HD6433822RD	HD6433822R(***)H	80-pin QFP (FP-80A)
			specification products	HD6433822RE	HD6433822R(***)F	80-pin QFP (FP-80B)
			products	HD6433822RWI	HD6433822R(***)W	80-pin TQFP (TFP-80C)
	H8/3823R	Mask	Regular	HD6433823RH	HD6433823R(***)H	80-pin QFP (FP-80A)
		ROM versions	products	HD6433823RF	HD6433823R(***)F	80-pin QFP (FP-80B)
		VC1310113		HD6433823RW	HD6433823R(***)W	80-pin TQFP (TFP-80C)
				HCD6433823R	_	Die
			Wide-range specification products	HD6433823RD	HD6433823R(***)H	80-pin QFP (FP-80A)
				HD6433823RE	HD6433823R(***)F	80-pin QFP (FP-80B)
				HD6433823RWI	HD6433823R(***)W	80-pin TQFP (TFP-80C)
	H8/3824R	Mask ROM versions	Regular	HD6433824RH	HD6433824R(***)H	80-pin QFP (FP-80A)
			products	HD6433824RF	HD6433824R(***)F	80-pin QFP (FP-80B)
				HD6433824RW	HD6433824R(***)W	80-pin TQFP (TFP-80C)
				HCD6433824R	_	Die
			Wide-range	HD6433824RD	HD6433824R(***)H	80-pin QFP (FP-80A)
			specification products	HD6433824RE	HD6433824R(***)F	80-pin QFP (FP-80B)
			producio	HD6433824RWI	HD6433824R(***)W	80-pin TQFP (TFP-80C)
	H8/3825R	Mask	Regular	HD6433825RH	HD6433825R(***)H	80-pin QFP (FP-80A)
		ROM versions	products	HD6433825RF	HD6433825R(***)F	80-pin QFP (FP-80B)
		Vereiene		HD6433825RW	HD6433825R(***)W	80-pin TQFP (TFP-80C)
				HCD6433825R	_	Die
			Wide-range	HD6433825RD	HD6433825R(***)H	80-pin QFP (FP-80A)
			specification products	HD6433825RE	HD6433825R(***)F	80-pin QFP (FP-80B)
			F. 000010	HD6433825RWI	HD6433825R(***)W	80-pin TQFP (TFP-80C)

Product Ty	/pe			Product Code	Mark Code	Package (Package Code)
H8/3827R Group	H8/3826R	Mask	Regular	HD6433826RH	HD6433826R(***)H	80-pin QFP (FP-80A)
Group		ROM versions	products	HD6433826RF	HD6433826R(***)F	80-pin QFP (FP-80B)
		Versions		HD6433826RW	HD6433826R(***)W	80-pin TQFP (TFP-80C)
				HCD6433826R	_	Die
			Wide-range	HD6433826RD	HD6433826R(***)H	80-pin QFP (FP-80A)
			specification products	HD6433826RE	HD6433826R(***)F	80-pin QFP (FP-80B)
			producto	HD6433826RWI	HD6433826R(***)W	80-pin TQFP (TFP-80C)
	H8/3827R	Mask	Regular	HD6433827RH	HD6433827R(***)H	80-pin QFP (FP-80A)
		ROM versions	products	HD6433827RF	HD6433827R(***)F	80-pin QFP (FP-80B)
		VC1310113		HD6433827RW	HD6433827R(***)W	80-pin TQFP (TFP-80C)
				HCD6433827R	_	Die
			Wide-range specification products	HD6433827RD	HD6433827R(***)H	80-pin QFP (FP-80A)
				HD6433827RE	HD6433827R(***)F	80-pin QFP (FP-80B)
				HD6433827RWI	HD6433827R(***)W	80-pin TQFP (TFP-80C)
		ZTAT versions	Regular products	HD6473827RH	HD6473827RH	80-pin QFP (FP-80A)
				HD6473827RF	HD6473827RF	80-pin QFP (FP-80B)
				HD6473827RW	HD6473827RW	80-pin TQFP (TFP-80C)
			Wide-range specification products	HD6473827RD	HD6473827RH	80-pin QFP (FP-80A)
				HD6473827RE	HD6473827RF	80-pin QFP (FP-80B)
				HD6473827RWI	HD6473827RW	80-pin TQFP (TFP-80C)
H8/3827S	H8/3824S			HD6433824SH	HD6433824S(***)H	80-pin QFP (FP-80A)
Group		ROM versions	products	HD6433824SW	HD6433824S(***)W	80-pin TQFP (TFP-80C)
		, el		HCD6433824S	_	Die
			Wide-range	HD6433824SD	HD6433824S(***)H	80-pin QFP (FP-80A)
			specification products	HD6433824SWI	HD6433824S(***)W	80-pin TQFP (TFP-80C)
	H8/3825S	Mask	Regular	HD6433825SH	HD6433825S(***)H	80-pin QFP (FP-80A)
		ROM versions	products	HD6433825SW	HD6433825S(***)W	80-pin TQFP (TFP-80C)
				HCD6433825S		Die
			Wide-range	HD6433825SD	HD6433825S(***)H	80-pin QFP (FP-80A)
			specification products	HD6433825SWI	HD6433825S(***)W	80-pin TQFP (TFP-80C)

Product Ty	/pe			Product Code	Mark Code	Package (Package Code)	
H8/3827S Group	H8/3826S	Mask	Regular	HD6433826SH	HD6433826S(***)H	80-pin QFP (FP-80A)	
Group		ROM versions	products	HD6433826SW	HD6433826S(***)W	80-pin TQFP (TFP-80C)	
		Versions		HCD6433826S	_	Die	
			Wide-range	HD6433826SD	HD6433826S(***)H	80-pin QFP (FP-80A)	
			specification products	HD6433826SWI	HD6433826S(***)W	80-pin TQFP (TFP-80C)	
	H8/3827S	Mask	Regular	HD6433827SH	HD6433827S(***)H	80-pin QFP (FP-80A)	
		ROM versions	products	HD6433827SW	HD6433827S(***)W	80-pin TQFP (TFP-80C)	
		Vereiene		HCD6433827S	_	Die	
			Wide-range	HD6433827SD	HD6433827S(***)H	80-pin QFP (FP-80A)	
			specification products	HD6433827SWI	HD6433827S(***)W	80-pin TQFP (TFP-80C)	
H8/38327	H8/38322	Mask	Regular	HD64338322H	38322H	80-pin QFP (FP-80A)	
Group		ROM versions	products	HD64338322W	38322W	80-pin TQFP (TFP-80C)	
				HCD64338322	—	Die	
			Wide-range specification products	HD64338322HW	38322H	80-pin QFP (FP-80A)	
				HD64338322WW	38322W	80-pin TQFP (TFP-80C)	
	H8/38323	Mask ROM versions	Regular products	HD64338323H	38323H	80-pin QFP (FP-80A)	
				HD64338323W	38323W	80-pin TQFP (TFP-80C)	
				HCD64338323	_	Die	
			Wide-range specification products	HD64338323HW	38323H	80-pin QFP (FP-80A)	
				HD64338323WW	38323W	80-pin TQFP (TFP-80C)	
	H8/38324	Mask	Regular	HD64338324H	38324H	80-pin QFP (FP-80A)	
		ROM versions	products	HD64338324W	38324W	80-pin TQFP (TFP-80C)	
				HCD64338324	—	Die	
			Wide-range	HD64338324HW	38324H	80-pin QFP (FP-80A)	
		_	specification products	HD64338324WW	38324W	80-pin TQFP (TFP-80C)	
		F-ZTAT	Regular	HD64F38324H	F38324H	80-pin QFP (FP-80A)	
		versions	products	HD64F38324W	F38324W	80-pin TQFP (TFP-80C)	
			Wide-range	HD64F38324HW	F38324H	80-pin QFP (FP-80A)	
			specification products	HD64F38324WW	F38324W	80-pin TQFP (TFP-80C)	

Product Ty	уре			Product Code	Mark Code	Package (Package Code)
H8/38327 Group	H8/38325	Mask	Regular	HD64338325H	38325H	80-pin QFP (FP-80A)
		ROM versions	products	HD64338325W	38325W	80-pin TQFP (TFP-80C)
		Versions		HCD64338325	_	Die
			Wide-range	HD64338325HW	38325H	80-pin QFP (FP-80A)
			specification products	HD64338325WW	38325W	80-pin TQFP (TFP-80C)
	H8/38326	Mask	Regular	HD64338326H	38326H	80-pin QFP (FP-80A)
		ROM versions	products	HD64338326W	38326W	80-pin TQFP (TFP-80C)
		Vereiene		HCD64338326	_	Die
			Wide-range	HD64338326HW	38326H	80-pin QFP (FP-80A)
			specification products	HD64338326WW	38326W	80-pin TQFP (TFP-80C)
	H8/38327	Mask	Regular	HD64338327H	38327H	80-pin QFP (FP-80A)
		ROM versions	products	HD64338327W	38327W	80-pin TQFP (TFP-80C)
				HCD64338327	_	Die
			Wide-range specification products	HD64338327HW	38327H	80-pin QFP (FP-80A)
				HD64338327WW	38327W	80-pin TQFP (TFP-80C)
		F-ZTAT versions	Regular products Wide-range specification products	HD64F38327H	F38327H	80-pin QFP (FP-80A)
				HD64F38327W	F38327W	80-pin TQFP (TFP-80C)
				HCD64F38327	_	Die
				HD64F38327HW	F38327H	80-pin QFP (FP-80A)
				HD64F38327WW	F38327W	80-pin TQFP (TFP-80C)
H8/38427	H8/38422	Mask	ROM products	HD64338422H	38422H	80-pin QFP (FP-80A)
Group		ROM versions		HD64338422W	38422W	80-pin TQFP (TFP-80C)
				HCD64338422	_	Die
			Wide-range	HD64338422HW	38422H	80-pin QFP (FP-80A)
			specification products	HD64338422WW	38422W	80-pin TQFP (TFP-80C)
	H8/38423	Mask	Regular	HD64338423H	38423H	80-pin QFP (FP-80A)
		ROM versions	products	HD64338423W	38423W	80-pin TQFP (TFP-80C)
				HCD64338423	_	Die
			Wide-range	HD64338423HW	38423H	80-pin QFP (FP-80A)
			specification products	HD64338423WW	38423W	80-pin TQFP (TFP-80C)
Product Type				Product Code	Mark Code	Package (Package Code)
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H8/38427 Group	H8/38424	Mask ROM versions	Regular products	HD64338424H	38424H	80-pin QFP (FP-80A)
				HD64338424W	38424W	80-pin TQFP (TFP-80C)
				HCD64338424	_	Die
			Wide-range specification products	HD64338424HW	38424H	80-pin QFP (FP-80A)
				HD64338424WW	38424W	80-pin TQFP (TFP-80C)
		F-ZTAT versions	Regular products	HD64F38424H	F38424H	80-pin QFP (FP-80A)
				HD64F38424W	F38424W	80-pin TQFP (TFP-80C)
			Wide-range specification products	HD64F38424HW	F38424H	80-pin QFP (FP-80A)
				HD64F38424WW	F38424W	80-pin TQFP (TFP-80C)
	H8/38425	Mask ROM versions	Regular products	HD64338425H	38425H	80-pin QFP (FP-80A)
				HD64338425W	38425W	80-pin TQFP (TFP-80C)
				HCD64338425	_	Die
			Wide-range specification products	HD64338425HW	38425H	80-pin QFP (FP-80A)
				HD64338425WW	38425W	80-pin TQFP (TFP-80C)
	H8/38426	Mask ROM versions	Regular products	HD64338426H	38426H	80-pin QFP (FP-80A)
				HD64338426W	38426W	80-pin TQFP (TFP-80C)
				HCD64338426	_	Die
			Wide-range specification products	HD64338426HW	38426H	80-pin QFP (FP-80A)
				HD64338426WW	38426W	80-pin TQFP (TFP-80C)
	H8/38427	Mask ROM versions	Regular products	HD64338427H	38427H	80-pin QFP (FP-80A)
				HD64338427W	38427W	80-pin TQFP (TFP-80C)
				HCD64338427	_	Die
			Wide-range specification products	HD64338427HW	38427H	80-pin QFP (FP-80A)
				HD64338427WW	38427W	80-pin TQFP (TFP-80C)
		F-ZTAT versions	Regular products	HD64F38427H	F38427H	80-pin QFP (FP-80A)
				HD64F38427W	F38427W	80-pin TQFP (TFP-80C)
				HCD64F38427	_	Die
			Wide-range specification products	HD64F38427HW	F38427H	80-pin QFP (FP-80A)
				HD64F38427WW	F38427W	80-pin TQFP (TFP-80C)

Note: For mask ROM versions, (***) is the ROM code.

Appendix F Package Dimensions

Dimensional drawings of H8/3827R Group, H8/3827S Group, H8/38327 Group, and H8/38427 Group packages FP-80A, FP-80B and TFP-80C are shown in figures F.1, F.2 (only H8/3827R Group) and F.3 below.



Figure F.1 FP-80A Package Dimensions



Figure F.2 FP-80B Package Dimensions



Figure F.3 TFP-80C Package Dimensions



Appendix G Specifications of Chip Form

The specifications of the chip form of the HCD6433827R, HCD6433826R, HCD6433825R, HCD6433824R, HCD6433823R, and HCD6433822R are shown in figure G.1.



Figure G.1 Chip Sectional Figure

The specifications of the chip form of the HCD6433827S, HCD6433826S, HCD6433825S, and HCD6433824S are shown in figure G.2.



Figure G.2 Chip Sectional Figure

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The specifications of the chip form of the HCD64F38327 and HCD64F38427 are shown in figure G.3.



Figure G.3 Chip Sectional Figure

The specifications of the chip form of the H8/38327 Group (mask ROM version) and H8/38427 Group (mask ROM version) are shown in figure G.4.



Figure G.4 Chip Sectional Figure

Appendix H Form of Bonding Pads

The form of the bonding pads for the HCD6433827R, HCD6433826R, HCD6433825R, HCD6433824R, HCD6433823R, and HCD6433822R is shown in figure H.1.



Figure H.1 Bonding Pad Form

The form of the bonding pads for the HCD6433827S, HCD6433826S, HCD6433825S, and HCD6433824S is shown in figure H.2.



Figure H.2 Bonding Pad Form



The form of the bonding pads for the HCD64F38327, HCD64F38427, H8/38327 Group (mask ROM version), and H8/38427 Group (mask ROM version) is shown in figure H.3.



Figure H.3 Bonding Pad Form

Appendix I Specifications of Chip Tray

The specifications of the chip tray for the HCD6433827R, HCD6433826R, HCD6433825R, HCD6433824R, HCD6433823R, and HCD6433822R is shown in figure I.1.





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The specifications of the chip tray for the HCD6433827S, HCD6433826S, HCD6433825S, and HCD6433824S is shown in figure I.2.



Figure I.2 Specifications of Chip Tray

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The specifications of the chip tray for the HCD64F38327 and HCD64F38427 is shown in figure I.3.





The specifications of the chip tray for the H8/38327 Group (mask ROM version) and H8/38427 Group (mask ROM version) is shown in figure I.4.







Renesas 8-Bit Single-Chip Microcomputer Hardware Manual H8/3827R Group, H8/3827S Group, H8/38327 Group, H8/38427 Group

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H8/3827R Group, H8/3827S Group, H8/38327 Group, H8/38427 Group Hardware Manual



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